Freescale Semiconductor

Advance Information

Ultra-Mobile Platform PMIC

The 900841 is a high-efficiency, Power Management Integrated Circuit (PMIC), capable of providing all operating voltages for ultramobile platforms through its 29 voltage rails. It has nine switching power supplies running at frequencies from 1.0 to 4.0 MHz,17 highly-efficient LDOs and three, 3.3 V power switches. It incorporates a switching mode Li-lon battery charger, advanced audio path, signaling and backlight LED drivers, 22-channel ADC, real time clock, 8 GPIO, 8 GPO, and 4 GPOSW for specific platform switches control.

The SC900841 is fully configurable and controllable through its SPI and Mini SPI interfaces. Along with companion chip SC900842, it provides an optimized power management solution for ultra-mobile platforms used on Mobile Internet Devices (MID), netbooks, tablets, slates, smart phones and other high-tech portable devices.

Optimum partitioning, high feature integration, and state-of-the-art technology allow Freescale to effectively serve this growing market segment.

Features

- Complete system power management, battery charging and audio support integrated in a single chip
- Advanced audio path
- Fully programmable DC/DC switching, low drop-out regulators, and load switches
- Power path management & switching mode Li-Ion/Li-Polymer battery charger
- · LCD backlight and system lighting support
- SPI interface (up to 25 MHz operation)
- 22-channel (32 capable) 10-bit ADC for internal and external sensing with touch screen interface
- Real time clock (RTC)
- 8 Interrupt capable GPIOs and 8 GPOs
- 4 GPOs for controlling platform switches
- I/O interrupt and reset controller

900841

POWER MANAGEMENT



ORDERING INFORMATION

Device	Temperature Range (T _A)	Package		
SC900841JVK/R2	-40°C to 85°C	338-MAPBGA		

Applications

- Mobile Internet Devices (MID)
- Tablet PC
- Netbooks



Figure 1. 900841 Simplified Application Diagram

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VRoHS

ELECTRICAL CHARACTERISTICS

MAXIMUM RATINGS

Table 1. Maximum Ratings

All voltages are with respect to ground, unless otherwise noted. Exceeding these ratings may cause malfunction or permanent damage to the device. The detailed maximum voltage rating per pin can be found in the pin list section.

Ratings	Symbol	Value	Unit
ELECTRICAL RATINGS			•
Charger Input Voltage	-	-0.3 to +20	V
LCD Backlight Circuitry Voltage	-	-0.3 to +28	V
Battery Voltage	-	-0.3 to +4.4	V
Coin Cell Voltage	-	-0.3 to +3.6	V
ESD Rating, All Pins, Human Body Model (HBM) ⁽³⁾	V _{ESDHBM}	±2000	V
ESD Rating, All Pins, Charge Device Model (CDM) ^{(3), (4)}	V _{ESDCDM}	±450	V

THERMAL RATINGS

Ambient Operating Temperature Range	T _A	-40 to +85	°C
Operating Junction Temperature Range	TJ	-30 to +125	°C
Storage Temperature Range	T _{ST}	-65 to +150	°C
Peak Package Reflow Temperature ^{(1), (2)}	T _{PPRT}	260	°C

Notes

1. Pin soldering temperature limit is for 10 seconds maximum duration. Not designed for immersion soldering. Exceeding these limits may cause a malfunction or permanent damage to the device.

- 2. Freescale's Package Reflow capability meets the Pb-free requirements for JEDEC standard J-STD-020C, for Peak Package Reflow Temperature and Moisture Sensitivity Levels (MSL)
- 3. ESD testing is performed in accordance with the Human Body Model (HBM) (CZAP = 100 pF, RZAP = 1500 Ω), and the Charge Device Model (CDM), Robotic (CZAP = 4.0 pF).
- 4. All pins meet 500 V CDM except VCOREREF.

POWER DISSIPATION

During operation, the temperature of the die must not exceed the maximum junction temperature. Depending on the operating ambient temperature and the total internal dissipation this limit can be exceeded.

To optimize the thermal management scheme and avoid overheating, the 900841 provides a thermal management system that protects against overheating. This protection should be considered as a fail-safe mechanism, and the application design should initiate thermal shutdown under normal conditions. Reference Thermal Management for more details.

POWER CONSUMPTION

<u>Table 2</u> defines the maximum power consumption specifications in the various system and device states. For each entry in the table, the component is assumed to be configured for driving purely capacitive loads, and the voltages listed in each entry are nominal output voltages.

Note that the "Soft Mechanical Off" state is a transitional state. The device will spend less than 150 μ s in this state before V15 starts to turn on, upon detection of a valid USB device or valid battery.

Table 2. Power Rating

Condition	Description	Logic	Maximum Power Consumption
Hard Mechanical Off	There is no Valid USB device or valid battery connected to SC900841	USBDET = 0 BATDET = 0	0 mW
Soft Mechanical Off	SC900841 has input power from either a USB device or a battery. All VRs are programmed "OFF"	USBDET = 1 BATDET = 0	50 mW
		USBDET = 0 BATDET = 1	5 mW
Power On	SC900841 has input power from either a USB device or a battery. The cold-boot rails are "ON".	USBDET = 0 BATDET = 1	100 mW
	V21 = 2.1 V V15 = 1.5 V VAON = 1.2 V VCCPAOAC = 1.05 V VPMIC = 1.8 V All VR outputs are set in PFM or APS mode driving purely capacitive loads.	USBDET = 1 BATDET = 0	10 mW

STATIC ELECTRICAL CHARACTERISTICS

Table 3. Static Electrical Characteristics

Characteristic	Symbol	Min	Тур	Мах	Unit
SYSTEM CONTROL INTERFACE					
Input Low Voltage VYMXGPSEN, VYMXPAEN, VYMX3GEN, SDATA, SCK, CS	V _{IL}	0	_	0.3*V _{PMIC}	V
EXITSTBY, VID[6:0] THRMTRIPB, VIDEN[1:0]		0 0	-	0.3*V _{CCP} 0.3*V _{CCPA}	
V33STTS, V3GPASTTS		0	-	OAC 0.3*V _{PMIC}	
Input High Voltage VYMXGPSEN, VYMXPAEN, VYMX3GEN, SDATA, SCK, CS EXITSTBY, VID[6:0] THRMTRIPB, VIDEN[1:0]	V _{IH}	0.7*V _{PMIC} 0.7*V _{CCP} 0.7*V _{CCPA}	- - -	V _{PMIC} V _{CCP} V _{CCPAOAC}	V
V33STTS, V3GPASTTS		oac 0.7*V _{PMIC}	-	V _{PMIC}	
Output Low Voltage PMICINT, VRCOMP, RESETB, PWRGD, V33EN, V3GPAEN	V _{OL}	0	-	0.1	V
Output High Voltage PMICINT, VRCOMP, RESETB, PWRGD, V33EN, V3GPAEN	V _{OH}	V _{PMIC} - 0.1	-	V _{PMIC}	V
SPI INTERFACE LOGIC IO					
Operating Voltage Range (SPIVCC Pin)	V _{SPIVCC}	1.74	1.8	3.1	V
Input High SPICSB, MOSI, SPICLK	-	0.7* V _{SPIVCC}	-	V _{SPIVCC} +0.3	V
Input Low SPICSB, MOSI, SPICLK	-	0	-	0.3* V _{SPIVCC}	V
Output Low MISO (Output sink 100 μA)	-	0	-	0.1	V
Output High MISO (Output source 100 μA)	-	V _{SPIVCC} -0.1	-	V _{SPIVCC}	V
OSCILLATOR AND CLOCK OUTPUTS MAIN CHARACTERISTICS					
Operating Voltage	-	1.2	-	1.5	V
RTC OSC Consumption Current (RTC Mode: All blocks disabled, no main battery attached, coin cell is attached to COINCELL)	-	-	1.0	2.0	μA
26 MHz OSC Consumption Current	-	-	-	500	μA
Output Low CLK32K & CLK26M (Output sink 100 µA)	-	0	-	0.1	V
Output High CLK32K & CLK26M (Output source 100 µA)	-	V _{SPIVCC} - 0.1	-	V _{SPIVCC}	V
CLK32K & CLK26M Output Duty Cycle	-	40	50	60	%

Table 3. Static Electrical Characteristics

 T_A = -40 °C to 85 °C, V_{PWR} = 3.0 to 4.4 V, typical external component values, and full load current range, unless otherwise noted. Typical values are characterized at V_{PWR} = 3.6 V and 25 °C.

Characteristic	Symbol	Min	Тур	Мах	Unit
RTC					
Input Voltage Range	-	1.2	-	1.5	V
Consumption Current	-	-	15	25	μA
Crystal OSC Frequency Tolerance	-	-30	-	+30	ppm
Crystal OSC Peak Temperature Frequency (Turn Over Temperature)	-	20	25	30	°C
Crystal OSC Maximum Series Resistance	-	-	80	-	KΩ
Crystal OSC Maximum Drive Level	-	-	0.5	-	μW
Crystal OSC Operating Drive Level	-	0.25	-	0.5	μW
Crystal OSC Nominal Lead Capacitance	-	-	9.0	-	pF
Crystal OSC Aging	-	-	-	3	ppm/ year
COIN CELL CHARGER					
Coin cell Charge Voltage (Selectable through VCOIN[2:0] bits)	V _{COINCELL}	2.5	-	3.3	V
Coin cell Charge Voltage Accuracy	-	-100	-	100	mV
Coin cell Charge Current	I _{COIN}	-	60	-	μA
Coin cell Charge Current Accuracy	-	-15	-	15	%
POWER STATES DETECTION THRESHOLDS			•		
Input Voltage Rising Detection Threshold	V _{RAWCHGDET}	-	-	4.50	V
Input Voltage Rising Detection Threshold Hysteresis	V _{RAWCHGDETHY} S	-	100	-	mV
Battery Cutoff Threshold (Depending on Battery Model)	VBATOFF	2.2	-	2.4	V
Coin Cell Disconnect Threshold	V _{COINOFF}	1.8	-	2.0	V
Low Battery Threshold	V _{LOWBAT}	3.2	-	-	V
Valid Battery Threshold	V _{TRKL}	-	3.0	-	V
VPWR Rising Under-voltage Threshold	V _{PWRUVR}	-	3.1	-	V
VPWR Falling Under-voltage Threshold	V _{PWRUVF}	-	2.55	-	V
VCC ELECTRICAL CHARACTERISTICS			•		
Input Voltage Range	V _{PWR}	3.0	3.6	4.4	V
Extended Input Voltage Range	V _{PWR}	2.8	3.6	4.7	V
Output Voltage Programmability Range					V
Low Power Mode	V _{CC}	0.3	-	0.7	
Active Mode		0.65	-	1.2	
Output Voltage Programmability Step Size	-	-	12.5	-	mV
Output Voltage Accuracy	-				%
0.6 V < V _{CC} < 12 V, 1.5 A < I _{CC} < 3.5 A		-5.0	-	5.0	
$0.6 \text{ V} < \text{V}_{\text{CC}} < 12 \text{ V}, \text{I}_{\text{CC}} < 1.5 \text{ A}$		-4.0	-	4.0	
0.3 V < V _{CC} < 0.6 V		-7.0	-	7.0	
Output Voltage Overshoot	V _{OS}				mV
Maximum overshoot voltage above VID setting voltage. Maximum overshoot time is 10-30 s, output voltage = 0.9 V at 50 mA		-	-	50	

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Table 3. Static Electrical Characteristics

Characteristic	Symbol	Min	Тур	Max	Unit
Continuous Output Load Current					Α
Low Power mode	I _{CC}	-	-	0.2	
Active Mode		0.2	-	3.5	
Peak Current Limit	ILIMCC	-	5.0	-	А
Output Current Limit Accuracy	-		±15	-	%
Transient Load Change	Δl _{CC}				Α
Low Power Mode		-	-	0.2	
Active Mode		-	-	1.2	
/NN ELECTRICAL CHARACTERISTICS					
Input Voltage Range	V _{PWR}	3.0	3.6	4.4	V
Extended Input Voltage Range	V _{PWR}	2.8	3.6	4.7	V
Output Voltage Programmability Range (Set by VID Control Signals)	V _{NN}	0.65	-	1.2	V
Output Voltage Programmability Step Size	-	-	12.5	-	mV
Output Voltage Accuracy	-	-5.0	-	5.0	%
Output Voltage Overshoot	V _{OS}	-	-	50	mV
Maximum overshoot voltage above VID setting voltage. Maximum overshoot time is 10 s, output voltage = 0.9 V at 50 mA					
Continuous Output Load Current	I _{NN}				А
Low Power Mode		-	-	0.2	
Active Mode		0.2	-	1.6	
Peak Current Limit	I _{LIMNN}	-	2.5	-	А
Output Current Limit Accuracy	-	-	±20	-	%
Transient Load Change	۵I _{NN}	-	-	0.5	А
/DDQ ELECTRICAL CHARACTERISTICS					
Input Voltage Range	V _{PWR}	3.0	3.6	4.4	V
Extended Input Voltage Range	V _{PWR}	2.8	3.6	4.7	V
Output Voltage Setting	V _{DDQ}	-	1.8	-	V
Output Voltage Accuracy	-	-5.0	-	5.0	%
Continuous Output Load Current	I _{DDQ}	-	-	1.3	А
Peak Current Limit	ILIMDDQ	-	1.78	-	Α
Output Current Limit Accuracy	-				%
0.5 A < I _{DDQ} < 1.3 A		-15	-	+15	
$I_{\text{DDQ}} < 0.5 \text{ A}$		-20	-	+20	
Transient Load Change	I _{DDQ}	-	-	0.5	А
Effective Quiescent Current Consumption (PWM, No Load)	I _{QDDQ}	-	30	-	μA
/21 ELECTRICAL CHARACTERISTICS		1	_	<u> </u>	
Input Voltage Range	V _{PWR}	3.0	3.6	4.4	V
Extended Input Voltage Range	V _{PWR}	2.8	3.6	4.7	v
Output Voltage Setting	VPWR V ₂₁	-	2.1	-	V
Output Voltage Accuracy	⊻21		<u> </u>	-	v

Table 3. Static Electrical Characteristics

Characteristic	Symbol	Min	Тур	Max	Unit
Continuous Output Load Current	I ₂₁	-	-	1.0	А
Peak Current Limit	I _{LIM21}	-	1.42	-	Α
Output Current Limit Accuracy	-	-20	-	+20	%
Transient Load Change	I ₂₁	-	-	0.5	А
Effective Quiescent Current Consumption (PWM, No Load)	I _{Q21}	-	30	-	μA
V15 ELECTRICAL CHARACTERISTICS					
Input Voltage Range	V _{PWR}	3.0	3.6	4.4	V
Extended Input Voltage Range	V _{PWR}	2.8	3.6	4.7	V
Output Voltage Setting (Also programmable to 1.6 V typical)	V ₁₅	-	1.5	-	V
Output Voltage Accuracy	-	-5.0	-	5.0	%
Continuous Output Load Current	I ₁₅	0	0.75	1.5	А
Peak Current Limit	I _{LIM15}	-	1.6	-	А
Output Current Limit Accuracy	-	-20	-	+20	%
Transient Load Change	I ₁₅	-	-	0.5	А
Effective Quiescent Current Consumption (PWM, No Load)	I _{Q15}	-	30	-	μA
VYMX3G ELECTRICAL CHARACTERISTICS			1		
Input Voltage Range	V _{PWR}	3.0	3.6	4.4	V
Extended Input Voltage Range	V _{PWR}	2.8	3.6	4.7	V
Output Voltage Setting	V _{YMX3G}				V
YMX		-	1.25	-	
3G (Programmable through Mini-SPI)		0.6	-	1.375	
Output Voltage Accuracy	-	-5.0	-	5.0	%
Output Voltage Ripple (PWM mode)	ΔI _{YMX3G}	-10	-	+10	mV
Continuous Output Load Current	I _{YMX3G}	0	-	0.8	А
Peak Current Limit	I _{LIMYMX3G}	-	1.46	-	А
Output Current Limit Accuracy	-	-20	-	+20	%
Transient Load Change	ΔI_{YMX3G}	-	-	0.2	А
Effective Quiescent Current Consumption (PWM, No Load)	I _{QYMX3G}	-	30	-	μA
VYMXPA ELECTRICAL CHARACTERISTICS					
Input Voltage Range	V _{PWR}	3.0	3.6	4.4	V
Extended Input Voltage Range	V _{PWR}	2.8	3.6	4.7	V
Typical Output Voltage Range	V _{OYMXPA}	(Selec	table, see <mark>Ta</mark>	able 37)	V
Output Accuracy	-	-5.0	-	+5.0	%
Output Voltage Ripple	ΔV_{YMXPA}	-10	-	10	mV
Continuous Output Load Current	I _{OYMXPA}				А
V _{YMXPA} = 4.2 V		-	-	0.70	
V _{YMXPA} = 5.0 V		-	-	0.50	
Under-voltage Protection Threshold	V _{UVYMXPA}	-	3.7	-	V
Under-voltage Protection Threshold Hysteresis	V _{UVYMXPAHYS}	-	0.2	-	V

Table 3. Static Electrical Characteristics

Characteristic	Symbol	Min	Тур	Мах	Unit
Over-voltage Protection Threshold	V _{OVYMXPA}	-	5.75	-	V
Over-voltage Protection Threshold Hysteresis	V _{OVYMXPAHYS}	-	0.16	-	V
Over-current limit threshold	I _{LIMYMXPA}	-	1.9	-	А
Over-current limit threshold Accuracy	-	-20	-	20	%
Short-circuit Protection Threshold (Measured at the output voltage)	V _{SCYMXPA}	-	3.0	-	V
Short-circuit Protection Threshold Accuracy (Measured at the output voltage)	-	-20	-	20	%
Transient Load Change (I _{OYMXPA} from 1.0 to 201 mA)	ΔI_{YMXPA}	-	-	0.2	А
FBYMXPA Leakage Current	I _{FBYMXPALKG}	-	0.1	-	μA
YMXPAGTIN Leakage Current	IYMXPAGTINLKG	-	-	5.0	μA
YMXPAGT Leakage Current	I _{YMXPAGTLKG}				μA
V _{OL} =100 mV, V _{OH} =V _{YMXPA} - 100 mV		-25	-	25	
Discharge FET Resistance	R _{DSCHYMXPA}	-	45	-	Ω
Effective Quiescent Current Consumption (No Load)	I _{QYMXPA}	-	125	-	μA
VOTG ELECTRICAL CHARACTERISTICS					
Input Voltage Range	V _{PWR}	3.0	3.6	4.4	V
Extended Input Voltage Range	V _{PWR}	2.8	3.6	4.7	V
Typical Output Voltage Range	V _{OTG}	-	5.0	-	V
Output Accuracy	-	-4.0	-	+4.0	%
Continuous Output Load Current	I _{OOTG}	0	-	0.35	A
Under-voltage Protection Threshold	V _{UVOTG}	-	4.5	-	V
Under-voltage Protection Threshold Hysteresis	V _{UVOTGHYS}	-	0.2	-	V
Over-voltage Protection Threshold	V _{OVOTG}	-	5.76	-	V
Over-voltage Protection Threshold Hysteresis	V _{OVOTGHYS}	-	0.16	-	V
Over-current limit threshold	I _{LIMOTG}	-	1.5	-	A
Over-current limit threshold Accuracy	-	-20	-	20	%
Short-circuit Protection Threshold (Measured at the output voltage)	V _{SCOTG}	-	3.5	-	V
Short-circuit Protection Threshold Accuracy (Measured at the output voltage)	-	-20	-	20	%
Transient Load Change (I _{OOTG} from 1.0 mA to 201 mA)	I _{OTG}	-	-	0.2	A
FBOTG Leakage Current	I _{FBOTGLKG}	-	0.1	-	μA
OTGGTIN Leakage Current	IOTGGTINLKG	-	-	5.0	μA
OTGGT Leakage Current	IOTGGTLKG	-25	-	25	μA
Discharge FET Resistance	R _{DSCHOTG}	-	100	-	Ω
Effective Quiescent Current Consumption (No Load)	I _{QOTG}	-	100	-	μA

Table 3. Static Electrical Characteristics

Characteristic	Symbol	Min	Тур	Max	Unit
VBKLT ELECTRICAL CHARACTERISTICS				I	
Input Voltage Range	V _{PWR}	3.0	3.6	4.4	V
Extended Input Voltage Range	V _{PWR}	2.8	3.6	4.7	V
Typical Output Voltage Range	V _{BKLT}				V
LCD Backlight Active		6.0	-	23	
Only Camera Scene		21	22	23	
Maximum Output Load Current	I _{BKLTMAX}	-	-	120	mA
LED Forward Voltage Range	V _F	-	-	4.0	V
Under-voltage Detection Threshold	V _{UVBKLT}	-	20	-	V
Under-voltage Detection Threshold Hysteresis	V _{UVBKLTHYS}	-	1.0	-	V
Over-voltage Protection Threshold	V _{OVBKLT}	-	24	-	V
Over-voltage Protection Threshold Hysteresis	V _{OVBKLTHYS}	-	1.0	-	V
Over-current limit threshold	I _{LIMBKLT}	-	1.9	-	А
Over-current limit threshold Accuracy	-	-20	-	20	%
Short-circuit Protection Threshold (Measured at the output voltage)	V _{SCBKLT}	-	4.0	-	V
Short-circuit Protection Threshold Accuracy (Measured at the output voltage)	-	-20	-	20	%
LED Current Sink Headroom	-	0.4	0.5	0.6	mV
FBBKLT Leakage Current	I _{FBBKLTLKG}	-	0.1	-	μA
WLEDx and LEDSCN Leakage Current (VBKLT is disabled and current sink is OFF)	-	-	-	1.0	μA
Effective Quiescent Current Consumption (No Load)	I _{QBKLT}	-	500	-	μA
VBG ELECTRICAL CHARACTERISTICS			•		•
Input Voltage Range	V _{DDQ}	1.71	1.80	1.89	V
Output Voltage Setting	V _{BG}	-	1.25	-	V
Output Voltage Accuracy	-	-2.0	-	2.0	%
Under-voltage Detection Threshold (With respect to the output voltage)	V _{BGUV}	-	-12	-	%
Under-voltage Detection Threshold Hysteresis	V _{BGUVH}	-	1.0	-	%
Continuous Output Load Current					
Active Mode	I _{BG}	-	-	2.0	mA
Low Power Mode	-	-	-	40	μA
Current Limit	I _{LIMBG}	-	94	-	mA
Transient Load Change	∆l _{BG}	-	-	1.0	mA
Power Supply Rejection Ratio (PSRR) (20 to 100 kHz, I_{BG} = 1.5 mA, V_{DDQ} = 1.8 V)	PSRR _{BG}	50	60	-	dB
Effective Quiescent Current Consumption	I _{QBG}				μA
Active Mode		-	-	18	
Low Power Mode		-	-	10	

Table 3. Static Electrical Characteristics

 T_A = -40 °C to 85 °C, V_{PWR} = 3.0 to 4.4 V, typical external component values, and full load current range, unless otherwise noted. Typical values are characterized at V_{PWR} = 3.6 V and 25 °C.

Characteristic	Symbol	Min	Тур	Max	Unit
/CCA ELECTRICAL CHARACTERISTICS					
Input Voltage Range	V _{DDQ}	1.71	1.80	1.89	V
Output Voltage Setting	V _{CCA}	-	1.5	-	V
Output Voltage Accuracy	-	-2.0	-	2.0	%
Under Voltage Detection Threshold (With respect to the output voltage)	V _{CCAUV}	-	-12	-	%
Under Voltage Detection Threshold Hysteresis	V _{CCAUVH}	-	1.0	-	%
Continuous Output Load Current	I _{CCA}				
Active Mode		-	-	150	mA
Low Power Mode		-	-	3.0	mA
Current Limit	ILIMCCA	-	225	-	mA
Transient Load Change	ΔI_{CCA}	-	-	50	mA
Power Supply Rejection Ratio (PSRR) (20 to 100 kHz, I_{CCA} = 112.5 mA, V_{DDQ} = 1.8 V)	PSRR _{CCA}	50	60	-	dB
Effective Quiescent Current Consumption	I _{QCCA}				μA
Active Mode		-	-	18	
Low Power Mode		-	-	10	
CC180 ELECTRICAL CHARACTERISTICS					
Input Voltage Range	V ₂₁	1.995	2.1	2.205	V
Output Voltage Setting	V _{CC180}	-	1.8	-	V
Output Voltage Accuracy	-	-5.0	-	5.0	%
Under-voltage Detection Threshold (With respect to the output voltage)	V _{CC180UV}	-	-12	-	%
Under-voltage Detection Threshold Hysteresis	V _{CC180UVH}	-	1.0	-	%
Continuous Output Load Current	I _{CC180}				
Active Mode		-	-	390	mA
Low Power Mode		-	-	7.8	mA
Current Limit	I _{LIMCC180}	-	585	-	mA
Transient Load Change	ΔI_{CC180}	-	-	350	mA
Power Supply Rejection Ratio (PSRR) (20 to 100 kHz, I_{CC180} = 292.5 mA, V_{21} = 2.1 V)	PSRR _{CC180}	50	60	-	dB
Effective Quiescent Current Consumption	I _{QCC180}				μA
Active Mode		-	-	18	
Low Power Mode		-	-	10	
/PNL18 ELECTRICAL CHARACTERISTICS SPECIFICATION					
Input Voltage Range	V ₂₁	1.995	2.1	2.205	V
Output Voltage Setting	V _{PNL18}	-	1.8	-	V
Output Voltage Accuracy	-	-5.0	-	5.0	%

-

-

%

%

-12

1.0

-

-

V_{PNL18UV}

V_{PNL18UVH}

Under-voltage Detection Threshold (With respect to the output voltage)

Under-voltage Detection Threshold Hysteresis

Table 3. Static Electrical Characteristics

 T_A = -40 °C to 85 °C, V_{PWR} = 3.0 to 4.4 V, typical external component values, and full load current range, unless otherwise noted. Typical values are characterized at V_{PWR} = 3.6 V and 25 °C.

Characteristic	Symbol	Min	Тур	Max	Unit
Continuous Output Load Current					mA
Active Mode	I _{PNL18}	-	-	210	
Low Power Mode		-	-	4.2	
Current Limit	I _{LIMPNL18}	-	315	-	mA
Transient Load Change	ΔI_{PNL18}	-	-	100	mA
Power Supply Rejection Ratio (PSRR) (20 to 100 kHz, $\rm I_{PNL18}$ = 157.5 mA, $\rm V_{21}$ = 2.1 V)	PSRR _{PNL18}	50	60	-	dB
Effective Quiescent Current Consumption	I _{QPNL18}				μA
Active Mode		-	-	18	
Low Power Mode		-	-	10	
/PMIC ELECTRICAL CHARACTERISTICS					
Input Voltage Range	V ₂₁	1.995	2.1	2.205	V
Output Voltage Setting	V _{PMIC}	-	1.8	-	V
Output Voltage Accuracy	-	-5.0	-	5.0	%
Under-voltage Detection Threshold	V _{PMICUV}	-	-12	-	%
(With respect to the output voltage)					
Under Voltage Detection Threshold Hysteresis	V _{PMICUVH}	-	1.0	-	%
Continuous Output Load Current	I _{PMIC}				mA
Active Mode	1 Milo	-	-	100	
Low Power Mode		-	-	2.0	
Current Limit	ILIMPMIC	-	150	-	mA
Transient Load Change	Δl _{PMIC}	-	-	20	mA
Power Supply Rejection Ratio (PSRR) (20 to 100 kHz, I_{PMIC} = 75 mA, V_{21} = 2.1 V)	PSRR _{PMIC}	50	60	-	dB
Effective Quiescent Current Consumption					μA
Active Mode	I _{QPMIC}	-	-	18	
Low Power Mode		-	-	10	
/YMXYFI18 ELECTRICAL CHARACTERISTICS					
Input Voltage Range					V
Supplied by V ₂₁ DC/DC	V ₂₁	1.995	2.1	2.205	
Supplied by V _{PWR}	V _{PWR}	3.0	3.6	4.4	
Output Voltage Setting	V _{YMXYFI18}	-	1.8	-	V
Output Voltage Accuracy	-	-5.0	-	5.0	%
Under-voltage Detection Threshold (With respect to the output voltage)	V _{YMXYFI18UV}	-	-12	-	%
Under-voltage Detection Threshold Hysteresis	V _{YMXYFI18UVH}	-	1.0	-	%
Continuous Output Load Current	I _{YMXYFI18}				mA
Active Mode	THE COLOR	-	-	200	
Low Power Mode		-	-	4.0	
Current Limit	I _{LIMYMXYFI18}	-	300	-	mA
Transient Load Change	ΔI _{YMXYFI18}	-	-	100	mA
Power Supply Rejection Ratio (PSRR) (20 to 100 kHz, $I_{YMXYF118}$ = 150 mA), (V ₂₁ = 2.1 V or V _{PWR} = 3.6 V)	PSRR _{YMXYFI18}	40	-	-	dB

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Table 3. Static Electrical Characteristics

Characteristic	Symbol	Min	Тур	Max	Unit
Output Noise (10 Hz to 100 kHz, $I_{YMXYFI18}$ = 200 mA), (V ₂₁ = 2.1 V or V _{PWR} = 3.6 V)	V _{NOISEYMXYFI18}	-	-	40	μV _{RMS}
Effective Quiescent Current Consumption	I _{QYMXYFI18}				μA
Active Mode		-	-	18	
Low Power Mode		-	-	10	
VYMXYFI ELECTRICAL CHARACTERISTICS					
Input Voltage Range					V
Supplied by V ₁₅ DC/DC (WiFiBT Applications)	V ₁₅	1.425	1.5	1.575	
Supplied by V ₃₃ DC/DC (WiMAX Applications)	V ₃₃	3.168	3.3	3.432	
Supplied by V _{PWR} (WiMAX Applications)	V _{PWR}	3.0	3.6	4.4	
Output Voltage Setting	V _{YMXYFI}				V
WiFiBT Applications		-	1.2	-	
WiMAX Applications		-	2.5	-	
Output Voltage Accuracy	-	-5.0	-	5.0	%
Under-voltage Detection Threshold (With respect to the output voltage)	V _{YMXYFIUV}	-	-12	-	%
Under Voltage Detection Threshold Hysteresis	V _{YMXYFIUVH}	-	1.0	-	%
Continuous Output Load Current	I _{YMXYFI}				mA
Active Mode (WiFiBT Applications)		-	-	60	
Active Mode (WiMAX Applications)		-	-	150	
Low Power Mode		-	-	1.2	
Current Limit	I _{LIMYMXYFI}	-	225	-	mA
Transient Load Change	ΔI_{YMXYFI}				mA
WiFiBT Applications		-	-	32	
WiMAX Applications		-	-	130	
Power Supply Rejection Ratio (PSRR) (20 kHz, I_{YMXYFI} = 45 mA), (V ₁₅ = 1.5) (WiFiBT Applications)	PSRR _{YMXYFI}	50	60	-	dB
Power Supply Rejection Ratio (PSRR) (100 kHz, I_{YMXYFI} = 112.5 mA), (V ₃₃ = 3.3 V or V _{PWR} = 3.6 V) (WiMAX Applications)	PSRR _{YMXYFI}	40	-	-	dB
Output Noise (10 Hz to 100 kHz, I_{YMXYFI} = 60 mA), (V ₁₅ = 1.5 V) (WiFiBT Applications)	V _{NOISEYMXYFI}	-	-	40	μV _{RMS}
Output Noise (10 Hz to 100 kHz, I_{YMXYFI} = 150 mA), (V ₃₃ = 3.3 V or V _{PWR} = 3.6 V) (WiMAX Applications)	V _{NOISEYMXYFI}	-	-	40	μV _{RMS}
Effective Quiescent Current Consumption	I _{QYMXYFI}				μA
Active Mode		-	-	18	
Low Power Mode		-	-	10	

Table 3. Static Electrical Characteristics

Characteristic	Symbol	Min	Тур	Max	Unit
/YMXGPS ELECTRICAL CHARACTERISTICS	-				
Input Voltage Range					V
Supplied by V ₁₅ DC/DC (WiMAX Applications)	V ₁₅	1.52	1.6	1.68	
Supplied by V ₂₁ DC/DC (GPS Applications)	V ₂₁	1.995	2.1	2.205	
Supplied by V _{PWR} (GPS Applications)	V _{PWR}	3.0	3.6	4.4	
Output Voltage Setting	V _{YMXGPS}				V
WiMAX Applications		-	1.3	-	
GPS Applications		-	1.8	-	
Output Voltage Accuracy	-	-5.0	-	5.0	%
Under-voltage Detection Threshold (With respect to the output voltage)	V _{YMXGPSUV}	-	-12	-	%
Under-voltage Detection Threshold Hysteresis	V _{YMXGPSUVH}	-	1.0	-	%
Continuous Output Load Current	I _{YMXGPS}				mA
Active Mode (WIMAX Applications)		-	-	350	
Active Mode (GPS Applications)		-	-	170	
Low Power Mode		-	-	3.4	
Current Limit	I _{LIMYMXGPS}	-	525	-	mA
Transient Load Change	ΔI _{YMXGPS}				mA
WiMAX Applications		-	-	200	
GPS Applications		-	-	130	
Power Supply Rejection Ratio (PSRR) (20 kHz, I_{YMXGPS} = 262.5 mA), (V ₁₅ = 1.6 V) (WiMAX Applications)	PSRR _{YMXGPS}	50	60	-	dB
Power Supply Rejection Ratio (PSRR), (20 to 100 kHz, I_{YMXGPS} = 127.5 mA), (V ₂₁ = 2.1 V or V _{PWR} = 3.6 V) (GPS Applications)	PSRR _{YMXGPS}	40	-	-	dB
Output Noise (10 Hz to 100 kHz, I_{YMXGPS} = 350 mA), (V ₁₅ = 1.6 V) (WiMAX Applications)	V _{NOISEYMXGPS}	-	-	40	μV _{RM}
Output Noise (10 Hz to 100 kHz, I_{YMXGPS} = 170 mA), (V ₂₁ = 2.1 V or V _{PWR} = 3.6 V) (GPS Applications)	V _{NOISEYMXGPS}	-	-	40	μV _{RM}
Effective Quiescent Current Consumption	I _{QYMXGPS}				μA
Active Mode		-	-	18	
Low Power Mode		-	-	10	
CCPAOAC ELECTRICAL CHARACTERISTICS					
Input Voltage Range	V ₁₅	1.425	1.5	1.680	V
Output Voltage Setting		-	1.05	-	V

input voltage italige	V ₁₅	1.425	1.5	1.000	v
Output Voltage Setting	V _{CCPAOAC}	-	1.05	-	V
Output Voltage Accuracy	-	-5.0	-	5.0	%
Under-voltage Detection Threshold (With respect to the output voltage)	V _{CCPAOACUV}	-	-12	-	%
Under-voltage Detection Threshold Hysteresis	V _{CCPAOACUVH}	-	1.0	-	%
Continuous Output Load Current	I _{CCPAOAC}				mA
Active Mode		-	-	155	
Low Power Mode		-	-	3.1	
Current Limit	ILIMCCPAOAC	-	232.5	-	mA

Table 3. Static Electrical Characteristics

Characteristic	Symbol	Min	Тур	Max	Unit
Transient Load Change		-	-	50	mA
Power Supply Rejection Ratio (PSRR) (20 to 100 kHz, $I_{CCPAOAC}$ = 116 mA, V_{15} = 1.5 V)	PSRR _{CCPAOAC}	50	60	-	dB
Effective Quiescent Current Consumption	I _{QCCPAOAC}				μA
Active Mode		-	-	18	
Low Power Mode		-	-	10	
VCCPDDR ELECTRICAL CHARACTERISTICS					
Input Voltage Range	V ₁₅	1.425	1.5	1.680	V
Output Voltage Setting	V _{CCPDDR}	-	1.05	-	V
Output Voltage Accuracy	-	-2.0	-	2.0	%
Under-voltage Detection Threshold (With respect to the output voltage)	V _{CCPDDRUV}	-	-12	-	%
Under-voltage Detection Threshold Hysteresis	V _{CCPDDRUVH}	-	1.0	-	%
Continuous Output Load Current	I _{CCPDDR}				mA
Active Mode		-	-	60	
Low Power Mode		-	-	1.2	
Current Limit	ILIMCCPDDR	-	90	-	mA
Transient Load Change	ΔI_{CCPDDR}	-	-	10	mA
Power Supply Rejection Ratio (PSRR) (20 to 100 kHz, $\rm I_{CCPDDR}$ = 45 mA, $\rm V_{15}$ = 1.5 V)	PSRR _{CCPDDR}	50	60	-	dB
Effective Quiescent Current Consumption	IQCCPDDR				μA
Active Mode		-	-	18	
Low Power Mode		-	-	10	
VAON ELECTRICAL CHARACTERISTICS					
Input Voltage Range	V ₁₅	1.425	1.5	1.680	V
Output Voltage Setting	V _{AON}	-	1.2	-	V
Output Voltage Accuracy	-	-5.0	-	5.0	%
Under-voltage Detection Threshold (With respect to the output voltage)	V _{AONUV}	-	-12	-	%
Under-voltage Detection Threshold Hysteresis	V _{AONUVH}	-	1.0	-	%
Continuous Output Load Current	I _{AON}				mA
Active Mode		-	-	250	
Low Power Mode		-	-	5	
Current Limit	I _{LIMAON}	-	375	-	mA
Transient Load Change	ΔI _{AON}	-	-	100	mA
Power Supply Rejection Ratio (PSRR) (20 to 100 kHz, $\rm I_{AON}$ = 187.5 mA, $\rm V_{15}$ = 1.5 V)	PSRR _{AON}	50	60	-	dB
Effective Quiescent Current Consumption	I _{QAON}				μA
Active Mode	-	-	-	18	
Low Power Mode		-	-	10	

Table 3. Static Electrical Characteristics

Characteristic	Symbol	Min	Тур	Max	Unit
VMM ELECTRICAL CHARACTERISTICS					
Input Voltage Range	V ₁₅	1.425	1.5	1.680	V
Output Voltage Setting	V _{MM}	-	1.2	-	V
Output Voltage Accuracy	-	-5.0	-	5.0	%
Under-voltage Detection Threshold (With respect to the output voltage)	V _{MMUV}	-	-12	-	%
Under-voltage Detection Threshold Hysteresis	V _{MMUVH}	-	1.0	-	%
Continuous Output Load Current	I _{MM}				mA
Active Mode		-	-	5.0	
Low Power Mode		-	-	0.1	
Current Limit	ILIMMM	-	25	-	mA
Transient Load Change	ΔI_{MM}	-	-	3.0	mA
Power Supply Rejection Ratio (PSRR) (20 to 100 kHz, I_{MM} = 4.0 mA, V_{15} = 1.5 V)	PSRR _{MM}	50	60	-	dB
Effective Quiescent Current Consumption	I _{QMM}				μA
Active Mode		-	-	18	
Low Power Mode		-	-	10	
/CCP ELECTRICAL CHARACTERISTICS					
Input Voltage Range	V ₁₅	1.425	1.5	1.680	V
Output Voltage Setting	V _{CCP}	-	1.05	-	V
Output Voltage Accuracy	-	-5	-	5.0	%
Under-voltage Detection Threshold (With respect to the output voltage)	V _{CCPUV}	-	-12	-	%
Under-voltage Detection Threshold Hysteresis	V _{CCPUVH}	-	1.0	-	%
Continuous Output Load Current	I _{CCP}				mA
Active Mode		-	-	445	
Low Power Mode		-	-	8.9	
Current Limit	ILIMCCP	-	667.5	-	mA
Transient Load Change	ΔI_{CCP}	-	-	100	mA
Power Supply Rejection Ratio (PSRR) (20 to 100 kHz, I_{CCP} = 334 mA, V_{15} = 1.5 V)	PSRR _{CCP}	50	60	-	dB
Effective Quiescent Current Consumption	IQCCP				μA
Active Mode		-	-	18	
Low Power Mode		-	-	10	
/IMG25 ELECTRICAL CHARACTERISTICS					
Input Voltage Range					V
Supplied by V ₃₃ DC/DC	V ₃₃	3.168	3.3	3.432	
Supplied by V _{PWR}	V _{PWR}	3.0	3.6	4.4	
Output Voltage Setting	V _{IMG25}	-	2.5	-	V
Output Voltage Accuracy	-	-5.0	-	5.0	%
Under-voltage Detection Threshold (With respect to the output voltage)	V _{IMG25UV}	-	-12	-	%
Under-voltage Detection Threshold Hysteresis	V _{IMG25UVH}	_	1.0	_	%

Table 3. Static Electrical Characteristics

Characteristic	Symbol	Min	Тур	Max	Unit
Continuous Output Load Current	I _{IMG25}				mA
Active Mode		-	-	80	
Low Power Mode		-	-	1.6	
Current Limit	I _{LIMIMG25}	-	120	-	mA
Transient Load Change	ΔI_{IMG25}	-	-	10	mA
Power Supply Rejection Ratio (PSRR) (20 to 100 kHz, I_{IMG25} = 60 mA, V_{33} = 3.3 V)	PSRR _{IMG25}	50	60	-	dB
Effective Quiescent Current Consumption	I _{QIMG25}				μA
Active Mode		-	-	18	
Low Power Mode		-	-	10	
VIMG28 ELECTRICAL CHARACTERISTICS					
Input Voltage Range					V
Supplied by V ₃₃ DC/DC	V ₃₃	3.168	3.3	3.432	
Supplied by V _{PWR}	V _{PWR}	3.0	3.6	4.4	
Output Voltage Setting	V _{IMG28}	(Selectable, see Table 58)			V
Output Voltage Accuracy	-	-5.0	-	5.0	%
Under-voltage Detection Threshold (With respect to the output voltage)	V _{IMG28UV}	-	-12	-	%
Under-voltage Detection Threshold Hysteresis	V _{IMG28UVH}	-	1.0	-	%
Continuous Output Load Current	I _{IMG28}				mA
Active Mode		-	-	225	
Low Power Mode		-	-	4.5	
Current Limit	I _{LIMIMG28}	-	337.5	-	mA
Transient Load Change	ΔI_{IMG28}	-	-	100	mA
Power Supply Rejection Ratio (PSRR) (20 to 100 kHz, $\rm I_{IMG28}$ = 169 mA, $\rm V_{33}$ = 3.3 V)	PSRR _{IMG28}	50	60	-	dB
Effective Quiescent Current Consumption	I _{QIMG28}				μA
Active Mode		-	-	18	
Low Power Mode		-	-	10	

Table 3. Static Electrical Characteristics

 T_A = -40 °C to 85 °C, V_{PWR} = 3.0 to 4.4 V, typical external component values, and full load current range, unless otherwise noted. Typical values are characterized at V_{PWR} = 3.6 V and 25 °C.

Characteristic	Symbol	Min	Тур	Max	Unit
VIB ELECTRICAL CHARACTERISTICS					
Input Voltage Range ⁽⁵⁾	V _{PWR}	3.0	3.6	4.4	V
Output Voltage Setting	V _{VIB}	(Select	able, see <mark>Ta</mark>	able <u>59</u>)	V
Output Voltage Accuracy	-	-5.0	-	5.0	%
Under-voltage Detection Threshold (With respect to the output voltage)	V _{VIBUV}	-	-12	-	%
Under-voltage Detection Threshold Hysteresis	V _{VIBUVH}	-	1	-	%
Continuous Output Load Current Active Mode Low Power Mode	I _{VIB}	-	-	200 4.0	mA
Current Limit	I _{LIMVIB}	-	300	-	mA
Transient Load Change	Δl _{VIB}	-	-	100	mA
Power Supply Rejection Ratio (PSRR) (20 to 100 kHz, I_{VIB} = 150 mA, V_{PWR} = 3.6 V)	PSRR _{VIB}	50	60	-	dB
Effective Quiescent Current Consumption Active Mode Low Power Mode /SDIO ELECTRICAL CHARACTERISTICS	Ι _{QVIB}	-	-	18 10	μA
Input Voltage Range	V ₃₃	3.168	3.3	3.432	V
Output Voltage Setting	V _{SDIO}		able, see Ta		v
Output Voltage Accuracy	• SDIO	-5.0		5.0	v %
Under-voltage Detection Threshold (With respect to the output voltage)	V _{SDIOUV}	-	-12	-	%
Under-voltage Detection Threshold Hysteresis	V _{SDIOUVH}	-	1.0	-	%
Continuous Output Load Current Active Mode Low Power Mode	I _{SDIO}		-	215 4.3	mA
Current Limit	ILIMSDIO	-	322.5	-	mA
Transient Load Change	ΔI _{SDIO}	-	-	100	mA
Power Supply Rejection Ratio (PSRR) (20 to 100 kHz, I_{SDIO} = 161 mA, V_{33} = 3.3 V)	PSRR _{SDIO}	50	60	-	dB
Effective Quiescent Current Consumption Active Mode Low Power Mode	I _{QSDIO}	-	-	18 10	μA

Notes

5. PVINVIB pin has to always be connected to VPWR node, even if the vibrator is not used.

Table 3. Static Electrical Characteristics

Characteristic	Symbol	Min	Тур	Max	Unit
POWER SWITCHES ELECTRICAL CHARACTERISTICS	·				
Input Voltage Range	V ₃₃	3.168	3.3	3.432	V
Drop Across Switch with reference to V ₃₃	-				%
VGPS33, VYMXGPS33, and VPNL33		-	-	3.0	
Continuous Output Load Current					mA
VPNL33	I _{PNL33}	-	-	100	
VGP33	I _{GP33}	-	-	60	
VYMXGPS33	I _{YMXGPS33}	-	-	60	
LCD BACKLIGHT DRIVERS (WLED) ELECTRICAL CHARACTERISTICS					
Current Sink Capability per string	I _{SINK}	-	-	30	mA
LED Forward Voltage Range	V _F	-	-	4.0	V
LED Current Accuracy (I _{SINK} = 10 mA)	-				%
T = 25°C		-3.0	-	3.0	
LED Current Matching Accuracy	-				%
T = 25°C		-2.0	-	2.0	
CAMERA SCENE ILLUMINATION DRIVERS ELECTRICAL CHARACTERIS	STICS				•
Current Sink Capability	I _{SINK}	-	-	30	mA
LED Forward Voltage Range	V _F	-	-	4.0	V
LED Current Accuracy (I _{SINK} = 10 mA)	-				%
T = 25°C		-3.0	-	3.0	
LED Current Matching Accuracy (When used as backlight 4 th string)	-				%
T = 25°C		-2.0	-	2.0	
SIGNALING/STATUS LED DRIVERS ELECTRICAL CHARACTERISTICS	L		1		1
LED Absolute Current Tolerance	-	-	0	15	%
LED Current Sink capability (Selectable)	-	0	-	28	mA
LED Current Matching Within Banks (With Respect to Average Current in the Bank, V_{DRIVER} = 400 mV, I_{LED} = 20 mA)	-	-	-	5.0	%
LED Channel Off Current (LED Disabled)	-	-	0	1.0	μA
Quiescent Consumption (Duty Cycle set to 000000, Current Levels set to 00)	-	-	10	-	μA
LED Current Sink Headroom	-	0.3	0.4	-	mV
Driver Pin Voltage Range	-	0	-	6.0	V
POWER PATH MANAGER PLUS LI-ION CHARGER ELECTRICAL CHARA	ACTERISTICS				
Input voltage Range (Normal Operation)	V _{RAWCHG}	4.75	5.00	5.25	V
Input Voltage Rising Detection Threshold	V _{RAWCHGDET}	_	_	4.5	V
Input Voltage Rising Detection Threshold Hysteresis	V _{RAWCHGDETHY} S	-	100	-	mV
Input Over-voltage Protection Threshold	V _{RAWCHOVP}	5.50	5.75	6.00	V
Input Over-voltage Protection Threshold Hysteresis	V _{RAWCHOVP} HYS	-	75	-	mV

Table 3. Static Electrical Characteristics

Characteristic	Symbol	Min	Тур	Max	Unit
V _{PWR} Output Voltage Range	V _{PWR}				V
V _{BAT} < V _{TRKL}		-	4.2	-	
V _{PWR} Output Voltage Range	V _{PWR}				V
100% Duty-cycle mode		-	-	4.7	
Constant Charge Voltage (V _{CHRGCV}) Accuracy	-				%
Initial Accuracy at 25°C		-0.2	-	+0.2	
-20°C to 70°C		-0.8	-	+0.8	
-40°C to 85°C		-1.0	-	+1.0	
Battery Charge Voltage	V _{CHGCV}	Selectable	, CHRGCV I <u>Table 79</u>	Register on	V
Battery Charge Voltage Over-voltage Threshold (V _{CHGCV} + Setting)	V _{OVRVOLT}		ole, see CHF ister on <u>Tab</u>		mV
Maximum Continuous Input Average Current	-		ole, see CHF ister on <u>Tab</u>		mA
Maximum Continuous Input Average Current Accuracy	-	-5.0	-	5.0	%
Trickle Charge Threshold Voltage	V _{TRKL}	-	3.0	-	V
Trickle Charge Threshold Accuracy	-	-3.0	-	+3.0	%
Constant Charge Current Range	ICHGCC	Selectal Reg	mA		
Discharge Current Over-current Threshold	IBATOC	Selectable, see BATOCP Register on <u>Table 67</u>			A
Constant Charge Current Accuracy	-				%
I _{CC} < 400 mA		-15	-	+15	
I _{CC} > 400 mA		-10	-	+10	
Trickle Charge Current Value	I _{TRKL}	Select	table, see <mark>Ta</mark>	able 81	mA
Trickle Charge Current Accuracy	-	-30	-	+30	%
EOC Detect Threshold	ICHGCOMP		ble, see CHF ister on <u>Tab</u>		mA
EOC Detect Threshold Accuracy	-	-12	-	+12	%
Discharge Indication Threshold (Used to turn on M _{CHGBYP})	V _{BAT} -V _{PWR}	100	-	-	mV
NTC Bias Voltage	V _{NTC}	-	V _{CORE}	-	V
NTC Low Temperature Threshold (As a ratio of V _{NTC,} 3500 B factor)	V _{COLD}		-		
During Charging (0°C)		-	0.746	-	-
During Discharging (-10°C)		-	0.825	-	-
NTC Low Temperature Hysteresis	V _{COLDHYS}	-	0.06	-	-
NTC High Temperature Threshold (As a ratio of V _{NTC,} 3500 B factor) During Charging (45°C)	V _{HOT}				
During Discharging (60°C)		-	0.324	-	-
		-	0.227	-	-
NTC High Temperature Hysteresis	V _{HOTHYS}	_	0.06	-	-

Table 3. Static Electrical Characteristics

 T_A = -40 °C to 85 °C, V_{PWR} = 3.0 to 4.4 V, typical external component values, and full load current range, unless otherwise noted. Typical values are characterized at V_{PWR} = 3.6 V and 25 °C.

Characteristic	Symbol	Min	Тур	Мах	Unit
ADC ELECTRICAL CHARACTERISTICS			•		
Conversion Current	-	-	-	1.2	mA
OFF Supply Current	-	-	-	1.0	μA
Converter Reference Voltage	-	-	2.4	-	V
Integral Nonlinearity (Rs = 5.0 k Ω maximum) ⁽⁶⁾	-	-	-	±3.0	LSB
Differential Nonlinearity (Rs = 5.0 k Ω maximum) ⁽⁶⁾	-	-	-	±1.0	LSB
Zero Scale Error (Offset) (Rs = 5.0 k Ω maximum) ⁽⁶⁾	-	-	-	10	LSB
Full Scale Error (Gain) (Rs = 5.0 k Ω maximum) ^{(6), (10)}	-	-	-	11	LSB
Drift Over Temperature				±2.0	LSB
Source Impedance					
No Bypass Capacitor at Input	-	-	-	5.0	kΩ
Bypass Capacitor at Input of (10 nF)	-	-	-	30	kΩ
Input Buffer Input Range ⁽⁷⁾	-	0.02	-	2.4	V
BATTERY CURRENT READING					
Amplifier ⁽⁸⁾ Gain	-	19	20	21	-
Amplifier Offset	-	-2.0	-	2.0	mV
Sense Resistor	-	-	20	-	mΩ
BATTERY THERMISTOR INTERFACE TARGET			•		
Thermistor Input Range	-	2.0	-	100	k
Internal Current Source	-	-	20	-	μA
Absolute Resistance Measurement Inaccuracy Over Temperature	-	-	10	-	%
Battery Removal Detection Threshold ⁽⁹⁾	-	-	31/32* V _{NTC}	-	V
COULOMB COUNTER			•		
Sense Resistor R _{CC}	-	-	20	-	mΩ
Sense Current though R _{CC}	-	+/-1.0	-	+/-3000	mA
Quiescent Current Consumption	-	-	10	20	μA
Resolution (1LSB Increment in CCOUT with ONEC=1)	-	-	366.2	_	μC

6. Rs represents a possible external series resistor between the voltage source and the ADIN input.

7. Refer to Table 96 for analog valid input range and input buffer range characteristics for each ADC Channel

8. Amplifier bias current accounted for in overall ADC current drain

- 9. This is equivalent to a 10 k Ω pull-up and a 10 k Ω thermistor at -35°C
- 10. At room temperature

Table 3. Static Electrical Characteristics

Characteristic	Symbol	Min	Тур	Max	Unit
GPIOS ELECTRICAL CHARACTERISTICS					
GPIO Voltage Level (This is wired externally though GPIOVCC pin)	V _{GPIOVCC}	-	1.8V,2.5V, 3.3V	-	V
GPOSW Voltage Level (This is wired externally though GPOSWVCC pin)	V _{GPOSWVCC}	-	V _{BAT}	-	V
GPO Voltage Level (This is wired externally though GPOVCC pin)	V _{GPOVCC}	-	1.8V,2.5V, 3.3V	-	V
Accuracy for GPIOVCC, GPOVCC	-	-5.0	-	5.0	%
GPIO Output Drive Capability	-	-	20	-	Ω
GPOSW Typical Drive Capacitance	Look at the Si84		as an exam apability	ple for maxir	num drive
Input Low Voltage	V _{IL}	0	-	0.3*V _{CC}	V
Input High Voltage	V _{IH}	0.7*V _{CC}	-	V _{CC}	V
Output Low Voltage (V _{CC} = V _{CC_MIN} , I _{OL} = 4.0 mA)	V _{OL}	-	-	0.1	V
Output High Voltage ($V_{CC} = V_{CC_MIN}$, $I_{OH} = -4.0$ mA)	V _{OL}	V _{CC} -0.1	-	-	V

DYNAMIC ELECTRICAL CHARACTERISTICS

Table 4. Dynamic Electrical Characteristics

Characteristic	Symbol	Min	Тур	Max	Unit	
SPI INTERFACE TIMING AND LOGIC IO						
Time SPICSB has to be low before the first rising edge of SPICLK	t _{SELSU}	20	-	-	ns	
Time SPICSB has to remain low after the last falling edge of SPICLK	t _{SELHLD}	20	-	-	ns	
Time SPICSB has to remain high between two transfers	t _{SELHIGH}	20	-	-	ns	
Clock period of SPICLK (Equivalent to a maximum clock frequency of 25 MHz)	t _{CLKPER}	40	-	-	ns	
Part of the clock period where SPICLK has to remain high	t _{CLKHIGH}	18	-	-	ns	
Part of the clock period where SPICLK has to remain low	t _{CLKLOW}	18	-	-	ns	
Time MOSI has to be stable before the next falling edge of SPICLK	t _{WRTSU}	5.0	-	-	ns	
Time MOSI has to remain stable after the falling edge of SPICLK	t _{WRTHLD}	5.0	-	-	ns	
Time MISO will be stable before the next falling edge of SPICLK	t _{RDSU}	5.0	-	-	ns	
Time MISO will remain stable after the falling edge of SPICLK	t _{RDHLD}	5.0	-	-	ns	
Time MISO needs to become active after the falling edge of SPICSB	t _{RDEN}	Refe	Refer to Figure 5 for more details			
Time MISO needs to become inactive after the rising edge of SPICSB	t _{RDDIS}	5.0	-	-	ns	
VIDEN/VID TIMING SPECIFICATION					·	
VIDEN/VID Debounce time	t _{DB}	100	-	400	ns	
VIDEN Invalid State Hold Time	t _{HOLD}	1.0	-	-	μs	
OSCILLATOR AND CLOCK OUTPUTS MAIN CHARACTERISTICS						
RTC OSC Startup Time (Upon Application of Power)	-	-	-	500	ms	
26 MHz OSC Startup Time	-	-	-	1.0	ms	
RTC					·	
RTC Clock Frequency, Crystal OSC Nominal Frequency	-	-	32.768	-	KHz	
VCC ELECTRICAL CHARACTERISTICS			•	•		
Transient Load Speed of Change	I _{CC} /t	-	-	1	A/ns	
Soft Start Time (Enable to output voltage ramp up from 0 to 1.0 V (25 mV/s))	t _{sscc}	-	-	0.06	ms	
Turn Off Time (OFF to output voltage ramp down to 0 V)	t _{CCOFF}	-	-	1	ms	
DAC Slew Rate	-	-	25	-	mV/µs	
Switching Frequency	f _{SW}	-	1.0	-	MHz	
VNN ELECTRICAL CHARACTERISTICS					·	
Transient Load Speed of Change	I _{NN} /t	-	-	1.0	A/ns	
Soft Start Time (Enable to output voltage ramp up from 0 V to 1.0 V (25 mV/s))	t _{SSNN}	-	-	0.06	ms	
Turn Off Time (OFF to output voltage ramp down to 0 V)	t _{NNOFF}	-	-	1.0	ms	
DAC Slew Rate	-	-	25	-	mV/µs	
Switching Frequency	f _{SW}	-	1.0	-	MHz	

Table 4. Dynamic Electrical Characteristics

Characteristic	Symbol	Min	Тур	Max	Unit
VDDQ ELECTRICAL CHARACTERISTICS					
Transient Load Speed of Change	I _{DDQ} /t	-	-	1.0	A/µs
Soft Start Time (Enable to output voltage ramp up from 0 to 1.8 V)	t _{SSDDQ}	-	-	200	μs
Turn Off Time (OFF to output voltage ramp down to 0 V)	t _{DDQOFF}	-	-	1.0	ms
Switching Frequency	f _{SW}	-	4.0	-	MHz
V21 ELECTRICAL CHARACTERISTICS					
Transient Load Speed of Change	I ₂₁ /t	-	-	0.1	A/µs
Soft Start Time (Enable to output voltage ramp up from 0 V to 2.1 V)	t _{SS21}	-	-	84	μs
Turn Off Time (OFF to output voltage ramp down to 0 V)	t _{210FF}	-	-	1.0	ms
Switching Frequency	f _{SW}	-	4.0	-	MHz
V15 ELECTRICAL CHARACTERISTICS	11		1		•
Transient Load Speed of Change	I ₁₅ /t	-	-	0.1	A/µs
Soft Start Time	t _{SS15}	-	-	100	μs
(Enable to output voltage ramp up from 0 to 2.1 V)					
Turn Off Time (OFF to output voltage ramp down to 0 V)	t _{150FF}	-	-	1.0	ms
Switching Frequency	f _{SW}	-	4.0	-	MHz
VYMX3G ELECTRICAL CHARACTERISTICS					
Transient Load Speed of Change	I _{YMX3G} /t	-	-	0.1	A/µs
Soft Start Time (Enable to output voltage ramp up from 0 to 2.1 V)	t _{SSYMX3G}	-	-	0.5	ms
Turn Off Time (OFF to output voltage ramp down to 0 V)	t _{YMX3GOFF}	-	-	1.0	ms
Transition Time (3G mode), VOUT delta = ± 0.3 V with 100 mA load current	t _{YMX3GTRAN}	-	-	100	μs
Switching Frequency	f _{SW}	-	4.0	-	MHz
VYMXPA ELECTRICAL CHARACTERISTICS					
Transient Load Speed of Change	I _{YMXPA} /t	-	-	0.03	A/µs
Soft Start Time	t _{SSYMXPA}				ms
No Load		-	0.5	-	
Full Load		-	2.0	-	
Turn Off Time	t _{YMXPAOFF}	-	1.0	-	ms
Switching Frequency	f _{SWYMXPA}	-	2.0	-	MHz
VOTG ELECTRICAL CHARACTERISTICS					
Transient Load Speed of Change	I _{OTG} /t	-	-	0.03	A/µs
Soft Start Time	t _{SSOTG}				ms
No Load		-	0.5	-	
Full Load		-	2.0	-	
Turn Off Time	t _{OTGOFF}	-	1.0	-	ms
Switching Frequency	f _{SWOTG}	-	2.0	-	MHz
VBKLT ELECTRICAL CHARACTERISTICS	<u>т т</u>		T		1
Soft Start Time	t _{SSBKLT}	-	2.0	-	ms
Switching Frequency	f _{SWBKLT}	-	2.0	-	MHz

Table 4. Dynamic Electrical Characteristics

Characteristic	Symbol	Min	Тур	Мах	Unit
VBG ELECTRICAL CHARACTERISTICS	· ·		·	•	
Transient Load Speed of Change	I _{BG} /t	-	-	0.001	A/µs
Soft Start Time (Enable to output voltage ramp up from 0 to 1.0 V)	t _{SSBG}	-	-	20	μs
Turn Off Time (OFF to output voltage ramp down to 0 V)	t _{BGOFF}	-	-	5.0	ms
VCCA ELECTRICAL CHARACTERISTICS					
Transient Load Speed of Change	I _{CCA} /t	-	-	0.01	A/µs
Soft Start Time (Enable to output voltage ramp up from 0 to 1.5 V)	t _{SSCCA}	-	-	30	μs
Turn Off Time (OFF to output voltage ramp down to 0 V)	t _{CCAOFF}	-	-	5.0	ms
VCC180 ELECTRICAL CHARACTERISTICS					•
Transient Load Speed of Change	I _{CC180} /t	-	-	1	A/µs
Soft Start Time (Enable to output voltage ramp up from 0 to 1.8 V)	t _{SSCC180}	-	-	30	μs
Turn Off Time (OFF to output voltage ramp down to 0 V)	t _{CC1800FF}	-	-	5.0	ms
VPNL18 ELECTRICAL CHARACTERISTICS					
Transient Load Speed of Change	I _{PNL18} /t	-	-	0.1	A/µs
Soft Start Time (Enable to output voltage ramp up from 0 to 1.8 V)	t _{SSPNL18}	-	-	140	μs
Turn Off Time (OFF to output voltage ramp down to 0 V)	t _{PNL180FF}	-	-	5.0	ms
VPMIC ELECTRICAL CHARACTERISTICS					•
Transient Load Speed of Change	I _{PMIC} /t	-	-	0.01	A/µs
Soft Start Time (Enable to output voltage ramp up from 0 to 1.8 V)	t _{SSPMIC}	-	-	700	μs
Turn Off Time (OFF to output voltage ramp down to 0 V)	t _{PMICOFF}	-	-	5.0	ms
VYMXYFI18 ELECTRICAL CHARACTERISTICS					•
Transient Load Speed of Change	I _{YMXYFI18} /t	-	-	0.1	A/µs
Soft Start Time (Enable to output voltage ramp up from 0 to 1.8 V)	t _{SSYMXYFI18}	-	-	200	μs
Turn Off Time (OFF to output voltage ramp down to 0 V)	t _{YMXYFI180FF}	-	-	5.0	ms
VYMXYFI ELECTRICAL CHARACTERISTICS					•
Transient Load Speed of Change	I _{YMXYFI} /t	-	-	0.01	A/µs
Soft Start Time (Enable to output voltage ramp up from 0 to 1.0 V for WiFiBT applications and 0 to 1.8 V for WiMAX applications)	t _{SSYMXYFI}				μs
WiFiBT Applications		-	-	20	
WiMAX Applications		-	-	35	
Turn Off Time (OFF to output voltage ramp down to 0 V)	t _{YMXYFIOFF}	-	-	5.0	ms
VYMXGPS ELECTRICAL CHARACTERISTICS					
Transient Load Speed of Change	I _{YMXGPS} /t	-	-	0.01	A/µs
Soft Start Time (Enable to output voltage ramp up from 0 to 1.0 V for WiMAX applications and 0 to 1.8 V for GPS applications)	t _{SSYMXGPS}				μs
WiMAX Applications		-	-	15	
GPS Applications		-	-	15	

Table 4. Dynamic Electrical Characteristics

Transient Load Speed of Change I _{CCPAOAC} /t - 0.1 Α/μs Soft Start Time (Enable to output voltage ramp up from 0 to 1.0 V) tsSCCPAOAC - 30 μs Tum Off Time (OFF to output voltage ramp down to 0 V) tsCCPAOACOFF - 5.0 ms VCODDE ELECTRICAL CHARACTERISTICS Transient Load Speed of Change I_CCPDORF - 0.1 A/μs Soft Start Time (Enable to output voltage ramp up from 0 to 1.0 V) tsSCCPDOR - 35 μs YAON ELECTRICAL CHARACTERISTICS - 0.1 A/μs - 5.0 ms YAON ELECTRICAL CHARACTERISTICS - 0.1 A/μs - 0.1 A/μs Soft Start Time (Enable to output voltage ramp up from 0 to 1.0 V) tsSAON - - 25.0 ms Yum Off Time (OFF to output voltage ramp up from 0 to 1.0 V) tsSAON - - 5.0 ms Yum Off Time (DFF to output voltage ramp up from 0 to 1.2 V) tsSAON - - 125 µs Tum Off Time (DFF to output voltage ramp up from 0 to 1.2 V) tsSAM -	Characteristic	Symbol	Min	Тур	Max	Unit
Soft Start Time (Enable to output voltage ramp up from 0 to 1.0 V) USCCPADAC - 30 µs Turn Off Time (CFF to output voltage ramp down to 0 V) IscCPADACOFF - 5.0 ms VCCPDDR ELECTRICAL CHARACTERISTICS Transient Load Speed of Change IscCPDDR/F - 0.1 A/µs Soft Start Time (Enable to output voltage ramp down to 0 V) IssCCPDDR/F - 0.1 A/µs Soft Start Time (Enable to output voltage ramp down to 0 V) IssCCPDDR/F - 0.1 A/µs Soft Start Time (Enable to output voltage ramp down to 0 V) IssCCPDDR/F - 0.1 A/µs Soft Start Time (Enable to output voltage ramp down to 0 V) IssCCPDDR/F - 0.1 A/µs Soft Start Time (Enable to output voltage ramp down to 0 V) IssCCPD IssCCP - 5.0 ms VMM ELECTRICAL CHARACTERISTICS Transient Load Speed of Change IssCCPT IsSCCP - 125 µs Turn Off Time (OFF to output voltage ramp down to 0 V) IssCCPT IsSCCP - 0.01 A/µs Soft Start Time (Enable to output voltage ramp down to 0 V) IssCCPT IsSCCP -	VCCPAOAC ELECTRICAL CHARACTERISTICS					
Turn Off Time (CFF to output voltage ramp down to 0 V) t_CCPADACOFF - 5.0 ms VCCPDDR ELECTRICAL CHARACTERISTICS Transient Load Speed of Change t_OCPDDR/t - 3.5 µs Soft Start Time (Enable to output voltage ramp down to 0 V) t_SSCCPDDR - 3.5 µs YAON ELECTRICAL CHARACTERISTICS - 0.1 A/µs Soft Start Time (Enable to output voltage ramp down to 0 V) t_SSCCPDDR/F - 5.0 ms YAON ELECTRICAL CHARACTERISTICS - 0.1 A/µs Soft Start Time (Enable to output voltage ramp down to 0 V) t_SSCCP - 5.0 ms VMM ELECTRICAL CHARACTERISTICS - 0.01 A/µs Soft Start Time (Enable to output voltage ramp down to 0 V) t_SSMM - - 12.5 µs Transient Load Speed of Change I_MM/t - - 0.01 A/µs Soft Start Time (Enable to output voltage ramp down to 0 V) t_SSMM - - 12.5 µs Transient Load Speed of Change I_MC2P/t - 0.1 A/µs <t< td=""><td>Transient Load Speed of Change</td><td>I_{CCPAOAC}/t</td><td>-</td><td>-</td><td>0.1</td><td>A/µs</td></t<>	Transient Load Speed of Change	I _{CCPAOAC} /t	-	-	0.1	A/µs
VCCPDDR ELECTRICAL CHARACTERISTICS Incremental construction Incremental construction Transient Load Speed of Change I_CCPDDR/I - 0.1 A/µs Soft Start Time (Enable to output voltage ramp up from 0 to 1.0 V) ItsSCCPDDR - - 35 µs YAON ELECTRICAL CHARACTERISTICS Transient Load Speed of Change I_AOW/I - - 0.1 A/µs Soft Start Time (Enable to output voltage ramp up from 0 to 1.0 V) ItsSADN - - 25 µs Transient Load Speed of Change I_AOW/I - - 0.1 A/µs Soft Start Time (Enable to output voltage ramp up from 0 to 1.0 V) ItsSADN - - 5.0 ms VIM ELECTRICAL CHARACTERISTICS Transient Load Speed of Change I_MM2F - - 0.01 A/µs Soft Start Time (Enable to output voltage ramp up from 0 to 1.2 V) ItsSADM - - 5.0 ms VIM2E ELECTRICAL CHARACTERISTICS Transient Load Speed of Change I_CCP/I - - 5.0 ms Tum Off Time (Enable to output voltage ramp u	Soft Start Time (Enable to output voltage ramp up from 0 to 1.0 V)		-	-	30	μs
Transient Load Speed of Change I _{CCPDDR} /t - 0.1 A/μs Soft Start Time (Enable to output voltage ramp up from 0 to 1.0 V) IsSCCPDDR - 35 μs Turn Off Time (OFF to output voltage ramp down to 0 V) IsCPDDROFF - - 5.0 ms VAON ELECTRICAL CHARACTERISTICS Transient Load Speed of Change I_AON/t - - 25 μs Soft Start Time (Enable to output voltage ramp down to 0 V) ItesSANON - - 25.0 ms Yum Off Time (OFF to output voltage ramp down to 0 V) ItesSANON - - 25.0 ms YUM ELECTRICAL CHARACTERISTICS Transient Load Speed of Change IsoNOFF - 0.01 A/μs Soft Start Time (Enable to output voltage ramp up from 0 to 1.2 V) ItesSMM - - 125 μs Turn Off Time (OFF to output voltage ramp up from 0 to 1.0 V) ItesSecCP - - 5.0 ms VIGCP ELECTRICAL CHARACTERISTICS Transient Load Speed of Change IssNC2CP - 2.6 μs Turn Off Time (OFF to output voltage ramp	Turn Off Time (OFF to output voltage ramp down to 0 V)	t _{CCPAOACOFF}	-	-	5.0	ms
Soft Start Time (Enable to output voltage ramp up from 0 to 1.0 V) IssCCPDDR - 35 Just Tum Off Time (OFF to output voltage ramp down to 0 V) IsSCCPDDROFF - - 5.0 ms VAON ELECTRICAL CHARACTERISTICS Transient Load Speed of Change I_AOWI - - 0.1 A/µs Soft Start Time (Enable to output voltage ramp down to 0 V) IsSANOFF - - 2.5 µs Tum Off Time (OFF to output voltage ramp down to 0 V) IsSANOFF - - 5.0 ms VMM ELECTRICAL CHARACTERISTICS Transient Load Speed of Change I_MMYI - - 0.01 A/µs Soft Start Time (OFF to output voltage ramp up from 0 to 1.2 V) IsSMM - - 12.5 µs Tum Off Time (OFF to output voltage ramp up from 0 to 1.0 V) IsSCCP - - 5.0 ms VIMG2S ELECTRICAL CHARACTERISTICS Transient Load Speed of Change IsSCCP - - 5.0 ms Tum Off Time (OFF to output voltage ramp up from 0 to 2.5 V) IsSIM225 - - 20.0 µs	VCCPDDR ELECTRICAL CHARACTERISTICS					
Turn Off Time (OFF to output voltage ramp down to 0 V) LocPODROFF - 5.0 ms VAON ELECTRICAL CHARACTERISTICS Transient Load Speed of Change I _{AON} /t - - 0.1 A/µs Soft Start Time (Enable to output voltage ramp up from 0 to 1.0 V) IssAON - - 25 µs Turn Off Time (OFF to output voltage ramp up from 0 to 1.0 V) IsSAON - - 5.0 ms VMM ELECTRICAL CHARACTERISTICS Transient Load Speed of Change I _{MM} /t - 0.01 A/µs Soft Start Time (Enable to output voltage ramp up from 0 to 1.2 V) IsSMM - - 125 µs Turn Off Time (OFF to output voltage ramp down to 0 V) IsSMM - - 125 µs Turn Off Time (OFF to output voltage ramp down to 0 V) IsSMMOFF - 0.01 A/µs Soft Start Time (Enable to output voltage ramp up from 0 to 1.0 V) IsSMCPF - 0.1 A/µs Soft Start Time (CFF to output voltage ramp down to 0 V) IcCPOFF - 0.01 A/µs Soft Start Time (OFF to output voltage ramp down to 0 V)	Transient Load Speed of Change	I _{CCPDDR} /t	-	-	0.1	A/µs
VAON ELECTRICAL CHARACTERISTICS IAON/I - - 0.1 A/µs Soft Start Time (Enable to output voltage ramp up from 0 to 1.0 V) Issaon - 25 µs Turn Off Time (OFF to output voltage ramp up from 0 to 1.0 V) Issaon - 25 µs Turn Off Time (OFF to output voltage ramp up from 0 to 1.0 V) Issaon - 25 µs Transient Load Speed of Change Issaon - - 5.0 ms Soft Start Time (Enable to output voltage ramp up from 0 to 1.2 V) Issaon - 125 µs Turn Off Time (OFF to output voltage ramp down to 0 V) Ussond - 5.0 ms VCCP ELECTRICAL CHARACTERISTICS Transient Load Speed of Change Iccp/t - - 0.1 A/µs Soft Start Time (Enable to output voltage ramp up from 0 to 1.0 V) ItsscccP - 26 µs Turn Off Time (OFF to output voltage ramp up from 0 to 2.5 V) Itssind255 - 200 µs Turn Off Time (OFF to output voltage ramp up from 0 to 2.5 V) Itssind226 - 5.0 ms	Soft Start Time (Enable to output voltage ramp up from 0 to 1.0 V)	t _{SSCCPDDR}	-	-	35	μs
Transient Load Speed of Change I _{AON} /t - 0.1 A/μs Soft Start Time (Enable to output voltage ramp up from 0 to 1.0 V) IssAON - - 25 μs Turn Off Time (OFF to output voltage ramp down to 0 V) tsAONOFF - - 5.0 ms VMM ELECTRICAL CHARACTERISTICS Transient Load Speed of Change I _{MM} /t - - 125 μs Soft Start Time (Enable to output voltage ramp up from 0 to 1.2 V) tsSMM - - 125 μs Turn Off Time (OFF to output voltage ramp down to 0 V) tyMMOFF - 0.01 A/μs Soft Start Time (Enable to output voltage ramp down to 0 V) tyMMOFF - 0.1 A/μs Soft Start Time (CFF to output voltage ramp up from 0 to 1.0 V) tsSCCP - 2.6 μs Turn Off Time (OFF to output voltage ramp up from 0 to 2.5 V) tsSIM225 - 2.00 μs Turn Off Time (OFF to output voltage ramp down to 0 V) tyMG25 - 2.00 μs Turn Off Time (OFF to output voltage ramp down to 0 V) tyMG26 - 5.0 <td< td=""><td>Turn Off Time (OFF to output voltage ramp down to 0 V)</td><td>t_{CCPDDROFF}</td><td>-</td><td>-</td><td>5.0</td><td>ms</td></td<>	Turn Off Time (OFF to output voltage ramp down to 0 V)	t _{CCPDDROFF}	-	-	5.0	ms
Soft Start Time (Enable to output voltage ramp up from 0 to 1.0 V) t_SSAON - 25 μs Tum Off Time (OFF to output voltage ramp down to 0 V) t_SSAON - - 5.0 ms VMM ELECTRICAL CHARACTERISTICS Transient Load Speed of Change I_MM/1 - 0.01 A/μs Soft Start Time (Enable to output voltage ramp up from 0 to 1.2 V) t_SSMM - - 5.0 ms VCCP ELECTRICAL CHARACTERISTICS Transient Load Speed of Change I_LCP/t - 0.01 A/μs Soft Start Time (Enable to output voltage ramp up from 0 to 1.2 V) t_SSMM - - 5.0 ms VCCP ELECTRICAL CHARACTERISTICS Transient Load Speed of Change I_LCP/t - 0.1 A/μs Soft Start Time (Enable to output voltage ramp up from 0 to 1.0 V) t_SSOCP - 2.6 μs Tum Off Time (OFF to output voltage ramp up from 0 to 2.5 V) t_SSIMG25 - 2.00 μs Transient Load Speed of Change I_MG25/t - - 5.0 ms VIM225 ELECTRICAL CHARACTERISTICS Transient Load Speed of	VAON ELECTRICAL CHARACTERISTICS					
Turn Off Time (OFF to output voltage ramp down to 0 V) t _{AONOFF} - 5.0 ms YMM ELECTRICAL CHARACTERISTICS Transient Load Speed of Change I _{MM} /t - 0.01 A/μs Soft Start Time (Enable to output voltage ramp up from 0 to 1.2 V) t _{SSMM} - - 125 μs Turn Off Time (OFF to output voltage ramp down to 0 V) t _{MMOFF} - - 5.0 ms VCCP ELECTRICAL CHARACTERISTICS Transient Load Speed of Change I _{CCP} /t - 0.1 A/μs Soft Start Time (Enable to output voltage ramp up from 0 to 1.0 V) t _{SSCCP} - 2.6 μs Turn Off Time (OFF to output voltage ramp up from 0 to 2.5 V) t _{SSIMC25} - 5.0 ms VIM225 ELECTRICAL CHARACTERISTICS Transient Load Speed of Change I _{IMC25} /t - 0.01 A/μs Soft Start Time (Enable to output voltage ramp up from 0 to 2.5 V) t _{SSIMC25} - 2.00 μs Turn Off Time (OFF to output voltage ramp up from 0 to 2.9 V) t _{IMC25} /t - - 5.0 ms VIM282 ELECTRICAL CHARACTERISTICS Tr	Transient Load Speed of Change	I _{AON} /t	-	-	0.1	A/µs
VMM ELECTRICAL CHARACTERISTICS Transient Load Speed of Change I _{MM} /t - - 0.01 A/μs Soft Start Time (Enable to output voltage ramp down to 0 V) t _{SSMM} - - 125 µs Turn Off Time (OFF to output voltage ramp down to 0 V) t _{MMOFF} - - 5.0 ms VCCP ELECTRICAL CHARACTERISTICS Transient Load Speed of Change I _{CCP} /t - - 0.1 A/µs Soft Start Time (Enable to output voltage ramp down to 0 V) t _{SSCCP} - - 2.6 µs Transient Load Speed of Change I _{CCP} /t - 0.1 A/µs Soft Start Time (Enable to output voltage ramp down to 0 V) t _{SSCCP} - 5.0 ms VIMG25 ELECTRICAL CHARACTERISTICS Transient Load Speed of Change I _{IMG29} /t - - 0.01 A/µs Soft Start Time (Enable to output voltage ramp down to 0 V) t _{IMG250FF} - - 0.01 A/µs Soft Start Time (Enable to output voltage ramp up from 0 to 2.5 V) t _{SSIMG28} - - 0.01 A/µs <td>Soft Start Time (Enable to output voltage ramp up from 0 to 1.0 V)</td> <td>t_{SSAON}</td> <td>-</td> <td>-</td> <td>25</td> <td>μs</td>	Soft Start Time (Enable to output voltage ramp up from 0 to 1.0 V)	t _{SSAON}	-	-	25	μs
Transient Load Speed of Change I _{MM} /t - 0.01 A/μs Soft Start Time (Enable to output voltage ramp up from 0 to 1.2 V) t _{SSMM} - - 125 μs Turn Off Time (OFF to output voltage ramp down to 0 V) t _{MMOFF} - - 5.0 ms VCCP ELECTRICAL CHARACTERISTICS Transient Load Speed of Change I _{CCP} /t - - 0.1 A/μs Soft Start Time (Enable to output voltage ramp up from 0 to 1.0 V) t _{SSCCP} - - 2.6 μs Turn Off Time (OFF to output voltage ramp down to 0 V) t _{CCPOFF} - - 5.0 ms VIMG25 ELECTRICAL CHARACTERISTICS Transient Load Speed of Change I _{IMG29} /t - - 0.01 A/μs Soft Start Time (Enable to output voltage ramp down to 0 V) t _{SSIMC25} - - 2.00 μs Turn Off Time (OFF to output voltage ramp down to 0 V) t _{MG250FF} - - 5.0 ms VIMG28 ELECTRICAL CHARACTERISTICS Transient Load Speed of Change I _{IMG29} /t - - 0.1 A/μs	Turn Off Time (OFF to output voltage ramp down to 0 V)	t _{AONOFF}	-	-	5.0	ms
Soft Start Time (Enable to output voltage ramp up from 0 to 1.2 V) Item Model Item M	VMM ELECTRICAL CHARACTERISTICS					
Turn Off Time (OFF to output voltage ramp down to 0 V) t_MMOFF - 5.0 ms VCCP ELECTRICAL CHARACTERISTICS - 5.0 ms Transient Load Speed of Change I _{CCP} /t - 0.1 A/µs Soft Start Time (Enable to output voltage ramp up from 0 to 1.0 V) t _{SSCCP} - 2.6 µs Turn Off Time (OFF to output voltage ramp down to 0 V) t _{CCPOFF} - 5.0 ms VIMG25 ELECTRICAL CHARACTERISTICS - 0.01 A/µs Soft Start Time (Enable to output voltage ramp up from 0 to 2.5 V) t _{SSIMG25} - 2.00 µs Turn Off Time (OFF to output voltage ramp down to 0 V) t _{IMG26/T} - 0.01 A/µs Soft Start Time (Enable to output voltage ramp up from 0 to 2.5 V) t _{SSIMG26} - 2.00 µs Turn Off Time (OFF to output voltage ramp down to 0 V) t _{IMG29} /t - - 5.0 ms VIM625 ELECTRICAL CHARACTERISTICS - 0.1 A/µs Soft Start Time (Enable to output voltage ramp down to 0 V) t _{IMG29} /t - - 5.0 ms	Transient Load Speed of Change	I _{MM} /t	-	-	0.01	A/µs
VCCP ELECTRICAL CHARACTERISTICSI I CCP/L0.1A/µsSoft Start Time (Enable to output voltage ramp up from 0 to 1.0 V) t_{SSCCP} 26µsTurn Off Time (OFF to output voltage ramp down to 0 V) t_{CCPOFF} 26µsVIMG25 ELECTRICAL CHARACTERISTICSTransient Load Speed of Change I_{IMG25}/t 0.01A/µsSoft Start Time (Enable to output voltage ramp up from 0 to 2.5 V) $t_{SSIMG25}$ 200µsTurn Off Time (OFF to output voltage ramp down to 0 V) $t_{IMG25/FF}$ 5.0msVIMG28 ELECTRICAL CHARACTERISTICSTransient Load Speed of Change I_{IMG28}/t 0.1A/µsSoft Start Time (Enable to output voltage ramp down to 0 V) $t_{IMG280FF}$ 0.1A/µsVIMG28 ELECTRICAL CHARACTERISTICSTransient Load Speed of Change I_{IMG28}/t 0.1A/µsSoft Start Time (Enable to output voltage ramp down to 0 V) $t_{IMG280FF}$ 0.1A/µsVIB ELECTRICAL CHARACTERISTICSTransient Load Speed of Change I_{VIB}/t 0.1A/µsSoft Start Time (Enable to output voltage ramp up from 0 to 2.7 V) t_{SSVIB} 0.0µsTurn Off Time (OFF to output voltage ramp up from 0 to 2.7 V) t_{SSVIB} 5.0msVIBELECTRICAL CHARACTERISTICSTransient Load Speed of Change I_{VIB}/t 5.0 </td <td>Soft Start Time (Enable to output voltage ramp up from 0 to 1.2 V)</td> <td>t_{SSMM}</td> <td>-</td> <td>-</td> <td>125</td> <td>μs</td>	Soft Start Time (Enable to output voltage ramp up from 0 to 1.2 V)	t _{SSMM}	-	-	125	μs
Transient Load Speed of Change I_{CCP}/t -0.1 $A/\mu s$ Soft Start Time (Enable to output voltage ramp up from 0 to 1.0 V) t_{SSCCP} -2.6 μs Turn Off Time (OFF to output voltage ramp down to 0 V) t_{CCPOFF} 2.6 μs VIMG25 ELECTRICAL CHARACTERISTICSTransient Load Speed of Change I_{IMG25}/t 0.01 $A/\mu s$ Soft Start Time (Enable to output voltage ramp up from 0 to 2.5 V) $t_{SSIMG25}$ 2.00 μs Turn Off Time (OFF to output voltage ramp down to 0 V) t_{IMG25}/t 5.0msVIMG28 ELECTRICAL CHARACTERISTICSTransient Load Speed of Change I_{IMG28}/t 0.1 $A/\mu s$ Soft Start Time (Enable to output voltage ramp up from 0 to 2.9 V) $t_{SSIMG28}$ 0.1 $A/\mu s$ Soft Start Time (Enable to output voltage ramp up from 0 to 2.9 V) $t_{SSIMG28}$ 0.1 $A/\mu s$ Soft Start Time (Enable to output voltage ramp down to 0 V) $t_{IMG280FF}$ 0.1 $A/\mu s$ VIB ELECTRICAL CHARACTERISTICSTransient Load Speed of Change I_{VIB}/t 0.1 $A/\mu s$ Soft Start Time (Enable to output voltage ramp up from 0 to 2.7 V) t_{SSVIB} 0.1 $A/\mu s$ Soft Start Time (Enable to output voltage ramp down to 0 V) t_{VIBOFF} 0.01 $A/\mu s$ Soft Start Time (Enable to output voltage ramp down to 0 V) t_{VIBOFF} -<	Turn Off Time (OFF to output voltage ramp down to 0 V)	t _{MMOFF}	-	-	5.0	ms
Soft Start Time (Enable to output voltage ramp up from 0 to 1.0 V) t_{SSCCP} -26 μs Turn Off Time (OFF to output voltage ramp down to 0 V) t_{CCPOFF} 26 μs VIMG25 ELECTRICAL CHARACTERISTICSTransient Load Speed of Change I_{IMG25}/t 0.01 $A/\mu s$ Soft Start Time (Enable to output voltage ramp up from 0 to 2.5 V) $t_{SSIMG25}$ 200 μs Turn Off Time (OFF to output voltage ramp down to 0 V) $t_{IMG25OFF}$ 5.0msVIMG28 ELECTRICAL CHARACTERISTICSTransient Load Speed of Change I_{IMG28}/t 0.1 $A/\mu s$ Soft Start Time (Enable to output voltage ramp up from 0 to 2.9 V) $t_{SSIMG28}$ 200 μs Turn Off Time (OFF to output voltage ramp down to 0 V) $t_{IMG28OFF}$ 5.0msVIMEELECTRICAL CHARACTERISTICSTransient Load Speed of Change I_{VIB}/t 0.1 $A/\mu s$ Soft Start Time (Enable to output voltage ramp up from 0 to 2.7 V) t_{SSVIB} 200 μs Turn Off Time (OFF to output voltage ramp up from 0 to 2.7 V) t_{SSVIB} 0.1 $A/\mu s$ Soft Start Time (Enable to output voltage ramp down to 0 V) $t_{VIB/F}$ 5.0msVIBELECTRICAL CHARACTERISTICSTurn	VCCP ELECTRICAL CHARACTERISTICS					
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Transient Load Speed of Change I_{IMG25}/t 0.01 $A/\mu s$ Soft Start Time (Enable to output voltage ramp up from 0 to 2.5 V) $t_{SSIMG25}$ 200 μs Turn Off Time (OFF to output voltage ramp down to 0 V) $t_{IMG250FF}$ 5.0msVIMG28 ELECTRICAL CHARACTERISTICSTransient Load Speed of Change I_{IMG20}/t 0.1 $A/\mu s$ Soft Start Time (Enable to output voltage ramp up from 0 to 2.9 V) $t_{SSIMG28}$ 200 μs Turn Off Time (OFF to output voltage ramp up from 0 to 2.9 V) $t_{SSIMG28}$ 5.0msVIBELECTRICAL CHARACTERISTICSTransient Load Speed of Change I_{VIB}/t 0.1 $A/\mu s$ Soft Start Time (Enable to output voltage ramp up from 0 to 2.7 V) t_{SSVIB} 0.1 $A/\mu s$ Soft Start Time (Enable to output voltage ramp up from 0 to 2.7 V) t_{SSVIB} 0.1 $A/\mu s$ Soft Start Time (Enable to output voltage ramp down to 0 V) t_{VIBOFF} 5.0msVSDIO ELECTRICAL CHARACTERISTICSTransient Load Speed of Change I_{SDIO}/t 0.01 $A/\mu s$ Soft Start Time (Enable to output voltage ramp down to 0 V) t_{VIBOFF} 0.01 $A/\mu s$ Soft Start Time (CFF to output voltage ramp down to 0 V) t_{VIBOFF}	Turn Off Time (OFF to output voltage ramp down to 0 V)	t _{CCPOFF}	-	-	5.0	ms
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Transient Load Speed of Change I_{IMG28}/t 0.1 $A/\mu s$ Soft Start Time (Enable to output voltage ramp up from 0 to 2.9 V) $t_{SSIMG28}$ 200 μs Turn Off Time (OFF to output voltage ramp down to 0 V) $t_{IMG280FF}$ 5.0msVVIB ELECTRICAL CHARACTERISTICSTransient Load Speed of Change I_{VIB}/t 0.1 $A/\mu s$ Soft Start Time (Enable to output voltage ramp up from 0 to 2.7 V) t_{SSVIB} 200 μs Turn Off Time (OFF to output voltage ramp up from 0 to 2.7 V) t_{SSVIB} 200 μs Turn Off Time (OFF to output voltage ramp down to 0 V) t_{VIBOFF} 5.0msVSDIO ELECTRICAL CHARACTERISTICSTransient Load Speed of Change I_{SDIO}/t 0.01 $A/\mu s$ Soft Start Time (Enable to output voltage ramp up from 0 to 1.8 V) t_{SSSDIO} 100 μs Soft Start Time (Enable to output voltage ramp up from 0 to 1.8 V) t_{SSSDIO} 100 μs	Turn Off Time (OFF to output voltage ramp down to 0 V)	t _{IMG250FF}	-	-	5.0	ms
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Transient Load Speed of Change I_{VIB}/t 0.1 $A/\mu s$ Soft Start Time (Enable to output voltage ramp up from 0 to 2.7 V) t_{SSVIB} 200 μs Turn Off Time (OFF to output voltage ramp down to 0 V) t_{VIBOFF} 5.0msVSDIO ELECTRICAL CHARACTERISTICSTransient Load Speed of Change I_{SDIO}/t 0.01 $A/\mu s$ Soft Start Time (Enable to output voltage ramp up from 0 to 1.8 V) t_{SSSDIO} 100 μs	Turn Off Time (OFF to output voltage ramp down to 0 V)	t _{IMG280FF}	-	-	5.0	ms
Soft Start Time (Enable to output voltage ramp up from 0 to 2.7 V) t_{SSVIB} 200 μs Turn Off Time (OFF to output voltage ramp down to 0 V) t_{VIBOFF} 5.0msVSDIO ELECTRICAL CHARACTERISTICSTransient Load Speed of Change I_{SDIO}/t 0.01 $A/\mu s$ Soft Start Time (Enable to output voltage ramp up from 0 to 1.8 V) t_{SSSDIO} 100 μs	VVIB ELECTRICAL CHARACTERISTICS					
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Transient Load Speed of Change I _{SDIO} /t - 0.01 Α/μs Soft Start Time (Enable to output voltage ramp up from 0 to 1.8 V) t _{SSSDIO} - - 100 μs	Turn Off Time (OFF to output voltage ramp down to 0 V)	t _{VIBOFF}	-	-	5.0	ms
Soft Start Time (Enable to output voltage ramp up from 0 to 1.8 V) t _{SSSDIO} 100 µs	VSDIO ELECTRICAL CHARACTERISTICS					
	Transient Load Speed of Change	I _{SDIO} /t	-	-	0.01	A/µs
Turn Off Time (OFF to output voltage ramp down to 0 V) t _{SDIOOFF} - - 5.0 ms	Soft Start Time (Enable to output voltage ramp up from 0 to 1.8 V)	tsssdio	-	-	100	μs
	Turn Off Time (OFF to output voltage ramp down to 0 V)	t _{SDIOOFF}	-	-	5.0	ms

Table 4. Dynamic Electrical Characteristics

Characteristic	Symbol	Min	Тур	Max	Unit
POWER SWITCHES ELECTRICAL CHARACTERISTICS					
Ramp Up Time	-	-	-	50	μs
LCD BACKLIGHT DRIVERS (WLED) ELECTRICAL CHARACTERISTICS					
PWM Frequency (Register Setting)	f _{PWM}	128	-	8192	Hz
PWM Frequency Accuracy	-	-10	-	10	%
PWM Duty Cycle Resolution	-	-	-	8.0	Bit
Backlight string minimum on time	-	-	2.0	-	S
PWM Duty Cycle Accuracy	-	-0.3	-	0.3	%
CAMERA SCENE ILLUMINATION DRIVERS ELECTRICAL CHARACTERIST	ICS				
PWM Frequency	f _{PWM}	-	256	-	Hz
PWM Frequency Accuracy	-	-10	-	10	%
PWM Duty Cycle Resolution	-	-	-	3.0	Bit
POWER PATH MANAGER PLUS LI-ION CHARGER ELECTRICAL CHARAC	TERISTICS		-		
Input Over-voltage Protection Threshold Response Time (M_{OVPCHG} FET OFF)	t _{OVP}	-	2.0	5.0	μs
Trickle Charge Threshold Filter Time	-	-	32	-	ms
EOC Detect Threshold Filter Time	-	-	1.0	-	ms
ADC ELECTRICAL CHARACTERISTICS		-	•		-
Conversion Time Per Channel	-	-	-	10	μS
Turn on/off Time				31	μS

FUNCTIONAL DESCRIPTION

GENERAL DESCRIPTION

The 900841 is a high efficiency Power Management Integrated Circuit(PMIC), incorporating a Li-Ion battery charger. It is optimized for Ultra-mobile platforms of which Mobile Internet Devices(MID) are representative. Other enduser applications include but are not limited to Netbooks, Tablets, Slates, and Smartphones.

The 900841 PMIC, along with the companion chip 900842, is designed for optimum partitioning, as an integral part of Freescale's power management solution to meet the needs of Ultra-mobile platforms. Optimum partitioning, high feature integration, and state of the art technology, enable Freescale to support Ultra-mobile platforms that are cost effective, by reducing component count and board area. The Freescale solution also allows ease of system design, resulting in a faster time to market development cycle.

It accepts input from commonly available single-cell Li-Ion (Li+) or Li-Polymer battery, and delivers regulated power to various components (CPU, chip sets, wireless, memory, storage, display, sensors, and others) on Ultra-mobile platforms.

SWITCHERS+3 x2 x VID4.0 MHz SwitchingHig	17 x LDO EGULATORS x Power Switch Low Noise gh Performance ator Motor Driver	LED DRIVERS with RGB control 2 x RGB Banks Duty Cycle Control	BATTERY MANAGEMENT Li-Ion/Li-Polymer Switching CC / CV, Wall/USB Up to 1.6 A Charging Power Path management Coulomb Counter
Advanced Audio Pa 16 bit Voice CODEC (>85 24 bit Audio DAC (100 dB SNR, Microphone Support (Handset-H Class A Line-out Amp Class AB Earpiece Am Class AB Headset Am	dB SNR) , < 0.1% THD) leadset-Digital) lifier plifier	Freescale,Ä Ultra-mobile Platform PMIC Solution	22 Channel 10 bit ADC Battery Vitals Monitoring PMIC Temp Monitoring 4-Wire Resistive Touch Screen Select Rails Current Monitoring General Purpose Inputs
500 mW into 8.0 ohm Class D Loud Headset Detection PCM / I ² S (Voice and A	lspeaker Amplifier	RTC 32.768 kHz Xtal Oscillator	5.0 V DC/DC Boost USB OTG Bus Isolation Switch
Control Interface 8 Interrupt Capable GPIOs 4 Platform Switch Con SPI Interface + Status and Control	s / GPOs ntrol	Power Control Logic State Machine	High Voltage DC / DC Boost LCD Backlight (3p5s) Scene Illumination (1p5s) Adaptive Boost

Figure 2. Freescale's Ultra-mobile Platform Power Management Solution High Level Block Diagram

FEATURE LIST

- Complete system power management, battery charging and audio support integrated in a single chip reducing board space and component count
- · Ultra-mobile platform Architecture Support
- Audio System Capabilities:
 - PCM / I²S (Voice & Audio) All formatting and flexibility including automatic sample rate detection in slave mode
 - 16 bit Voice CODEC (>85 dB SNR)
 - 24 bit Audio DAC (100 dB SNR, <0.1%THD)
 - · Microphone Support

- Handset with bias / Headset with bias and detection / Digital with clock

- Stereo Line Inputs
- Single ended outputs Class A Line-Out Amplifier - 2.0 V_{PP} into 10 k Ω
- Battery supplied Class AB Ear piece Amplifier with differential outputs
 - 4.0 V_{PP} into 32 Ω
- Single ended output Class AB Headset Amplifier with negative charge pump for capacitor less headset coupling
 - 20 mWrms typical per channel
 - Headset insertion/stereo detection circuit

900841

FUNCTIONAL DESCRIPTION GENERAL DESCRIPTION

- 500 mW into 8.0 Ω Class-D Loudspeaker Amplifier with differential outputs
- Fully Programmable DC/DC Switching, Low Drop-Out Regulators, and Load Switches
 - Delivers regulated reliable power to various system components
 - High efficiency multi mode power conversion ensuring extended battery life
 - Fully programmable with extensive protection features and complete fault reporting for best in class overall system reliability
 - Internal Compensation
 - 6 Buck DC/DC Regulators
 - 2x VID Controlled with 1.0 MHz switching and external switches for CPU and Graphics core support
 - 4x with 4.0 MHz switching and integrated switches for system support and LDO supply for optimized thermal performance and power efficiency
 - 3 Boost DC/DC Regulators (Non-Synchronous with integrated low side switch)
 - High voltage boost regulator for backlight support
 - 5.0 V boost regulator for RGB LED supply and OTG Host Mode support
 - 4.2 V boost regulator for WiMAX PA supply support
 - 17 Low Drop-Out (LDO) regulators including a vibrator motor regulator
 - 1 configurable LDO/Switch regulator for SDIO card support
 - Three 3.3 V load switches for system support

- Power Path Management & Switching Mode Li-Ion/Li-Polymer Battery Charger
 - Efficient switching Li-Ion battery charger allowing for reduced power dissipation and reduced charge time
 - Power path management that allows power to the system even in the absence of the battery through an external power supply
 - Programmable options for various charging parameters
 - · Charger input over-voltage protection
 - · Battery vitals monitoring/reporting/protecting
 - Coin Cell Backup battery charger
- LCD Backlight support with up to 15 LEDs (3p5s)
- Camera Scene Illumination support (1p5s)
- 2xRGB banks LED drivers with optimized LED control
- SPI interface supporting Ultra-mobile Platform architecture (up to 25 MHz operation)
- 22-channel (32 capable) 10-bit ADC for internal and external sensing with touch screen interface
- · Low power 32.786 kHz XTAL oscillator.
- Real Time Clock (RTC) to provide time reference and alarm functions with wake up control.
- 8 Interrupt capable GPIOs and 8 GPOs
- 4 GPOs for controlling platform switches
- Various control and status reporting I/Os
- Interrupt and Reset controller. All interrupt signals can be masked.
- Overall solution size target of < 900 mm² (including clearance and routing)
- Operating temperature of -40°C to +85°C

INTERNAL BLOCK DIAGRAM



Figure 3. Functional Block Diagram

PIN OUT DESCRIPTION AND BALL MAP

Refer to Pin Description for a detailed list of pins and ball assignments. The ball map of the package is given in

<u>Figure 4</u> as a top view. The BGA footprint on the application PCB will have the same mapping as given in <u>Figure 4</u>.

	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20	21	22	23	24	25	26	27	28	29
А	NC1		NC1		PVIN1P5		FBCCP		SDATA		PVIN2P1		VOUT PNL18		SPICLK		REFD		GND LSPR		GND LSPL		HSL		REFB		NC2		NC2
в		NC1		VOUTCC PAOAC		LDO REFP8		CS		VOUT PMIC		VOUT CC180		VCORE		PMICINT		VINLSPR		VYMX3G EN		LSPLP		HSR		REFA		NC2	
с	NC1		VOUT CCA		PVIN1P5		VOUT AON		VOUT CCP		PVIN2P1		VCORE REF		RESETB		LSPRP		VYMXPA EN		VINLSPL		RXINR						NC2
D		VOUTBG		VIDEN0		PVIN1P8								SPICSB				LSPRM		LSPLM								CPC2	
E	VID2		VID0		VIDEN1		FBCCA																		CPOUT		GNDCP		CPC1
F		VID6		VID4																								CPIN	
G	CSPCC		SWFBCC				FBCC PDDR		VOUTCC PDDR		PWRBTN		LDO REFP9		MOSI		THERM TRIPB		VYMX GPSEN		GND AUD4		GND AUD1				AUD XTAL		GNDAUD XTAL
н		LSCCGT		LSCCGT				VID1		GND1P5		SCK		GND CORE		VRCOMP		GNDSUB		RXINL		GNDSUB				CLK26M		RX2	
L	PGNDCC		PGNDCC				VID5		VID3		VOUTMM		VCORE DIG		MISO		EXITSTB Y		GNDSUB		GNDSUB		GNDSUB		-		FS2		BCL2
к		HSCCGT		HSCCGT				VOUT FBCC														TX1				TX2		BCL1	
L	HSNNGT		PVINNN		PVINCC		PVINCC		PGNDNN		GNDREF VCC		GNDSPI		SPIVCC		GNDSUB		GNDSUB		GND AUD2		RX1		I2SVCC		FS1		SPM
м		LSNNGT		VOUT FBNN		PGND DDQ		PGND DDQ				GND2P1		GNDSUB		PWRGD		GNDSUB				MCCLK						GNDSP	
N	SWDDQ		SWDDQ		PGND DDQ		PGND DDQ		SWFBNN		CSPNN		GND1P8		GNDSUB		GNDSUB		GNDSUB		MC2IN		MC2B				VINSP		SPP
Ρ		SWDDQ		SWDDQ		PVINDDQ		PVINDDQ				GNDSUB		GNDSUB		GNDSUB		GNDSUB				MC1IN				MC1B		RXOUTR	
R	PGND YMX3G		PGND YMX3G		PVINDDQ		PVINDDQ		FBDDQ		GNDSUB		GNDSUB		GNDSUB		GNDSUB		GND AUD3		RXOUTL		ICTEST				LEDB2		GNDLED
т		SWYMX 3G		SWYMX 3G		PVINYMX 3G		PVINYMX 3G				GNDSUB		GNDSUB		GNDSUB		GNDSUB				GNDSUB				LEDG2		LEDR1	
U	PGND21		PGND21		PGND21		REFGND SW		FBYMX 3G		GNDSUB		GNDSUB		GNDSUB		GNDSUB		GNDSUB		OTGGTIN		LEDG1		LEDR2		SWOTG		SWOTG
v		SW21		SW21		SW21		FB21				GNDSUB		GNDIMG		GNDADC		GNDSUB				LEDB1		FBOTG		PGND OTG		PGND OTG	
w	PVIN21		PVIN21		PVIN21		FB15				GND COMS2		FB YMXPA		ADIN20		TSREF		V33STTS		OTGGT		FBBKLT		LEDSCN		SWBKLT		SWBKLT
Y		PGND15		PGND15		PGND15		GPO4								I						WLED3				PGND BKLT		PGND BKLT	
AA	SW15		SW15		SW15		GND COMS1		GPOSW0		GPIO3		YMXPA GTIN		YMXPA GT		ADIN13		REV PCHGGT		GNDBAT		V3GPA EN		V3GPA STTS		WLED1		WLED2
AB		PVIN15		PVIN15		PVIN15		GPO7		GPIO1		SDIOGT		GND CTRL		ADIN11		GPI06		V33EN		CFP				VPWR		GND BKLT	
AC	PVIN YMXGPS	0.01	VOUT YMXGPS		1		GPO1		GPOSW VCC		GPIOVCC		FBSDIO		ADIN21		ADIN15		GPIO4		REFGND CHG		NTC		CHGBYP GT		VBAT		COIN CELL
AD	VOUT	PVIN YMXYFI1 8		GPO2		1				1		PGND YMXPA								1		PVINCHG				ISNS BATP		CFM	
AE	YMXYFI1 8		PVINYMX YFI		GPOVCC						SW YMXPA		r				ADIN14				OVPCHG GT		ISNSINP		LSCHG GT		CHGGT		VNTC
AF		VOUTYM XYFI		GPO0		GPOSW1		i		i		PGND YMXPA				ı.		XTAL2		GPI05		PVINCHG		HSCHG GT		PGND CHG		ISNS BATN	
AG	NC3		GPO3		GPO6		GPI00		VOUT PNL33		SW YMXPA		PVINVIB		VOUT IMG28		ADIN16		XTAL1		GPIO7		RAW CHG		LSCHG GT		ISNSINN		NC4
AH		NC3		GPO5		GPOSW3		VOUT GP33		VOUTYM XGPS33		PGND YMXPA		VOUT IMG25	_	ADIN19		ADIN17		ADIN10		CLK32K		HSCHG GT		PGND CHG		NC4	
AJ	NC3		NC3		GPOSW2		GPIO2		PVIN3P3		SW YMXPA		VOUTVIB		PVINIMG		ADIN18		ADIN12		GNDRTC		V33ISNS		SWFB CHG		NC4		NC4

Figure 4. SC900841 Package Ball Map (Top view)

PIN DESCRIPTION

The Type Column indicates the maximum average current through each ball assigned to the different nodes, 500 mA

maximum for HIPWR, 300 mA maximum for MDPWR, and 100 mA maximum for LOPWR

Node Name	Туре	I/O	Rating	# of Balls	BGA Location	Pin Description
	-	VC	C - (0.65 \	/-1.2 V) / :	3.5 A VID CPU BUC	CK with External FETs
PVINCC	HIPWR	-	4.8 V	2	L5, L7	Gate Drivers Power Supply Input
HSCCGT	HIPWR	-	4.8 V	2	K2, K4	High Side FET Gate Drive
LSCCGT	HIPWR	-	4.8 V	2	H2, H4	Low Side FET Gate Drive
PGNDCC	HIPWRGND	-	-	2	J1, J3	Local Ground for Internal Circuitry
VOUTFBCC	SGNL	I	4.8 V	1	K8	Output Voltage Sensing Input and Negative Current Sens Terminal
SWFBCC	SGNL	I	3.6 V	1	G3	Switch Node Feedback
CSPCC	SGNL	Ι	3.6 V	1	G1	Positive Current Sense Terminal
		VN	N - (0.65 V	/-1.2 V) / '	1.6 A VID CPU BUC	CK with External FETs
PVINNN	HIPWR	-	4.8 V	1	L3	Gate Drivers Power Supply Input
HSNNGT	HIPWR	-	4.8 V	1	L1	High Side FET Gate Drive
LSNNGT	HIPWR	-	4.8 V	1	M2	Low Side FET Gate Drive
PGNDNN	HIPWRGND	-	-	1	L9	Local Ground for Internal Circuitry
VOUTFBNN	SGNL	I	4.8 V	1	M4	Output Voltage Sensing Input and Negative Current Sens
SWFBNN	SGNL	Ι	3.6 V	1	N9	Switch Node Feedback
CSPNN	SGNL	Ι	3.6 V	1	N11	Positive Current Sense Terminal
			I	VDD	Q - 1.8 V / 1.3 A BI	nck
PVINDDQ	HIPWR	-	4.8 V	4	P6, P8, R5, R7	Power Supply Input
SWDDQ	HIPWR	-	4.8 V	4	N1, N3, P2, P4	Switch Node
PGNDDDQ	HIPWRGND	-	-	4	M6, M8, N5, N7	Power Ground
FBDDQ	SGNL	Ι	3.6 V	1	R9	Output Voltage Feedback Input
			1	V2	1 - 2.1 V / 1.0 A BU	ск
PVIN21	HIPWR	-	4.8 V	3	W1, W3, W5	Power Supply Input
SW21	HIPWR	-	4.8 V	3	V2, V4, V6	Switch Node
PGND21	HIPWRGND	-	-	3	U1, U3, U5	Power Ground
FB21	SGNL	Ι	3.6 V	1	V8	Output Voltage Feedback Input
			I	V15 - 1.	5 V (or 1.6 V) / 1.5 /	ABUCK
PVIN15	HIPWR	-	4.8 V	3	AB2, AB4, AB6	Power Supply Input
SW15	HIPWR	-	4.8 V	3	AA1, AA3, AA5	Switch Node
PGND15	HIPWRGND	-	-	3	Y2, Y4, Y6	Power Ground
FB15	SGNL	I	3.6 V	1	W7	Output Voltage Feedback Input
			1	V33	Interface (SC9008	342)
V33EN	SGNL	0	2.5 V	1	AB20	V33 Enable output pin
V33STTS	SGNL	I	2.5 V	1	W19	V33 Status input pin. Active low when V33 output is on
V33ISNS	SGNL	I	2.5 V	1	AJ23	Input Interface with the ADC to measure V33 output current



Node Name	Туре	I/O	Rating	# of Balls	BGA Location	Pin Description
	II.	V	YMX3G -	(YMX: 1.:	25 V or 3G: 0.6 V-1.3	375 V) / 1.0 A BUCK
PVINYMX3G	HIPWR	-	4.8 V	2	Т6, Т8	Power Supply Input
SWYMX3G	HIPWR	-	4.8 V	2	T2, T4	Switch Node
PGNDYMX3G	HIPWRGND	-	-	2	R1, R3	Power Ground
FBYMX3G	SGNL	Ι	3.6 V	1	U9	Output Voltage Feedback Input
			I	VYM	XPA - 4.2 V / 0.7 A B	Boost
SWYMXPA	HIPWR	-	5.5 V	3	AE11, AG11, AJ11	Switch Node
PGNDYMXPA	HIPWRGND	-	-	3	AD12, AF12, AH12	Power Ground
FBYMXPA	SGNL	Ι	5.5 V	1	W13	Output Voltage Feedback Input
YMXPAGTIN	MDPWR	-	5.5 V	1	AA13	Gate Drive Input for VYMXPA isolation FET
YMXPAGT	MDPWR	-	5.5 V	1	AA15	Gate Driver for external switch if output isolation is required
	ll.		1	V3G	PA Interface (Reser	ved)
V3GPAEN	SGNL	0	2.5 V	1	AA23	V3GPA Enable output pin. Reserved
V3GPASTTS	SGNL	I	2.5 V	1	AA25	V3GPA Status input pin. Reserved
	L.		I	VOT	G - 5.0 V / 0.35 A Bo	post
SWOTG	HIPWR	-	5.5 V	2	U27, U29	Switch Node
PGNDOTG	HIPWRGND	-	-	2	V26, V28	Power Ground
FBOTG	SGNL	Ι	5.5 V	1	V24	Output Voltage Feedback Input
OTGGTIN	MDPWR	-	5.5 V	1	U21	Gate Drive Input for VOTG Isolation FET
OTGGT	MDPWR	-	5.5 V	1	W21	Gate Driver for external switch if output isolation is required
		VBKL	T - 5s3p (I	Backligh	t) and 5s1p (Camera	a Scene) / 120 mA Boost
SWBKLT	HIPWR	-	26 V	2	W27, W29	Switch Node
PGNDBKLT	HIPWRGND	-	-	2	Y26, Y28	Power Ground
FBBKLT	SGNL	I	26 V	1	W23	Output Voltage Feedback Input
	1		I		3G - 1.25 V/2 mA LD CA - 1.5 V/150 mA L	
PVIN1P8	LOPWR	-	3.6 V	1	D6	Power Supply Input, shared by VBG and VCCA
GND1P8	GND	-	-	1	N13	Ground Reference
VOUTBG	LOPWR	-	2.5 V	1	D2	VBG Output Voltage Node
VOUTCCA	LOPWR	-	2.5 V	1	C3	VCCA Output Voltage Node
FBCCA	SGNL	Ι	2.5 V	1	E7	VCCA Output Voltage Feedback Input

Node Name	Туре	I/O	Rating	# of Balls	BGA Location	Pin Description							
	VCC180- 1.8 V/390 mA LDO VPNL18- 1.8 V/225 mA LDO VPMIC - 1.8 V/50 mA LDO												
PVIN2P1	HIPWR	-	3.6 V	2	A11, C11	Power Supply Input, shared by VCC180, VPNL18, and VPMIC							
GND2P1	GND	-	-	1	M12	Ground Reference							
VOUTCC180	HIPWR	-	2.5 V	1	B12	VCC180 Output Voltage Node							
VOUTPNL18	MDPWR	-	2.5 V	1	A13	VPNL18 Output Voltage Node							
VOUTPMIC	LOPWR	-	2.5 V	1	B10	VPMIC Output Voltage Node							
I		١	YMXYFI1	8 - (YMX:	1.8 V/200 mA - YFI	:1.8 V/200 mA) LDO							
PVINYMXYFI18	MDPWR	-	4.8 V	1	AD2	Power Supply Input for VYMXYFI18							
VOUTYMXYFI18	MDPWR	-	3.6 V	1	AE1	VYMXYFI18 Output Voltage Node							
GNDCOMS1	GND	-	-	1	AA7	Ground Reference							
GNDCOMS2	GND	-	-	1	W11	Ground Reference							
			VYMXYF	I - (YMX:2	2.5 V/150 mA - YFI:	1.2 V/60 mA) LDO							
PVINYMXYFI	MDPWR	-	4.8 V	1	AE3	Power Supply Input for VYMXYFI							
VOUTYMXYFI	MDPWR	-	3.6 V	1	AF2	VYMXYFI Output Voltage Node							
		\	YMXGPS	- (YMX:1	.3 V/350 mA - GPS	:1.8 V/170 mA) LDO							
PVINYMXGPS	HIPWR	-	4.8 V	1	AC1	Power Supply Input for VYMXGPS							
VOUTYMXGPS	HIPWR	-	3.6 V	1	AC3	VYMXGPS Output Voltage Node							
				VCCP VAC VI	.OAC- 1.05 V/155 m DDR - 1.05 V/60 m/ DN - 1.2 V/250 mA L MM- 1.2 V/5 mA LD P - 1.05 V/445 mA	A LDO LDO IO							
PVIN1P5	HIPWR	-	3.6 V	2	A5, C5	Power Supply Input, shared by VCCPAOAC, VCCPDDR, VAON, VMM, and VCCP							
GND1P5	GND	-	-	1	H10	Ground Reference							
VOUTCCPAOAC	LOPWR	-	2.5 V	1	B4	VCCPAOAC Output Voltage Node							
VOUTCCPDDR	LOPWR	-	2.5 V	1	G9	VCCPDDR Output Voltage Node							
FBCCPDDR	SGNL	I	2.5 V	1	G7	VCCPDDR Output Voltage Feedback Input							
VOUTAON	MDPWR	-	2.5 V	1	C7	VAON Output Voltage Node							
VOUTMM	LOPWR	-	2.5 V	1	J11	VMM Output Voltage Node							
VOUTCCP	HIPWR	-	2.5 V	1	C9	VCCP Output Voltage Node							
FBCCP	SGNL	I	2.5 V	1	A7	VCCP Output Voltage Feedback Input							
			•		G25- 2.5 V/80 mA L G28- 2.8 V/225 mA								
PVINIMG	MDPWR	-	4.8 V	1	AJ15	Power Supply Input, shared by VIMG25 and VIMG28							
GNDIMG	GND	-	-	1	V14	Ground Reference							
VOUTIMG25	LOPWR	-	3.6 V	1	AH14	VIMG25 Output Voltage Node							
VOUTIMG28	MDPWR	-	3.6 V	1	AG15	VIMG28 Output Voltage Node							

Node Name	Туре	I/O	Rating	# of Balls	BGA Location	Pin Description
				٧١	/IB - xV/200 mA LI	00
PVINVIB	MDPWR	-	4.8 V	1	AG13	Power Supply Input for VVIB and Reference Generation. This must always be connected to VPWR.
VOUTVIB	MDPWR	-	3.6 V	1	AJ13	VVIB Output Voltage Node
		1	L	VGP	33 - 3.3 V/100 mA 3 33 - 3.3 V/60 mA S PS33 - 3.3 V/60 mA	witch
PVIN3P3	MDPWR	-	3.6 V	1	AJ9	Power Supply Input, shared by VPNL33, VGP33, VYMXGPS33 and VSDIO
VOUTPNL33	LOPWR	-	3.6 V	1	AG9	VPNL33 Output Voltage Node
VOUTGP33	LOPWR	-	3.6 V	1	AH8	VPG33 Output Voltage Node
VOUTYMXGPS33	LOPWR	-	3.6 V	1	AH10	VYMXGPS33 Output Voltage Node
	ļ	1	VSDIO	3.3 V/21	5 mA Switch OR 1	.8 V/215 mA LDO
SDIOGT	LOPWR	-	3.6 V	1	AB12	Gate Driver Output for VSDIO pass FET
FBSDIO	SGNL	-	3.6 V	1	AC13	Feedback node when VSDIO is in Switch mode; Output voltage node when VSDIO is in LDO mode.
	I				Internal Supplies	
VCORE	LOPWR	-	3.6 V	1	B14	Internal Supply Output Voltage Node
VCOREDIG	LOPWR	-	1.5 V	1	J13	Internal Supply Output Voltage Node
VCOREREF	LOPWR	-	3.6 V	1	C13	Internal BandGap Supply Output Voltage Node
LDOREFP8	LOPWR	-	3.6 V	1	B6	Internal Divided Down BandGap Supply Output Voltage Node dedicated for LDOs
LDOREFP9	LOPWR	-	3.6 V	1	G13	Internal Divided Down BandGap Supply Output Voltage Node dedicated for LDOs
GNDCORE	LOPWRGND	-	-	1	H14	Ground for Internal Supplies
					Audio Bus	
I2SVCC	LOPWR	-	3.6 V	1	L25	Supply Voltage to the I2S Bus
BCL1	SGNL	I/O	3.6 V	1	K28	Bit clock for audio bus 1. Input in slave mode, output in master mode
FS1	SGNL	I/O	3.6 V	1	L27	Frame synchronization clock for audio bus 1. Input in slave mode, output in master mode.
RX1	SGNL	I	3.6 V	1	L23	Receive Data for audio bus 1
TX1	SGNL	0	3.6 V	1	K22	Transmit data for audio bus 1
BCL2	SGNL	I/O	3.6 V	1	J29	Bit clock for audio bus 2. Input in slave mode, output in master mode
FS2	SGNL	I/O	3.6 V	1	J27	Frame synchronization clock for audio bus 2. Input in slave mode, output in master mode.
RX2	SGNL	I	3.6 V	1	H28	Receive Data for audio bus 2
TX2	SGNL	0	3.6 V	1	K26	Transmit data for audio bus 2

Node Name	Туре	I/O	Rating	# of Balls	BGA Location	Pin Description
		1			Audio Transmit	-
MC1B	LOPWR	-	3.6 V	1	P26	Handset primary/right and secondary/left microphone bias supply
MC2B	LOPWR	-	3.6 V	1	N23	Headset microphone bias supply with integrated bias resistor and headset microphone detect
MC1IN	SGNL	I	3.6 V	1	P22	Handset primary or right microphone amplifier input. Requires external DC blocking capacitor
MC2IN	SGNL	I	3.6 V	1	N21	Headset microphone input. Requires external DC blocking capacitor
MCCLK	SGNL	0	3.6 V	1	M22	Digital MIC Clock output
RXINR	LOPWR	-	3.6 V	1	C23	Analog Audio Input R
RXINL	LOPWR	-	3.6 V	1	H20	Analog Audio Input L
					Audio Receive	
VINLSPR	MDPWR	-	5.5 V	1	B18	Handset speaker-phone or alert differential power amplifier supply input, Right Channel
VINLSPL	MDPWR	-	5.5 V	1	C21	Handset speaker-phone or alert differential power amplifier supply input, Left Channel
LSPRP	MDPWR	-	5.5 V	1	C17	Handset speaker-phone or alert differential power amplifier positive terminal, Right Channel
LSPRM	MDPWR	-	5.5 V	1	D18	Handset speaker-phone or alert differential power amplifier minus terminal, Right Channel
LSPLP	MDPWR	-	5.5 V	1	B22	Handset speaker-phone or alert differential power amplifier positive terminal, Left Channel
LSPLM	MDPWR	-	5.5 V	1	D20	Handset speaker-phone or alert differential power amplifier minus terminal, Left Channel
VINSP	LOPWR	-	5.5 V	1	N27	Handset ear piece supply input
SPP	LOPWR	-	5.5 V	1	N29	Handset ear piece speaker differential amplifier output positive terminal
SPM	LOPWR	-	5.5 V	1	L29	Handset ear piece speaker differential power amplifier output minus terminal
GNDSP	LOPWRGND	-	-	1	M28	Ground Handset ear piece speaker
GNDLSPR	MDPWRGND	-	-	1	A19	Ground for Handset speaker-phone or alert differential power amplifier, Right Channel
GNDLSPL	MDPWRGND	-	-	1	A21	Ground for Handset speaker-phone or alert differential power amplifier, Left Channel
RXOUTL	LOPWR	-	4.8 V	1	R21	Analog Line Out, Left Channel
RXOUTR	LOPWR	-	4.8 V	1	P28	Analog Line Out, Right Channel
HSL	LOPWR	-	2.5 V	1	A23	Headset output to left channel ear piece
HSR	LOPWR	-	2.5 V	1	B24	Headset output to right channel ear piece
CPIN	LOPWR	-	3.6 V	1	F28	Negative Charge Pump Supply input and supply input to headset amplifier
CPC1	LOPWR	-	5.5 V	1	E29	Negative Charge Pump Capacitor Connection 1
CPC2	LOPWR	-	4.8 V	1	D28	Negative Charge Pump Capacitor Connection 2

Node Name	Туре	I/O	Rating	# of Balls	BGA Location	Pin Description
CPOUT	LOPWR	-	6.6 V	1	E25	Negative Charge Pump Output
GNDCP	LOPWRGND	-	-	1	E27	Ground for negative charge pump
	I			A	Audio 26 MHz Cloc	k
AUDXTAL	SGNL	I/O	2.5 V	1	G27	26 MHz Oscillator crystal connection 1
GNDAUDXTAL	GND	-	-	1	G29	26 MHz Oscillator crystal connection 2
CLK26M	SGNL	0	2.5 V	1	H26	26 MHz Oscillator clock output
	I				Audio Other	
REFA	LOPWR	-	1.5 V	1	B26	Reference for audio amplifiers
REFB	LOPWR	-	1.5 V	1	A25	Reference for low noise audio bandgap
REFD	LOPWR	-	1.5 V	1	A17	Reference for stereo DAC
GNDAUD1	GND	-	-	1	G23	Ground for audio circuitry 1 (analog)
GNDAUD2	GND	-	-	1	L21	Ground for audio circuitry 2 (analog)
GNDAUD3	GND	-	-	1	R19	Ground for audio circuitry 3 (analog)
GNDAUD4	GND	-	-	1	G21	Ground for audio circuitry 4 (analog)
	I				Lighting System	
WLED1	LOPWR	-	26 V	1	AA27	Backlight String #1 Current Feedback Input
WLED2	LOPWR	-	26 V	1	AA29	Backlight String #2 Current Feedback Input
WLED3	LOPWR	-	26 V	1	Y22	Backlight String #3 Current Feedback Input
LEDSCN	LOPWR	-	26 V	1	W25	Camera Scene Illumination LED driver output 1
GNDBKLT	GND	-	-	1	AB28	Ground for Backlight and Camera Scene LED drivers
LEDR1	LOPWR	-	5.5 V	1	T28	Tricolor red LED driver output 1
LEDG1	LOPWR	-	5.5 V	1	U23	Tricolor green LED driver output 1
LEDB1	LOPWR	-	5.5 V	1	V22	Tricolor blue LED driver output 1
LEDR2	LOPWR	-	5.5 V	1	U25	Tricolor red LED driver output 2
LEDG2	LOPWR	-	5.5 V	1	T26	Tricolor green LED driver output 2
LEDB2	LOPWR	-	5.5 V	1	R27	Tricolor blue LED driver output 2
GNDLED	GND	-	-	1	R29	Ground for RGB LED drivers
				:	Switching Charger	r
RAWCHG	MDPWR	-	20 V	1	AG23	Charger Input Voltage Detection Node
OVPCHGGT	MDPWR	-	20 V	1	AE21	Charger Input Over-voltage Protection FET Gate Drive
REVPCHGGT	MDPWR	-	20 V	1	AA19	Charger Input Reverse Current Protection FET Gate Drive
ISNSINP	SGNL	I	5.5 V	1	AE23	Charger Input Current Sensing Positive Terminal
ISNSINN	SGNL	Ι	5.5 V	1	AG27	Charger Input Current Sensing Negative Terminal
PVINCHG	HIPWR	-	5.5 V	2	AD22, AF22	Charger Buck Stage Input Voltage Node
HSCHGGT	HIPWR	-	5.5 V	2	AF24, AH24	Charger Buck High Side FET Gate Drive
SWFBCHG	SGNL	Ι	5.5 V	1	AJ25	Charger Buck Switch Node Feedback

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Node Name	Туре	I/O	Rating	# of Balls	BGA Location	Pin Description
LSCHGGT	HIPWR	-	5.5 V	2	AE25, AG25	Charger Buck Low Side FET Gate Drive
PGNDCHG	HIPWRGND	-	-	2	AF26, AH26	Charger Buck Stage Power Ground
VPWR	MDPWR	-	4.8 V	1	AB26	Charger Buck Output Voltage Sense Node and Main Input for System Supplies.
CHGGT	MDPWR	-	4.8 V	1	AE27	Charger FET Gate Drive
CHGBYPGT	MDPWR	-	4.8 V	1	AC25	Charger Bypass FET Gate Drive
ISNSBATP	SGNL	Ι	4.8 V	1	AD26	Battery/Charging Current Sensing Input Point 1
ISNSBATN	SGNL	I	4.8 V	1	AF28	Battery/Charging Current Sensing Input Point 2, Coulomb Counter Sensing Input Point 1
CFP	LOPWR	-	4.8 V	1	AB22	Accumulated Current Filter Capacitor Plus Terminal
CFM	LOPWR	-	4.8 V	1	AD28	Accumulated Current Filter Capacitor Minus Terminal
VBAT	LOPWR	-	4.8 V	1	AC27	Battery Voltage Sensing Input, Coulomb Counter Sensing Input Point 2
GNDBAT	LOPWRGND	-	-	1	AA21	Kelvin Sensing Connection To The Battery Ground
VNTC	LOPWR	-	3.6 V	1	AE29	Bias voltage for NTC resistor stack
NTC	SGNL	I	3.6 V	1	AC23	NTC connection node
	-	1	I	1	Coin Cell Charger	
COINCELL	LOPWR	-	3.6 V	1	AC29	Coin cell Supply Input, Coin cell Charger Output
					ADC + TS I/F	
ADIN10	SGNL	Ι	4.8 V	1	AH20	ADC Generic Input 1, Used as Touchscreen Input X1, TSX1
ADIN11	SGNL	I	4.8 V	1	AB16	ADC Generic Input 2, Used as Touchscreen Input X2, TSX2
ADIN12	SGNL	I	4.8 V	1	AJ19	ADC Generic Input 3, Used as Touchscreen Input Y1, TSY1
ADIN13	SGNL	I	4.8 V	1	AA17	ADC Generic Input 4, Used as Touchscreen Input Y2, TSY2
ADIN14	SGNL	I	4.8 V	1	AE17	ADC Generic Input 5
ADIN15	SGNL	I	4.8 V	1	AC17	ADC Generic Input 6
ADIN16	SGNL	I	4.8 V	1	AG17	ADC Generic Input 7
ADIN17	SGNL	I	4.8 V	1	AH18	ADC Generic Input 8
ADIN18	SGNL	I	4.8 V	1	AJ17	ADC Generic Input 9
ADIN19	SGNL	I	4.8 V	1	AH16	ADC Generic Input 10
ADIN20	SGNL	I	4.8 V	1	W15	ADC Generic Input 11
ADIN21	SGNL	I	4.8 V	1	AC15	ADC Generic Input 12
TSREF	LOPWR	-	3.6 V	1	W17	Reference for Touchscreen interface
GNDADC	LOPWRGND	-	-	1	V16	Ground Reference for ADC
			. (Oscillato	r and Real Time Cl	lock - RTC
XTAL1	SGNL	Ι	2.5 V	1	AG19	32.768 kHz Oscillator crystal connection 1
XTAL2	SGNL	0	2.5 V	1	AF18	32.768 kHz Oscillator crystal connection 2
CLK32K	SGNL	0	3.6 V	1	AH22	32 kHz Clock output
GNDRTC	GND	-	-	1	AJ21	Ground for the RTC block

Node Name	Туре	I/O	Rating	# of Balls	BGA Location	Pin Description
			Ultra-mo	bile Plat	form Architecture	Sideband Signals
PMICINT	SGNL	0	2.5 V	1	B16	PMIC Interrupt. Asserted by PMIC to wake Platform controller hub and begin communications. Level-sensitive, read to clear.
VRCOMP	SGNL	0	2.5 V	1	H16	Voltage Regulator Complete. Asserted high by the PMIC when a SPI voltage regulation request has been decoded. The signal is de-asserted on completion of the request (i.e. the rail is in regulation).
RESETB	SGNL	0	2.5 V	1	C15	Active low hard reset for Platform controller hub. When asserted, Platform controller hub should return to its initial default state.
PWRGD	SGNL	0	2.5 V	1	M16	POWER GOOD: SC900841 asserts this signal to indicate that all power rails to Platform controller hub are good. Assertion of PWRGD also means that VCCA_OSC has been valid for at least 30 microseconds. The Platform Controller Hub will remain "off" until this signal is asserted.
EXITSTBY	SGNL	I	2.5 V	1	J17	EXIT Standby. When asserted, SC900841 exits the AOAC Standby settings for regulating the platform supplies. When asserted SC900841 switches VRs on which are defined in registers 0x09 through 0x0D. This is a low latency VR context switch.
THERMTRIPB	SGNL	I	1.5 V	1	G17	Thermal trip. Asserted by the CPU to indicate a catastrophic thermal event.
VIDEN0	SGNL	I	1.5 V	1	D4	Driven by the CPU to indicate which VR the VID bus is
VIDEN1	SGNL	I	1.5 V	1	E5	addressed to (VCC or VNN). Debounced inside SC900841 for 150 ns. The CPU will hold the value for at least 300 ns.
VID0	SGNL	I	1.5 V	1	E3	
VID1	SGNL	I	1.5 V	1	H8	-
VID2	SGNL	I	1.5 V	1	E1	Driven by the CPU to indicate the output voltage setting for
VID3	SGNL	I	1.5 V	1	J9	the VCC and VNN rails. Debounced inside SC900841 for
VID4	SGNL	I	1.5 V	1	F4	-150 ns. The CPU will hold the value for at least 300 ns.
VID5	SGNL	I	1.5 V	1	J7	
VID6	SGNL	I	1.5 V	1	F2	-
VYMXGPSEN	SGNL	I	2.5 V	1	G19	Enable Input signal for the VYMXGPS rail. Asserted by the communications subsystem to enable a supply voltage with minimal latency.
VYMXPAEN	SGNL	I	2.5 V	1	C19	Enable Input signal for the VYMXPA rail. Asserted by the communications subsystem to enable a supply voltage with minimal latency.
VYMX3GEN	SGNL	I	2.5 V	1	B20	Enable Input signal for the VYMX3G rail. Asserted by the communications subsystem to turn on/off a supply voltage with minimal latency.
GNDCTRL	GND	-	-	1	AB14	Logic Control Ground

Node Name	Туре	I/O	Rating	# of Balls	BGA Location	Pin Description
			I	I	SPI Interface	
SPIVCC	LOPWR	-	3.6 V	1	L15	Supply for SPI Bus and Audio Bus
SPICLK	SGNL	I	3.6 V	1	A15	SPI Clock Input
MOSI	SGNL	I	3.6 V	1	G15	SPI Write Input
MISO	SGNL	0	3.6 V	1	J15	SPI Read Output
SPICSB	SGNL	I	3.6 V	1	D14	SPI Chip Select Input
GNDSPI	GND	-	-	1	L13	Ground for SPI Interface
	I		I	I	Mini SPI Interface	
SDATA	SGNL	I	3.6 V	1	A9	Mini SPI Bus Data In
SCK	SGNL	I	3.6 V	1	H12	Mini SPI Bus Clock
CS	SGNL	I	3.6 V	1	B8	Mini SPI Bus Chip Select
			GPI	Os & GP	OSWs & GPOs & F	ower Button
GPIOVCC	LOPWR	-	3.6 V	1	AC11	GPIO Power
GPIO0	SGNL	I/O	3.6 V	1	AG7	
GPI01	SGNL	I/O	3.6 V	1	AB10	-
GPIO2	SGNL	I/O	3.6 V	1	AJ7	
GPIO3	SGNL	I/O	3.6 V	1	AA11	Fully Configurable GPIO inputs/outputs for general purpose
GPIO4	SGNL	I/O	3.6 V	1	AC19	sensing and platform control
GPIO5	SGNL	I/O	3.6 V	1	AF20	-
GPIO6	SGNL	I/O	3.6 V	1	AB18	_
GPI07	SGNL	I/O	3.6 V	1	AG21	-
GPOSWVCC	MDPWR	-	5.5 V	1	AC9	GPOSW Power
GPOSW0	MDPWR	-	5.5 V	1	AA9	
GPOSW1	MDPWR	-	5.5 V	1	AF6	
GPOSW2	MDPWR	-	5.5 V	1	AJ5	- Gating Signals for Discrete Platform VR Switches
GPOSW3	MDPWR	-	5.5 V	1	AH6	
GPOVCC	LOPWR	-	3.6 V	1	AE5	GPO Power
GPO0	SGNL	0	3.6 V	1	AF4	
GPO1	SGNL	0	3.6 V	1	AC7	1
GPO2	SGNL	0	3.6 V	1	AD4	
GPO3	SGNL	0	3.6 V	1	AG3	
GPO4	SGNL	0	3.6 V	1	Y8	General Purpose Outputs
GPO5	SGNL	0	3.6 V	1	AH4	
GPO6	SGNL	0	3.6 V	1	AG5	1
GPO7	SGNL	0	3.6 V	1	AB8	
PWRBTN	SGNL	I	5.5 V	1	G11	PMIC Hardware On/Off Button

Node Name	Туре	I/O	Rating	# of Balls	BGA Location	Pin Description				
Test Pin										
ICTEST	SGNL	I	7.5 V	1	R23	IC Test Mode enable input				
L			L		Substrate Ground					
REFGNDCHG	GND	-	-	1	AC21	Dedicated Reference Ground for the Switching Charger				
REFGNDSW	GND	-	-	1	U7	Dedicated Reference Ground for the Switching Regulators				
GNDREFVCC	GND	-	-	1	L11	Dedicated Reference Ground for VCC regulator				
GNDSUB	GND	-	-	32	H18, H22, J19, J21, J23, L17, L19, M14, M18, N15, N17, N19, P12, P14, P16, P18, R11, R13, R15, R17, T12, T14, T16, T18, T22, U11, U13, U15, U17, U19, V12, V18	Substrate Ground				

11. The Type Column indicates the maximum average current through each ball assigned to the different nodes. 500 mA maximum for HIPWR, 300 mA maximum for MDPWR, and 100 mA maximum for LOPWR

FUNCTIONAL DEVICE OPERATION

SYSTEM CONTROL INTERFACE

OVERVIEW

This section addresses the various interfaces and I/Os between the PMIC solution and the rest of the system.

System control interface includes the following:

- SPI interface: This is the serial communications interface between the 900841 and the System Control Unit (SCU) in the platform controller hub.
- Communications (COMMs) Module Interface: This is the interface between the various basic and advanced communication modules, and the PMIC solution. It consists of two components:
 - · A Serial Communications port (Mini-SPI): This port goes to the 900841 PMIC, which houses the digital core supply of the COMMs module.
 - · Dedicated I/O signals for direct COMMs control of the PMIC solution.
- Interrupt controller
- Sideband signals: These are I/O signals between the 900841 and the Ultra-mobile Platform architecture for control and status reporting.
- I²S Bus Interface for Audio/Voice
- Freescale chip set communications signals: This includes control and status reporting signal between the 900841 and the companion chip, 900842 in Freescale's power management solution.
- · Special registers

SPI INTERFACE

The 900841 contains a SPI interface port, which allows a host controller to access the register set. Using these registers, 900841 resources can be controlled. The registers provide information on the PMIC status, as well as information on external signals.

The addressable register map spans 1024 registers of 8 data bits each. The map is not fully populated. A detailed structure of the register set along with bit names, positions, and basic descriptions, are given in Table 116. Expanded bit descriptions are included in the individual functional sections for application guidance.

Note that not all bits are truly writable. Refer to the individual sub-circuit descriptions and the Table 116 to determine the read/write capability of each bit.

Pin Name	SPI Functionality
SPICLK	SPI Clock Input (up to 25 MHz)
MOSI	Master Out / Slave In (Serial Data In)
MISO	Master In / Slave Out (Serial Data Out)
SPICSB	Chip Select (Active Low)
SPIVCC	SPI Bus Supply - 1.8 V typical

Table 6. SPI Interface Pin Functionality

The Platform controller hub is the master, while the PMIC is the slave. The SPI interface operates at a typical frequency of 12.5 MHz, and at a maximum frequency of 25 MHz, with lower speeds supported.

The SPI interface is configured in mode 1: clock polarity is active high (CPOL = 0), and data is latched on the falling edge of clock (CPHA = 1). The chip select signal, SPICSB, is active low. The SPICSB line must remain active during the entire SPI transfer. The MISO line will be tri-stated while SPICSB is high.

The SPI frame consists of 24 bits: a Read/Write bit, a 10bit address code (MSB first), 5 "dead" bits and 8 data bits (also MSB first). The Read/Write bit selects whether the SPI transaction is a read or a write: for a write operation, the R/W bit must be a one: for a read operation, it must be a zero.

For a read transaction, any data on the MOSI pin after the address bits is ignored. The MISO pin will output the data field pointed to by the 10-bit address loaded at the beginning of the SPI sequence. SPI read backs of the address field and unused bits are returned as zero. For read operations, the PMIC supports address auto-increment.

For a write operation, once all the data bits are written, the data is transferred into the registers on the falling edge of the 24th clock cycle. All unused SPI bits in each register must be written to a zero.

To start a new SPI transfer, the SPICSB line must go inactive and then active again. After the LSB of data is sent, if the SPICSB line is held low, up to seven additional address/ data packets may be sent as writes to the PMIC. Refer to the VRCOMP Pin section.

The following diagrams illustrate the SPI Write Protocol, SPI Read Protocol, and SPI Timing.



Figure 5. SPI Read from PMIC Diagram (One Address/Data Packet shown)

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FUNCTIONAL DEVICE OPERATION SYSTEM CONTROL INTERFACE



COMMS MODULE INTERFACE

The 900841 supports the following communication modules:

- 1. Basic COMMs: WiFi, Bluetooth (BT), and GPS. The basic COMMs subsystem is present on all Ultra-mobile Platforms.
- 2. Advanced COMMs: WiMax and 3G options.

The 900841 provides a set of pins to enable/disable the voltage rails that support the Advanced COMMs module(s): VYMXGPS, VYMXPA, and VYMX3G.

Table 7. COMMs Modules Interface Pin Functionality

Pin Name	Pin Functionality
VYMXGPSEN	Enable Input signal for the VYMXGPS rail. Only applicable when the VYMXGPS rail is set to the 1.3 V option.
VYMXPAEN	Enable Input signal for the VYMXPA rail. Only applicable when the VYMXPA rail is set to the 4.2V option.
VYMX3GEN	Enable Input signal for the VYMX3G rail

The Advanced COMMs rails can be controlled either by hardware or software. If a software control is desired, the enable input signal must always be active, and the internal SPI register is used to turn on/off the output voltage. If hardware control is desired, the internal SPI register must be configured to turn on the voltage rail, and the ENABLE pin is used to enable/disable the voltage rail. <u>Table 8</u> shows the control logic of the Advanced COMMs rails. For a voltage rail to be active, both the SPI register setting and the ENABLE pin must be active.

Table 8. COMMs Modules Interface Pins vs. Control Registers

Signal	Register Setting	Rail Output
OFF (Low)	OFF	OFF
OFF (Low)	ON	OFF
ON (High)	OFF	OFF
ON (High)	ON	ON

Each enable pin includes an internal pull-down resistor. If the pin is left open, the enable signal will be asserted low by the internal pull-down, and the voltage rail will be inactive.

The enable signals follow the DC signaling specifications in <u>Table 3</u> with a reference of 1.8 V (VPMIC).

Advanced COMMs Serial Interface

The advanced COMMs module interfaces with the 900841 through a simple serial interface, referred to as the "Mini-SPI" in this document. This interface is used to control the output voltage levels of the Advanced COMMs rails and has the following characteristics:

- SPI maximum clock speed is 10 MHz
- · SPI interface consists of 16-bit word
- MSB Bit 15 is sent first followed by MSB-1 and so forth.
- SPI configured with rising-edge clock where data is sampled on the rising edge of clock
- CS (Chip Select) indicates when the master starts SPI data exchange. It is also used to reset the SPI slave so that

it is ready to receive the next word. This improves the noise immunity of the system.

- Next five bits, SDATA[15:11] are dedicated to core voltage levels
- Following five bits, SDATA[10:6] are reserved
- Last six bits, SDATA[5:0] are unused. These bits are read as zeroes
- Changes to core supply voltage levels are applied only after receiving all 16-bits of data

The VYMX3G output voltage is determined by bits 11 through 15 as follows:

 VYMX3G =0.6V+ 0.025*{2^4*SDATA[15] + 2^3*SDATA[14] + 2^2*SDATA[13] + 2^1*SDATA[12] + SDATA[11]}

Table 9. Advanced COMMs Mini-SPI Pin Functionality

Pin Name	Pin Functionality
SDATA	Advanced COMMs SPI Bus Data In
SCK	Advanced COMMs SPI Bus Clock Input
CS	Advanced COMMs SPI Bus Chip Select Input

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Figure 8. Mini-SPI Architecture and Simplified Timing Diagram

INTERRUPT CONTROLLER

Control

The PMIC informs the system of important events using interrupts. Unmasked interrupt events are signaled to the host by driving the PMICINT pin high.

Each interrupt is latched so that even if the interrupt source becomes inactive, the interrupt will remain set until cleared. If a new interrupt occurs while the controller clears an existing interrupt bit, the interrupt line will remain high.

Each interrupt can be masked by setting the corresponding mask bit to a '1'. As a result, when a masked interrupt bit goes high, the interrupt line will not go high. A masked interrupt can still be read from the register. If a masked interrupt bit was already high, the interrupt line will go high after unmasking.

The following is the interrupt handling mechanism which has inherent latency that the clients must expect:

- 1. PMIC interrupts SCU, if both the 1st and 2nd level bits are not masked.
- 2. SCU reads PMIC master, 1st level, interrupt event register.

- 3. SCU then traverses all the branches of the interrupt tree where events are indicated.
- 4. SCU will service events in leaf node registers.

When an unmasked interrupt event happens:

- The 2nd level bit is set.
- The 1st level bit is set by a rising edge sent from the 2nd level register, and the PMICINT signal goes from low to high
- When the system controller, the SCU, reads the 1st level register the 2nd level registers that were set, remain set. Any unset registers are free to accept an interrupt event.
- When the 1st level register is read, any 1st level register bits that were set at the point the SPI read strobe shifts the register value into the SPI transmit shift register, that bit will be cleared by the SPI self clear signal immediately following the read strobe. This allows new interrupts to be recorded without being lost. If all unmasked 1st level bits get cleared by the read, the PIMCINT pin will de-assert. If a new unmasked 1st level interrupt event happens, just after the read of the 1st level register, the PIMCINT pin interrupt pin will remain asserted. The SCU reads each 2nd level register and these are cleared on read.

 When the 2nd level register is read, any 2nd level register bits that were set at the point the SPI read strobe sweeps, the register value into the SPI transmit shift register, that bit will be cleared by the SPI self clear signal immediately following the read strobe. This allows new interrupts to be recorded without being lost. If a new unmasked 2nd level interrupt event happens just after the read of the 2nd level register, the PMICINT pin will assert if the 1st level bit is not masked.

Block	Address	Register Name	RW	D7	D6	D5	D4	D3	D2	D1	D0	Initial
IRQ	0x04	INTERRUP T	R	EXT	AUX	VRFAUL T	GPIO	RTC	CHR	ADC	PWRBTN	0x00
IRQ	0x05	INTMASK	R/W	MEXT	MAUX	MVRFAU LT	MGPIO	MRTC	MCHR	MADC	MPWRBT N	0xFA
RTC	0x1C	RTCC	R	IRQF	PF (=0)	AF	UF	RSVD	RSVD	RSVD	RSVD	0x00
POWER	0x30	VRFAULTI NT	R	RSVD	RSVD	RSVD	RSVD	RSVD	VRFAIL	BATOCP	THRM	0x00
POWER	0x31	MVRFAUL TINT	R/W	RSVD	RSVD	RSVD	RSVD	RSVD	MVRFAIL	MBATOC P	MTHRM	0x03
ADC	0x5F	ADCINT	R	RSVD	RSVD	RSVD	RSVD	RSVD	OVERFLO W	PENDET	RND	0x00
ADC	0x60	MADCINT	R/W	RSVD	RSVD	RSVD	RSVD	RSVD	MOVERFL OW	MPENDET	MRND	0x00
CHARGE R	0xD0	CHRGINT	R	USBOV P	DCLMT	BATDET	USBDE T	COMP	TEMP	BATOVP	RSVD	0x00
CHARGE R	0xD1	MCHRGIN T	R/W	MUSBO VP	MDCLM T	MBATDE T	MUSBD ET	MCOMP	MTEMP	MBATOVP	RSVD	0x00
GPIO	0xE8	GPIOINT	R	GPIINT7	GPIINT6	GPIINT5	GPIINT4	GPIINT3	GPIINT2	GPIINT1	GPIINT0	0x00
AUDIO	0X197	AUD24	R	RSVD	RSVD	RSVD	RSVD	HSDET	HPDET	SWMPINT	SWLPINT	0X00
AUDIO	0X198	AUD25	RW	RSVD	RSVD	RSVD	RSVD	MHSDE T	MHPDET	MSWMPI NT	MSWLPIN T	0X0F

Table 10. Interrupt Registers Summary

Notes

12. Because of the design of the clear on read logic, any interrupt event is allowed to happen at any time. If the interrupt event happens close to when a read of the interrupt register happens, if the SPI read captures that interrupt bit as being set, then that bit will get cleared. If the read does not capture the bit as being set, it will not be cleared. In this way no interrupt events are lost.

- 13. The 2nd level interrupts that get "Ored" together to set the 1st level interrupt bits can block other 2nd level interrupts from setting the 1st level interrupt register. This is because if any of the 2nd level interrupts is high, the output of the OR will remain high, blocking the other 2nd level interrupt's rising edge. This should not be a problem. because when the 2nd level register is read, the SCU will see all the bits that are active when it is read. The software will decide which one to service first, just as it needs to do when more than one 1st level interrupt bits are set when that register is read.
- 14. Masking has no affect on interrupt bits being set or cleared. Masking just prevents the interrupt event from asserting the interrupt pin. If an interrupt bit is set, but is masked, the interrupt pin does not assert. If the mask bit is cleared while the bit is still set, the interrupt pin will assert. Most interrupt registers have 1st and 2nd level mask bits. Both mask bits must be in the unmasked state to generate an interrupt to the SCU.
- 15. Some 2nd level interrupt registers are level sensitive. If the level that sets these interrupts registers is active when the register is read, it will clear during the active time of the clear on read signal and then reassert. This will reassert the 1st level interrupt bit.
- 16. The GPIO interrupts do not have interrupt masking bits, they have interrupt prevention bits. This is controlled by bits 5:4 of the GPIO control register. See GPIOs for more details on using the GPIO as interrupt inputs.
- 17. Interrupts generated by external events are de-bounced. Therefore, the event needs to be stable throughout the de-bounce period before an interrupt is generated. Nominal de-bounce periods for each event are documented in <u>Table 11</u>. Due to the asynchronous nature of the de-bounce timer, the effective de-bounce time can vary slightly.

FUNCTIONAL DEVICE OPERATION SYSTEM CONTROL INTERFACE

Interrupt Bit Summary

The following table summarizes all 1st and 2nd level interrupt bits associated with the Interrupt Controller. For

Table 11. Interrupt Bit Summary

more detailed behavioral descriptions, refer to the related sections.

1st Lev	el	2nd Lev	/el	Interment Friend Condition	Detect	Debounce
Name	Bit Name Bit		Bit	Interrupt Event Condition	Detect	time
PWRBTN	D0	-	-	PWRBTN falling edge detection	Falling	10 ms
ADC	D1	RND	D0	ADC Round Robin Cycle Complete	Hi Level	-
		PENDET	D1	Touch Screen Wake-up	Rising	-
		OVERFLOW	D2	Coulomb Counter is > 50% of its full value	Hi level	-
		RSVD	D7:D3	-	-	-
CHR	D2	RSVD	D0	-	-	-
		BATOVP	D1	Battery Over-voltage	Rising/Falling	see note (19)
		TEMP	D2	Battery Temperature Outside Valid Window	Hi Level	1.0 ms
		COMP	D3	Battery Charger Cycle Completion	Rising	1.0 ms
		USBDET	D4	USB Connect/Disconnect	Rising/Falling	10 ms
		BATDET	D5	Battery Connect/Disconnect	Hi Level	0.5 sec
		DCLMT	D6	Input Current Limit Reached	Hi Level	32 ms
		USBOVP	D7	Input Over-voltage Reached	Hi level	10 ms
RTC	D3	RSVD	D3:D0	-	-	-
		UF	D4	Update Cycle	Hi Level	-
		AF	D5	Current Time = Alarm Time	Hi Level	-
		RSVD	D6	-	-	-
		IRQF	D7	IRQF=UIE*UF + AIE*AF	Hi Level	-
GPIO	D4	GPINT0	D0	Edge Detect	Rising/Falling/Both	GPIDBNC0
		GPINT1	D1	Edge Detect	Rising/Falling/Both	GPIDBNC1
		GPINT2	D2	Edge Detect	Rising/Falling/Both	GPIDBNC2
		GPINT3	D3	Edge Detect	Rising/Falling/Both	GPIDBNC3
		GPINT4	D4	Edge Detect	Rising/Falling/Both	GPIDBNC4
		GPINT5	D5	Edge Detect	Rising/Falling/Both	GPIDBNC5
		GPINT6	D6	Edge Detect	Rising/Falling/Both	GPIDBNC6
		GPINT7	D7	Edge Detect	Rising/Falling/Both	GPIDBNC7
VRFAULT	D5	THRM	D0	Junction Temperature > Thermal Warning Threshold	Hi Level	10 ms
		BATOCP	D1	Battery Current > BATOCPSET	Hi Level	BATOCPT
		VRFAIL	D2	Regulator Fault Present	Hi Level	see note ⁽¹⁸⁾
		RSVD	D7:D3	-	-	-
AUX	D6	SWLPINT	D0	Long Button Press Interrupt	Rising	80 ms
		SWMPINT	D1	Momentary Button Press Interrupt	Rising	80 ms
		HPDET	D2	Stereo Headphone Connect/Disconnect	Rising/Falling	30 ms
		HSDET	D3	Stereo Headset Connect/Disconnect	Rising/Falling	30 ms
		RSVD	D7:D4	-	-	-
EXT	D7			Not supported		

Notes

18. Varies by regulator. Normally it is 1.5 times the regulator turn on time.

19. 32 ms rising and 120 μs falling

SIDEBAND SIGNALS

The following pins are included as part of the Sideband signals:

Table 12.	Sidebands	Pin	Functionality
-----------	-----------	-----	---------------

Pin Name	I/O	Pin Functionality
PMICINT	0	Active high PMIC Interrupt Output pin
VRCOMP	0	Active high Voltage Regulator Complete signal
RESETB	0	Active low hard reset for Platform controller hub
PWRGD	0	Active high Power Good Output signal
EXITSTBY	I	Active high Exit Standby signal
THRMTRIPB	I	Active low Thermal Trip Assertion Input signal
VIDEN[1:0]	I	Active high Input signals driven by the CPU, to indicate if the VID bus is addressing VCC or VNN.
VID[6:0]	I	Active high input signals driven by the CPU, to indicate the output voltage setting for the VCC and VNN rails.

PMCINT Pin

The PMICINT pin interrupts the Platform controller hub by rising from low to high when an unmasked interrupt event occurs. It is a level sensitive pin and it is cleared when the Platform controller hub reads the Interrupt registers. Reference Interrupt Controller for a more detailed explanation of the Interrupt mechanism.

The PMICINT pin follows the DC Signaling specifications in <u>Table 3</u> with a reference of 1.8 V (VPMIC).

VRCOMP Pin

This is an active high voltage regulator complete signal. It is asserted low by the PMIC when a SPI voltage regulation request, or other write request has been decoded. The signal is de-asserted on completion of the request (i.e. the rail is in regulation). This signal is relevant to the SPI initiated writes and EXITSTBY assertion. The VRCOMP pin follows the DC Signaling specifications in <u>Table 3</u> with a reference of 1.8 V (VPMIC).

Figure 9 illustrates the Voltage Regulators register write cycles and VRCOMP functionality. The rising edge on the SPICSB pin indicates the end of the block of Voltage Regulators configurations, at which point the VRCOMP pin is driven low. As an address/data block is written, the PMIC can start to ramp those rails (DC-DC, LDO, or switch). Once all of the rails are in regulation, the PMIC drives the VRCOMP pin high, indicating to the Platform controller hub that the voltage regulator configuration request is completed, and the PMIC is ready for subsequent transactions. The maximum number of voltage regulator change packets (address/data combinations) is 8. The voltage regulators should ramp at the rate defined in the regulators tables. Due to the relatively long turn-off time of the voltage regulators, the VRCOMP signal is to be gated-off after a 500 ns minimum (30 ms max.) low time.



Figure 9. VRCOMP Functionality in a SPI Voltage Regulators Configuration

RESET Pin

This is an active low, hard reset for the Platform controller hub. When this pin is asserted, the Platform controller hub returns to its initial default state. This signal can be asserted when a cold or warm reset is initiated, depending on the settings in the CHIPCNTL register.

The $\overrightarrow{\text{RESET}}$ pin follows the DC Signaling specifications in <u>Table 3</u> with a VCC of 1.8 V (VPMIC)

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PWRGD Pin

This is a Power Good Output Signal from the 900841 to the Platform controller hub. Assertion of PWRGD means that the VCCPAOAC, VAON, and VPMIC rails have been valid for at least 100 microseconds. The Platform Controller Hub will remain off until this signal is asserted. This signal is only deasserted if VCCPAOAC, VAON, or VPMIC is out of regulation, or a cold reset is initiated by the firmware.

The PWRGD pin follows the DC Signaling specifications in Table 3 with a reference of 1.8 V (VPMIC)

WARM and COLD RESET

The RESET and PWRGD signals have two functions which are initiated through the register file. Together they define a warm reset or cold reset to the Platform controller hub. The sequencing shown in Figure 10 and is controlled from the register CHIPCNTRL through bits WARMRST and COLDRST. The pulse should be held low for 5s < t < 31s.]





Table 13. CHIPCNTL Register Structure and Bit Description

Name	Bits	Description			
CHIPCNTI	CHIPCNTL (ADDR 0x 06 - R/W - Default Value: 0x00)				
COLDRST	0	Cold Reset Function Enable			
		x0 = No Change			
		x1 = Pulse RESET and PWRGD Low			
WARMRST	1	Warm Reset Function Enable			
		x0 = No Change			
		x1 = Pulse RESET Low			
Reserved	7:2	Reserved			

EXITSTBY Pin

When the EXITSTBY pin is asserted high, the 900841 exits the AOAC standby settings for regulating the platform supplies. When asserted, the PMIC switches the voltage regulators, as defined in the voltage regulator registers from the CTL Bits to the AOACTL Bits. This is a low latency voltage regulators context switch.

EXITSTBY pin follows the DC signaling specifications in Table 3 with a reference of 1.05 V (VCCP)

AOAC Exit Standby

When the EXITSTBY signal is asserted high from the Platform controller hub, the VRCOMP signal should be driven low. On the rising edge of the EXITSTBY signal, the AOACTL bits should be copied to the CTL bits in the different voltage regulator control registers, unless Bit 5 is '0'. If Bit 5 is '0', then the CTL bits are not modified. The VRCOMP signal is deasserted at this point. Next the rails defined in the new CTL registers should be ramped up together or remain in the same state, as if the AOACTL settings were the same as the previous CTL setting. Once all of the rails are in regulation, the VRCOMP signal should be driven high.

Figure 11 shows the timing diagram of the EXITSTBY signal. There is a special case (Optimized Case) when the EXITSTBY signal is asserted with the VCCP, VCCPDDR, VCCA, and VCC180 rails. If some combination of these four rails turn on with the assertion of the EXITSTBY signal, the entire time for the re-configuration should take no longer than 30 ms. See Figure 12.

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Figure 12. Optimized Exit Standby Diagram

The power-on default AOACCTLVxx register setting for the VCCP, VCCPDDR, VCCA, and VCC180 rails are to be turned on by the assertion of the EXITSTBY signal. However, every regulator has an AOACCTLVxx register setting, and can be configured to turn on, turn off, or have no change. The power-on default AOACCTLVxx register setting for all other regulators is set to no change. Note that the VDDQ regulator has to be enabled in order for the VCCA regulator to turn on.

THERMTRIPB Pin

THERMTRIPB is an active low Thermal Trip input signal. It is asserted by the CPU to indicate a catastrophic thermal event. On the falling edge of THERMTRIPB, the PMIC has 500 ms to sequence off all rails from the highest to lowest. The PMIC will turn on automatically upon detecting a turn on event, at which point the cold boot flow should be followed as shown in Turn on Events. The PMIC provides a weak (50 -100 k Ω) pull-up to VCCPAOAC. The PMIC only responds to a THERMTRIPB signal if the VCCP regulator is on. The Platform controller hub output driver is 55 Ω nominal.

The THERMTRIPB pin follows the DC Signaling specifications in <u>Table 3</u> with a reference of 1.05 V (VCCPAOAC).

VIDEN[1:0] & VID[6:0] Pins

Both VCC and VNN regulators are variable in the CPU and supply two different sub-systems. The CPU implements a VID mechanism that minimizes the number of required pins. The VID for VNN and VCC are multiplexed on to the same set of pins and a separate 2-bit enable/ID is defined to specify to which sub-system the driven VID corresponds. One of the combinations is used to notify that the VID is invalid. This is used when the CPU is in C6/Standby, to tri-state the VID pins to save power.

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Table 14. VIDEN Selections

VIDEN[1:0] Bits		Selection
0	0	Invalid
0	1	VCC
1	0	VNN
1	1	Unused

Both VCC and VNN have initial boot voltage (VCC VBOOT = 1.1 V; VNN VBOOT = 0.9 V) settings that the Platform controller hub sets to the VNN and VCC regulators by a SPI write to the VNNLATCH and VCCLATCH registers. Once all of the platform voltage rails are up, the CPU will drive the VID and VIDEN signals to set the VNN and VCC output voltage to the appropriate level. The VID and VIDEN signals will go through the sequence INVALID >> VNN >> INVALID >> VCC.

VID[6:0] and VIDEN[1:0] will transition together and the PMIC must de-bounce the VID[6:0] and VIDEN[1:0] for 100 to 400 ns. The CPU will hold these signals valid for at least 500 ns. VID signals are disabled from controlling VCC/VNN unless the VCCP regulator is enabled

Both regulators support dynamic VID transitioning during normal runtime operation. For the VNN regulator, dynamic VIDs require the CPU to change the VIDEN signals to INVALID each time to change the VNN output voltage. The VCC regulator is different in that it does not require the VIDEN signals to change to change the VCC output voltage. If the VIDEN signals are set for VCC (01) the VID signals can change and the VCC regulator will respond by changing the output voltage accordingly.

Figure 13 shows how the VCC output voltage can change during normal runtime operation when the VIDEN signals are set to VCC (01). If the VIDEN signals are set to VCC (01), the VCC regulator must monitor the VID signals, latch any changes, and change the output voltage setting accordingly. During normal operation, when the CPU is dynamically changing the VID setting for the VCC regulator, it will only change the VID combination by 1 step, which corresponds to

a voltage step of ± 12.5 mV. During these changes, the VCC regulator must follow the 25 mV/ms slew rate specification.

The VNN regulator differs from the VCC regulator, in that dynamic changes to the VNN regulator output voltage require the VIDEN signals to change to INVALID each time. <u>Figure 14</u> shows how the VNN output voltage can change during normal runtime operation.

The VIDEN[1:0] pins are active high signals driven by the CPU to indicate if the VID bus is addressing VCC or VNN. They follow the DC Signaling specifications in <u>Table 3</u> with a reference of 1.05 V (VCCPAOAC)

The VID[6:0] pins are active high signals driven by the CPU to indicate the output voltage setting for the VCC and VNN rails. They follow the DC Signaling specifications in Table 3 with a reference of 1.05 V (VCCP)

The VID output buffer driver is of the CMOS type. The Platform controller hub output driver Impedance is a pull-up (55 Ω +20%/-55%) and pull-down (55 Ω +20%/-55%). Motherboard Impedance is 55 Ω ±15%. Under extreme conditions, there could be ringing that cross the 70/30% threshold, hence the de-bounce requirements. Maximum leakage current on the VID pins is 100 mA.

VID[6:0] for each of the VCC and VNN rails will be latched in an internal register that will be updated with every VID[6:0] pin signaling

Table 15. VCC and VNN Latch Register Structure and Bit Description

Name	Bits	Description		
FSLVCCLATCH (ADDR 0x1C9 - R - Default Value: 0x7F)				
VCCVID	6:0	This register latches an Image of the last VID[6:0] signals for VCC		
Reserved	7	Reserved		
FSLV	INLATC	H (ADDR 0x1CA - R - Default Value: 0x7F)		
VNNVID	6:0	This register latches an Image of the last VID[6:0] signals for VNN		
Reserved	7	Reserved		



Figure 13. Dynamic VCC Timing Diagram

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Figure 14. Dynamic VNN Timing Diagram

Figure 15 shows the 7-bit VID codes vs. the output voltage of VCC and VNN.

VID VID (V)	VID		VID		VID	VID (V)
6 5 4 3 2 1 0	6 5 4 3 2 1 0	VID (V)	6 5 4 3 2 1 0	VID (V)	6 5 4 3 2 1 0	VID (V)
000000001.2000	0 1 0 0 0 0 0	1.1000	1000000	0.7000	1 1 0 0 0 0 0	0.3000
00000011.2000	0 1 0 0 0 1	1.0875	1000001	0.6875	1 1 0 0 0 0 1	OFF
0 0 0 0 0 1 0 1.2000	0 1 0 0 0 1 0	1.0750	1000010	0.6750	1 1 0 0 0 1 0	OFF
0 0 0 0 0 1 1 1.2000	0 1 0 0 0 1 1	1.0625	1000011	0.6625	1 1 0 0 0 1 1	OFF
0 0 0 0 1 0 0 1.2000	0 1 0 0 1 0 0	1.0500	1000100	0.6500	1 1 0 0 1 0 0	OFF
0 0 0 0 1 0 1 1.2000	0 1 0 0 1 0 1	1.0375	1000101	0.6375	1 1 0 0 1 0 1	OFF
000011010	0 1 0 0 1 1 0	1.0250	1000110	0.6250	1 1 0 0 1 1 0	OFF
0 0 0 0 1 1 1 1 1.2000	0 1 0 0 1 1 1	1.0125	1000111	0.6125	1 1 0 0 1 1 1	OFF
0 0 0 1 0 0 0 1.2000	0 1 0 1 0 0 0	1.0000	1001000	0.6000	1 1 0 1 0 0 0	OFF
0 0 0 1 0 0 1 1.2000	0 1 0 1 0 0 1	0.9875	100101	0.5875	1 1 0 1 0 0 1	OFF
0 0 0 1 0 1 0 1.2000	0 1 0 1 0 1 0	0.9750	1001010	0.5750	1 1 0 1 0 1 0	OFF
0 0 0 1 0 1 1 1.2000	0 1 0 1 0 1 1	0.9625	1001011	0.5625	1 1 0 1 0 1 1	OFF
0 0 0 1 1 0 0 1.2000	0 1 0 1 1 0 0	0.9500	1001100	0.5500	1 1 0 1 1 0 0	OFF
0 0 0 1 1 0 1 1.2000	0 1 0 1 1 0 1	0.9375	1001101	0.5375	1 1 0 1 1 0 1	OFF
0 0 0 1 1 1 0 1.2000	0 1 0 1 1 1 0	0.9250	1001110	0.5250	1 1 0 1 1 1 0	OFF
0 0 0 1 1 1 1 1 1.2000	0 1 0 1 1 1 1	0.9125	1001111	0.5125	1 1 0 1 1 1 1	OFF
0 0 1 0 0 0 0 1.2000	0 1 1 0 0 0 0	0.9000	1010000	0.5000	1 1 1 0 0 0 0	OFF
0 0 1 0 0 0 1 1.2000	0 1 1 0 0 0 1	0.8875	1010001	0.4875	1 1 1 0 0 0 1	OFF
0 0 1 0 0 1 0 1.2000	0 1 1 0 0 1 0	0.8750	1010010	0.4750	1 1 1 0 0 1 0	OFF
0 0 1 0 0 1 1 1.2000	0 1 1 0 0 1 1	0.8625	1010011	0.4625	1 1 1 0 0 1 1	OFF
0 0 1 0 1 0 0 1.2000	0 1 1 0 1 0 0	0.8500	1010100	0.4500	1 1 1 0 1 0 0	OFF
0 0 1 0 1 0 1 1.2000	0 1 1 0 1 0 1	0.8375	1010101	0.4375	1 1 1 0 1 0 1	OFF
0 0 1 0 1 1 0 1.2000	0 1 1 0 1 1 0	0.8250	1010110	0.4250	1 1 1 0 1 1 0	OFF
0 0 1 0 1 1 1 1 1.2000	0 1 1 0 1 1 1	0.8125	1010111	0.4125	1 1 1 0 1 1 1	OFF
0 0 1 1 0 0 0 1.2000	0 1 1 1 0 0 0	0.8000	1011000	0.4000	1 1 1 1 0 0 0	OFF
0 0 1 1 0 0 1 1.1875	0 1 1 1 0 0 1	0.7875	1011001	0.3875	1 1 1 1 0 0 1	OFF
0 0 1 1 0 1 0 1.1750	0 1 1 1 0 1 0	0.7750	1011010	0.3750	1 1 1 1 0 1 0	OFF
0 0 1 1 0 1 1 1.1625	0 1 1 1 0 1 1	0.7625	1011011	0.3625	1 1 1 1 0 1 1	OFF
0 0 1 1 1 0 0 1.1500	0 1 1 1 1 0 0	0.7500	1011100	0.3500	1 1 1 1 1 0 0	OFF
0 0 1 1 1 0 1 1.1375	0 1 1 1 1 0 1	0.7375	1011101	0.3375	1 1 1 1 1 0 1	OFF
0 0 1 1 1 1 0 1.1250	0 1 1 1 1 1 0	0.7250	1011110	0.3250	1 1 1 1 1 1 0	OFF
0 0 1 1 1 1 1 1 1.1125	0 1 1 1 1 1 1	0.7125	1011111	0.3125	1 1 1 1 1 1 1	OFF

Figure 15. 7-Bit VID Code vs. VCC/VNN Output Voltage

As explained previously, the output voltage setting for the VCC and VNN regulators can be set via the VID/VIDEN pins from the CPU, or by programming the VNNLATCH and VCCLATCH registers through the SPI interface via the Platform controller hub. Figure 16 shows the relationship between the VID/VIDEN signals, the DVPxVRD bit in the

Latch registers, and the VRCOMP output signal. The figure shows VCC as an example, but is also applicable to VNN

The DVPxVRD bit in the VNNLATCH and VCCLATCH registers controls the select input to the multiplexer. If the DVPxVRD bit is set to a '0', the regulator uses the VID/VIDEN

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pins from the CPU, and if the DVPxVRD bit is set to a '1', the regulator uses the VNNLATCH and VCCLATCH registers to set the output voltage.

When the DVPxVRD bit is set to a '0', any changes to the VNNLATCH and VCCLATCH registers should be ignored. When the DVPxVRD bit is set to a '1', any changes on the VID/VIDEN pins from the CPU should be ignored.

As soon as the DVPxVRD bit is set to a '1', the regulator switches from using the VID/VIDEN pins to using the

VCCLATCH register, and the output voltage of the regulator changes to what the VCCLATCH register is set.

Figure 16 also shows how the PMIC controls the VRCOMP signal. The PMIC toggles the VRCOMP signal any time the DVPxVRD bit is set to a '1' and the output voltage of the VNN or the VCC regulator changes. If the output voltage of the VCC/VNN regulator changes and the DVPxVRD bit is set to a '0', the VRCOMP signal should not toggle. In other words, VRCOMP only toggles for changes to VCC and VNN through the SPI registers.



Figure 16. Relationship Between the VID/VIDEN Pins, the DPV1VRD Bit, and VRCOMP Signal

I2S/PCM INTERFACE

A detailed description of the I2S interface is provided in Audio.

FREESCALE CHIP SET COMMUNICATION SIGNALS

This includes the control and status reporting signal between the 900841 and the companion chip, 900842, in Freescale's power management solution.

Table 16. Freescale Chipset Communication Signals Pin Functionality

Pin Name	I/O	Pin Functionality
V33EN	0	V33 Enable output pin
V33STTS	I	V33 Status input pin. Active low when V33 output is on
V33ISNS	I	Input Interface with the ADC to measure V33 output current
V3GPAEN	0	Reserved
V3GPASTTS	Ι	Reserved

As explained in General Description, Freescale's power management solution consists of two chips. The 900842 supplies the 3.3 V rail (V33).

The 900841 interfaces with the 900842 using the signals outlined above for control and status reporting functions.

The Platform controller hub has full control over the V33 chip, by setting the desired voltage regulator control setting in the 900841 register space. The 900841 in turn uses the V33EN pin to enable or disable the V33 chip. This transaction is seamless to the Platform controller hub.

If the 900841 is going through a forced shutdown event, like THERMTRIPB assertion, it can also use the V33EN pin to turn off the V33 rail. In turn, the V33 rail communicates back to the 900841 its output voltage status, through the V33STTS pin, so the 900841 has full visibility on the health of the 3.3 V rail and can report back to the Platform controller hub through the VRFAULT Interrupt if V33 has shutdown, due to a local problem, such as over-temperature.

V33 also sends its output current information to the 900841 for sampling by the ADC through the V33ISNS pin.

SPECIAL REGISTERS

Vendor ID and Version ID

The Vendor ID and other version details can be read via the Identification bits. These are hard-wired on the chip.

Table 17. Vendor ID Registers Structure and Bits Description

Name	Bits	Description			
ID	ID1 (ADDR 0x00 - R - Default Value: 0x28)				
VENDID1	2:0	Chip1 Vendor ID			
REV1	5:3	Chip1 Revision ID			
Reserved	7:6	Reserved			
IC	ID2 (ADDR 0x01 - R - Default Value: 0x00)				
VENDID2	2:0	Chip2 Vendor ID			
REV2	5:3	Chip2 Revision ID			
Reserved	7:6	Reserved			
ID	3 (ADDR ()x02 - R - Default Value: 0x00)			
Reserved	7:0	Reserved			
ID	ID4 (ADDR 0x03 - R - Default Value: 0x00)				
Reserved	7:0	Reserved			

Embedded Memory

There are 24 register banks of general purpose embedded memory, accessible by the processor to store critical data during power down. The data written to these registers is maintained by the coin cell when the main battery is deeply discharged or removed, and is part of the RTC block. The content of the embedded memory is reset by RTCPORB. The banks can be used for any system need, for bit retention with coin cell backup.

X is from 1 to 8 in Table 18.

Table 18. General Purpose Memory MEMx Register Structure and Bits Description

Register	Name	Bits	Description
MEMx	-	7:0	General Purpose Memory Register x

The rest of the 24 registers reside in the Freescale dedicated register space.

X is from 1 to 16 in the following table

Table 19. General Purpose Memory FSLMEMx Register Structure and Bits Description

Register	Name	Bits	Description
FSLMEMx	-	7:0	General Purpose Memory Register x

Output Driver Control

Select output pins output drive capability can be programmed for 4 different settings as shows in the following tables. All of the following outputs follow the settings as shown.

Table 20. Output Driver Control Selection

Slope	Select	Rise Time (ns)	Fall Time (ns)
0	0	8.4	7.0
0	1	6.2	6.2
1	0	Hi-Z	Hi-Z
1	1	22.3	21.3

Table 21. Output Driver Register Structure and Bit Description

Name	Bits	Description		
FSLOUTDRVCNTL1 (ADDR 0x1BF - R/W - Default Value: 0x00				
PWRGDDRV	1:0	PWRGD Output Pin Driver Capability		
VRCOMPBDRV	3:2	VRCOMP Output Pin Driver Capability		
PMICINTDRV	5:4	PMICINT Output Pin Driver Capability		
RESETBDRV	7:6	RESETB Output Pin Driver Capability		
FSLOUTDRVCN	TL2 (ADD	DR 0x1C0 - R/W - Default Value: 0x04)		
CLK26KDRV	1:0	CLK26K Output Pin Driver Capability		
CLK26MDRV	3:2	CLK26M Output Pin Driver Capability		
V3GPAENDRV	5:4	V3GPAEN Output Pin Driver Capability		
V33ENDRV	7:6	V33EN Output Pin Driver Capability		
FSLOUTDRVCN	FSLOUTDRVCNTL3 (ADDR 0x1C1 - R/W - Default Value: 0x01)			
SPISDODRV	1:0	MISO Output Pin Driver Capability		
RSVD	7:2	Reserved		

PLL Control

The following register controls the PLL and the different divider values for different output frequencies.

Name	Bits	Description
FSLPLLC	CNTL (A	DDR 0x1E4 - R/W - Default Value: 0x1B)
PLLDIVIDE	2:0	PLL Divide Ratio and Effective VCO Frequency Settings
		x0 = 112, 3.670 MHz
		x1 = 116, 3.801 MHz
		x2 = 120, 3.932 MHz
		x3 = 124, 4.063 MHz
		x4 = 128, 4.194 MHz
		x5 = 132, 4.325 MHz
		x6 = 136, 4.456 MHz
		x7 = 140, 4.588 MHz
PLL16MEN	3	16 MHz frequency enable
		x0 = 16 MHz clock disabled
		x1 = 16 MHz clock enabled and PLL enabled
PLLEN	4	PLL Enable, even if there is no block requesting a clock
		x0 = PLL enabled based on device enables only
		x1 = PLL enabled
Reserved	7:5	Reserved

Table 22. PLL Control Register Structure and Bit Description

TEST MODES

Test Mode Configuration

During evaluation and testing, the IC can be configured for normal operation or test mode via the ICTEST pin and other register configurations. Details of Test mode programmability are not documented herein, but should be referenced from other Design for Test documentation.

Test modes are for Freescale use only, and must not be accessed in applications. In test modes, signals are multiplexed on existing functional pins. The ICTEST pin must therefore be tied to ground (for normal operation) at the board level, in product applications

Test mode also disables the thermal protection for high temperature op life testing. A proprietary protocol is included for scan chain test configurations, which reuses the SPI pins.

In-package Trimming

During IC final test, several parameters are trimmed in the package, such as the main bandgap, and other precision analog functions. Trim registers are for Freescale use only and must not be accessed in product applications. Fuse programming circuitry will be blocked during normal and test mode operation.

CLOCK GENERATION AND REAL TIME CLOCK (RTC)

CLOCK GENERATION

A system clock is generated for internal digital circuitry, as well as for external applications utilizing the clock output pins. A crystal oscillator is used for the 32.768 kHz time base and generation of related derivative clocks. If the crystal oscillator is not running (for example, if the crystal is not present), an internal 32 kHz oscillator will be used instead.

In addition, another crystal oscillator is used to generate a 26 MHz clock for Audio usage. This clock is also routed to the companion chip, 900842, through the CLK26M pin.

Clocking Scheme

The internal 32 kHz oscillator is an integrated backup for the crystal oscillator and provides a 32.768 kHz nominal frequency at 50% accuracy, if running. The internal oscillator only runs if a valid supply is available at the charger input, battery, or coin cell, and would not be used as long as the crystal oscillator is active. The crystal oscillator continues running, supplied from one of the sources as described previously, until all power is depleted or removed. All control functions will run off the crystal derived frequency, occasionally referred to as the "32 kHz".

At system startup, the 32 kHz clock is driven to the CLK32K output pin, which is SPIVCC referenced. CLK32K is provided as a peripheral clock reference. The driver is enabled by the startup sequencer. Additionally, a SPI bit

M32KCLK bit is provided for direct SPI control. The M32KCLK bit defaults to 0 to enable the driver and resets on the RTCPORB to ensure the buffer is activated at the first power up and configured as desired, for subsequent power ups.

The drive strength of the output drivers is programmable with CLK32KDRV[1:0] (master control bits that affect the drive strength of CLK32K), see FSLOUTDRVCNTL2 Register in Table 21.

If a switchover occurs between the two clock sources (such as when the crystal oscillator is starting up), it will occur during the active low phase of both clocks, to avoid clocking glitches. A status bit, OSCSTP, is available to indicate to the processor which clock is currently selected: OSCSTP=1 when the internal RC is used, and OSCSTP=0 if the XTAL source is used.

The 26 MHz XTAL is necessary to provide a low jitter clock operation for the Audio block of 900841. The 26 MHz signal is needed internally for Audio operation, but is also provided to the companion chip, 900842, via the CLK26M output pin when the V33 voltage rail is enabled..

The drive strength of the output drivers is programmable with CLK26MDRV[1:0] (master control bits that affect the drive strength of CLK26M), see the FSLOUTDRVCNTL2 Register in Table 21.

Oscillator Specifications

The 32 kHz crystal oscillator has been optimized for use in conjunction with the Abracon™ ABS07-32.768KHZ-T or equivalent, and is capable of handling its parametric variations.

The 26 MHz is targeting for use in conjunction with the NDK[™] NX2016AB-26MHZ SB1 or equivalent, and is capable of handling its parametric variations.

The electrical characteristics of the 32 kHz and 26 MHz Crystal oscillators are given in the Oscillator section on <u>Table 3</u> and <u>Table 4</u>, taking into account the crystal characteristics noted previously. The oscillator accuracy depends largely on the temperature characteristics of the used crystal. Application circuits can be optimized for required accuracy by adapting the external crystal oscillator network (via component accuracy and/or tuning). Additionally, a clock calibration system is provided to adjust the 32.768 cycle counter that generates the 1.0 Hz timer and RTC registers; see Real Time Clock (RTC) for more detail.

REAL TIME CLOCK (RTC)

The RTC block provides a real-time clock with time-of-day, year, month, and date, as well as daily alarm capabilities. The real-time clock will use the 32.768 kHz oscillator as its input clock. The real-time clock will be powered by the coin cell backup battery as a last resort, if no other power source is available (Battery or USB/Wall plug). The register set is compatible with the Motorola[™] MC146818 RTC device.

Overview

The RTC module uses a 15-bit counter to generate a 1.0 Hz clock for timekeeping. The seven time and calendar registers keep track of seconds, minutes, hours, day-of-week, day-of-month, month, and year. The three seconds, minutes, and hours alarm registers can be used to generate time-of-day alarm interrupts.

The RTC time, alarm, and calendar values can be represented in 8-bit binary or BCD format. The hours and hours alarm values can be represented in 24 hour or 12 hour format, with AM/PM in the 12 hour mode. RTC control register B allows for software configurable clock formatting and interrupt masking. Control registers A, C, and D, report software testable RTC status, including interrupt flags, update-in-progress, and valid-RAM-time.

The RTC resets when the RTCPORB signal is driven low. The clock and calendar registers will be initialized to 00:00:00, Sunday, January 1, 2000.

Features

The RTC module includes the following features:

- · Counts seconds, minutes, and hours of the day
- · Counts days of the week, date, month, and year
- · Binary or BCD representation of time, calendar, and alarm
- 12 or 24 hour clock with AM and PM in 12 hour mode
- Automatic leap year compensation
- 900841

- · Automatic end of month recognition
- 15 bytes of clock, calendar, RTC control, and coin cell registers
- Two interrupts are separately software maskable and testable
- · Time-of-day Alarm
- · End-of-clock update cycle interrupt
- 15-bit counter to generate 1.0 Hz RTC clock
- Software testable Valid-ram-and-time status bit indicates data integrity

Modes of Operation

NORMAL MODE

In Normal mode, the RTC module updates time and calendar registers using the internal 1.0 Hz RTC clock. Once per second, the alarm registers are compared to the current time, and if enabled, an alarm interrupt will occur when the alarm time matches the current time. During normal operation, all 14 bytes of RTC and coin cell battery registers can be read through the SPI interface. Control register B may be updated to enable End-of-clock Update interrupts, alarm interrupts, or to put the RTC in Set mode.

The coin cell charger register is available for R/W in normal mode.

Coin Cell mode

When the application is powered down, the RTC will continue to keep track of time using power provided by the coin cell battery.

Since the system SPI will be powered down during this time, there is no read or write access to the RTC registers in Coin Cell mode.

Set mode

In Set mode, the clock and calendar updates are suspended, and the software may update the time, calendar, and alarm registers. The time and calendar formats must match the formats specified by the DM and 12/24 format bits in RTC register B. When the format bits are modified, all 14 time, calendar, and alarm registers must be updated in the specified format.

Scan/Test mode

Internal Test mode not available for the end application.

Setting the Time, Calendar, and Alarm

Before initializing the internal registers, the Set bit in Register B should be set to a "1" to prevent time/calendar updates from occurring. Select the data format by writing the appropriate values to the DM and 24/12 bits in Register B.

Next, the program should initialize all 10 time, calendar, and alarm locations in the format specified by Register B (binary or BCD, 12 or 24 hour). All 10 time, calendar, and

alarm bytes must use the same data mode, either binary or BCD. Both the alarm hours, and the hours bytes must use the same hours format, either 12 or 24.

The Set bit may now be cleared to allow updates. Once initialized, the real-time clock makes all updates in the selected data mode. The data mode (DM) cannot be changed without re-initializing the 10 data bytes.

The 24/12 bit in Register B establishes whether the hour locations represent 1-to-12 or 0-to-23. When the 12 hour format is selected the high order bit of the hour bytes represents PM when it is a "1". The 24/12 bit cannot be changed without re-initializing the hour and alarm-hour locations.

<u>Table 23</u> shows the binary and BCD formats of the 10 time, calendar, and alarm locations.

Address		Desimal	Ran	ge	Example ⁽²⁰⁾	
location	Function	Decimal Range	Binary Data Mode	BCD Data Mode	Binary Data Mode	BCD Data Mode
0x10	Seconds	0-59	\$00-\$3B	\$00-\$59	15	21
0x11	Seconds Alarm	0-59	\$00-\$3B	\$00-\$59	15	21
0x12	Minutes	0-59	\$00-\$3B	\$00-\$59	3A	58
0x13	Minutes Alarm	0-59	\$00-\$3B	\$00-\$59	3A	58
0x14	Hours				0B	11
	(12 Hour Mode)	1-12	\$01-\$0C(AM) / \$81-\$92(PM)	\$01-\$12(AM) / \$81-\$92(PM)		
	(24 Hour Mode)	0-23	\$00-\$17	\$00-\$23		
0x15	Hours Alarm				0B	11
	(12 Hour Mode)	1-12	\$01-\$0C(AM) / \$81-\$92(PM)	\$01-\$12(AM) / \$81-\$92(PM)		
	(24 Hour Mode)	0-23	\$00-\$17	\$00-\$23		
0x16	Day of the Week	1-7	\$01-\$07	\$01-\$07	05	05
	Sunday=1					
0x17	Date of the Month	1-31	\$01-\$1F	\$01-\$31	0F	15
0x18	Month	1-12	\$01-\$0C	\$01-\$12	02	02
0x19	Year	0-99	\$00-\$63	\$00-\$99	08	08

Table 23. Time, Calendar, and Alarm Data Modes

Notes

20. Example: 11:58:21 Thursday 15 February 2008 (time is AM)

Reading the Time, Calendar, and Alarm

Under normal operation, the current time and date may be read by accessing the RTC registers through the system SPI. Since the alarm is only updated by a SPI write instruction, the three alarm registers may be read at any time and will always be defined.

The 900841 SPI will run at a minimum of 12.5 MHz. Each individual SPI read transaction requires 25 cycles (less for burst-read). The RTC contains seven timekeeping registers to keep track of seconds, minutes, hours, day-of-week, day-of-month, month, and year. If the SPI is clocked at the slowest frequency, and the RTC is read using individual (not burst) SPI read commands, the following equation gives the maximum amount of time it takes the processor to read a complete date and time (assuming the reads are done sequentially, and uninterrupted): (25 * 7) / (12.5 MHz) = 14 μ s.

This equation shows that a program which randomly accesses the time and date information will find the data in transition statistically 14 times per million attempts. If a clock update occurs during the time it takes to read all seven timekeeping registers, the values read may be inconsistent. In other words, if the program starts to read the seven date/time registers and an RTC update occurs, the data collected may be in transition. In this event, it is possible to read transition data in one of the registers, resulting in undefined output. It is more likely that the registers read after the update would be incremented (by one second), and the registers read before the update would not.

The time, calendar, and alarm bytes are always accessible by the processor program. Once per second the seven bytes are advanced by one second and checked for an alarm condition. If any of the seven bytes are read at this time, the data outputs should be considered undefined. Similarly, all seven bytes should be read between updates to get a consistent time and date. Reading some of the bytes before an update and some after, may result in an erroneous output. The Update Cycle section explains how to accommodate the update cycle in the processor program.

Update Cycle

The RTC module executes an update cycle once per second, assuming one of the proper time bases is in place and

the SET bit in Register B is clear. The SET bit in the "1" state permits the program to initialize the time and calendar bytes by stopping an existing update and preventing a new one from occurring.

The primary function of the update cycle is to increment the Seconds byte, check for overflow, increment the Minutes byte when appropriate, and so forth, up through the month and year bytes. The update cycle also compares each alarm byte with the corresponding time byte and issues an alarm if a match is present in all three positions.

Two methods of avoiding undefined output during updates are usable by the program. In discussing the two methods, it is assumed that at random points, user programs are able to call a subroutine to obtain the time of day.

The first method uses the update-ended interrupt. If enabled, an interrupt occurs after every update cycle, which indicates that over 999 ms are available to read valid time and date information. Before leaving the interrupt service routine, the IRQF bit in Register C should be cleared.

The second method uses the update-in-progress bit (UIP) in Register A, to determine if the update cycle is in progress. The UIP bit will pulse once per second. Statistically, the UIP bit will indicate that time and date information is unavailable once every 3,640 attempts. After the UIP bit goes high, the update cycle begins 244.1 μ s later. Therefore, if a low is read on the UIP bit, the user has at least 244.1 μ s before the time/calendar data may not be valid. The user should avoid interrupt service routines which would cause the time needed to read valid time/calendar data to exceed 244.1 μ s.

The RTC uses seven synchronous counters to increment the time and calendar values. All seven timekeeping registers are clocked by the same internal 1.0 Hz clock, so updates occur simultaneously, even during rollover. After the counters are incremented, the current time is compared to the time-of-day alarm registers 30.5 μ s later, and if they match, the AF bit in register C will be set.

The Update-cycle begins when the clock and calendar registers are incremented, and ends when the alarm comparison is complete. During this $30.5 \ \mu$ s update cycle, the time, calendar, and alarm bytes are fully accessible by the processor program. If the processor reads these locations during an update, the transitional output may be undefined. The update in progress (UIP) status bit is set 244.1 μ s before this interval, and is cleared when the update cycle completes.

Interrupts

The RTC includes two separate, fully automatic sources of interrupts to the processor. The alarm interrupt may be programmed to occur at a rate of once per day. The updateended interrupt may be used to indicate to the program that an update cycle is completed.

The processor program selects which interrupts, if any, it wishes to receive. Two bits in Register B enable the two

interrupts. Writing a "1" to an interrupt-enable bit permits that interrupt to be initiated when the event occurs. A "0" in the interrupt-enable bit, prohibits the IRQF bit from being asserted due to the interrupt cause.

If an interrupt flag is already set when the interrupt becomes enabled, the IRQF bit is immediately activated, though the interrupt initiating the event may have occurred much earlier. Thus, there are cases where the program should clear such earlier initiated interrupts before enabling new interrupts.

When an interrupt event occurs, a flag bit is set to a "1" in Register C. Each of the two interrupt sources have separate flag bits in Register C, which are set independent of the state of the corresponding enable bits in Register B. The flag bit may be used with or without enabling the corresponding enable bits.

In the software scanned case, the program does not enable the interrupt. The interrupt flag bit becomes a status bit, which the software interrogates when it wishes. When the software detects the flag is set, it is an indication to the software an interrupt event occurred since the bit was last read.

However, there is one precaution. The flag bits in Register C are cleared (record of the interrupt event is erased) when Register C is read. Double latching is included with Register C, so the bits which are set are stable throughout the read cycle. All bits which are high when read by the program are cleared, and new interrupts (on any bits) are held until after the read cycle. One or two flag bits may be found to be set when Register C is used. The program should inspect all utilized flag bits every time Register C is read to insure that no interrupts are lost.

The second flag bit usage method is with fully enabled interrupts. When an interrupt flag bit is set and the corresponding interrupt enable bit is also set, the IRQF bit is asserted high. IRQF is asserted as long as at least one of the two interrupt sources has its flag and enable bits both set.

The processor program can determine that the RTC initiated the interrupt by reading Register C. A "1" in bit 7 (IRQF bit) indicates that one or more interrupts have been initiated by the part. The act of reading Register C clears all the then active flag bits, plus the IRQF bit. When the program finds IRQF set, it should look at each of the individual flag bits in the same byte which have the corresponding interrupt mask bits set and service each interrupt which is set. Again, more than one interrupt flag bit may be set.

ALARM INTERRUPT

The three alarm bytes may be used to generate a daily alarm interrupt. When the program inserts an alarm time in the appropriate hours, minutes, and seconds alarm locations, the alarm interrupt is initiated at the specified time each day, if the alarm enable bit is high.

Update-Ended Interrupt

If enabled, an interrupt occurs after every update cycle which indicates that there is over 999 ms available to read valid time and date information.

RTC Timer Calibration

By default, the calibration circuit is off and clock accuracy is limited to the performance of the 32.768 kHz crystal input. For clock accuracy beyond the limits of the crystal oscillator, a calibration circuit is included. The processor can use a highfrequency clock to sample the 32.768 kHz output to determine if it is fast or slow, and calculate an adjustment value. The adjustment algorithm has a resolution of ±477 nanoseconds-per-second average adjustment, which equates to a time accuracy of approximately 1.2 seconds per month. Calibration can be turned on by setting the RTC ADJ bit of the ADJ register. A "0" in the ADJ bit turns calibration off. The Sign bit in the Trim register determines if periodic adjustments are made to speed up or slow down the clock.

When calibration is enabled, the Trim register is used to grow or shrink the average 1.0 Hz clock period. By default, one second is defined as 32,768 periods of the CLK32K input pin. Each period of the input clock is approximately 30.5 μ s. By occasionally adding (or subtracting) one extra cycle per second, the average second can be adjusted. If SIGN is high (subtract one), occasional seconds will be trimmed to 32,767 cycles. If SIGN is low (add one), occasional seconds will be trimmed to 32,769 cycles.

The 6-bit TRIMVAL in the Trim register represents the number of seconds to adjust out of every 64 seconds, and can range from 0-63. For example, TRIMVAL = 0x08 then 8 seconds out of every 64 will be adjusted up or down, according to the SIGN bit.

CLOCK GENERATION AND REAL TIME CLOCK (RTC) REGISTERS AND BITS DESCRIPTION

Name	Bits	Description					
RTCS (ADDR 0x10 - R/W - Default Value: 0x00)							
SEC	6:0	econds Counter Register					
Reserved	7	Reserved					
		RTCSA (ADDR 0x11 - R/W - Default Value: 0x00)					
SECALARM	6:0	Seconds Alarm Setting Register					
Reserved	7	Reserved					
		RTCM1 (ADDR 0x12 -R/W - Default Value: 0x00)					
MIN	6:0	Minutes Counter Register					
Reserved	7	Reserved					
		RTCMA (ADDR 0x13 - R/W - Default Value: 0x00)					
MINALARM	6:0	Minutes Alarm Setting Register					
Reserved	7	leserved					
		RTCH (ADDR 0x14 - R/W - Default Value: 0x00)					
HRS	5:0	Hours Counter Register					
Reserved	6	Fixed to 0					
PA-H	7	AM/PM Indication, Only active during 12 Hr mode					
		x0 = AM					
		x1 = PM					
		RTCHA (ADDR 0x15 - R/W - Default value: 0x00)					
HRSALARM	5:0	Hours Alarm Setting Register					
Reserved	6	Fixed to 0					
PA-HA	7	AM/PM Alarm Setting, Only active during 12 Hr mode					
		x0 = AM					
		x1 = PM					

Table 24. RTC Date/Time Configuration Register Structure and Bits Description

RTCDW (ADDR 0x16 - R/W - Default Value: 0x01) Day of Week counter register : 1= Sunday ... 7= Saturday DOW 2:0 Reserved 7:3 Reserved RTCDM (ADDR 0x17 - R/W - Default Value: 0x01) DOM 5:0 Day Of Month Counter Register 7:6 Reserved Reserved RTCM2 (ADDR 0x18 - R/W - Default Value: 0x01) MONTH 4:0 Months Counter Register Reserved Reserved 6:5 19/20 7 THIS BIT IS NOT SUPPORTED Always Reads 0 (treated as a reserved bit) RTCY (ADDR 0x19 - R/W - Default Value: 0x00) YEAR 7:0 Year Counter Register. Note: Values range from 0 to 99

Table 24. RTC Date/Time Configuration Register Structure and Bits Description

Table 25. RTC Control Registers Structure and Bit Description

Name	Bits	Description			
		RTCA (ADDR 0x1A - R - Default Value: 0x20)			
Reserved	6:0	Fixed to 010000			
UIP	7	his is the Update In Progress (UIP) bit used as a status flag			
		= Update cycle not in progress			
		x1 = Update cycle is in progress or will begin soon			
		RTCB (ADDR 0x1B - R/W - Default Value: 0x02)			
Reserved	0	Fixed to 0			
HRMODE	1	Hour Format Control			
		x0 = 12 Hour Mode			
		x1 = 24 Hour Mode			
DM	2	Data Mode for Time and Calendar Updates			
		x0 = Binary-Coded-Decimal (BCD)			
		x1 = Binary			
Reserved	3	Fixed to 0			
UIE	4	Update-Ended Interrupt Enable			
		x0 = Update-End (UF) bit in Register C is not permitted to assert the interrupt request flag (IRQF) in Register C			
		x1 = Update-End (UF) bit in Register C is permitted to assert the interrupt request flag (IRQF) in Register C			
AIE	5	Alarm Interrupt Enable			
		x0 = Alarm flag (AF) bit in Register C is not permitted to assert the interrupt request flag (IRQF) in Register C			
		x1 = Alarm flag (AF) bit in Register C is permitted to assert the interrupt request flag (IRQF) in Register C			
Reserved	6	Fixed to 0			
SET	7	Set mode enable bit for the program to initialize the time and calendar bytes			
		x0 = The update cycle functions normally by advancing the counts once-per-second.			
		x1 = Any update cycle in progress is aborted and the program may initialize the time and calendar bytes without an update occurring in the midst of initializing.			

Table 25. RTC Control Registers Structure and Bit Description

		RTCC (ADDR 0x1C - R - Default Value: 0x00)					
Reserved	3:0	Reserved					
UF	4	Update-Ended Interrupt Flag. Set after each update cycle.					
		X0 = UIE bit will not effect IRQF state					
		x1 = When UIE bit goes high, the IRQF bit goes high					
AF 5		Alarm Interrupt Flag. Indicates that the current time has matched the alarm time.					
		X0 = AIE bit will not effect IRQF state					
		x1 = When AIE bit goes high, the IRQF bit goes high					
Reserved	6	Fixed to 0					
IRQF	7	Interrupt Request Flag. IRQF = (AF&AIE) + (UF&UIE)					
		The interrupt request flag (IRQF) is set to a "1" when one or more of the following are true:					
		AF = AIE = "1"					
		UF = UIE = "1"					
		x0 = Above Equation is not true					
		x1 = Above Equation is true					
		RTCD (ADDR 0x1D - R - Default Value: 0x00)					
Reserved	6:0	Fixed to 000000					
VRT	7	The Valid RAM and Time (VRT) bit indicates the condition of the contents of the RTC time and calendar registers . A					
		"0" appears in the VRT bit when the RTC registers have been reset. The processor program should set the VRT bit					
		after the time and calendar are initialized to indicate that the time and calendar are valid. The VRT bit can only be set by reading register D.					
		RTCE (ADDR 0x1E - R/W - Default Value: 0x05)					
OSCSTP	0	Oscillator (32 kHz) Clock Stop Flag					
000011	Ŭ	$x_0 = XTAL Oscillator$					
		x1 = Internal RC Oscillator					
BKDET	1	Coin Cell Backup Voltage Status					
DRDET		x0 = No change					
		x1 = Coin Cell below "low-voltage" threshold					
		When this bit is set to 1, the SW takes corresponding action for a coin cell well below the operating voltage, and clear					
		the BKDET in order to get ready for the next event.					
POR	2	RTC Reset Flag					
		x0 = No reset was detected					
		x1 = POR occurred					
SCRATCH	7:3	These bits shall not exert any control over the operation of the RTC, and are intended to be used as scratch pad					
		registers by the system controller. Their contents are erased on RTCPORB.					
		ADJ (ADDR 0x1F - R/W - Default Value: 0x00)					
ADJ	0	RTC Trim Enable Signal					
		x0 = Do Not Trim					
		x1 = Trim					
Reserved	7:1	Fixed to 0000000					
		TRIM (ADDR 0x20 - R/W - Default Value: 0x00)					
TRIMVAL	5:0	6-Bit Trim Control					
		This is a number from 0 to 63 that represents the number of seconds to adjust out of every 64 seconds					
SIGN	6	RTC Calibration Sign Bit					
		x0 = Add					
		x1 = Subtract					

Reserved	7	Fixed to 0			
		CLKOUT (ADDR 0x21 - R/W - Default Value: 0x00)			
M32KCLK	0	32 kHz clock output mask			
		= 32 kHz clock output enabled			
		x1 = 32 kHz clock output masked (disabled)			
Reserved	7:1	Fixed to 0000000			

Table 25. RTC Control Registers Structure and Bit Description

POWER STATES AND CONTROL

OVERVIEW

The following section discusses the different Power States of the 900841 PMIC, what causes the 900841 to be in each of them, and how the SCU is involved.

In Ultra-mobile platforms, the SCU is required to be alive as long as a valid battery or a valid charger input (a USB source or a wall plug) exists. If any of the previous two power sources are present, the 900841 powers up the SCU part of Platform controller hub, with a minimum set of power supplies, and the SCU takes over the system.

The previous paragraph simplifies the operation modes and power states of the 900841 solution, and essentially limits the power states to 3 different states, that is discussed at length later:

- 1. No Power: Depleted or no coin cell battery, main battery, and charger input
- RTC State: 900841 has enough power to support the RTC operation and keep registers alive, but not to power the SCU
- 3. Active State: 900841 has enough power to supply the SCU

INTERNAL SUPPLIES POWER TREE

Before going into the Power State of 900841 solution as a system and how it interacts with Platform controller hub to support the needs of the platform, first examine how the 900841 powers itself up and its internal power tree.

Figure 17 is a block diagram of the 900841 internal power tree.





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It is important to note that the VPWR node is the main supply to the loads and the rest of the system (see Battery Interface and Power Path Management). The availability of V_{PWR} determines what power state the 900841 IC is in. Availability of V_{PWR} is discussed later. The next subject is the effect of V_{PWR} voltage on how the 900841 is internally powered.

V_{PWR} < V_{PWRUVF}

If V_{PWR} is less than the under-voltage falling threshold of 2.65 V, then the system cannot power up, and the RTC circuitry and clock, and the keep alive registers, receive their supply from a node, called the Best of Supply node (V_{BOS}), see <u>Figure 17</u>. These ensure that power to these critical circuits is maintained for maximum life.

 V_{BOS} represents the highest of the following voltages:

- 1. V_{PVINCHG}: This is the charger input voltage after the protection circuitry, reference Battery Interface and Power Path Management for more information
- 2. V_{BAT} : This is the main battery voltage

3. V_{COINCELL}: This is the coin cell battery voltage, backup battery

$V_{PWR} > V_{PWRUVR}$

If V_{PWR} is available and valid ($V_{PWR} > 3.0$ V), then the main internal supplies that provide power to the rest of the circuitry can power up:

- 1. V_{COREREF}: This is the main bandgap and reference voltage for all internal circuitries.
- 2. V_{CORE}: This is the supply for the 900841 analog circuitry.
- 3. V_{COREDIG}: This is the supply for the 900841 digital circuitry.

Notice that when V_{COREDIG} is > 1.2 V, a switch is closed, and the circuitry that was powered from V_{BOS} is now powered from V_{COREDIG}.

The following table summarizes the voltage references on the 900841.

Reference	Parameter	Target
VCOREREF	Output Voltage	1.2 V
(Bandgap & Regulators Reference)	Bypass Capacitor	100 nF typ.
VCOREDIG	Output Voltage	1.5 V
(Digital Core Supply)	Bypass Capacitor	2.2 μF typ.
VCORE	Output Voltage	2.775 V
(Analog Core Supply)	Bypass Capacitor	2.2 μF typ.

POWER STATES

Figure 18 shows the flow of power, the different power states, and the conditions necessary to transition between

the different states. This diagram serves as the basis for the description in the remainder of this section.



Figure 18. 900841 Power States

FUNCTIONAL DEVICE OPERATION POWER STATES AND CONTROL

No Power State

In this state, every source of power has been removed or is fully depleted:

- V_{RAWCHG} < V_{RAWCHGDET}: The charger input is not available or is below the detection threshold
- V_{BAT} < V_{BATOFF}: The main battery has been removed or has been isolated by its own protection circuitry to stop it from depleting even further
- V_{COIN} < V_{COINOFF}: The coin cell backup battery has been removed or has been isolated by the 900841 coin cell discharge prevention circuitry (see Coin Cell Battery Backup/Charger)

The 900841 has lost any source of power to maintain the RTC and its keep alive registers, and all circuitry will power down and time of day cannot be kept.

RTC State

If one of the following two conditions is satisfied, then SC900841 goes from the No Power State to the RTC State:

- V_{RAWCHG} > V_{RAWCHGDET}: A charger input is valid and has been detected.
- V_{BAT} > V_{BATOFF}: A main battery has been inserted with a valid voltage range.

If either of the previous two conditions occur, the V_{BOS} is available and will route the power to the $V_{CORERTC}$ and the Keep Alive bandgap. As a result, the RTC is powered, Time of day is initialized to a factory set value, see Real Time Clock (RTC), and all keep alive registers are maintained.

During this mode the main battery is isolated and all other circuits are off. SCU cannot be powered up.

In order to route the power from the RAWCHG node to the PVINCHG node, which is one of the supplies to the Best of Supply circuitry, MOVPCHG and MREVPCHG have to turn on upon valid charger input voltage detection. See Battery Interface and Power Path Management for more information.

During this mode no turn on is accepted. The only blocks operational are:

- The charger interface (monitoring of the charger input voltage)
- RTC module
- · Keep alive registers

No specific power control timer is running in this mode. All main and external supplies are off. The Platform controller hub will also be off by virtue of the loss of its supply source.

The 900841 stays in this state as long as the previous two conditions are satisfied, and V_{PWR} is below its rising threshold V_{PWRUVR}

Active State

In this state the 900841 internal circuits are fully powered, the Platform controller hub SCU and I/Os are powered, and SPI communication is available. All features of the 900841 are either operating or can be enabled, which is under the control of the Platform controller hub. The key to entering the active state is a valid V_{PWR} voltage. The following examines how the 900841 ramps up V_{PWR} depending on the available power source:.

V_{PWR} RAMP UP

One of the following two conditions causes a VPWR ramp up sequence:

- V_{RAWCHG} > V_{RAWCHGDET}: A charger input is valid and has been detected. Note that this is the same condition for an RTC state. This means that if this condition occurs, the device goes through the RTC state, then directly into a VPWR ramp up sequence to try and get to the active state (see <u>Figure 18</u> for more details).
- V_{BAT} > V_{LOWBAT}: The main battery voltage is above the V_{LOWBAT} threshold of 3.2 V.

For number 1, the Buck Charger turns on and regulates V_{PWR} to a voltage that depends on the state of the battery:

- If $V_{BAT} < V_{TRICKLE}$, then $V_{PWR} = 4.2 V$
- If $V_{BAT} > V_{TRICKLE}$, then $V_{PWR} = V_{BAT} + 0.3 V$
- For number 2, the Buck charger stays off, and the MCHG and MCHGBYP FETs turn on to short the battery voltage with the V_{PWR} node. Note that number 2 implies that the charger input is not present or is not valid.

After V_{PWR} crosses the under-voltage rising detection threshold (V_{PWRUVR}) of 3.0 V, the internal supplies power on, the logic is reset, initial power sequence is performed, SPI communication is ready, and the Platform controller hub is interrupted. The system is now completely under SCU control. Now it is in the active state.

In the active state, the following types of operations are possible. Note that for simplicity, a valid charger input operation is called the USB Operation:

- 1. Battery Operation
- V_{BAT} > V_{LOWBAT} and V_{RAWCHG} < V_{RAWCHGDET}.
- V_{PWR} = V_{BAT}
- MCHG and MCHGBYP are ON, shorting the battery with the VPWR node
- MOVPCHG and MREVPCHG are OFF, isolating the charging input from the battery
- Charging is not possible
- · OTG host mode operation is possible
- Note: If OTG host mode operation is enabled, the USBDET Interrupt flag is ignored.
- 2. USB Operation
- V_{RAWCHG} > V_{RAWCHGDET} and V_{BAT} < V_{TRICKLE}.
- V_{PWR} = 4.2 V
- · MCHG and MCHGBYP are OFF, isolating the battery
- MOVPCHG and MREVPCHG are ON
- · Charging is possible
- OTG host mode operation is not possible
- 3. USB + Battery Operation
- V_{RAWCHG} > V_{RAWCHGDET} and V_{BAT} > V_{TRICKLE}.
- V_{PWR} = V_{BAT} + 0.3 V
- · MCHG and MCHGBYP are OFF, isolating the battery

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- MOVPCHG and MREVPCHG are ON
- · Charging is possible
- OTG host mode operation is not possible

During 2 and 3, if at any time $V_{PWR} < V_{BAT} - 100 \text{ mV}$, MCHG and MCHGBYP turn on fully to support the system power requirements.

Table 27.	Power	Selection	Summary

Reference Figure 18 and Battery Interface and Power Path Management.

<u>Table 27</u> summarizes the power selection, V_{PWR} value, and the operation mode of the 900841, depending on the state of battery and charger input.

Dete	Detection		Register Setting		Mode of Operation					
USBDET	BATDET	CHRENB	CHR	отдв	Buck Charger	MOVPCHG & MREVPCHG	мснд	MCHGBYP	VPWR	Comment
0	0	Х	Х	Х	OFF	OFF	OFF	OFF	Floating	System not in operation
0	1	х	0	х	OFF	OFF	ON	ON	VBAT	System can turn on - No OTG Host mode
		х	1	0	OFF	ON	ON	ON	VBAT	System Can turn on & OTG Host mode ON (VOTG = 5.0 V)
		Х	1	1	OFF	OFF	ON	ON	VBAT	System can turn on - No OTG Host mode
1	0	0	Х	Х	ON	ON	ON	OFF	4.2 V	Charging
		1	Х	Х	ON	ON	OFF	OFF	4.2 V	USB Supplies System - No Battery Operation - No Charging
1	1	0	Х	Х	ON	ON	ON	OFF	VBAT+0.3 V	Charging
		1	Х	Х	ON	ON	OFF	OFF	VBAT+0.3 V	USB Supplies System - No Battery Operation - No Charging

TURN ON EVENTS

If the 900841 is in the RTC State, full operation as outlined previously to reach to the active state, can be obtained via a turn on event. The turn on events are listed by the following. To indicate to the SC, which turn on event caused the system to power on, a corresponding interrupt status bit is set, allowing the system controller to retrieve when it is up.

- V_{RAWCHG} > V_{RAWCHGDET}: Valid Charger Input present. USBDET Interrupt bit is set
- V_{BAT} > V_{LOWBAT}: Valid Battery for system turn on present. The BATDET Interrupt bit is set

Reference Interrupt Controller for more information on the various system interrupts.

These are the only 2 turn on events. Otherwise, the 900841 is in the RTC State or the No Power State.

Initial Power Up Sequence

The following diagram shows the initial power up sequence the 900841 performs when a turn on event is detected:



Figure 19. 900841 Initial Power Up Sequence

- 1. A turn on event as outlined above is detected
- 2. V_{PWR} ramps up
- 3. The 900841 internal circuits are powered
- 4. The 900841 turns on a minimal set of voltage rails as outlined in Figure 19
- 5. SPI communication is ready
- 6. PMICINT pin is asserted
- 7. The system controller reads the 900841 interrupt flag register (over SPI) to see why the 900841 interrupted the Platform controller hub.
- 8. SC decides whether to boot the rest of the system, or just run SC code to manage charger or other functions.
- If SC decides to power up system, then CPU (central processing unit) drives VNN VID, VIDEN[1:0] = 10 to the 900841 and BSEL to the Platform controller hub.
- 10. The 900841 drives CPU selected voltage for VNN
- 11. There will be no explicit signaling from the 900841 that indicates that the VNN ramp has been complete.
- 12. VIDEN[1:0] is driven to 00 to avoid it switching from 10 to 01 directly.
- 13. NC drives the VCC boot VID on the VID pins. The VIDEN[1:0] = 1 enables, only after HPLL has locked.
- 14. X86 Instruction Executions starts.

Table 28. SC900841 Initial Power Up Timing

Parameter	Description	Min	Тур	Max
t ₁	PMIC internal regulator Ramp-up	-	-	100 μs
t ₂	V15 turn on delay	0 μs	-	31 μs
t ₃	V15 Ramp-up	-	-	10 μs
t ₄	VAON/VCCPAOAC turn on delay	0 μ s	-	31 μs
t ₅	VAON/VCCPAOAC ramp-up	-	-	700 μs
t ₆	V21 turn on delay	0 μs	-	31 μs
t ₇	V21 ramp-up	-	-	100 μs
t ₈	VPMIC turn on delay	0 μs	-	31 μs
t ₉	VPMIC ramp-up	-	-	700 μs
t ₁₀	PWRGD delay	70 ms	-	90 ms
t ₁₁	RESET delay	1.0 μs	-	31 μs
t ₁₂	PMICINT delay	31 μs	-	124 μs

TURN OFF EVENTS

Once in the active state, the following causes the 900841 to power off the system, including the SCU. The 900841 internal circuitry and logic is still active:

• PWRBTN pressed for more than 5 seconds. See Power Button Functionality (PWRBTN).

FUNCTIONAL DEVICE OPERATION POWER STATES AND CONTROL

- The 900841 junction temperature is above the thermal shutdown threshold. See Thermal Management for more details.
- A THERMTRIPB assertion. See THERMTRIPB Pin for more details.
- A BATOCP detection. See BATOCP.

The following causes the 900841 to power the entire system, including its internal circuitry if $V_{PWR} < V_{PWRUVF}$ occurs.

Power Button Functionality (PWRBTN)

The Power button is pulled up internally through a 132 k resistor to the V_{COREDIG} output voltage node. See Figure 20 for more details. This guarantees the functionality of the button when either power source available.



Figure 20. PWRBTN Circuit Diagram

Figure 21 describes the functionality of the PWRBTN:



DETECTION THRESHOLDS

<u>Table 29</u> summarizes the various detection thresholds between the different states:

Characteristic	Symbol	Min	Тур	Max	Unit
Input Voltage Rising Detection Threshold	V _{RAWCHGDET}	-	-	4.50	V
Input Voltage Rising Detection Threshold Hysteresis	V _{RAWCHGDETHYS}	-	100	-	mV
Battery Cutoff Threshold	V _{BATOFF}	2.2	-	2.4	V
(Depending on Battery Model)					
Coin Cell Disconnect Threshold	V _{COINOFF}	1.8	-	2.0	V
Low Battery Threshold	V _{LOWBAT}	3.2	-	-	V
Valid Battery Threshold	V _{TRKL}	-	3.0	-	V
VPWR Rising Under-voltage Threshold	V _{PWRUVR}	-	3.1	-	V
VPWR Falling Under-voltage Threshold	V _{PWRUVF}	-	2.55	-	V

POWER SUPPLIES

POWER MAP

Figure 22 is a power map of Freescale's power management solution for Ultra-mobile platforms:



Figure 22. SC900841 Power Map

DC/DC POWER SUPPLIES

Freescale's power management solution for the Ultramobile platform for MID includes 10 DC/DC switching regulators, nine are included in the 900841 PMIC, and one is implemented in the companion chip, 900842. Six out of the nine regulators are Buck converters, and the remaining three are Boost converters, and these can be set to work in the following operation modes:

Buck converters Operation Modes Selections (VCC, VNN, VDDQ, V21, V15, VYMX3G)

- OFF The regulator is switched off and the output voltage is discharged.
- PFM The regulator is switched on and set to PFM mode operation. In this mode, the regulator is always running in PFM mode. Useful at light loads for optimized efficiency.
- Automatic Pulse Skip The regulator is switched on and set to Automatic Pulse Skipping. In this mode, the regulator moves automatically between pulse skipping and full PWM mode depending on load conditions.
- PWM The regulator is switched on and set to PWM mode. In this mode, the regulator is always in full PWM mode operation regardless of load conditions.

 TEST/TRIM - This is not a functional mode, thus requiring certain steps to prevent unintentional activation of this mode. During this mode, the device performs measurements and trimming.

Boost Converters Operation Modes Selections (VYMXPA, VOTG, VBKLT)

- OFF The regulator is switched off
- ON
 - The regulator is switched on and the output is at the programmed level
 - · Maximum load current allowed
- TEST/TRIM
 - This is not a functional mode, thus requiring certain steps to prevent unintentional activation of this mode
 - During this mode, the device performs measurements and trimming

DC-DC Power Supply Summary Table

Table 30 provides a summary of all DC/DC regulators on the 900841.

Regulator	Typ. Voltage	Max Continuous Current	Description
VCC	0.3 - 1.2 V	3.5 A	1.0 MHz synchronous Buck converter with external switching MOSFETs. Internally compensated.
			VID is controlled using a shared 7-bit bus for voltage coding and 2 VID enable signals for VCC or VNN selection.
VNN	0.3 - 1.2 V	1.6 A	1.0 MHz synchronous Buck converter with external switching MOSFETs. Internally compensated.
			VID is controlled using a shared 7-bit bus for voltage coding and 2 VID enable signals for VCC or VNN selection.
VDDQ	1.8 V	1.3 A	4.0 MHz fully integrated 2-switch synchronous Buck PWM voltage mode control DC/DC regulator.
V21	2.1 V	1.0 A	4.0 MHz fully integrated 2-switch synchronous Buck PWM voltage mode control DC/DC regulator.
V15	1.5 V	1.5 A	4.0 MHz fully integrated 2-switch synchronous Buck PWM voltage mode control DC/DC regulator.
VYMX3G	1.25 V	1.0 A	4.0 MHz fully integrated 2-switch synchronous Buck PWM voltage mode control
	0.6-1.375 V		DC/DC regulator.
VYMXPA	4.2 V	0.7 A	2.0 MHz non-synchronous Boost PWM current mode control DC/DC regulator
	5.0 V	0.5 A	with internal low side FET.
VOTG	5.0 V	0.35 A	2.0 MHz non-synchronous Boost PWM current mode control DC/DC regulator with internal low side FET to support host mode in USB On-The-Go systems.
VBKLT	6.0 - 23.0 V	120 mA	2.0 MHz non-synchronous Boost PWM current mode control DC/DC regulator with internal low side FET to support LED backlighting system.

Table 30. SC900841 DC-DC power supplies.

Note that all of the DC/DC regulators specify an extended input voltage range beyond the 3.0 to 4.4 V applications range. Under this extended range, functionality is maintained, but parametric performance might be compromised.

VCC

This is a VID controlled single-phase 1.0 MHz 2-switch synchronous Buck PWM voltage mode control DC/DC regulator, designed to power high performance CPUs. VCC uses external MOSFETs, P-Ch high side and N-Ch low side.

VCC includes support for VID active voltage positioning requirements. A 7-bit DAC reads the VID input signals and sets the output voltage level. The output voltage has a range of 0.3 to 1.2 V. The programming step size is 12.5 mV. Values will be read in real time and will be stored in internal registers not accessible to the system host. Reference VIDEN[1:0] & VID[6:0] Pins for more details.

The same VID input signals are shared between VCC and VNN, where a latch signal for each regulator decides which regulator takes control of the VID input signals.

The DAC value represents the output voltage value. The output voltage node is connected directly to the inverting input of the error amplifier that uses the DAC output as its reference, unity gain configuration. Using this configuration with internal compensation eliminates the need for the feedback and compensation network, which saves board space and cost. The DAC/output voltage slew rate is internally set 25 mV/ $\!\mu s$ to minimize transient currents and audible noise.

The switcher can operate in different modes depending on the load conditions. These modes can be set through the SPI and include a PFM mode, an Automatic Pulse Skipping mode, and a PWM mode. The above selection is optimized to maximum battery life based on load conditions.

VCC will be discharged every time the regulator is shutting down.

The output current will be sensed using an intelligent implementation of the DCR sensing method using internal sensing circuitry, which eliminates the need for an external RC filter network in parallel with the output inductor and its winding resistance.

DCR sensing theory is that if the impedance of the two filters are matching by insuring that $R^*C = L/R_W$, then the voltage across the capacitor is equal to the value of the voltage across the winding resistance R_W , $V_{CAP} = I_{LOAD} * R_W$. Based on this, the voltage across the capacitor is measured, and with a known R_W value, the load current can be extracted. The measured current value will be digitized by the ADC and stored in a register for the processor to access. The method used on the 900841 measures the voltage across R_W in a similar fashion, while using internal sensing circuitry.

The sensed output current value will also be used for overcurrent protection. If an over-current condition is detected, the regulator will limit the current through cycle by cycle operation, and alert the system through the VCCFAULT signal, which will in turn assert the VRFAULT Interrupt signal.



Figure 23. VCC Detailed Internal Block Diagram

Main Features

- Uses the V_{PWR} rail as its power supply
- · It is used to provide power to the CPU Core.
- Single-Phase Solution with Integrated Drivers and external MOSFETs
- VID Controlled for dynamic voltage scaling requirements of high performance processors
- 1.0 MHz switching frequency
- High efficiency operating modes depending on load conditions
- Output can be discharged through the low side switch.

900841

FUNCTIONAL DEVICE OPERATION POWER SUPPLIES

- Loss-Less Output Current Sensing with over-current protection
- Uses internal compensation
- · Gate drive circuits are supplied directly from VPWR

Efficiency Curves

The efficiency curves in <u>Figure 24</u> are calculated under PWM mode, based on the recommended external component values and typical output voltage of 1.2 V. 3.0 V \leq VPWR \leq 4.4 V.



Figure 24. VCC Efficiency Curve

VCC Status/Control Registers and Bits Description

Reference the register map for read/write conditions and default state for each of these registers.

Table 31.	VCC Status	Registers Structure	and Bits Description
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Name	Bits	Description				
VCCCNT (ADDR 0x35 - R/W - Default Value: 0x24)						
CTLVCC	2:0	VCC State Control				
		x0 = Reserved	x4 = OFF			
		x1 = Reserved	x5 = PFM			
		x2 = Reserved	x6 = Automatic Pulse Skipping			
		x3 = Reserved	x7 = PWM			
· · · · · · · · · · · · · · · · · · ·		VCC State Control during AOAC Exit (when Exit pin is EX system SPI controller after power up.	ng AOAC Exit (when Exit pin is EXITSTBY pin is asserted). These bits will be initialized by the fter power up.			
		X0 = Do not copy	x4 = OFF			
		x1 = Do not copy	x5 = PFM			
		x2 = Do not copy	x6 = Automatic Pulse Skipping			
		x3 = Do not copy	x7 = PWM			
Reserved	7:6	Reserved				
		VCCLATCH (ADDR 0X32 - R/W - Det	fault value: 0x7F)			
VIDVCC	6:0	VID VCC Control Through SPI. Signal codes are identical to the VID signal codes. Reference Figures 15 for more details				
DVP1VRD	7	VCC Register override enable bit.				
		X0 = VCC VID control follows the external pins				
		x1 = VCC VID control follows the VIDVCC control register bits				

FUNCTIONAL DEVICE OPERATION POWER SUPPLIES

VNN

This is a VID controlled single-phase 1.0 MHz 2-switch synchronous Buck PWM voltage mode control DC/DC regulator, designed to power high performance CPUs. VNN uses external MOSFETs, P-ch high side and N-ch low side.

VNN includes support for VID active voltage positioning requirements. A 7-bit DAC reads the VID input signals and sets the output voltage level. The output voltage has a range of 0.3 to 1.2 V. The programming step size is 12.5 mV. Values will be read in real time and will be stored in internal registers not accessible to the system host. Reference VIDEN[1:0] & VID[6:0] Pins.

The same VID input signals are shared between VNN and VNN, where a latch signal for each regulator decides which regulator takes control of the VID input signals.

The DAC value represents the output voltage value. The output voltage node is connected directly to the inverting input of the error amplifier that uses the DAC output as its reference, unity gain configuration. Using this configuration with internal compensation eliminates the need for the feedback and compensation network, which saves board space and cost. The DAC/output voltage slew rate is internally set 25 mV/µs to minimize transient currents and audible noise.

The switcher can operate in different modes depending on the load conditions. These modes can be set through the SPI and include a PFM mode, an Automatic Pulse Skipping mode, and a PWM mode. The previous selection is optimized to maximum battery life based on load conditions.

VNN will be discharged every time the regulator is shutting down.

The output current is sense in the same way as it is done on VCC regulator. (See VCC)

The sensed output current value will also be used for overcurrent protection. If an over-current condition is detected, the regulator will limit the current through cycle by cycle operation and alert the system through the VNNFAULT signal, which will in turn assert the VRFAULT Interrupt signal.



Figure 25. VNN Detailed Internal Block Diagram

Main Features

- + Uses the $V_{\mbox{PWR}}$ rail as its power supply
- · It is used to provide power to the Graphics Core.
- Single-Phase Solution with Integrated Drivers and external MOSFETs
- VID Controlled for dynamic voltage scaling requirements of high performance processors
- 1.0 MHz switching frequency
- High efficiency operating modes depending on load conditions

- Output can be discharged through the low side switch.
- Loss-Less Output Current Sensing with over-current protection
- · Uses internal compensation
- · Gate drive circuits are supplied directly from VPWR

Efficiency Curves

The following efficiency curves are calculated under PWM mode based on the recommended external component values and typical output voltage of 1.2. 3.0 V \leq VPWR \leq 4.4 V.



Figure 26. VNN Efficiency Curve

VNN Status/Control Registers and Bits Description

Reference the register map for read/write conditions and default state for each of these registers

Name	Bits	Description				
VNNCNT (ADDR 0x36 - R/W - Default value: 0x04)						
CTLVNN 2:0		VNN State Control				
		x0 = Reserved	x4 = OFF			
		x1 = Reserved	x5 = PFM			
		x2 = Reserved	x6 = Automatic Pulse Skipping			
		x3 = Reserved	x7 = PWM			
		VNN State Control during AOAC Exit (when the Exit pin i by the system SPI controller after power up.	tate Control during AOAC Exit (when the Exit pin is EXITSTBY pin is asserted). These bits will be initialized system SPI controller after power up.			
		X0 = Do not copy	x4 = OFF			
		x1 = Do not copy	x5 = PFM			
		x2 = Do not copy	x6 = Automatic Pulse Skipping			
		x3 = Do not copy	x7 = PWM			
Reserved	7:6	Reserved				
		VNNLATCH (ADDR 0x33 - R/W - Defau	Ilt value: 0x7F)			
VIDVNN	6:0	VID VNN Control Through SPI. Signal codes are identical to the VID signal codes. Reference Figure 15 for more details				
DVP1VRD	7	VNN Register override enable bit.				
		X0 = VNN VID control follows the external pins				
		x1 = VNN VID control follows the VIDVNN control register bits				
VDDQ

This is a 4.0 MHz fully integrated 2-switch synchronous Buck PWM voltage-mode control DC/DC regulator.

The switcher can operate in different modes depending on the load conditions. These modes can be set through the SPI and include a PFM mode, an Automatic Pulse Skipping mode, and a PWM mode. VDDQ will be discharged every time the regulator is shutting down.

The output current is measured internally, digitized by the ADC, and stored in a register for the processor to access. The peak current is sensed internally for over-current protection purposes. If an over-current condition is detected, the regulator will limit the current through a cycle by cycle operation and alert the system through the VDDQFAULT signal, which will in turn assert the VRFAULT Interrupt signal.



Figure 27. VDDQ Detailed Internal Block Diagram

Main Features

- Uses the V_{PWR} rail as its power supply
- It is used as a pre-regulator to many LDO rails, for enhanced efficiency and reduced thermal dissipation. It also supplies power to rails in the CPU (central processing unit), Platform controller hub, and the platform
- Uses Integrated MOSFETs
- 4.0 MHz switching frequency
- High efficiency operating modes depending on load conditions

- Output can be discharged through the low side switch.
- · Peak current sensing with over-current protection
- Uses internal compensation
- · Gate drive circuits are supplied directly from VPWR

Efficiency Curves

The following efficiency curves are calculated under PWM mode, based on the recommended external component values and typical output voltage of 1.8 V. 3.0 V \leq VPWR \leq 4.4 V.



Figure 28. VDDQ Efficiency Curves

VDDQ Status/Control Registers and Bits Description

Reference the register map for read/write conditions and default state for each of these registers.

Table 33.	VDDQ Status and Cor	ntrol Register Structure a	and Bits Description

Name	Bits	Description					
	VDDQCNT (ADDR 0x37 - R/W - Default Value: 0x04)						
CTLVDDQ	2:0	VDDQ State Control					
		x0 = Reserved	x4 = OFF				
		x1 = Reserved	x5 = PFM				
		x2 = Reserved	x6 = Automatic Pulse Skipping				
		x3 = Reserved	x7 = PWM				
AOACCTLVDDQ	5:3	VDDQ State Control during AOAC Exit (when EXITSTBY pin is asserted). These bits will be initialized by the system SPI controller after power up.					
		X0 = Do not copy	x4 = OFF				
		x1 = Do not copy	x5 = PFM				
		x2 = Do not copy	x6 = Automatic Pulse Skipping				
		x3 = Do not copy	x7 = PWM				
Reserved	7:6	Reserved					

V21

This is a 4.0 MHz fully integrated 2-switch synchronous Buck PWM voltage-mode control DC/DC regulator.

The switcher can operate in different modes depending on the load conditions. These modes can be set through the SPI and include a PFM mode, an Automatic Pulse Skipping mode, and a PWM mode. The previous selection is optimized to maximum battery life based on load conditions. V21 will be discharged every time the regulator is shutting down.

The output current is measured internally, digitized by the ADC, and stored in a register for the processor to access.

The peak current is sensed internally for over-current protection purposes. If an over-current condition is detected, the regulator will limit the current through cycle by cycle operation and alert the system through the V21FAULT signal, which will in turn assert the VRFAULT Interrupt signal.



Figure 29. V21 Detailed Internal Block Diagram

Main Features

- Uses the V_{PWR} rail as its power supply
- It is used as a pre-regulator to many LDO rails, for enhanced efficiency and reduced thermal dissipation.
- Uses Integrated MOSFETs
- 4.0 MHz switching frequency

- High efficiency operating modes depending on load conditions
- Output can be discharged through the low side switch.
- · Peak current sensing with over-current protection
- Uses internal compensation
- · Gate drive circuits are supplied directly from VPWR

Efficiency Curves

The following efficiency curves are calculated under PWM mode, based on the recommended external component

values and typical output voltage of 2.1 V. 3.0 V \leq VPW \leq 4.4 V.



Figure 30. V21 Efficiency Waveforms

V21 Status/Control Registers and Bits Description

Reference the register map for read/write conditions and default state for each of these registers.

Table 34. V21 Status/Control Regist	ers Structure and Bits Description
-------------------------------------	------------------------------------

Name	Bits	Description		
		V21CNT (ADDR 0x38 - R/W - Defa	ult value: 0x07)	
CTLV21	2:0	V21 State Control		
		x0 = Reserved	x4 = OFF	
		x1 = Reserved	x5 = PFM	
		x2 = Reserved	x6 = Automatic Pulse Skipping	
		x3 = Reserved	x7 = PWM	
AOACCTLV21	5:3	V21 State Control during AOAC Exit (when EXITSTBY pin is asserted). These bits will be initialized by the system SP controller after power up		
		X0 = Do not copy	x4 = OFF	
		x1 = Do not copy	x5 = PFM	
		x2 = Do not copy	x6 = Automatic Pulse Skipping	
		x3 = Do not copy	x7 = PWM	
Reserved	7:6	Reserved		

V15

This is a 4.0 MHz fully integrated 2-switch synchronous Buck PWM voltage-mode control DC/DC regulator.

The switcher can operate in different modes depending on the load conditions. These modes can be set through the SPI and include a PFM mode, an Automatic Pulse Skipping mode, and a PWM mode. The above selection is optimized to maximum battery life based on load conditions.

V15 will be discharged every time the regulator is shutting down.

The output current is measured internally, digitized by the ADC, and stored in a register for the processor to access.

The peak current is sensed internally for over-current protection purposes. If an over-current condition is detected, the regulator will limit the current through cycle by cycle operation and alert the system through the V15FAULT signal, which will in turn assert the VRFAULT Interrupt signal.

Please note that when VYMXGPS is set at 1.3 V, V15 is automatically set at 1.6 V to maintain voltage headroom for the operation of 1.3 V VYMXGPS, reference VYMXGPS for more details.

FUNCTIONAL DEVICE OPERATION POWER SUPPLIES



Figure 31. V15 Detailed Internal Block Diagram

Main Features

- Uses the V_{PWR} rail as its power supply
- It is used as a pre-regulator to many LDO rails, for enhanced efficiency and reduced thermal dissipation. It also supplies power to rails in the Platform controller hub
- Uses Integrated MOSFETs
- 4.0 MHz switching frequency
- High efficiency operating modes depending on load conditions

- · Output can be discharged through the low side switch.
- Peak current sensing with over-current protection
- Uses internal compensation
- · Gate drive circuits are supplied directly from VPWR

Efficiency Curves

The following efficiency curves are calculated under PWM mode, based on the recommended external component values and typical output voltage of 1.5 V. 3.0 V \leq VPWR \leq 4.4 V.



Figure 32. V15 Efficiency Curves

V15 Status/Control Registers and Bits Description

Reference the register map for read/write conditions and default state for each of these registers.

Table 35. V15CNT Register Structure and Bits Description

Name	Bits	Description				
	V15CNT (ADDR 0x39 - R/W - Default value: 0x07)					
CTLV15	2:0	V15 State Control				
		x0 = Reserved	x4 = OFF			
		x1 = Reserved	x5 = PFM			
		x2 = Reserved	x6 = Automatic Pulse Skipping			
		x3 = Reserved	x7 = PWM			
AOACCTLV15	5:3	5:3 V15 State Control during AOAC Exit (when EXITSTBY pin is asserted). These bits will be initialize controller after power up				
		X0 = Do not copy	x4 = OFF			
		x1 = Do not copy	x5 = PFM			
		x2 = Do not copy	x6 = Automatic Pulse Skipping			
		x3 = Do not copy	x7 = PWM			
SELV15	7:6	V15 Output Voltage Selection (FSL Usage Only)				
		X0 = 1.5 V				
		x1 = 1.6 V x2, x3 = Reserved				

VYMX3G

This is a 4.0 MHz fully integrated 2-switch synchronous Buck PWM voltage-mode control DC/DC regulator.

The switcher can operate in different modes depending on the load conditions. These modes can be set through the SPI and include a PFM mode, an Automatic Pulse Skipping mode, and a PWM mode. The above selection is optimized to maximum battery life based on load conditions.

VYMX3G will be discharged every time the regulator is shutting down.

The output current is measured internally, digitized by the ADC, and stored in a register for the processor to access.

The peak current is sensed internally for over-current protection purposes. If an over-current condition is detected, the regulator will limit the current through cycle by cycle operation and alert the system through the VYMX3GFAULT signal, which will in turn assert the VRFAULT Interrupt signal.

This regulator is used as the advanced communications modules digital core supply and has to different output voltage settings depending on the application. For WiMAX applications the output voltage is set to 1.25 V. For 3G applications the output voltage can be varied between 0.6 to 1.375 V through the Mini-SPI interface. See Advanced COMMs Serial Interface for more details.



Figure 33. VYMX3G Detailed Internal Block Diagram

FUNCTIONAL DEVICE OPERATION POWER SUPPLIES

Main Features

- Uses the V_{PWR} rail as its power supply
- Used as the advanced communications module digital core supply
- Uses Integrated MOSFETs
- 4.0 MHz switching frequency
- High efficiency operating modes depending on load conditions
- · Output can be discharged through the low side switch

- · Output current sensing with over-current protection
- Uses internal compensation
- · Gate drive circuits are supplied directly from VPWR

Efficiency Curves

The following efficiency curves are calculated under PWM mode based on the recommended external component values and typical output voltage of 1.2 V. 3.0 V \leq VPWR \leq 4.4 V.



Figure 34. VYMX3G Efficiency Curves

VYMX3G Status/Control Registers and Bits Description

Reference the register map for read/write conditions and default state for each of these registers.

Table 36. VYMX3G Control Register Structure and Bits Description

Name	Bits	Description		
		VYMX3GCNT (ADDR 0x3C - R/W - Defau	lt Value: 0x24)	
CTLVYMX3G	2:0	VYMX3G State Control		
		x0 = Reserved	x4 = OFF	
		x1 = Reserved	x5 = PFM	
		x2 = Reserved	x6 = Automatic Pulse Skipping	
		x3 = Reserved	x7 = PWM	
AOACCTLVYMX3G 5:3 VYMX3G State Control during AOAC Exit (when Exit pin is EXITSTBY pin is ass initialized by the system SPI controller after power up.		in is EXITSTBY pin is asserted). These bits will be		
		X0 = Do not copy	x4 = OFF	
		x1 = Do not copy	x5 = PFM	
		x2 = Do not copy	x6 = Automatic Pulse Skipping	
		x3 = Do not copy	x7 = PWM	
SELVYMX3G	7:6	VYMX3G Output Voltage Selection.		
		X0 = 1.25 V (WiMAX Operation)		
		x1 = 1.0 V (Default 3G Operation Mini-SPI controls output voltage)		
		x2, x3 = Reserved		

VYMXPA

This is a 2.0 MHz non-synchronous Boost PWM currentmode control DC/DC regulator with internal low side FET.

VYMXPA is designed to supply the Power Amplifier for the WiMAX module, it provides a fixed 4.2V output voltage, and capability to supply up to 700 mA of drive current. It can also be used to support many applications that need a 5.0 V supply voltage, as in motor drives and high current OTG Buses. If used as a 5.0 V supply then the current capability is limited to a 500 mA maximum.

Since the output of VYMXPA is close to the maximum battery voltage, at very high battery input voltage conditions, the output will track the battery voltage minus a diode forward voltage drop (output is directly connected to the input through the inductor and an external diode).

Due to the possible need to isolate the output of VYMXPA boost from the actual load, an external PMOS switch (M_{YMXPA}) will be used to switch in VYMXPA output to the load, as shown in Figure 13. M_{YMXPA} is always enabled and if it is not needed,

then do not populate the switch and ground the YMXPAGTIN and YMXPAGT pins.

When M_{YMXPA} is used, then users can either connect the feedback node after or before the switch. Accuracy is maintained where the feedback node is connected. The output capacitor C_{OYMXPA} can also connect to either node but is recommended to follow the feedback node connection.

VYMXPA can be discharged only if M_{YMXPA} is used and the feedback node is taken after the switch. The discharge FET is connected internally to the FBYMXPA pin. If M_{YMXPA} is not used, then the discharge FET should be disabled by setting the VYMXPADISDSCH bit, since VYMXPA cannot be discharged due to the lack of an isolation FET (the output is directly connected to the input through the inductor and an external diode).

Since VYMXPA is supplying the power amplifier of a WiMAX module, it can be presented with a high load transient current, so close attention to the VYMXPA transient response is in order here to account for these possible load changes.

VYMXPA includes under-voltage, over-voltage, overcurrent, and short-circuit protection.



Figure 35. VYMXPA Detailed Internal Block Diagram

Under-voltage Detection

VYMXPA features an output under-voltage detection comparator that serves as an output ready signal, along with the absence of faults. When VYMXPA is turned on, a VYMXPAFAULT is asserted, the under-voltage comparator is turned on, and V_{OYMXPA} starts ramping up. When V_{OYMXPA} (measured at FBYMXPA) reaches a steady state, VYMXPAFAULT is de-asserted to indicate the VYMXPA output readiness to start. During operation, if the output voltage is decreased below the under-voltage threshold, an undervoltage condition is detected, and VYMXPAFAULT is asserted. If the output voltage rises above the under-voltage threshold plus hysteresis, the VYMXPAFAULT signal is cleared, assuming no other faults are occurring.

Over-current Protection

VYMXPA limits the peak inductor current by sensing the switch MOSFET current. The over-current threshold value is set higher than the worst peak inductor current value. If an over-current is detected, the switch MOSFET turns off, the VYMXPAFAULT flag is asserted, and the regulator goes into a cycle by cycle current limiting until the fault is serviced. If the

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output current falls below the over-current threshold, normal operation is regained and the VYMXPAFAULT is cleared, assuming no other faults are occurring.

Short-circuit Protection

VYMXPA protects the internal MOSFET from excessive currents, in case of an output short, by detecting the voltage on the feedback pin FBYMXPA. If the FBYMXPA voltage falls below a set threshold, VYMXPA detects a short-circuit, turns off VYMXPA, turns off the isolation switch, and asserts the VYMXPAFAULT flag. There is no automatic restart after this event, and VYMXPA has to be re-enabled in order to clear the VYMXPAFAULT flag.

Short-circuit protection is disabled during soft start, to prevent false or premature detection of a short-circuit condition, as the block will be subjected to an inrush current possibly higher than the trip threshold. If a short were already present when starting up, soft start would end after about 4.0 ms, SC is detected, and the boost is disabled as described.

Over-voltage Protection

VYMXPA features an output over-voltage protection comparator that senses the output voltage through an internal resistor divider connected at FBYMXPA pin, compares it to an internal reference, and shuts down the regulator, in the case an excessive voltage occurs for any reason, and asserts the VYMXPAFAULT flag. The overvoltage threshold is fixed at a 5.77 V typical. There is no automatic restart after this event. VYMXPA has to be reenabled in order to clear the VYMXPAFAULT flag.

Main Features

- Supplies the power amplifier of a WiMAX module.
- Uses the V_{PWR} rail as its power supply
- Supports up to 700 mA (500 mA) of output current at 4.2 V (5.0 V) fixed output voltage
- 2.0 MHz switching frequency
- Uses internal compensation
- · Soft Start feature to minimize inrush currents at power up
- Uses internal low side switch MOSFET
- Gate drive circuits are supplied directly from V_{PWR}
- Output over-voltage, under-voltage, over-current, and short-circuit protection
- · External switch control for output isolation when needed

Efficiency Curves

The following efficiency curves are calculated based on the recommended external component values and typical output voltage. 3.0 V \leq VPWR \leq 4.4 V. Curves below do not take in account the switch drop across M_{YMXPA}.



Figure 36. VYMXPA Efficiency Curves (V_{OYMXPA} = 4.2 V)



Figure 37. VYMXPA Efficiency Curves (V_{OYMXPA} = 5.0 V)

VYMXPA Status/Control Registers and Bits Description

Reference the register map for read/write conditions and default state for each of these registers.

Name	Bits	Description				
	VYMX3GPACNTL (ADDR 0x3B - R/W - Default value: 0x24)					
CTLVYMX3GPA	2:0	VYMX3GPA State Control				
		x0 = Reserved	x4 = Output is OFF			
		x1 = Reserved	x5 = Not Used			
		x2 = Reserved	x6 = Not Used			
		x3 = Reserved	x7 = Output is ON			
AOACCTLVYMX3GPA	5:3	5:3 VYMX3GPA State Control during AOAC Exit (when Exit pin is EXITSTBY pin is asserte initialized by the system SPI controller after power up.				
		X0 = Don't Copy	x4 = Output is OFF			
		x1 = Don't Copy	x5 = Not Used			
		x2 = Don't Copy	x6 = Not Used			
		x3 = Don't Copy	x7 = Output is ON			
SELVYMX3GPA	7:6	VYMX3GPA Output Voltage Settings				
	x0 = 4.2 V (WiMAX application)					
		x1 = Reserved				
		x2 = 5.0 V (General use applications)				
		x3 = Not Used				

VYMXPA Status/Control Registers and Bits Description (Freescale Defined)

Reference the register map for read/write conditions and default state for each of these registers

Table 38. FSLVYMXPACNTL Register Structure and Bits Description

Name	Bits	Description		
FSLVYMXPACNTL (ADDR 0x1C7 - R/W - 0x01)				
VYMXPADISDSCH	0	VYMXPA Discharge FET Disable Signal		
		x0 = Discharged enabled		
		x1 = Discharged disabled		
Reserved	7:1	Reserved		

VOTG

This is a 2.0 MHz non-synchronous Boost PWM currentmode control DC/DC regulator with internal low side FET. VOTG provides a fixed 5.0 V output voltage and capability to supply up to 350 mA of drive current. It can be used separately to support many applications that need a 5.0 V supply voltage, as in motor drives. The following are the typical loads for VOTG in SC900841 application

- Signaling/Status LED Drivers, See Lighting System.
- USB Bus (VBUS) while 900841 is operating in host mode as part of an UBS On-The-Go (OTG) System.

VOTG allows the 900841 the capability to support host mode in USB-OTG systems. It offers the capability of up to 100 mA to supply to the USB Bus (VBUS). Due to the need to isolate the USB Bus from the rest of the system when not in use, an external PMOS switch (M_{OTG}) will be used to switch in a VOTG output to VBUS, as shown in Figure 16.

 M_{OTG} enable is controlled through the CHRG and OTGB bits in the CHRGCNTL register. Reference Active State for more details into when the OTG host mode is enabled and M_{OTG} is enabled. OTG host mode is only possible when under battery operation and no input power is connected. When OTG host mode is enabled, the USBDET interrupt flag is ignored.

If OTG support is not needed, this switch does not need to be populated, reducing the overall system cost, while the OTGGTIN and OTGGT pins are grounded

The rest of the VOTG load consists of a total of 6 LED drivers at 30 mA maximum each. These LED drivers may turn on one at a time, at different drive values, or they may all turn on together at the maximum driver value for each. Close attention to VOTG transient response is in order here, to account for these possible load changes.

If OTG host mode is not used, M_{OTG} can still be used as an isolation switch. When M_{OTG} is used, then users can either connect the feedback node after or before the switch. Accuracy is maintained where the feedback node is connected. The output capacitor C_{OOTG} can also connect to either node, but is recommended to follow the feedback node connection.

VOTG can be discharged only if M_{OTG} is used and the feedback node is taken after the switch. The discharge FET is connected internally to the FBOTG pin. If M_{OTG} is not used, then the discharge FET should be disabled by setting the VOTGDISDSCH bit, since VOTG cannot be discharged due to the lack of an isolation FET (the output is directly connected to the input through the inductor and an external diode).

VOTG includes under-voltage, over-voltage, over-current, and short-circuit protection.



Figure 38. VOTG Detailed Internal Block Diagram (Using OTG Host Mode)

VOTG Operation

VOTG on/off control is based on a combination of signals, FSLVOTGCNTL2 bits (<u>Table 40</u>), and CHRG and OTGB bits in the CHRGCNTL register. <u>Table 39</u> summarizes VOTG response to the signals.

The CHRG bit will direct if the OTG Host mode is allowed, and the OTGB bit will control if the OTG Boost voltage is fed to the connector. In other words, if CHRG=0, then the isolation FET is OFF, regardless of the status of OTGB and CTLVOTG, and the boost is controlled directly via the CTLVOTG.

If CHRG=1, then the isolation FET is controlled via the OTGB signal. If OTGB=0, then the boost is on and the isolation FET is on. If OTGB=1, then the boost is controlled via CTLVOTG.

Remember that the VOTG can handle two different loads, before the switch (LEDs) and after the switch (OTG Host). This is why it is extremely important to separate the operation of the Boost output and the isolation FET. See <u>Table 39</u> for a truth table of the discussion.

CHRG	OTGB	CTLVOTG	VOTG	Isolation FET	SC900841	Comments
0	0	OFF	OFF	OFF	Since CHRG=0, then	This does not mean that we cannot use VOTG (the
0	0	ON	ON	OFF	SC900841 the system intends for the charger to	node before the isolation switch) to supply other loads like RGB LEDs. This is why the VOTG output is
0	1	OFF	OFF	OFF	work in the buck mode, so no	controlled directly by the CTLVOTG. Notice if
0	1	ON	ON	OFF	OTG host mode is required. The isolation FET should stay OFF	CHRG=0, OTGB does not play a role, and software should plan for that
1	0	OFF	ON	ON	Since CHRG=1, then the	OTG mode is allowed, now supplying the voltage to
1	0	ON	ON	ON	system intends the charger to work in the boost mode, so	the connector, which is controlled via the OTGB bit, directly turning the isolation FET on/off.
1	1	OFF	OFF	OFF	the OTG host mode is	If OTGB=0, then the OTG voltage is supplied to the
1	1	ON	ON	OFF	allowed. The isolation FET can be turned off/on to supply OTG voltage to the connector	connector (VOTG and isolation FET are on). If OTGB=1, then the isolation FET is OFF and the VOTG voltage is controlled directly through the CTLVOTG bits to supply another load if desired

Table 39. VOTG On/Off Control

Under-voltage Detection

VOTG features an output under-voltage detection comparator that serves as an output ready signal along with the absence of faults. When VOTG is turned on, VOTGFAULT is asserted, the under-voltage comparator is turned on, and V_{OOTG} starts ramping up. When V_{OOTG} (measured at FBOTG) reaches a steady state, VOTGFAULT is de-asserted to indicate the VOTG output readiness to start. During operation, if the output voltage decreased below the under-voltage threshold, an under-voltage condition is detected and VOTGFAULT is asserted. If the output voltage rises above the under-voltage threshold plus hysteresis, the VOTGFAULT signal is cleared, assuming no other fault are occurring.

Over-current Protection

VOTG limits the peak inductor current by sensing the switch MOSFET current. The over-current threshold value is set higher than the worst peak inductor current value. If an over-current is detected, the switch MOSFET turns off, the VOTGFAULT flag is asserted, and the regulator goes into a cycle by cycle current limiting until the fault is serviced. If the output current falls below the over-current threshold, normal operation is regained and the VOTGFAULT is cleared, assuming no other faults are occurring.

automatic restart after this event, and VOTG has to be re-

Short-circuit Protection

VOTG protects the internal MOSFET from excessive currents, in case of an output short, by detecting the voltage on the FBOTG feedback pin. If the FBOTG voltage falls below a set threshold, VOTG detects a short-circuit, turns off VOTG, turns off the isolation switch, and asserts the VOTGFAULT flag. There is no automatic restart after this event, and VOTG has to be re-enabled in order to clear the VOTGFAULT flag.

Short-circuit protection is disabled during soft start to prevent false or premature detection of a short-circuit condition, as the block will be subjected to an inrush current, possibly higher than the trip threshold. If a short were already present when starting up, soft start would end after about 4.0 ms and then, SC is detected and the boost is disabled as described.

Over-voltage Protection

VOTG features an output over-voltage protection comparator that senses the output voltage through an internal resistor divider connected at the FBOTG pin. It compares it to an internal reference, shuts down the regulator, in the case that an excessive voltage occurs for any reason. It then asserts the VOTGFAULT flag. The overvoltage threshold is fixed at 5.77V, typical. There is no enabled in order to clear the VOTGFAULT flag.

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Main Features

- · Supplies signaling/status LEDs and USB OTG
- Uses the V_{PWR} rail as its power supply
- Supports up to 350 mA of output current at a 5.0 V fixed output voltage
- 2.0 MHz switching frequency
- · Uses internal compensation
- Soft start feature to minimize inrush currents at power up
- · Uses an internal low side switch MOSFET

- Gate drive circuits are supplied directly from V_{PWR}
- Output over-voltage, over-current, and short-circuit protection
- · External switch control for output isolation when needed

Efficiency Curves

The following efficiency curves are calculated, based on the recommended external component values and typical output voltage. 3.0 V \leq VPWR \leq 4.4 V. The following curves do not take in account the switch drop across M_{OTG}



Figure 39. VOTG Efficiency Curves

VOTG Status/Control Registers and Bits Description

The following registers are defined by Freescale in order to provide extended functionality to the VOTG regulator.

Table 40.	VOTG Status and	Control Registers	s Structure and	d Bits Description
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Name	Bits	Description				
	FSLVOTGCNTL2 (ADDR 0x1C6 - R/W - Default Value: 0x24)					
CTLVOTG	2:0	VOTG State Control				
		x0 = Reserved	x4 = VOTG is OFF			
		x1 = Reserved	x5 = Not Used			
		x2 = Reserved	x6 = Not Used			
		x3 = Reserved	x7 = VOTG is ON			
AOACCTLVOTG	OACCTLVOTG 5:3 VOTG State Control during AOAC Exit (when the Exit pin is EXITSTBY pin is asserted). These bits by the system SPI controller after power up.		is EXITSTBY pin is asserted). These bits will be initialized			
		X0 = Don't Copy	x4 = VOTG is OFF			
		x1 = Don't Copy	x5 = Not Used			
		x2 = Don't Copy	x6 = Not Used			
		x3 = Don't Copy	x7 = VOTG is ON			
Reserved	7:6	Reserved				

Table 40. VOTG Status and Control Registers Structure and Bits Description

FSLVOTGCNTL1 (ADDR 0x1C5 - R/W - Default Value: 0x01)						
VOTGDISDSCH	0	VOTG Discharge FET Disable Signal				
	x0 = Discharged enabled					
	x1 = Discharged disabled					
Reserved	7:1	Reserved				

VBKLT

This is a 2.0 MHz non-synchronous Boost PWM current mode control DC/DC regulator with an internal low side FET.

VBKLT supplies two different loads (see Lighting System) as part of the 900841 LED support:

- 3 strings at up to 5 LEDs per string (3P5S) for LCD backlights. Each string is capable of up to 30 mA.
- 1 string of up to 5 LEDs (1P5S) capable of up to 30 mA for camera scene illumination support.

The Camera Scene Illumination string can be used to expand the backlight support to 4 strings of up to 5 LEDs each (4P5S).

The 900841 can also support an independent zone backlighting option, each supported by two strings. Both backlight displays are completely independent

VBKLT is dedicated to support the prior two loads and cannot be operated with any other load, i.e. VBKLT is

enabled only when one or both of the prior two loads is enabled.

It contains adaptive boost control when backlight LEDs are running, to minimize the voltage headroom across the backlight LED current sinks, which in turn reduces power dissipation and saves on overall efficiency. When only operating the camera scene illumination LEDs, the VBKLT output voltage is set to a fixed 22 V output. If the Camera scene string is selected as part of backlight operation, then it can also be selected as part of the adaptive boost control.

PWM signals for the backlight strings are staggered to reduce the amount of transient current on the output of VBKLT and inrush current from the battery.

VBKLT includes under-voltage detection, over-voltage protection, open LED protection, short-circuit and overcurrent protection



Figure 40. VBKLT Detailed Internal Block Diagram

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Operation

VBKLT is not independent and cannot be operated with another load, however the backlight LEDs can be operated without VBKLT.

When supplying only the LCD backlight or both loads, VBKLT uses the lowest voltage of WLED1, WLED2, WLED3, or LEDSCN (if used for backlight support and/or S4ADAPT bit in register FSLVBKLTADAPT is set) as its reference voltage for output voltage regulation. This method assures the string with the highest drop (lowest voltage) has enough voltage headroom to operate, and the minimum output voltage (maximum forward voltage drop across LED strings + voltage headroom necessary to operate the current sinks) is set at the minimum value necessary to drive all LED strings, which reduces power dissipation. If the 4th string is used for camera scene illumination application, then it does not control the output voltage VBKLT.

When supplying only the camera scene illumination string, the output voltage of VBKLT is fixed to 22 V, and uses a fixed reference voltage.

By setting the TWOPTWO bit in the FSLVBKLTCNTL, the 900841 can support an independent zone backlighting option, where strings 1 and 2 support one display backlight, and strings 3 and 4 (Camera scene) support another display. Both string groups are completely independent in terms of frequency and duty cycle control. They are both still supplied from the VBKLT rail.

This reference voltage selection is controlled by the MLED1EN, MLED2EN, MLED3EN, MLED4EN, and SLEDEN bits as shown in <u>Table 41</u>.

MLED1EN	MLED2EN	MLED3EN	MLED4EN	SLEDEN	S4ADAPT	VBKLT Voltage Reference
0	0	0	0	0	0	OFF
0	0	0	0	1	0	Fixed
0	0	0	0	1	1	Adaptive
0	0	0	1	0	x	Invalid
x	х	х	1	1	x	Adaptive
1	х	х	х	х	x	Adaptive
x	1	х	x	х	x	Adaptive
х	x	1	x	x	x	Adaptive

Table 41. VBKLT Reference Selection

The LED current sinks, WLED1-3, can be used as PWM outputs by providing a pull-up to a supply, such as 3.3 V. These PWM outputs can be used to drive an "Integrated Display" with local power supply. In this case, and in the event camera scene illumination is not needed either, then VBKLT is not used and the current sinks are enabled by the PWMEN signal. This signal only enables the current sinks and not VBKLT

VBKLT cannot drive LED(s) with a total minimum forward voltage drop of less than the maximum battery voltage.

VBKLT cannot be discharged due to the lack of an isolation FET (the output is directly connected to the input through the inductor and the external diode). VBKLT however limits the LED leakage current in the off state through the internal current sinks.

VBKLT can support higher number of LEDs in series, with an applications work-around. Reference the Freescale's

Evaluation Board KITINTMIDPMMEVBE schematics or discuss with your Freescale representative for more details.

VBKLT Enable Control

<u>Table 42</u> outlines different cases for VBKLT operation, depending on the display type used and the loads being supplied.

Note that the 4th string cannot be operated for backlighting unless the camera scene enable bit (SLEDEN) is asserted. Also, in order for the 4th string to have the ability to turn on VBKLT, SLEDEN has to be asserted.

In summary, in order for MLED4EN to have any effect, SLEDEN has to also be asserted. This holds true in all of the cases in <u>Table 42</u>.

Table 42 outlines the relation between the different enable bits, the status of VBKLT, and the application mode supported. An "x" in the MLEDxEN column refers to strings 1, 2, and 3.

PWMEN	MLEDxEN	ΤWOPTWO	SLEDEN	MLED4EN	VBKLT	String 1-3	String 4
0	0	х	0	х	OFF	OFF	OFF
0	0	0	1	0	ON	OFF	Camera Scene

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Table 42. Backlight and Camera Scene LED Enable Bits Control

	-						
0	0	0	1	1	ON	OFF	Backlight - BKLT1
0	0	1	1	х	ON	OFF	Backlight - BKLT2
0	1	0	0	х	ON	S1-3 Backlight - BKLT1	OFF
0	1	0	1	0	ON	S1-3 Backlight - BKLT1	Camera Scene
0	1	0	1	1	ON	S1-3 Backlight - BKLT1	Backlight - BKLT1
0	1	1	0	х	ON	S1-2 Backlight - BKLT1	OFF
						S3 Backlight - BKLT2	
0	1	1	1	х	ON	S1-2 Backlight - BKLT1	Backlight - BKLT2
						S3 Backilight - BKLT2	
1	0	0	0	х	OFF	S1-3 PWM - BKLT1	OFF
1	0	0	1	0	ON	S1-3 PWM - BKLT1	Camera Scene
1	0	0	1	1	ON	S1-3 PWM - BKLT1	Backlight - BKLT1
1	0	1	0	х	OFF	S1-2 PWM - BKLT1	OFF
						S3 PWM - BKLT2	
1	0	1	1	х	ON	S1-2 PWM - BKLT1	Backlight - BKLT2
						S3 PWM - BKLT2	
1	1	х	x	х	Invalid: PWM mode can't be set at the same time than Backlight for strings 1-3		

Under-voltage Detection

VBKLT features an output under-voltage detection comparator that serves as an output ready signal along with the absence of faults. When VBKLT is turned on, VBKLTFAULT is asserted, the under-voltage comparator is turned on, and VOBKLT starts ramping up. When VBKLT reaches a steady state, VBKLTFAULT is de-asserted, to indicate the VBKLT output readiness to start PWMing the LED sinks.

If VBKLT is supplying the backlight LEDs, the undervoltage comparator is turned off, since the output voltage will not be regulated and is moving, depending on the LED current level and forward voltage drop. If VBKLT is only supplying the camera scene illumination, the under-voltage comparator can stay on, as it is set as a fixed output voltage of 22 V.

MLEDXEN	SLEDEN	Under-voltage Comparator
0	0	OFF
0	1	Stays On After VBKLT Ready
1	0	Turns OFF After VBKLT Ready
1	1	Turns OFF After VBKLT Ready

During operation if the output voltage decreased below the undervoltage threshold, an undervoltage condition is detected, VBKLTFAULT is asserted. If the output voltage rises above the under-voltage threshold plus hysteresis, then the VBKLTFAULT signal is cleared, assuming no other faults are occurring.

Over-voltage Protection

VBKLT features an output over-voltage protection comparator that senses the output voltage through an internal resistor divider connected at the FBBKLT pin. It compares the output voltage to an internal reference and shuts down the regulator, in the case an excessive voltage occurs, due to an open LED or other reason, and asserts the VBKLTFAULT flag. The over-voltage threshold is fixed at 24 V, typical. The output is re-enabled, the VBKLTFAULT is cleared (assuming no other faults are occurring), and normal operation is resumed when the voltage drops below the overvoltage threshold, minus hysteresis.

Any current sinks being supplied from VBKLT are also turned off.

The output voltage can also be clamped by connecting a Zener diode from the output to ground. The Zener breakdown must be at least 3.0 V higher than the output voltage setting.

Over-current Protection

VBKLT also limits the peak inductor current by sensing the switch MOSFET current. The over-current threshold value is set higher than the worst peak inductor current value. If an over-current is detected, the switch MOSFET turns off, the VBKLTFAULT flag is asserted, and the regulator goes into a cycle by cycle current limiting until the fault is serviced. If the output current falls below the over-current threshold, normal operation is regained, and the VBKLTFAULT is cleared (assuming no other faults are occurring).

Short-circuit Protection

VBKLT protects the internal MOSFET from excessive currents, in case of an output short, by detecting the voltage on the FBBKLT feedback pin. If the FBBKLT voltage falls below a set threshold, VBKLT detects a short-circuit, turns off VBKLT, and asserts the VBKLTFAULT flag. There is no automatic restart after this event, and VBKLT has to be reenabled in order to clear the VBKLTFAULT flag.

Short-circuit protection is disabled during soft-start to prevent false or premature detection of a short-circuit condition. The block will be subjected to an inrush current, possibly higher than the trip threshold. If a short were already present when starting up, the soft-start would end after about 4.0 ms. SC is detected, and the boost is disabled as described.

Open LED Protection

VBKLT monitors the LED status at the 3 main backlight channels. If an LED fails open, the voltage at the WLEDx pin for the effected string falls close to ground. When this event is detected, the affected string is taken out of the VBKLT control loop, and the output voltage (V_{BKLT}) is determined by the other two strings. Normal operation can be resumed while the affected string is disabled. If this open LED event caused the output voltage to rise, the output voltage will be clamped to 22 V.

Leakage Current Limiting

The LED leakage current is limited to 1.0 μ A at room temperature when the current sinks are disabled.

Main Features

- Supplies the LCD backlight and camera scene illumination LEDs
- Drives up to 4 parallel strings of up to 5 LED(s) each at 30 mA maximum current
- · Uses the V_{PWR} rail as its power supply
- 120 mA maximum continuous output current for full voltage capabilities.
- · 2.0 MHz switching frequency
- · Uses internal compensation
- · Soft-start feature to minimize inrush currents at power up
- · Uses an internal 26 V low side switch MOSFET
- Output under-voltage detection and output over-voltage, short-circuit, and over-current protection
- Open LED protection
- · Minimum Leakage current in the off state

Efficiency Curves

The efficiency curves in Figure 41 are calculated based on the recommended external component values and typical output voltage. 3.0 V \leq VPWR \leq 4.4 V



Figure 41. VBKLT Efficiency Curves

VBKLT Status/Control Registers and Bits Description

LED Drivers registers will be detailed in Lighting System. There are no dedicated registers for VBKLT.

LDO POWER SUPPLIES

Freescale's power management solution for the Ultramobile platform for MID includes 17 LDO regulators, all of which are housed in the 900841 PMIC.

LDO OPERATION MODES SELECTIONS

- · OFF The regulator is switched off
- Active
 - The regulator is switched on and the output is at the programmed level
 - Maximum load current allowed
- Low Power
 - The regulator is switched on and the output is at the programmed level
 - load current is limited
- TEST/TRIM

- This is not a functional mode, thus requiring certain steps to prevent unintentional activation of this mode
- During this mode, the device performs measurements and trimming

All LDOS are able to work in a low power mode, in which the bias current is reduced. The output drive capability and performance are limited in this mode. This mode occurs automatically when the load current decreases below the low power mode limit, except on VBG and VMM, in which this mode can only be set through SPI programming. All other LDOS can set the low power mode through SPI programming.

Note: If low power mode is set through the SPI at a load current higher than the maximum allowed, the performance of the LDO is not guaranteed.

Table 44 is a summary of LDO characteristics

Regulator	Typ. Voltage	Max Continuous Current	Description
VBG	1.25 V	2.0 mA	Low Drop-out (LDO) fully integrated regulator with a P-CH Pass FET. It is high performance, low noise, and high PSRR with a low quiescent current and fast transient response.
VCCA	1.5 V	150 mA	Low Drop-out (LDO) fully integrated regulator with a P-CH Pass FET. It is high performance, low noise, and high PSRR with a low quiescent current and fast transient response.
VCC180	1.8 V	390 mA	Low Drop-out (LDO) fully integrated regulator with a P-CH Pass FET. It is high performance, low noise, and high PSRR with a low quiescent current and fast transient response.
VPNL18	1.8 V	225 mA	Low Drop-out (LDO) fully integrated regulator with a P-CH Pass FET. It is high performance, low noise, and high PSRR with a low quiescent current and fast transient response.
VPMIC	1.8 V	50 mA	Low Drop-out (LDO) fully integrated regulator with a P-CH Pass FET. It is high performance, low noise, and high PSRR with a low quiescent current and fast transient response.
VYMXYFI18	1.8 V	200 mA	Low Drop-out (LDO) fully integrated regulator with a P-CH Pass FET. It is high performance, low noise, and high PSRR with a low quiescent current and fast transient response.
VYMXYFI	1.2 V	60 mA	Low Drop-out (LDO) fully integrated regulator with a P-CH Pass FET. It is high performance, low noise, and high PSRR with a low quiescent current and fast transient response.
VYMXGPS	1.3 V	350 mA	Low Drop-out (LDO) fully integrated regulator with a P-CH Pass FET. It is high performance, low noise, and high PSRR with a low quiescent current and fast transient response.
VYMXYFI	2.5 V	150 mA	Low Drop-out (LDO) fully integrated regulator with a P-CH Pass FET. It is high performance, low noise, and high PSRR with a low quiescent current and fast transient response.
VYMXGPS	1.8 V	170 mA	Low Drop-out (LDO) fully integrated regulator with a P-CH Pass FET. It is high performance, low noise, and high PSRR with a low quiescent current and fast transient response.
VCCPAOAC	1.05 V	155 mA	Low Drop-out (LDO) fully integrated regulator with a P-CH Pass FET. It is high performance, low noise, and high PSRR with a low quiescent current and fast transient response.
VCCPDDR	1.05 V	60 mA	Low Drop-out (LDO) fully integrated regulator with a P-CH Pass FET. It is high performance, low noise, and high PSRR with a low quiescent current and fast transient response.
VAON	1.2 V	250 mA	Low Drop-out (LDO) fully integrated regulator with a P-CH Pass FET. It is high performance, low noise, and high PSRR with a low quiescent current and fast transient response.
VMM	1.2 V	5.0 mA	Low Drop-out (LDO) fully integrated regulator with a P-CH Pass FET. It is high performance, low noise, and high PSRR with a low quiescent current and fast transient response.

Table 44. SC900841 LDO Power Supplies Summary

Regulator	Typ. Voltage	Max Continuous Current	Description
VCCP	1.05 V	445 mA	Low Drop-out (LDO) fully integrated regulator with a P-CH Pass FET. It is high performance, low noise, and high PSRR with a low quiescent current and fast transient response.
VIMG25	2.5 V	80 mA	Low Drop-out (LDO) fully integrated regulator with a P-CH Pass FET. It is high performance, low noise, and high PSRR with a low quiescent current and fast transient response.
VIMG28	1.5 - 2.9 V	225 mA	Low Drop-out (LDO) fully integrated regulator with a P-CH Pass FET. It is high performance, low noise, and high PSRR with a low quiescent current and fast transient response.
VVIB	1.3 - 2.7 V	200 mA	Low Drop-out (LDO) fully integrated regulator with a P-CH Pass FET. It is high performance, low noise, and high PSRR with a low quiescent current and fast transient response. It is used to drive the vibrator motor for alert functions
VSDIO	1.8 or 3.3 V	215 mA	VSDIO is a combo Low Drop-out (LDO) and power switch. It uses an external P-CH Pass FET. VSDIO serves as an LDO when its output voltage is set to 1.8 V, and as a switch when its output voltage is set to 3.3 V.

Table 44. SC900841 LDO Power Supplies Summary

VBG

VBG is a low drop-out (LDO) fully integrated regulator with a P-CH Pass FET. It is high performance, low noise, and high PSRR, with a low quiescent current and fast transient response. VBG is actively discharged during shutdown. VBG shares an input voltage pin (PVIN1P8) and a reference ground pin (GND1P8) with the VCCA regulator, yet each has independent control. PVIN1P8 is supplied from the VDDQ voltage.



Figure 42. VBG Detailed Internal Block Diagram

Main Features

- Uses VDDQ as the main power supply
- · 2.0 mA maximum continuous output current
- Optimized for a 1.0 μF external filter capacitor with a maximum of 10 m Ω ESR
- Uses an internal pass FET

 The output for each LDO is monitored for over-current conditions and under-voltage events

VBG Status/Control Registers and Bits Description

Reference the register map for read/write conditions and default state for each of these registers.

Table 45. VBG Control Register Structure and Bits Description

Name	Bits	Description						
	VLBGCNT (ADDR 0x3F - R/W - Default Value: 0x24)							
CTLVBG	2:0	VBG State Control						
		x0 = Reserved	x4 = OFF					
		x1 = Reserved	x5 = Low Power					
		x2 = Reserved x6 = Active						
		x3 = Reserved	x7 = Active					
AOACCTLVBG	5:3	VBG State Control during AOAC Exit (when the Exit pin is EXITSTBY pin is asserted). These bits will be initialized by the system SPI controller after power up.						
		X0 = Do not copy	x4 = OFF					
		x1 = Do not copy x5 = Low Power						
		x2 = Do not copy x6 = Active						
		x3 = Do not copy x7 = Active						
Reserved	7:6	Reserved						

VCCA

VCCA is a low drop-out (LDO) fully integrated regulator with a P-CH Pass FET. It is high performance, low noise, and high PSRR, with a low quiescent current and fast transient response. VCCA is actively discharged during shutdown. VCCA shares an input voltage pin (PVIN1P8) and a reference ground pin (GND1P8) with VBG regulator, yet each has independent control. PVIN1P8 is supplied from the VDDQ voltage.



Figure 43. VCCA Detailed Internal Block Diagram

Main Features

- Uses VDDQ as the main power supply
- 150 mA maximum continuous output current
- Optimized for a 2.2 μF external filter capacitor with a maximum of 10 m Ω ESR
- Uses an internal pass FET
- The output for each LDO is monitored for over-current conditions and under-voltage events

VCCA Status/Control Registers and Bits Description

Table 46	VCCA Contro	l Register Str	ucture and Bits	Description
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Name	Bits	Description						
	VCCACNT (ADDR 0x40 - R/W - Default Value: 0x3C)							
CTLVCCA	2:0	VCCA State Control						
		x0 = Reserved x4 = OFF						
		x1 = Reserved	x5 = Low Power					
		x2 = Reserved	x6 = Active					
		x3 = Reserved	x7 = Active					

		-	
AOACCTLVCCA	5:3	VCCA State Control during AOAC Exit (when the Exit pin is EXITSTBY pin is asserted). These bits will be initialized by the system SPI controller after power up.	
		X0 = Do not copy	x4 = OFF
		x1 = Do not copy	x5 = Low Power
		x2 = Do not copy	x6 = Active
		x3 = Do not copy	x7 = Active
Reserved	7:6	Reserved	

Table 46. VCCA Control Register Structure and Bits Description

VCC180

VCC180 is a low drop-out (LDO) fully integrated regulator with a P-CH Pass FET. It is high performance, low noise, and high PSRR, with a low quiescent current and fast transient response. VCC180 is actively discharged during shutdown. VCC180 shares an input voltage pin (PVIN2P1) and a reference ground pin (GND2P1) with VPNL18 and VPMIC regulators, yet each has independent control. PVIN2P1 is supplied from the V21 voltage.

The output current for VCC180 is measured and reported through the ADC. Reference ADC Subsystem for more information.



Figure 44. VCC180 Detailed Internal Block Diagram

Main Features

- Uses V21 as the main power supply
- 390mA maximum continuous output current
- Optimized for a 2.2µF external filter capacitor with a maximum of 10mΩ ESR
- Uses an internal pass FET
- The output for each LDO is monitored for over-current conditions and under-voltage events

VCC180 Status/Control Registers and Bits Description

Table 47.	VCC180CNT	Register Structure	and Bits Description
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Name	Bits	Description		
VCC180CNT (ADDR 0x43 - R/W - 0x3C)				
CTLVCC180	2:0	VCC180 State Control		
		x0 = Reserved	x4 = OFF	
		x1 = Reserved	x5 = Low Power	
		x2 = Reserved	x6 = Active	
		x3 = Reserved	x7 = Active	

Table 47. VCC180CNT Register Structure and Bits Description

AOACCTLVCC180	5:3	VCC180 State Control during AOAC Exit (when the Exit pin is EXITSTBY pin is asserted). These bits will be initialized by the system SPI controller after power up.	
		X0 = Do not copy	x4 = OFF
		x1 = Do not copy	x5 = Low Power
		x2 = Do not copy	x6 = Active
		x3 = Do not copy	x7 = Active
Reserved	7:6	Reserved	

VPNL18

VPNL18 is a low drop-out (LDO) fully integrated regulator with a P-CH Pass FET. It is high performance, low noise, and high PSRR, with a low quiescent current and fast transient response. VPNL18 is actively discharged during shutdown. VPNL18 shares an input voltage pin (PVIN2P1) and a reference ground pin (GND2P1) with VCC180 and VPMIC regulators, yet each has independent control. PVIN2P1 is supplied from the V21 voltage.



Figure 45. VPNL18 Detailed Internal Block Diagram

Main Features

- Uses V21 as the main power supply
- 225 mA maximum continuous output current
- Optimized for a 2.2 μF external filter capacitor with a maximum of 10 m Ω ESR
- Uses an internal pass FET
- The output for each LDO is monitored for over-current conditions and under-voltage events

VPNL18 Status/Control Registers and Bits Description

Table 48. VPNL18 Control Register Structure and Bits Description

Name	Bits	Description			
	VPANEL18CNT (ADDR 0x46 - R/W - Default value: 0x24)				
CTLVPANEL18	2:0	VPNL18 State Control			
		x0 = Reserved	x4 = OFF		
		x1 = Reserved	x5 = Low Power		
		x2 = Reserved	x6 = Active		
		x3 = Reserved	x7 = Active		
AOACCTLVPANEL18	5:3	VPNL18 State Control during AOAC Exit (when the Exit pin is EXITSTBY pin is asserted). These bits will be initialized by the system SPI controller after power up.			
		X0 = Do not copy	x4 = OFF		
		x1 = Do not copy	x5 = Low Power		
		x2 = Do not copy	x6 = Active		
		x3 = Do not copy	x7 = Active		
Reserved	7:6	Reserved			

VPMIC

VPMIC is a low drop-out (LDO) fully integrated regulator with a P-CH pass FET. It is high performance, low noise, and high PSRR, with a low quiescent current and fast transient response. VPMIC is actively discharged during shutdown. VPMIC shares an input voltage pin (PVIN2P1) and a reference ground pin (GND2P1) with VCC180 and VPNL18 regulators, yet each has independent control. PVIN2P1 is supplied from the V21 voltage.



Figure 46. VPMIC Detailed Internal Block Diagram

Main Features

- Uses V21 as the main power supply
- 100 mA maximum continuous output current
- Optimized for a 2.2 μF external filter capacitor with a maximum of 10 m Ω ESR

Table 49. VPMIC Register Structure and Bits Descriptio
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- · Uses an internal pass FET
- The output for each LDO is monitored for over-current conditions and under-voltage events

VPMIC Status/Control Registers and Bits Description

Name	Bits	Description				
	VPMICCNT (ADDR 0x41 - R/W - Default Value: 0x07)					
CTLVPMIC	2:0	VPMIC State Control				
		x0 = Reserved	x4 = OFF			
		x1 = Reserved	x5 = Low Power			
		x2 = Reserved	x6 = Active			
		x3 = Reserved	x7 = Active			
AOACCTLVPMIC	5:3	VPMIC State Control during AOAC Exit (when the Exit pin is EXITSTBY pin is asserted). These bits initialized by the system SPI controller after power up.				
		X0 = Do not copy	x4 = OFF			
		x1 = Do not copy	x5 = Low Power			
		x2 = Do not copy	x6 = Active			
		x3 = Do not copy	x7 = Active			
Reserved	7:6	Reserved				

VYMXYFI18

VYMXYFI18 is a low drop-out (LDO) fully integrated regulator with a P-CH Pass FET. It is high performance, low noise, and high PSRR, with a low quiescent current and fast transient response. VYMXYFI18 is actively discharged during shutdown.

VYMXYFI18 supplies a 1.8 V output voltage to the communications modules in the system for WiMAX and WiFiBT applications

VYMXYFI18 can be supplied by either the V21 output voltage (V21) or directly from the VPWR node. Using V21 as the input voltage supply offers enhanced thermal performance and higher efficiency. Using the VPWR node can offer enhanced performance against noise coupling from an output of a DC/DC regulator. Users are encouraged to take the resulting thermal dissipation in account when supplying VYMXYFI18 directly from VPWR. For more information about package thermal capabilities, reference Thermal Management.



Figure 47. VYMXYFI18 Detailed Internal Block Diagram

Main Features

- Uses V21 or VPWR as the main power supply
- · 200 mA maximum continuous output current
- Optimized for a 2.2 μ F external filter capacitor with a maximum of 10 m Ω ESR
- Uses an internal pass FET
- The output for each LDO is monitored for over-current conditions and under-voltage events

VYMXYFI18 Status/Control Registers and Bits Description

Table 50. VYMXYFI18 Register Structure and Bits Description

Name	Bits	Description			
	VWYMXARFCNT (ADDR 0x4C - R/W - Default Value: 0x24)				
CTLVWYMXARF	2:0	VYMXYFI18 State Control			
		x0 = Reserved	x4 = OFF		
		x1 = Reserved	x5 = Low Power		
		x2 = Reserved	x6 = Active		
		x3 = Reserved	x7 = Active		
AOACCTLVWYMXARF	5:3	VYMXYFI18 State Control during AOAC Exit (when the Exit pin is EXITSTBY pin is asserted). These bits will be initialized by the system SPI controller after power up.			
		X0 = Do not copy	x4 = OFF		
		x1 = Do not copy	x5 = Low Power		
		x2 = Do not copy	x6 = Active		
		x3 = Do not copy	x7 = Active		
Reserved	7:6	Reserved			

VYMXYFI

VYMXYFI is a low drop-out (LDO) fully integrated regulator with a P-CH Pass FET. It is high performance, low noise, and high PSRR, with a low quiescent current and fast transient response. VYMXYFI is actively discharged during shutdown.

VYMXYFI supplies two different voltages, depending on the communications module used, 1.2 V for WiFiBT applications, and 2.5 V for WiMAX applications.

If set at 1.2 V, VYMXYFI is supplied by the V15 DC/DC regulator. When set at 2.5 V, VYMXYFI can be supplied by

either the V33 DC/DC output voltage (V33), or directly from the VPWR node. Using V33 as the input voltage supply offers enhanced thermal performance and higher efficiency. Using the VPWR node can offer enhanced performance against noise coupling from an output of a DC/DC regulator. Users are encouraged to take the resulting thermal dissipation in account when supplying VYMXYFI directly from VPWR. For more information about package thermal capabilities, reference Thermal Management.



Figure 48. VYMXYFI Detailed Internal Block Diagram

Main Features

- · Uses V15, V33, or VPWR as the main power supply
- 60 mA maximum continuous output current for the 1.2 V setting
- 150 mA maximum continuous output current for the 2.5 V setting
- Optimized for a 2.2 μ F external filter capacitor with a maximum of 10 m Ω ESR
- Uses an internal pass FET
- The output for each LDO is monitored for over-current conditions and under-voltage events
- The Status and Control registers of VYMXFYI will be discussed along with status/control registers for the VYMXGPS LDO in the following section VYMXGPS

VYMXGPS

VYMXGPS is a low drop-out (LDO) fully integrated regulator with a P-CH Pass FET. It is high performance, low noise, and high PSRR, with a low quiescent current and fast transient response. VYMXGPS is actively discharged during shutdown.

VYMXGPS supplies two different voltages, depending on the communications module used, 1.8 V for GPS applications, and 1.3 V for WiMAX applications.

If set at 1.8 V, VYMXGPS can be supplied by either V21 DC/DC output voltage (V21), or directly from the VPWR node. When set at 1.3 V, VYMXGPS is supplied from the V15 DC/DC output voltage (V15). Using V21 as the input voltage supply offers enhanced thermal performance and higher efficiency. Using the VPWR node can offer enhanced performance against noise coupling from an output of a DC/ DC regulator. Users are encouraged to take the resulting thermal dissipation in account when supplying VYMXGPS directly from VPWR. For more information about package thermal capabilities, reference Thermal Management.

Note that when VYMXGPS is set at 1.3 V, V15 is automatically set at 1.6 V, to maintain voltage headroom for the operation of 1.3V VYMXGPS. Reference V15 for more details.



Figure 49. VYMXGPS Detailed Internal Block Diagram

Main Features

- Uses V15, V21, or VPWR as the main power supply
- 170 mA maximum continuous output current for the 1.8 V setting
- 350 mA maximum continuous output current for the 1.3 V setting
- Optimized for a 2.2 μF external filter capacitor with a maximum of 10 m Ω ESR
- Uses an internal pass FET
- The output for each LDO is monitored for over-current conditions and under-voltage events

VYMXYFI/VYMXGPS Status/Control Registers and Bits Description

In order to minimize conductive loses in the Advance communication voltage rails, the Freescale Chipset uses the

VYMXYFI and VYMXGP rails to supply VWDYMXA and VGYMXIO on the Ultra-mobile platform. Figure 50 shows the voltage mapping for these signals.



Figure 50. Freescale vs. Customer LDO Mapping for Communication Modules

When the software programs a certain voltage rail, Freescale will turn on that voltage rail using the right LDO, see <u>Table 51</u>.

Table 51. VYMXYFI and VYMXGPS Control Register Structure and Bits Description

Name	Bits	Description			
	VGYMXIOCNT (ADDR 0x4A - R/W - Default Value: 0x24)				
CTLVGYMXIO	2:0	VGYMXIO State Control			
		x0 = Reserved	x4 = OFF		
		x1 = Reserved	x5 = Low Power		
		x2 = Reserved	x6 = Active		
		x3 = Reserved	x7 = Active		
AOACCTLVGYMXIO	5:3	VGYMXIO State Control during AOAC Exit (when the Exit pin is EXITSTBY pin is asserted). These bits will be initialized by the system SPI controller after power up			
		X0 = Do not copy	x4 = OFF		
		x1 = Do not copy	x5 = Low Power		
		x2 = Do not copy	x6 = Active		
		x3 = Do not copy	x7 = Active		
SELVGYMXIO	7:6	VGYMXIO output voltage selection bits			
		X0 = 1.8 V	x2 = Reserved		
		x1 = 2.5 V	x3 = Reserved		

FUNCTIONAL DEVICE OPERATION POWER SUPPLIES

Table 51.	VYMXYFI and	VYMXGPS Cont	ol Register S	Structure and Bits	Description
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VWDYMXACNT (ADDR 0x4B - R/W - Default Value: 0x24)				
CTLVWDYMXA	2:0	VWDYMXA State Control		
		x0 = Reserved	x4 = OFF	
		x1 = Reserved	x5 = Low Power	
		x2 = Reserved	x6 = Active	
		x3 = Reserved	x7 = Active	
AOACCTLVWDYMX A	5:3	VWDYMXA State Control during AOAC Exit (when the Exit pin is EXITSTBY pin is asserted). These bits will be initialized by the system SPI controller after power up.		
		X0 = Do not copy	x4 = OFF	
		x1 = Do not copy	x5 = Low Power	
		x2 = Do not copy	x6 = Active	
		x3 = Do not copy	x7 = Active	
SELVWDYMXA	7:6	VWDYMXA output voltage selection bits		
		X0 = 1.2 V	x2 = Reserved	
		x1 = 1.3 V	x3 = Reserved	

Freescale's control of these 4 application voltage rails depend on the SEL bits setting of VGYMXIO and VDWYMXA:

- When SELVGYMXIO is set to 1.8 V:
 - The VGYMXIO register is now controlling VYMXGPS.
 - VYMXGPS is set at 1.8 V
- When SELVGYMXIO is set to 2.5 V:
 - The VGYMXIO register is now controlling VYMXYFI.
 - VYMXYFI is set at 2.5 V
- When SELVDWYMXA is set to 1.2 V:
 - The VDWYMXA register is now controlling VYMXYFI.
 - VYMXYFI is set at 1.2 V
- When SELVDWYMXA is set to 1.3 V:
 - The VDWYMXA register is now controlling VYMXGPS.
 - VYMXGPS is set at 1.3 V

It is the responsibility of the user (firmware) to guarantee that no conflict will occur. For example, it is not permissible to set VGYMXIO for a 1.8 V output, and also to set VDWYMXA for a 1.3 V output.

VCCPAOAC

VCCPAOAC is a low drop-out (LDO) fully integrated regulator with a P-CH Pass FET. It is high performance, low noise, and high PSRR, with a low quiescent current and fast transient response. VCCPAOAC is actively discharged during shutdown.

VCCPAOAC shares an input voltage pin (PVIN1P5) and a reference ground pin (GND1P5) with VCCPDDR, VAON, VMM, and the VCCP regulator. Each has independent control. PVIN1P5 is supplied from the V15 voltage.



Figure 51. VCCPAOAC Detailed Internal Block Diagram

Main Features

- Uses V15 as the main power supply.
- 155 mA maximum continuous output current
- Optimized for a 2.2 μF external filter capacitor with a maximum of 10 m Ω ESR
- · Uses an internal pass FET
- The output for each LDO is monitored for over-current conditions and under-voltage events

VCCPAOAC Status/Control Registers and Bits Description

Name	Bits	Description	
		VCCPAOACCNT (ADDR 0x3D - R/W - Defaul	t Value: 0x07)
CTLVCCPAOAC	2:0	VCCPAOAC State Control	
		x0 = Reserved	x4 = OFF
		x1 = Reserved	x5 = Low Power
		x2 = Reserved	x6 = Active
		x3 = Reserved	x7 = Active
AOACCTLVCCPAOAC	5:3	VCCPAOAC State Control during AOAC Exit (when the Exit pin is EXITSTBY pin is asserted). These bits will be initialized by the system SPI controller after power up.	
		X0 = Do not copy	x4 = OFF
		x1 = Do not copy	x5 = Low Power
		x2 = Do not copy	x6 = Active
		x3 = Do not copy	x7 = Active
Reserved	7:6	Reserved	

Table 52. VCCPAOACCNT Register Structure and Bits Description

VCCPDDR

VCCPDDR is a low drop-out (LDO) fully integrated regulator with a P-CH Pass FET. It is high performance, low noise, and high PSRR, with a low quiescent current and fast transient response. VCCPDDR is actively discharged during shutdown. VCCPDDR shares an input voltage pin (PVIN1P5) and a reference ground pin (GND1P5) with the VCCPAOAC, VAON, VMM, and VCCP regulators, yet each has independent control. PVIN1P5 is supplied from the V15 voltage.



Figure 52. VCCPDDR Detailed Internal Block Diagram

Main Features

- Uses V15 as the main power supply
- 60 mA maximum continuous output current
- Optimized for a 1.0 μF external filter capacitor with a maximum of 10 m Ω ESR
- · Uses an internal pass FET
- The output for each LDO is monitored for over-current conditions and under-voltage events

VCCPDDR Status/Control Registers and Bits Description

Table 53.	VCCPDDR	Control	Register	Structure	and Bits	Description
		00111101	Register	onactarc	und Dits	Description

Name	Bits	Description			
	VCCPDDRCNT (ADDR 0x3E - R/W - Default value: 0x3C)				
CTLVCCPDDR	2:0	VCCPDDR State Control			
		x0 = Reserved	x4 = OFF		
		x1 = Reserved	x5 = Low Power		
		x2 = Reserved	x6 = Active		
		x3 = Reserved	x7 = Active		

		•	
AOACCTLVCCPDDR	5:3	VCCPDDR State Control during AOAC Exit (when the Exit pin is EXITSTBY pin is asserted). These bits will be initialized by the system SPI controller after power up.	
		X0 = Do not copy	x4 = OFF
		x1 = Do not copy	x5 = Low Power
		x2 = Do not copy	x6 = Active
		x3 = Do not copy	x7 = Active
Reserved	7:6	Reserved	

Table 53. VCCPDDR Control Register Structure and Bits Description

VAON

VAON is a low drop-out (LDO) fully integrated regulator with a P-CH Pass FET. It is high performance, low noise, and high PSRR, with a low quiescent current and fast transient response. VAON is actively discharged during shutdown. VAON shares an input voltage pin (PVIN1P5) and a reference ground pin (GND1P5) with the VCCPAOAC, VCCPDDR, VMM, and VCCP regulators, yet each has independent control. PVIN1P5 is supplied from the V15 voltage.



Main Features

- Uses V15 as the main power supply
- 250 mA maximum continuous output current
- Optimized for a 2.2 μF external filter capacitor with a maximum of 10 m Ω ESR
- · Uses an internal pass FET
- The output for each LDO is monitored for over-current conditions and under-voltage events

VAON Status/Control Registers and Bits Description

Table 54	VAON Control Register Structure and Bits Description
10010 041	There exists and bits becomption

Name	Bits	Description			
	VAONCNT (ADDR 0x45 - R/W - Default Value: 0x07)				
CTLVAON	2:0	VAON State Control			
		x0 = Reserved	x4 = OFF		
		x1 = Reserved	x5 = Low Power		
		x2 = Reserved	x6 = Active		
		x3 = Reserved	x7 = Active		
AOACCTLVAON	5:3	VAON State Control during AOAC Exit (when the Exit pin by the system SPI controller after power up.	is EXITSTBY pin is asserted). These bits will be initialized		
		X0 = Do not copy	x4 = OFF		
		x1 = Do not copy	x5 = Low Power		
		x2 = Do not copy	x6 = Active		
		x3 = Do not copy	x7 = Active		
Reserved	7:6	Reserved			

VMM

VMM is a low drop-out (LDO) fully integrated regulator with a P-CH Pass FET. It is high performance, low noise, and high PSRR, with a low quiescent current and fast transient response. VMM will be actively discharged during shutdown. VMM shares an input voltage pin (PVIN1P5) and a reference ground pin (GND1P5) with the VCCPAOAC, VCCPDDR, VAON, and VCCP regulators, yet each has independent control. PVIN1P5 is supplied from V15 voltage.



Figure 54. VMM Detailed Internal Block Diagram

Main Features

- Uses V15 as the main power supply
- 5.0 mA maximum continuous output current
- Optimized for a 1.0 μF external filter capacitor with a maximum of 10 m Ω ESR
- Uses an internal pass FET
- The output for each LDO is monitored for over-current conditions and under-voltage events

VMM Status/Control Registers and Bits Description

Bits	Description	
	VMMCNT (ADDR 0x47 -	R/W - Default Value: 0x24)
2:0	VMM State Control	
	x0 = Reserved	x4 = OFF
	x1 = Reserved	x5 = Low Power
	x2 = Reserved	x6 = Active
	x3 = Reserved	x7 = Active
5:3	VMM State Control during AOAC Exit (when the Exit pin is EXITSTBY pin is asserted). These bits by the system SPI controller after power up.	
	X0 = Do not copy	x4 = OFF
	x1 = Do not copy	x5 = Low Power
	x2 = Do not copy	x6 = Active
	x3 = Do not copy	x7 = Active
7:6	Reserved	I
	2:0	VMMCNT (ADDR 0x47 - I 2:0 VMM State Control x0 = Reserved x1 = Reserved x2 = Reserved x2 = Reserved 5:3 VMM State Control during AOAC Exit (wh by the system SPI controller after power of X0 = Do not copy x1 = Do not copy x1 = Do not copy x2 = Do not copy x3 = Do not copy

Table 55. VMM control Register Structure and Bits Description

VCCP

VCCP is a low drop-out (LDO) fully integrated regulator with a P-CH Pass FET. It is high performance, low noise, and high PSRR, with a low quiescent current and fast transient response. VCCP is actively discharged during shutdown. VCCP shares an input voltage pin (PVIN1P5) and a reference ground pin (GND1P5) with the VCCPAOAC, VCCPDDR, VAON, and VMM regulators, yet each has independent control. PVIN1P5 is supplied from V15 voltage.



Figure 55. VCCP Detailed Internal Block Diagram

Main Features

- Uses V15 as the main power supply
- 445 mA maximum continuous output current
- Optimized for a 2.2 μF external filter capacitor with a maximum of 10 m Ω ESR
- Uses an internal pass FET
- The output for each LDO is monitored for over-current conditions and under-voltage events

VCCP Status/Control Registers and Bits Description

Name	Bits	Description			
	VCCPCNT (ADDR 0x44 - R/W - Default Value: 0x3C)				
CTLVCCP	2:0	VCCP State Control			
		x0 = Reserved	x4 = OFF		
		x1 = Reserved	x5 = Low Power		
		x2 = Reserved	x6 = Active		
		x3 = Reserved	x7 = Active		
AOACCTLVCCP	5:3	VCCP State Control during AOAC Exit (when the Exit pin is EXITSTBY pin is asserted). These bits will be initialized by the system SPI controller after power up.			
		X0 = Do not copy	x4 = OFF		
		x1 = Do not copy	x5 = Low Power		
		x2 = Do not copy	x6 = Active		
		x3 = Do not copy	x7 = Active		
Reserved	7:6	Reserved			

Table 56. VCCP Control Register Structure and Bits Description

VIMG25

VIMG25 is a low drop-out (LDO) fully integrated regulator with a P-CH Pass FET. It is high performance, low noise, and high PSRR, with a low quiescent current and fast transient response. VIMG25 is actively discharged during shutdown. VIMG25 shares an input voltage pin (PVINIMG) and a reference ground pin (GNDIMG) with the VIMG28 regulator, yet each has independent control. Both can be supplied by either the V33 output voltage (V33) or directly from the VPWR node, depending on the output voltage selection of LDO VIMG28.



Figure 56. VIMG25 Detailed Internal Block Diagram

Main Features

- · Uses V33 or VPWR as the main power supply
- · 80 mA maximum continuous output current
- Optimized for a 2.2 μF external filter capacitor with a maximum of 10 m Ω ESR

Table 57. VIMG25 Register Structure and Bits Description

- Uses an internal pass FET
- The output for each LDO is monitored for over-current conditions and under-voltage events

VIMG25 Status/Control Registers and Bits Description

Name	Bits	Description			
	VIMG25CNT (ADDR 0x42 - R/W - Default Value: 0x04)				
CTLVIMG25	2:0	VIMG25 State Control			
		x0 = Reserved	x4 = OFF		
		x1 = Reserved	x5 = Low Power		
		x2 = Reserved	x6 = Active		
		x3 = Reserved	x7 = Active		
AOACCTLVIMG25	5:3	VIMG25 State Control during AOAC Exit (when the Exit pin is EXITSTBY pin is asserted). These bits will be initialized by the system SPI controller after power up.			
		X0 = Do not copy x4 = OFF			
		x1 = Do not copy	x5 = Low Power		
		x2 = Do not copy	x6 = Active		
		x3 = Do not copy	x7 = Active		
Reserved	7:6	Reserved			

VIMG28

VIMG28 is a low drop-out (LDO) fully integrated regulator with a P-CH Pass FET. It is high performance, low noise, and high PSRR, with a low quiescent current and fast transient response. VIMG28 is actively discharged during shutdown.

VIMG28 shares an input voltage pin (PVINIMG) and a reference ground pin (GNDIMG) with the VIMG25 regulator, yet each has independent control. Both can be supplied by either the V33 output voltage or directly from the V_{PWR} node, depending on its output voltage selections. It is recommended to supply VIMG28 from V33 at all times, regardless of the VIMG28 output voltage setting. This LDO is

optimized to work with 300 mV headroom, which leaves enough margin between the input and the highest output of this LDO. If it is desired to supply these LDO directly from VPWR, two notes are worth mentioning:

- Users are encouraged to take the resulting thermal dissipation into account when supplying VIMG28 (and VIMG25) directly from VPWR. For more information about package thermal capabilities, reference Thermal Management.
- At high VIMG28 output voltage selections, the output will start tracking the battery voltage when V_{BAT} decreases below V_{OIMG28} + 300 mV.



Figure 57. VIMG28 Detailed Internal Block Diagram

Main Features

- · Uses V33 or VPWR as the main power supply
- · 225 mA maximum continuous output current
- Optimized for a 2.2 μF external filter capacitor with a maximum of 10 m Ω ESR
- Uses internal pass FET
- The output for each LDO is monitored for over-current conditions and under-voltage events

VIMG28 Status/Control Registers and Bits Description

Table 58. VIMG28 Control Register Structure and Bits Description

Name	Bits	Description			
	VIMGACNT (ADDR 0x0x48 - R/W - Default Value: 0x24)				
CTLVIMGA	2:0	VIMG28 State Control			
		x0 = Reserved	x4 = OFF		
		x1 = Reserved	x5 = Low Power		
		x2 = Reserved	x6 = Active		
		x3 = Reserved	x7 = Active		
AOACCTLVIMGA	5:3	VIMG28 State Control during AOAC Exit (when the Exit pin is EXITSTBY pin is asserted). These bits v initialized by the system SPI controller after power up.			
		X0 = Do not copy	x4 = OFF		
		x1 = Do not copy	x5 = Low Power		
		x2 = Do not copy	x6 = Active		
		x3 = Do not copy	x7 = Active		
SELVIMGA	7:6	VIMG28 output voltage selections:			
		X0 = 1.5 V			
		x1 = 2.7 V x2 = 2.8 V			
		x3 = 2.9 V			

FUNCTIONAL DEVICE OPERATION POWER SUPPLIES

VVIB

VVIB is a low drop-out (LDO) fully integrated regulator with a P-CH Pass FET. It is high performance, low noise, and high

PSRR, with a low quiescent current and fast transient response. VVIB is actively discharged during shutdown.

It is used to drive the vibrator motor for alert functions, and it takes its input voltage directly from the VPWR node.



Figure 58. VVIB Detailed Internal Block Diagram

Main Features

- Uses VPWR as the main power supply
- 200 mA maximum continuous output current
- Optimized for a 2.2 μF external filter capacitor with a maximum of 10 m Ω ESR

•	Uses	an	internal	pass	FFT
	0303	un	interna	puss	

 The output is monitored for over-current conditions and under-voltage events

VVIB Status/Control Registers and Bits Description

Name	Bits	Description			
	VIBCNT (ADDR 0x49 - R/W - Default Value: 0x24)				
CTLVVIB	2:0	VVIB State Control			
		x0 = Reserved	x4 = OFF		
		x1 = Reserved	x5 = Low Power		
		x2 = Reserved	x6 = Active		
		x3 = Reserved	x7 = Active		
AOACCTLVVIB	5:3	VVIB State Control during AOAC Exit (when the Exit pin is EXITSTBY pin is asserted). These bits will be initialized by the system SPI controller after power up.			
		X0 = Do not copy	x4 = OFF		
		x1 = Do not copy	x5 = Low Power		
		x2 = Do not copy	x6 = Active		
		x3 = Do not copy	x7 = Active		
SELVVIB	7:6	VVIB output voltage selections:			
		X0 = 1.3 V			
		x1 = 1.5 V			
		x2 = 2.5 V			
		x3 = 2.7 V			

FUNCTIONAL DEVICE OPERATION POWER SUPPLIES

VSDIO

VSDIO is a combo low drop-out (LDO) and power switch. It uses an external P-CH pass FET in Switch mode, and internal pass FET on LDO mode.

VSDIO serves as an LDO when its output voltage is set to 1.8 V, and as a switch when its output voltage is set to 3.3 V. It

takes its input voltage directly from the V33 output voltage node (V33).

VSDIO supplies the SDIO card module. The card is initially powered up to 3.3 V. If the card is detected to be a low voltage card, then the rail will be shutdown, configured as 1.8 V, and then turned on.

VSDIO will be actively discharged during shutdown.



Figure 59. VSDIO Detailed Internal Block Diagram

MAIN FEATURES

- Uses V33 as the main power supply
- 215 mA maximum continuous output current
- Optimized for a 2.2 μF external filter capacitor with a maximum of 10 m Ω ESR
- Uses an internal pass FET on LDO mode, and external pass FET on Switch mode.
- The output is monitored for under-voltage and overcurrent conditions in LDO mode.

VSDIO Status/Control Registers and Bits Description

Table 60. VSDIO Control Register Structure and Bits Description

Name	Bits	Description						
	VSDIOCNT (ADDR 0x4D - R/W - Default Value: 0x64)							
CTLVSDIO	2:0	VSDIO State Control						
		x0 = Reserved	x4 = OFF					
		x1 = Reserved	x5 = Low Power					
		x2 = Reserved	x6 = Active					
		x3 = Reserved	x7 = Active					
AOACCTLVSDIO	5:3	VSDIO State Control during AOAC Exit (when Exit pin is EXITSTBY pin is asserted). These bits will be initialized by the system SPI controller after power up.						
		X0 = Do not copy	x4 = OFF					
		x1 = Do not copy	x5 = Low Power					
		x2 = Do not copy	x6 = Active					
		x3 = Do not copy	x7 = Active					
SELVSDIO	7:6	VSDIO output voltage selections:						
		X0 = 1.8 V						
		x1 = 3.3 V						
		x2 = Reserved						
		x3 = Reserved						

POWER SWITCHES

Freescale's power management solution for the Ultramobile platform for MID includes 3 dedicated power switches, all of which are housed in the 900841 PMIC. <u>Table 61</u> lists all Power switches and its power characteristics.

Switch	ch Typ. Voltage Max Current		Description					
VPNL33	3.3 V	100 mA	Power Switch with integrated MOSFET and less than 1% voltage drop.					
VGP33	3.3 V	60 mA	Power Switch with integrated MOSFET and less than 1% voltage drop.					
VYMXGPS33	3.3 V	60 mA	Power Switch with integrated MOSFET and less than 1% voltage drop.					

Table 61. SC900841 Power Switches summary

All of the switches in <u>Table 61</u> use an internal switch and are supplied from the V33 output voltage node.

Power Switches Status/Control Registers and Bits Description

Name	Bits	Description					
		VPANEL33CNT (ADDR 0x4F - R/W - Defau	It Value: 0x24)				
CTLVPANEL33	2:0	VPNL33 State Control					
		x0 = Reserved	x4 = OFF				
		x1 = Reserved	x5 = Low Power				
		x2 = Reserved	x6 = Active				
		x3 = Reserved	x7 = Active				
AOACCTLVPANEL33	5:3	VPNL33 State Control during AOAC Exit (when the Exi initialized by the system SPI controller after power up.	t pin is EXITSTBY pin is asserted). These bits will be				
		X0 = Do not copy	x4 = OFF				
		x1 = Do not copy	x5 = Low Power				
		x2 = Do not copy	x6 = Active				
		x3 = Do not copy	x7 = Active				
Reserved	7:6	Reserved					
		VGP33CNT (ADDR 0x50 - R/W - Default	Value: 0x24)				
CTLVGP33	2:0	VGP33 State Control					
		x0 = Reserved	x4 = OFF				
		x1 = Reserved	x5 = Low Power				
		x2 = Reserved	x6 = Active				
		x3 = Reserved	x7 = Active				
AOACCTLVGP33	5:3	VGP33 State Control during AOAC Exit (when the Exit pin is EXITSTBY pin is asserted). These bits will be initialized by the system SPI controller after power up.					
		X0 = Do not copy	x4 = OFF				
		x1 = Do not copy	x5 = Low Power				
		x2 = Do not copy	x6 = Active				
		x3 = Do not copy	x7 = Active				
Reserved	7:6	Reserved					
		GYMX33CNT (ADDR 0x4E - R/W - Default	: Value: 0x24)				
CTLVGYMX33	2:0	VYMXGPS33 State Control					
		x0 = Reserved	x4 = OFF				
		x1 = Reserved	x5 = Low Power				
		x2 = Reserved	x6 = Active				
		x3 = Reserved	x7 = Active				

		č 1					
AOACCTLVGYMX33	5:3	VYMXGPS33 State Control during AOAC Exit (when Exit pin is EXITSTBY pin is asserted). These bits will be initialized by the system SPI controller after power up.					
		X0 = Do not copy	x4 = OFF				
		x1 = Do not copy	x5 = Low Power				
		x2 = Do not copy	x6 = Active				
		x3 = Do not copy	x7 = Active				
Reserved	7:6	Reserved					

Table 62. Power Switches Control Registers Structure and Bits Description

STAND ALONE VOLTAGE SUPPLIES.

V33

This is a 1.625 MHz fully integrated 4-switch synchronous Buck-boost PWM voltage mode control DC/DC regulator.

This rail is implemented through an external standalone chip. See General Description.

A separate specification is provided for this rail in the 900842 datasheet.

Reference Freescale Chip set Communication Signals for more details about how the 900841 communicates to this standalone chip for complete system operation.

Main Features

- Uses the V_{PWR} rail as its power supply
- It is used as a pre-regulator to many LDO and Switch rails for enhanced efficiency and reduced thermal dissipation. It also supplies power to rails in Platform controller hub and the platform
- Uses Integrated MOSFETs
- 1.625 MHz switching frequency
- · Output can be discharged
- · Output Current Sensing with over-current protection
- Uses internal compensation
- · Gate drive circuits are supplied directly from VPWR

V33 Status/Control Registers and Bits Description

Name	Bits	Description						
V33CNT (ADDR 0x3A - R/W - Default Value: 0x24)								
CTLV33	2:0	V33 State Control						
		x0 = Reserved	x4 = OFF					
		x1 = Reserved x5 = Low power						
		x2 = Reserved	x6 = PWM					
		x3 = Reserved	x7 = PWM					
AOACCTLV33	5:3	V33 State Control during AOAC Exit (when Exit pin is EX the system SPI controller after power up.	XITSTBY pin is asserted). These bits will be initialized by					
		X0 = Do not copy	x4 = OFF					
		x1 = Do not copy	x5 = Low power					
		x2 = Do not copy	x6 = PWM					
		x3 = Do not copy	x7 = PWM					
Reserved	7:6	Reserved						

Table 63. V33 Control Register Structure and Bits Description

POWER SUPPLY REGISTER MASK

Mask writes to the power supply registers, in order to avoid the need for the system controller to do read-modify-write cycles. The mask register is shown in <u>Table 64</u>.

Table 64. Mask Register

Register name	ADDR	R/W	D7	D6	D5	D4	D3	D2	D1	D0	initial
PWRMASK	0x34	R/W	M7	M6	M5	M4	M3	M2	M1	MO	0x00
Figure 60 shows an example of the operation of the PWRMASK register.

	D7	D6	D5	D4	D3	D2	D1	D0
Power Supply Register Before Write	1	0	1	0	1	0	1	0
PWRMASK Register Settings	1	1	1	1	0	0	0	0
Example SPI Write to Power Supply	1	1	1	1	1	1	1	1
Power Supply Register After Write	1	0	1	0	1	1	1	1

Figure 60. PWRMASK Register Implementation Example

POWER SUPPLY PROGRAMMABLE RAMP RATE

Turn on time of all buck regulators can be programmed through the SPI, reference $\underline{\text{Table 65}}$

Name	Bits	Description
	•	FSLTONTCNTL1 (ADDR 0x1C8 - R/W - Default Value: 0xAA)
VCCTONT	1:0	Turn On Time Settings for VCC Regulator
		x0 = 180 µs
		x1 = 90 µs
		x2 = 45 μs
		x3 = 22 µs
VNNTONT	3:2	Turn On Time Settings for VNN Regulator
		x0 = 180 μs
		x1 = 90 µs
		x2 = 45 μs
		x3 = 22 µs
VDDQTONT	5:4	Turn On Time Settings for VDDQ Regulator
		x0 = 240 µs
		x1 = 120 μs
		x2 = 60 µs
		x3 = 30 µs
VYMX3GTONT	7:6	Turn On Time Settings for VYMX3G Regulator
		x0 = 160 µs
		x1 = 80 µs
		x2 = 40 μs
		x3 = 20 µs
		FSLTONTCNTL2 (ADDR 0x1CB - R/W - Default Value: 0xAA)
V21TONT	1:0	Turn On Time Settings for V21 Regulator
		x0 = 320 µs
		x1 = 160 μs
		x2 = 80 µs
		x3 = 40 µs
V15TONT	3:2	Turn On Time Settings for V15 Regulator
		x0 = 200 μs
		x1 = 100 μs
		x2 = 50 μs
		x3 = 25 µs
Reserved	7:4	Reserved

POWER SUPPLIES FAULT MANAGEMENT

The following section discusses faults related to, or caused by power supplies (directly or indirectly) operating outside their specified boundaries.

Reference Interrupt Controller for more information on the various interrupt signals, and the interrupt mechanism used to communicate to the system controller.

THERMAL MANAGEMENT

The thermal protection is based on a circuit with a voltage output that is proportional to the absolute temperature. This voltage can be read out via the ADC for precise temperature readouts. See ADC Subsystem.

This voltage is monitored by an integrated comparator. Interrupt THRM will be generated, if not masked, when crossing the thermal warning threshold TWARN, and sets the VRFAULT 1st level interrupt that causes the PMICINT pin to assert, notifying the system controller of a system event.

In addition to the previous, the 900841 includes integrated thermal protection that shuts down and powers off the system, in cases of over dissipation, if the junction temperature exceeds the TSHUTDOWN threshold. This thermal protection will act above the maximum junction temperature, to avoid any unwanted power downs. The protection is de-bounced by one period of the 32 kHz clock in order to suppress any (thermal) noise. This protection should be considered as a fail-safe mechanism. Therefore, the

application design should execute a thermal shutdown under normal conditions.

Once the thermal event is cleared and the temperature is back to its normal range, the SC900841 restarts

automatically, by following the steps outlined in Initial Power Up Sequence

Table 66.	Thermal	Warning/Shutdown	Thresholds
-----------	---------	------------------	------------

Parameter	Min	Тур	Max	Unit
Thermal Warning Threshold	115	120	125	°C
Thermal Warning Hysteresis	2	-	4	°C
Thermal Shutdown Threshold	130	140	150	°C

BATOCP

When the battery is being discharged, the current out of the battery is monitored. BATOCSET sets the maximum battery discharge current value. If the battery discharge current is greater than the value set by BATOCSET for more than a time set by BATOCPT, the BATOCP interrupt is set to interrupt the system. If the over-discharge current condition continues for another BATOCPT period, the 900841 initiates a system shutdown similar to the thermal shutdown event.

The BATOCP comparator can be shutdown when the battery is not being discharged.

Name	Bits	Description						
	CHRGPROT2 (ADDR 0xD8 - R/W - Default Value: 0x60)							
BATOCPSET	1:0	Battery Discharge Current Limit						
		x0 = 2.0 A						
		x1 = 3.0 A						
		x2 = 4.0 A						
		x3 = 5.0 A						
Reserved	4:2	Reserved						
TOCP	7:5	Battery Discharge Current Limit Filter Timer						
		x0 = 1.0 ms						
		x1 = 5.0 ms						
		x2 = 10 ms						
		x3 = 15 ms						
		x4 = 20 ms						
		x5 = 40 ms						
		x6 = 80 ms						
		x7 = 160 ms						

Table 67. BATOCP Control Register Structure and Bits Description

VRFAULT

Every supply is equipped with a fault reporting signal called xxxFAULT, where xxx is the name of the power supply. This FAULT signal is an OR function of all of the following possible faults, or just a subset of them depending on the power supply:

- Output under-voltage
- Output over-voltage
- Over-current
- Short-circuit

Reference each power supply's section for more information on what faults are included, and how the supply protects itself and the load in response to the fault. All of the xxxFAULT signals from all power supplies are ORed together into the BATOCP interrupt signal, which in turn if unmasked, sets the VRFAULT 1st level interrupt that causes the PMICINT pin to assert, notifying the SC of a system event. The SC can service the VRFAULT register and access the FAULTx registers for more information on which supply caused the fault. The SC can then take different measures, depending on the supply in question.

The xxxFAULT signals are stored in the Freescale defined registers section (Addr 0x180 - 0x1FF), which is meant for extended functionality.

Name	Bits	Description					
FSLFAULT1 (ADDR 0x1CC - R/W - Default Value: 0x00)							
VCCFAULT	0	VCC Regulator Fault Signal					
		x0 = No Fault Exists					
		x1 = Fault Exists					
VNNFAULT	1	VNN Regulator Fault Signal					
		x0 = No Fault Exists					
		x1 = Fault Exists					
VDDQFAULT	2	VDDQ Regulator Fault Signal					
		x0 = No Fault Exists					
		x1 = Fault Exists					
V21FAULT	3	V21 Regulator Fault Signal					
		x0 = No Fault Exists					
		x1 = Fault Exists					
V15FAULT	4	V15 Regulator Fault Signal					
		x0 = No Fault Exists					
		x1 = Fault Exists					
V33FAULT	5	V33 Regulator Fault Signal					
		x0 = No Fault Exists					
		x1 = Fault Exists					
VYMX3GFAULT	6	VYMX3G Regulator Fault Signal					
		x0 = No Fault Exists					
		x1 = Fault Exists					
V3GPAFAULT	7	Reserved					
		FSLFAULT2 (ADDR 0x1CD - R/W - Default Value: 0x00)					
VYMXPAFAULT	0	VYMXPA Regulator Fault Signal					
		x0 = No Fault Exists					
		x1 = Fault Exists					
VOTGFAULT	1	VOTG Regulator Fault Signal					
		x0 = No Fault Exists					
		x1 = Fault Exists					
VBKLTFAULT	2	VBKLT Regulator Fault Signal					
		x0 = No Fault Exists					
		x1 = Fault Exists					

Table 68. Fault Status Registers Structure and Bits Description

Table 68. Fault Status Registers Structure and Bits Description

VBGFAULT	3	VBG Regulator Fault Signal
		x0 = No Fault Exists
		x1 = Fault Exists
VCCAFAULT	4	VCCA Regulator Fault Signal
		x0 = No Fault Exists
		x1 = Fault Exists
VCC180FAULT	5	VCC180 Regulator Fault Signal
		x0 = No Fault Exists
		x1 = Fault Exists
VPNL18FAULT	6	VPNL18 Regulator Fault Signal
		x0 = No Fault Exists
		x1 = Fault Exists
VPMICFAULT	7	VPMIC Regulator Fault Signal
		x0 = No Fault Exists
		x1 = Fault Exists
		FSLFAULT3 (ADDR 0x1CE - R/W - Default Value: 0x00)
VYMXYFI18FAU	0	VYMXYFI18 Regulator Fault Signal
LT		x0 = No Fault Exists
		x1 = Fault Exists
VYMXYFIFAULT	1	VYMXYFI Regulator Fault Signal
		x0 = No Fault Exists
		x1 = Fault Exists
VYMXGPSFAUL	2	VYMXGPS Regulator Fault Signal
Т		x0 = No Fault Exists
		x1 = Fault Exists
VCCPAOACFAU	3	VCCPAOAC Regulator Fault Signal
LT		x0 = No Fault Exists
		x1 = Fault Exists
VCCPDDRFAUL	4	VCCPDDR Regulator Fault Signal
Т		x0 = No Fault Exists
		x1 = Fault Exists
VAONFAULT	5	VAON Regulator Fault Signal
		x0 = No Fault Exists
		x1 = Fault Exists
VMMFAULT	6	VMM Regulator Fault Signal
		x0 = No Fault Exists
		x1 = Fault Exists
VCCPFAULT	7	VCCP Regulator Fault Signal
		x0 = No Fault Exists
		x1 = Fault Exists
		FSLFAULT4 (ADDR 0x1CF - R/W - Default Value: 0x00)
VIMG25FAULT	0	VIMG25 Regulator Fault Signal
		x0 = No Fault Exists
		x1 = Fault Exists

Table 68. Fault Status Registers Structure and Bits Description

VIMG28FAULT	1	VIMG28 Regulator Fault Signal x0 = No Fault Exists x1 = Fault Exists
VVIBFAULT	2	VVIB Regulator Fault Signal x0 = No Fault Exists x1 = Fault Exists
VSDIOFAULT	3	VSDIO Regulator Fault Signal x0 = No Fault Exists x1 = Fault Exists
Reserved	7:4	Reserved

Power Supplies Fault Management Interrupt/Mask Registers.

Table 69. Fault Management Status and Control Register Structure and Bits Description

Name	Bits	Description						
	VRFAULTINT (ADDR 0X30 - R - Default Value: 0x00)							
THRM	THRM 0 PMIC Thermal Warning Flag							
		x0 = PMIC temperature below warning threshold						
		x1 = PMIC temperature above warning threshold						
BATOCP	1	Regulator fault present flag or battery discharge over current						
		x0 = No fault						
		x1 = Fault Exists						
VRFAIL	2	Regulator fault present flag or battery discharge over current						
		x0 = No fault						
		x1 = Fault Exists						
Reserved	7:3	Reserved						
		MVRFAULTINT (ADDR 0x31 - R/W - Default Value: 0x03)						
MTHRM	0	PMIC Thermal Warning Flag Mask						
		x0 = Flag unmasked						
		x1 = Flag masked						
MBATOCP	1	Regulator fault present flag or battery discharge over current Mask						
		x0 = Flag unmasked						
		x1 = Flag masked						
VRFAIL	2	Regulator fault present flag or battery discharge over current Mask						
		x0 = Flag unmasked						
		x1 = Flag masked						
Reserved	7:3	Reserved						

LIGHTING SYSTEM

The lighting system of the 900841 is comprised of LCD Backlight LED drivers, a Camera Scene Illumination LED driver, and general purpose LED drivers.

LCD BACKLIGHT DRIVERS

900841 supports up to four parallel strings with up to 5-6 LEDs each for LCD backlighting. The strings are powered from the VBKLT DC/DC boost regulator. The brightness control is done through 8-bit PWM duty cycle control and 3bit PWM frequency control.

Note: The minimum on time of the backlight LEDs should be limited to 2.0 ms

The backlight control resolution is needed to support DPST power savings architecture. The duty cycle change from the previous value will be typically <1%. Dynamic display duty cycle changes are made as frequently as every 100 ms, or 6 frames. The new duty cycle takes effect at the start of the next PWM cycle change. Refer to Figure 40 for a block diagram of how the backlight LED current sinks interface with VBKLT. Each one of the Backlight current sinks could be used with a pull-up resistor as a PWM output signal to drive an "Integrated Display".

Table 70. LCI	D Backlight Drivers Brightness Control PWM
Dı	ity Cycle Selections

	REG M								Duty	
Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0	N*256 clocks	cycle	
0	0	0	0	0	0	0	0	1	0.39%	
0	0	0	0	0	0	0	1	2	0.78%	
0	0	0	0	0	0	1	0	3	1.17%	
0	0	0	0	0	0	1	1	4	1.56%	
•		•	•	•	•	•		-	-	
		-	-	-	-	-	•			
	•	•	•	•	•	•	•		-	
1	1	1	1	1	1	1	1	256	100.00%	

Reg N							
Bit2	Bit1	Bit0	32.768 kHz divided by	PWM Freq [reg N] (Hz)	Period (s)	Min on time (s) Duty cycle [reg M=0]	Min on time (µs)
0	0	0	256	128	0.007813	3.06 e-05	30.64
0	0	1	128	256	0.003906	1.53 e-05	15.32
0	1	0	64	512	0.001953	7.66 e-06	7.66
0	1	1	32	1024	0.000977	3.83 e-06	3.83
1	0	0	16	2048	0.000488	1.91 e-06	1.91
1	0	1	8	4096	0.000244	9.57 e-07	0.96
1	1	0	4	8192	0.000122	4.79 e-07	0.48
1	1	1		I I	RSVD		





LCD Backlight Status/Control Registers and Bits Description

Name	Bits	Description
		BKLTCNT (ADDR 0x28 - R/W - Default Value: 0x00)
BKLTSS	1:0	No Supported, Reserved
Reserved	4:2	Reserved
MBKLT1EN	5	LCD Backlight String 1 Enable Bit to operate with VBKLT
		x0 = Disable
		x1 = Enable
MBKLT2EN	6	LCD Backlight String 2 Enable Bit to operate with VBKLT
		x0 = Disable
		x1 = Enable
MBKLT3EN	7	LCD Backlight String 3 Enable Bit to operate with VBKLT
		x0 = Disable
		x1 = Enable
		BKLTFREQ (ADDR 0x29 - R/W - Default Value: 0x00)
BKLTFREQ	2:0	LCD Backlight PWM Frequency Settings For Strings 1-3 in single backlight configuration or for Strings 1- 2 for independent zone backlighting configuration. See <u>Table 71</u> for Frequency settings
Reserved	5:3	Reserved
PWMEN	6	LCD Backlight Drivers Enable Bit as PWM outputs, not operating with VBKLT
		x0 = Disable
		x1 = Enable
Reserved	7	Reserved
		BKLTBRTL (ADDR 0x2A - R/W - Default Value: 0x00)
BKLTBRTL	7:0	LCD Backlight PWM Duty Cycle Settings For Strings 1-3 in single backlight configuration or for Strings 1- 2 for independent zone backlighting configuration. See <u>Table 70</u> for Duty Cycle Settings

Table 72.	Backlight	Control Re	aisters S	Structure	and Bits	Description
TUDIC / L.	Ducklight	00111101110	gisters t	Judetaic		Description

LCD Backlight Status/Control Registers and Bits Description

Table 73. Extended Backlight Control Registers Structure and Bits Description

Name	Bits	Des	cription	
		FSLVBKLTCNTL (ADDR 0x1D3 - R/W	- Default Value: 0x07)	
BKLTLED	2:0	LCD Backlight LED Maximum Current Settings		
		x0 = 0 mA	x4 = 17.2 mA	
		x1 = 4.3 mA	x5 = 21.5 mA	
		x2 = 8.6 mA	x6 = 25.8 mA	
		x3 = 12.9 mA	x7 = 30 mA	
MLED4EN	3 Enable camera scene string to be used as LCD Backlight String 4			
x0 = 4th string cannot be used for backlight applicatio		x0 = 4th string cannot be used for backlight applications (ns (Default)	
		x1 = 4th string can be used for backlight applications		
BKLTFREQ2	6:4	LCD Backlight PWM Frequency settings for string 4 in single backlight configuration or for strings 3-4 for independent zone backlighting configuration. See <u>Table 71</u> for Frequency settings		

Table 73. Extended Backlight Control Registers Structure and Bits Description

TWOPTWO	7	Independent Zone (Backlight) Configuration Enable		
		x0 = Independent Zone Backlighting Option is disabled (Default)		
		x1 = Independent Zone Backlighting Option is Enabled		
FSL4STRING	(ADD	R 0x1D4 - R/W - Default Value: 0x00)		
BKLTBRTL2	7:0	LCD Backlight PWM Duty Cycle Settings for string 4 in single backlight configuration or for Strings 3-4 for independent zone backlight configuration. See <u>Table 70</u> for Duty Cycle Settings		
FSLVBKLTAD	APT (ADDR 0x1D5 - R/W - Default Value: 0x00)		
S4ADAPT	0	Enable String 4 to be part of the adaptive boost control		
		x0 = Disable (Default)		
		x1 = Enable		
Reserved	7:1	Reserved		

CAMERA SCENE ILLUMINATION CURRENT DRIVER

The 900841 supports one string of up to 5-6 LEDs for Camera Scene Illumination. The string is powered from the VBKLT boost regulator. The brightness control is done through a 3-bit PWM duty cycle control with fixed PWM frequency. This string can also be used as an additional string for backlight support, see VBKLT, in which case it is controlled like the other LCD backlight strings, see LCD Backlight Drivers.

Camera Scene Illumination Drivers Status/Control Registers and Bits Description

Name	Bits	Descr	ription
		SSTRING (ADDR 0x2B - R/W - Default	t Value: 0x00)
SLEDEN	0	Camera Scene Illumination Drivers Enable Bit	
		x0 = Disable	
		x1 = Enable	
SILTBRT	3:1	Camera Scene Illumination PWM Duty Cycle Settings	
		x0 = 12.5%	x4 = 62.5%
		x1 = 25%	x5 = 75%
		x2 = 37.5%	x6 = 87.5%
		x3 = 50%	x7 = 100%
Reserved	7:4	Reserved	

SIGNALING/STATUS LED DRIVERS

The 900841 contains signaling/status LED drivers in the form of two banks of RGB LED drivers. The signaling LED drivers LEDR1, LEDG1, LEDB1, LEDR2, LEDG2, and LEDB2 are independent current sink channels. Each driver channel features programmable current levels via LEDxBRT[1:0] as well as programmable PWM duty cycle settings with LEDxDC[5:0]. By a combination of level and PWM settings, each channel provides flexible LED intensity control. By driving LEDs of different colors, color mixing can be achieved. The default duty cycle, when a blink period is set, not continuous, is 0.5 s on time.

Blue LEDs or bright green LEDs require more headroom than red and normal green signal LEDs. In the application, a 5.0 V or equivalent supply rail is therefore required. This is provided by the integrated 5.0 V boost converter VOTG.

Battery voltage can also be used to supply the RGB banks directly via VPWR, if enough headroom is possible, by using low forward voltage LEDs. Furthermore, each one of these drivers can be supplied from a different source, as they are completely independent. The PWM waveforms are staggered from each other by one cycle of 32 kHz to minimize sudden load changes on the LED supply.

The signaling LED drivers include ramp up and ramp down patterns implemented in hardware. Ramp patterns for each of the drivers are accessed with the corresponding LEDxRAMP bit. The ramp itself is generated by increasing or decreasing the PWM duty cycle with a 1/32 step every 1/64 seconds. The ramp time is therefore a function of the initial set PWM cycle and the final PWM cycle. As an example, starting from 0/32 and going to 32/32 will take 500 ms, while going to from 8/32 to 16/32 takes 125 ms. Note that the ramp function is executed upon every change in PWM cycle

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setting. If a PWM change is programmed via the SPI when the LEDxRAMP=0, then the change is immediate rather than spread out over a PWM sweep.

For color mixing and in order to guarantee a constant color, the color mixing should be obtained by the current level setting so that the intensity is set through the PWM duty cycle. In addition, programmable blink rates are provided. Blinking is obtained by lowering the PWM repetition rate of each of the drivers through LEDxBLNK[1:0] while the on period is determined by the duty cycle setting, default is 0.5 s ON time. To avoid high frequency spur coupling in the application, the switching edges of the output drivers are softened. During blinking, so LEDxBLNK[1:0] is not "00", ramping and dimming patterns cannot be applied.

Apart from using the signal/status LED drivers for driving LEDs they can also be used as general purpose open drain outputs for logic signaling or as generic PWM generator outputs. For the maximum voltage ratings see Maximum Ratings.

Signaling/Status LED Drivers Status/Control Registers and Bits Description

Table 75.	Signaling	/Status LED	Driver Register	and Bit Description
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x0 = 0 mA x1 = 8.0 mA x2 = 20 mA x3 = 28 mALEDOBLNK3.2LEDR1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLED1BRT5.4LEDG1 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x2 = 20 mA x3 = 28 mALED1BLNK7.6LEDG1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLED1BLNK7.6LEDG1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLED1BLNK7.6LEDG1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLEDBT1 (ADDR 0x26 - R/W - Default Value: 0x00)	Name	Bits	Description
kx0 = 0 mA x1 = 8.0 mA x2 = 20 mA x2 = 20 mAED0BLNK3.2LEDR1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLED1BRT5.4LEDG1 Driver Current Settings x0 = 0 mA x2 = 20 mA x3 = 28 mALED1BLNK7.6LEDG1 Blink Setting, with a default on time of 0.5 s x0 = 0 mA x2 = 20 mA x3 = 28 mALED1BLNK7.6LEDG1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x2 = 4.0 s x2 = 20 mA x3 = 28 mALED2BLNK1.0LEDB1 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x2 = 20 mA x3 = 28 mALED2BRT1.0LEDB1 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x3 = 28 mALED2BLNK1.0LEDB1 Driver Current Settings x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLED2BLNK1.0LEDB1 Driver Current Settings x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLED2BLNK3.2LEDB1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLED2BLNK3.2LEDB1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLED3BRT5.4LED2D Driver Current Settings x0 = 0 mA x1 = 8.0 mA x2 = 20 mA			LEDBRT0 (ADDR 0x25 - R/W - Default Value: 0x00)
kx1 = 8.0 mA x2 = 20 mA x3 = 28 mALED0BLNKS.2LEDR1 Bink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLED1BRT5.4LEDG1 Driver Current Settings x0 = 0 mA x3 = 28 mALED1BLNK7.6LEDG1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLED1BLNK7.6LEDG1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLED2BRT1.0LEDBRT1 (ADDR 0x26 - R/W - Default Value: 0x00)LED2BRT1.0LEDBRT1 (ADDR 0x26 - R/W - Default Value: 0x00)LED2BRT2.0mA x1 = 8.0 mA x2 = 2.0 mA x3 = 8.0 sLED2BRT1.0LEDBT Driver Current Settings x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLED2BRT5.4LEDB1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLED2BRT5.4LEDB1 Driver Current Settings x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLED3BRT5.4LEDR2 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x1 = 8.0 mA x2 = 20 mA	LED0BRT	1:0	LEDR1 Driver Current Settings
x2 = 20 mA x3 = 28 mALEDOBLNK3.2LEDR1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLED1BRT5.4LEDG1 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x2 = 20 mA x3 = 28 mALED1BLNK7.6LEDG1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLED1BLNK7.6LEDB1 Dlink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLED2BRT1.0LEDB1 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x2 = 2.0 mA x3 = 28 mALED2BRT1.0LEDB1 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x2 = 2.0 mA x3 = 8.0 sLED2BRT1.0LEDB1 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x2 = 2.0 mA x3 = 8.0 sLED2BRT3.2LEDB1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLED2BRT3.2LEDB1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLED2BRT5.4LEDR2 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x2 = 2.0 mALED3BRT5.4LEDR2 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x2 = 2.0 mA			x0 = 0 mA
LEDBLNKX3 = 28 mALEDDBLNK3.2LEDR1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLED1BRT5.4LEDG1 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x2 = 20 mA x3 = 28 mALED1BLNK7.6LEDG1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLED1BLNK7.6LEDG1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLED2BRT1.0LEDB1 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x2 = 20 mA x3 = 28 mALED2BRT1.0LEDB1 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x2 = 20 mA x3 = 28 mALED2BLNK3.2LED1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLED2BLNK3.2LED1 Blink Setting, with a default on time of 0.5 s x0 = No A x1 = 8.0 mA x2 = 20 mA x3 = 28 mALED2BLNK3.2LED1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLED3BRT5.4LED2D truer Current Settings x0 = 0 mA x1 = 8.0 mA<			x1 = 8.0 mA
EDOBLNK 3:2 LEDR1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 s LED1BRT 5:4 LEDG1 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x2 = 20 mA x3 = 28 mA LED1BLNK 7:6 LEDG1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 s LED1BLNK 7:6 LEDG1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 s LED2BRT 1:0 LEDB1 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x2 = 20 mA x3 = 28 mA LED2BLNK 3:2 LEDB1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 s LED2BRT 1:0 LEDB1 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x2 = 20 mA x3 = 8.0 s LED2BLNK 3:2 LEDB1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 s LED3BRT 5:4 LEDR2 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x1 = 8.0 mA x1 = 2.0 mA			
x0 = No Blink $x1 = 1.0 s$ $x2 = 4.0 s$ $x3 = 8.0 s$ LED1BRT5.4LEDG1 Driver Current Settings $x0 = 0 mA$ $x1 = 8.0 mA$ $x2 = 20 mA$ $x3 = 28 mA$ LED1BLNK7.6LEDG1 Dlink setting, with a default on time of 0.5 s $x0 = No Blink$ $x1 = 1.0 s$ $x2 = 4.0 s$ $x3 = 8.0 s$ LED2BRT1.0LEDBRT1 (ADDR 0x26 - R/W - Default Value: 0x00)LED2BRT1.0LED2BRT1.0LED2BLNK3.2LED2BLNK3.2LED2BLNK3.2LED2BLNK3.2LED2BLNK3.2LED2BLNK3.2LED2BLNK3.2LED2BLNK3.2LED2BLNK3.2LED2BLNK3.2LED3 Blink Setting, with a default on time of 0.5 s $x0 = No Blink$ $x1 = 8.0 mA$ $x2 = 20 mA$ $x3 = 28 mALED2BLNK3.2LED3 BLINK Setting, with a default on time of 0.5 sx0 = No Blinkx1 = 1.0 sx2 = 4.0 sx3 = 8.0 sLED3BRT5.4LED3 Driver Current Settingsx0 = 0 mAx1 = 8.0 mAx2 = 20 mA$			x3 = 28 mA
x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLED1BRT5.4LEDG1 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x2 = 20 mA x3 = 28 mALED1BLNK7.6LEDG1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLED2BRT1.0LEDBRT1 (ADDR 0x26 - R/W - Default Value: 0x00)LED2BRT1.0LEDB1 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x2 = 20 mA x3 = 8.0 sLED2BRT1.0LEDB1 Driver Current Settings x0 = No Blink x1 = 8.0 mA x2 = 20 mA x3 = 28 mALED2BRT1.2LEDB1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 8.0 mA x2 = 20 mA x3 = 8.0 sLED2BLNK3.2LEDB1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 8.0 mA x2 = 4.0 s x3 = 8.0 sLED3BRT5.4LEDCP2 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x2 = 2.0 mA	LED0BLNK	3:2	LEDR1 Blink Setting, with a default on time of 0.5 s
x = 4.0 s $x = 8.0 s$ LED1BRT 5.4 LEDG1 Driver Current Settings $x0 = 0 mA$ $x1 = 8.0 mA$ $x2 = 20 mA$ $x3 = 28 mA$ LED1BLNK 7.6 LEDG1 Blink Setting, with a default on time of 0.5 s $x0 = N0$ Blink $x1 = 1.0 s$ $x2 = 4.0 s$ $x3 = 8.0 s$ LED2BRT 1.0 LEDB1 Driver Current Settings $x0 = 0 mA$ $x1 = 8.0 mA$ $x2 = 20 mA$ $x3 = 8.0 s$ LED2BRT 1.0 LEDB1 Driver Current Settings $x0 = 0 mA$ $x1 = 8.0 mA$ $x2 = 20 mA$ $x3 = 28 mA$ LED2BLNK 3.2 LEDB1 Blink Setting, with a default on time of 0.5 s $x0 = N0 Blink$ $x1 = 1.0 s$ $x2 = 4.0 s$ $x3 = 28 mA$ LED2BLNK 3.2 LEDB1 Blink Setting, with a default on time of 0.5 s $x0 = N0 Blink$ $x1 = 1.0 s$ $x2 = 4.0 s$ $x3 = 8.0 s$ LED3BRT 5.4 LEDR2 Driver Current Settings $x0 = 0 mA$ $x1 = 8.0 mA$ $x2 = 2.0 mA$ $x2 = 2.0 mA$ LED3BRT 5.4 LEDR2 Driver Current Settings $x0 = 0 mA$ $x1 = 8.0 mA$ $x2 = 2.0 mA$ $x2 = 2.0 mA$			x0 = No Blink
x3 = 8.0 sLED1BRT5.4LEDG1 Driver Current Settings $x0 = 0 \text{ mA}$ $x1 = 8.0 \text{ mA}$ $x2 = 20 \text{ mA}$ $x3 = 28 \text{ mA}$ LED1BLNK7.6LEDG1 Blink Setting, with a default on time of 0.5 s $x0 = No Blink$ $x1 = 1.0 \text{ s}$ $x2 = 4.0 \text{ s}$ $x3 = 8.0 \text{ s}$ LEDBRT1 (ADDR 0x26 - R/W - Default Value: 0x00)LED2BRT1:0LED2BRT1:0LED2BRT1:0LED2BLNK3:2LED2BLNK3:2LED2BLNK3:2LED2BLNK3:2LED2BLNK3:2LED2BLNK3:2LED3BRT5:4LEDR 1 Driver Current Settings $x2 = 4.0 \text{ s}$ $x3 = 8.0 \text{ s}$ LED2BLNK3:2LED3BRT5:4LED3 1LEDR2 Driver Current Settings $x0 = 0 \text{ mA}$ $x1 = 8.0 \text{ mA}$ $x2 = 2.0 \text{ mA}$			
LED1BRT5.4LEDG1 Driver Current Settings $x0 = 0$ mA $x1 = 8.0$ mA $x2 = 20$ mA $x3 = 28$ mALED1BLNK7.6LEDG1 Blink Setting, with a default on time of 0.5 s $x0 = No Blink$ $x1 = 1.0$ s $x2 = 4.0$ s $x3 = 8.0$ sLEDBRT1 (ADDR 0x26 - R/W - Default Value: 0x00)LED2BRT1:0LED2BRT1:0LED2BLNK3:2LED2BLNK3:2LED2BLNK3:2LED2BLNK3:2LED2BLNK3:2LED2BLNK3:2LED2BLNK3:2LED2BLNK3:2LED2BLNK3:2LED3BRT5:4LED2 DIVEY Current Settings $x0 = 0$ mA $x1 = 8.0$ mA $x1 = 8.0$ mA $x2 = 2.0$ s $x3 = 8.0$ sLED2BLNK3:2LED3BRT5:4LED32 DIVEY Current Settings $x0 = 0$ mA $x1 = 8.0$ mA $x1 = 8.0$ mA $x2 = 2.0$ mA			
x0 = 0 mA x1 = 8.0 mA x2 = 20 mA x3 = 28 mAED1BLNK 7.6 LEDG1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLEDBRT1 (ADDR 0x26 - R/W - Default Value: 0x00)LED2BRT1.0LED2BRT1.0LED2BRT1.0LED2BLNKx0 = 0 mA x1 = 8.0 mA x3 = 28 mALED2BLNK3.2LED3BRT1.2LED2B Diver Current Settings x0 = 0 mA x1 = 8.0 mA x2 = 20 mA x3 = 28 mALED2BLNK3.2LED3 Diver Current Settings x0 = 0 mA x1 = 8.0 sLED3BRT5.4LED2 Diver Current Settings x0 = 0 mA x1 = 8.0 mA x2 = 4.0 s x3 = 8.0 sLED3BRT5.4LED3 Diver Current Settings x0 = 0 mA x1 = 8.0 mA x1 = 8.0 mA x1 = 8.0 mA x2 = 20 mA			x3 = 8.0 s
x1 = 8.0 mA x2 = 20 mA x3 = 28 mALED1BLNK7:6LEDG1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8LED2BRT1:0LEDB1 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x2 = 20 mA x3 = 28 mALED2BLNK3:2LEDB1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLED2BLNK3:2LEDB1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLED3BRT5:4LEDR2 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x2 = 20 mA x3 = 8.0 sLED3BRT5:4LEDR2 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x2 = 20 mA x3 = 20 mA x3 = 8.0 s	LED1BRT	5:4	LEDG1 Driver Current Settings
Image: Second systemImage: Second system			
kx3 = 28 mALED1BLNK7:6LEDG1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLEDBRT1 (ADDR 0x26 - R/W - Default Value: 0x00)LED2BRT1:0LEDB1 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x2 = 20 mA x3 = 28 mALED2BLNK3:2LEDB1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLED3BRT5:4LEDR2 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x2 = 20 mA x3 = 28 mA			
LED1BLNK7:6LEDG1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLEDBRT1 (ADDR 0x26 - R/W - Default Value: 0x00)LED2BRT1:0LEDB1 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x2 = 20 mA x3 = 28 mALED2BLNK3:2LEDB1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLED3BRT5:4LEDR2 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLED3BRT5:4LEDR2 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x2 = 20 mA x2 = 4.0 s x3 = 8.0 s			
x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLEDBRT1 (ADDR 0x26 - R/W - Default Value: 0x00)LED2BRT1:0 x0 = 0 mA x1 = 8.0 mA x2 = 20 mA x3 = 28 mALED2BLNK3:2 x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLED3BRT5:4 x0 = 0 mA x1 = 8.0 mA x2 = 20 mA x3 = 8.0 s			x3 = 28 mA
x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLEDBRT1 (ADDR 0x26 - R/W - Default Value: 0x00)LED2BRT1:0LEDB1 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x2 = 20 mA x3 = 28 mALED2BLNK3:2LEDB1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLED3BRT5:4LEDR2 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x2 = 20 mA	LED1BLNK	7:6	
x2 = 4.0 s x3 = 8.0 s LEDBRT1 (ADDR 0x26 - R/W - Default Value: 0x00) LED2BRT 1:0 LEDB1 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x2 = 20 mA x3 = 28 mA LED2BLNK 3:2 LEDB1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 s LED3BRT 5:4 LEDR2 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x2 = 20 mA x3 = 8.0 s			
Image: state stat			
LEDBRT1 (ADDR 0x26 - R/W - Default Value: 0x00) LED2BRT 1:0 LEDB1 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x2 = 20 mA x3 = 28 mA ED2BLNK 3:2 LEDB1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 s LED3BRT 5:4 LEDR2 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x1 = 8.0 mA x1 = 2 0 mA			
LED2BRT1:0LEDB1 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x2 = 20 mA x3 = 28 mALED2BLNK3:2LEDB1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLED3BRT5:4LEDR2 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x1 = 8.0 mA x2 = 20 mA			
x0 = 0 mAx1 = 8.0 mAx2 = 20 mAx3 = 28 mAED2BLNK3:2LEDB1 Blink Setting, with a default on time of 0.5 sx0 = No Blinkx1 = 1.0 sx2 = 4.0 sx3 = 8.0 sLED3BRT5:4LEDR2 Driver Current Settingsx0 = 0 mAx1 = 8.0 mAx2 = 20 mA		1	
x1 = 8.0 mAx2 = 20 mAx3 = 28 mALED2BLNK3:2LEDB1 Blink Setting, with a default on time of 0.5 sx0 = No Blinkx1 = 1.0 sx2 = 4.0 sx3 = 8.0 sLED3BRT5:4LEDR2 Driver Current Settingsx0 = 0 mAx1 = 8.0 mAx2 = 20 mA	LED2BRT	1:0	
x2 = 20 mAx3 = 28 mAED2BLNK3:2LEDB1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLED3BRT5:4LEDR2 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x2 = 20 mA			
x3 = 28 mALED2BLNK3:2LEDB1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLED3BRT5:4LEDR2 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x2 = 20 mA			
LED2BLNK3:2LEDB1 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 sLED3BRT5:4LEDR2 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x2 = 20 mA			
$x0 = No Blink$ $x1 = 1.0 s$ $x2 = 4.0 s$ $x3 = 8.0 s$ LED3BRT $5:4 \qquad LEDR2 Driver Current Settings$ $x0 = 0 mA$ $x1 = 8.0 mA$ $x1 = 8.0 mA$ $x2 = 20 mA$			
$x1 = 1.0 s$ $x2 = 4.0 s$ $x3 = 8.0 s$ LED3BRT $5:4 \qquad LEDR2 \text{ Driver Current Settings}$ $x0 = 0 \text{ mA}$ $x1 = 8.0 \text{ mA}$ $x2 = 20 \text{ mA}$	LED2BLNK	3:2	
x2 = 4.0 s x3 = 8.0 sLED3BRT5:4LEDR2 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x2 = 20 mA			
x3 = 8.0 s LED3BRT 5:4 LEDR2 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x2 = 20 mA			
LED3BRT 5:4 LEDR2 Driver Current Settings x0 = 0 mA x1 = 8.0 mA x2 = 20 mA			
x0 = 0 mA x1 = 8.0 mA x2 = 20 mA			
x1 = 8.0 mA x2 = 20 mA	LED3BRT	5:4	
x2 = 20 mA			
$\lambda 0 = 20 \text{ mA}$			
			x3 = 20 mA 90084

Table 75. Signaling /Status LED Driver Register and Bit Description

LED3BLNK	7:6	LEDR2 Blink Setting, with a default on time of 0.5 s
		x0 = No Blink
		x1 = 1.0 s
		x2 = 4.0 s
		x3 = 8.0 s
		LEDBRT2 (ADDR 0x27 - R/W - Default Value: 0x00)
LED4BRT	1:0	LEDG2 Driver Current Settings
		x0 = 0 mA
		x1 = 8.0 mA
		x2 = 20 mA
		x3 = 28 mA
LED4BLNK	3:2	LEDG2 Blink Setting, with a default on time of 0.5 s
		x0 = No Blink
		x1 = 1.0 s
		x2 = 4.0 s
		x3 = 8.0 s
LED5BRT	5:4	LEDB2 Driver Current Settings
		x0 = 0 mA
		x1 = 8.0 mA
		x2 = 20 mA
		x3 = 28 mA
LED5BLNK	7:6	LEDB2 Blink Setting, with a default on time of 0.5 s
		x0 = No Blink
		x1 = 1.0 s
		x2 = 4.0 s
		x3 = 8.0 s

Signaling/Status LED Drivers Status/Control Registers and Bits Description

FSL control registers are completely optional, but if the application wants to have an adjustable duty cycle and/or duty cycle ramping ("advance control"), the FSL registers are

activated by setting the LEDxBLNK fields to 00 = no blink. The default duty cycle in advance mode is set to 100%. After enabling the FSL register control, if the user wishes to revert back to "normal control" with 0.5 sec ON time, just write something different than 00 to the LEDxBLNK fields.

Table 76. I	RGB LED Control Register Structure and Bits Description
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Name	Bits			Description			
		FSL	LEDR1CNT (ADDR 0x1	1D6 - R/W - Default Valu	ie: 0xFC)		
LEDR1BLNK 1:0 LEDR1 Blink Setting, with a default on time of 0.5 s							
		x0 = No Blink					
		x1 = 1.0 s					
		x2 = 4.0 s					
		x3 = 8.0 s					
LEDR1DC	7:2	LEDR1 Driver PW	M Duty Cycle Settings				
		x00=0/32	x08=8/32	x10=16/32	x18=24/32		
		x01=1/32	x09=9/32	x11=17/32	x19=25/32		
		x02=2/32	x0A=10/32	x12=18/32	x1A=26/32		
		x03=3/32	x0B=11/32	x13=19/32	x1B=27/32		
		x04=4/32	x0C=12/32	x14=20/32	x1C=28/32		
		x05=5/32	x0D=13/32	x15=21/32	x1D=29/32		
		x06=6/32	x0E=14/32	x16=22/32	x1E=30/32		
		x07=7/32	x0F=15/32	x17=23/32	x1F=31/32		
					x20=32/32 (Continuous ON)		
					x21-x3F=Don't Care		
		FSL	LEDG1CNT (ADDR 0x1	1D7 - R/W - Default Valu	ie: 0xFC)		
LEDG1BLNK	1:0						
		x0 = No Blink					
		x1 = 1.0 s					
		x2 = 4.0 s					
		x3 = 8.0 s					
LEDG1DC	7:2	LEDG1 Driver PW	M Duty Cycle Settings				
		x00=0/32	x08=8/32	x10=16/32	x18=24/32		
		x01=1/32	x09=9/32	x11=17/32	x19=25/32		
		x02=2/32	x0A=10/32	x12=18/32	x1A=26/32		
		x03=3/32	x0B=11/32	x13=19/32	x1B=27/32		
		x04=4/32	x0C=12/32	x14=20/32	x1C=28/32		
		x05=5/32	x0D=13/32	x15=21/32	x1D=29/32		
		x06=6/32	x0E=14/32	x16=22/32	x1E=30/32		
		x07=7/32	x0F=15/32	x17=23/32	x1F=31/32		
					x20=32/32 (Continuous ON)		
					x21-x3F=Don't Care		

FUNCTIONAL DEVICE OPERATION LIGHTING SYSTEM

Table 76. RGB LED Control Register Structure and Bits Description	
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	FSLLED	B1CNT (ADDR 0x1D8	- R/W - Default Value: 0	0xFC)		
LEDB1BLNK 1:0 LEDB1 Blink Setting, with a default on time of 0.5 s						
	x0 = No Blink					
	x1 = 1.0 s					
	x2 = 4.0 s					
	x3 = 8.0 s					
7:2	LEDB1 Driver PWM D	uty Cycle Settings				
	x00=0/32	x08=8/32	x10=16/32	x18=24/32		
	x01=1/32	x09=9/32	x11=17/32	x19=25/32		
	x02=2/32	x0A=10/32	x12=18/32	x1A=26/32		
	x03=3/32	x0B=11/32	x13=19/32	x1B=27/32		
	x04=4/32	x0C=12/32	x14=20/32	x1C=28/32		
	x05=5/32	x0D=13/32	x15=21/32	x1D=29/32		
	x06=6/32	x0E=14/32	x16=22/32	x1E=30/32		
	x07=7/32	x0F=15/32	x17=23/32	x1F=31/32		
				x20=32/32 (Continuous ON)		
				x21-x3F=Don't Care		
	FSLLEE	R2CNT (ADDR 0x1D9) - R/W - Default Value: 0)xFC)		
1.0	1			,		
	x0 = No Blink					
	x1 = 1.0s					
	x2 = 4.0 s					
	x3 = 8.0 s					
7:2	LEDR2 Driver PWM D	uty Cycle Settings				
	x00=0/32	x08=8/32	x10=16/32	x18=24/32		
	x01=1/32	x09=9/32	x11=17/32	x19=25/32		
	x02=2/32	x0A=10/32	x12=18/32	x1A=26/32		
	x03=3/32	x0B=11/32	x13=19/32	x1B=27/32		
	x04=4/32	x0C=12/32	x14=20/32	x1C=28/32		
	x05=5/32	x0D=13/32	x15=21/32	x1D=29/32		
	x06=6/32	x0E=14/32	x16=22/32	x1E=30/32		
	x07=7/32	x0F=15/32	x17=23/32	x1F=31/32		
				x20=32/32 (Continuous ON)		
				x21-x3F=Don't Care		
	7:2	1:0 LEDB1 Blink Setting, v x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 s 7:2 LEDB1 Driver PWM Driver P	1:0 LEDB1 Blink Setting, with a default on time of x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 s 7:2 LEDB1 Driver PWM DUT Cycle Settings $x00=0/32$ x08=8/32 x09=9/32 $x01=1/32$ x09=9/32 x02=2/32 $x03=3/32$ x0B=11/32 x00=0/32 $x05=5/32$ x0D=13/32 x06=6/32 $x06=6/32$ x0E=14/32 x0F=15/32 $x0 = No Blink$ x1 = 1.0s x2 = 4.0 s x3 = 8.0 s 7:2 LEDR2 Driver PWM DUT Cycle Settings $x00=0/32$ x08=8/32 x0F=15/32 7:2 LEDR2 Driver PWM DUT Cycle Settings $x00=0/32$ x08=8/32 x01=1/32 x03=3/32 $x00=0/32$ x08=8/32 x01=1/32 x03=3/32 $x00=0/32$ x08=8/32 x01=1/32 x04=4/32 $x00=0/32$ x08=11/32 x02=12/32 x04=1/32 $x04=4/32$ x0C=12/32 x02=13/32 x00=13/32 x05=5/32 x0D=13/32	x0 = No Blink x1 = 1.0 s x2 = 4.0 s x3 = 8.0 s 7:2 LEDB1 Driver PWM Duty Cycle Settings x00=0/32 x08=8/32 x10=16/32 x01=1/32 x09=9/32 x11=17/32 x02=2/32 x0A=10/32 x12=18/32 x03=3/32 x0B=11/32 x13=19/32 x04=4/32 x0C=12/32 x14=20/32 x05=5/32 x0D=13/32 x15=21/32 x06=6/32 x0E=14/32 x16=22/32 x06=6/32 x0F=15/32 x17=23/32 x07=7/32 x0F=15/32 x17=23/32 x01 LEDR2 Blink Setting, with a default on time of 0.5 s x0 x0 = No Blink x1 = 1.0s x2 = 4.0 s x3 = 8.0 s x10=16/32 x10=16/32 7:2 LEDR2 Driver PWM Duty Cycle Settings x10=16/32 x00=0/32 x08=8/32 x10=16/32 x01=1/32 x09=9/32 x11=17/32 x02=2/32 x0A=10/32 x12=18/32 x01=1/32 x03=3/32 x01=11/32 x13=19/32 x02=2/32 x0A=10/32 x12=18/32 x03=3		

		FS	LLEDG2CNT (ADDR 0x1	DA - R/W - Default Valu	ue: 0xFC)			
LEDG2BLNK	1:0	LEDG2 Blink Setting, with a default on time of 0.5 s x0 = No Blink x1 = 1.0 s						
		x2 = 4.0 s						
		x3 = 8.0 s						
LEDG2DC	7:2	LEDG2 Driver P	VM Duty Cycle Settings					
		x00=0/32	x08=8/32	x10=16/32	x18=24/32			
		x01=1/32	x09=9/32	x11=17/32	x19=25/32			
		x02=2/32	x0A=10/32	x12=18/32	x1A=26/32			
		x03=3/32	x0B=11/32	x13=19/32	x1B=27/32			
		x04=4/32	x0C=12/32	x14=20/32	x1C=28/32			
		x05=5/32	x0D=13/32	x15=21/32	x1D=29/32			
		x06=6/32	x0E=14/32	x16=22/32	x1E=30/32			
		x07=7/32	x0F=15/32	x17=23/32	x1F=31/32			
					x20=32/32 (Continuous ON)			
					x21-x3F=Don't Care			
		FS	LLEDB2CNT (ADDR 0x1	DB - R/W - Default Valu	ue: 0xFC)			
LEDB2BLNK	1:0	LEDB2 Blink Set	LEDB2 Blink Setting, with a default on time of 0.5 s					
		x0 = No Blink						
		x1 = 1.0 s						
		x2 = 4.0 s						
		x3 = 8.0 s						
LEDB2DC	7:2	LEDB2 Driver PV	VM Duty Cycle Settings					
		x00=0/32	x08=8/32	x10=16/32	x18=24/32			
		x01=1/32	x09=9/32	x11=17/32	x19=25/32			
		x02=2/32	x0A=10/32	x12=18/32	x1A=26/32			
		x03=3/32	x0B=11/32	x13=19/32	x1B=27/32			
		x04=4/32	x0C=12/32	x14=20/32	x1C=28/32			
		x05=5/32	x0D=13/32	x15=21/32	x1D=29/32			
		x06=6/32	x0E=14/32	x16=22/32	x1E=30/32			
		x07=7/32	x0F=15/32	x17=23/32	x1F=31/32			
					x20=32/32 (Continuous ON)			
	1				x21-x3F=Don't Care			

Table 77. FSLLEDRAMPCNT Register Structure and Bits Description

Name	Bits	Description				
	FSLLEDRAMPCNTL (ADDR 0x1DC - R/W - Default Value: 0x00)					
LEDR1RAMP	EDR1RAMP 0 LEDR1 Driver Ramp Up – Ramp Down Patterns Enable Bit					
		x0 = Disable				
		x1 = Enable				
LEDG1RAMP	1	LEDR1 Driver Ramp Up – Ramp Down Patterns Enable Bit				
		x0 = Disable				
		x1 = Enable				
LEDB1RAMP	2	LEDR1 Driver Ramp Up – Ramp Down Patterns Enable Bit				
		x0 = Disable				
		x1 = Enable				

Table 77. FSLLEDRAMPCNT Register Structure and Bits Description

LEDR2RAMP	3	LEDR1 Driver Ramp Up – Ramp Down Patterns Enable Bit x0 = Disable x1 = Enable
LEDG2RAMP	4	LEDR1 Driver Ramp Up – Ramp Down Patterns Enable Bit x0 = Disable x1 = Enable
LEDB2RAMP	5	LEDR1 Driver Ramp Up – Ramp Down Patterns Enable Bit x0 = Disable x1 = Enable
Reserved	7:6	Reserved

BATTERY INTERFACE AND POWER PATH MANAGEMENT

POWER PATH MANAGER

The 900841 IC sources power to the platform loads through an intelligent power path that consists of the following two components listed in order of priority. Reference Figure 62 for more details:

• Input power source through a mini-USB connector that can be either an AC wall charger or a USB host adaptor. The

system host is responsible for notifying the 900841 of what type of input source it is connected to, by setting the maximum current the charger can draw from the input source (for example: 0.5 A USB or 1.8 A power source device).

• A bi-directional source in the form of a rechargeable single cell Li-Ion or Li-Polymer Battery.

FUNCTIONAL DEVICE OPERATION BATTERY INTERFACE AND POWER PATH MANAGEMENT





The multiplexed power output is made available at the VPWR node where all on-chip regulators draw their power from at a typical operating range of 3.0 to 4.4 V. See Figure 62. When a power source is detected at the RAWCHG pin, the respective input voltage is converted to a variable output voltage at the VPWR node through a buck switching DC/DC regulator, Charger buck.

CHARGER BUCK OPERATION

Charger buck takes its feedback from two sources, depending on the state of the battery:

 For batteries with a voltage less than the trickle charge threshold, V_{PWR} is set at a constant voltage of 4.2 V to supply the system loads. The feedback is taken from a conventional internal resistor divider connected at the VPWR pin. This supports dead battery operation and allows the system to operate if the battery does not exist, or is being trickle charged through a separate path.

 For batteries within normal operation of 3.0 to 4.4 V, V_{PWR} tracks the battery voltage level V_{BAT}. To keep power dissipation low during charging, VPWR is normally adjusted to be 300 mV above V_{BAT}, subject to a maximum of 4.7 V.

The buck regulator core implements PWM and auto-PFM modes. The charger buck needs to be able to support 100% duty operation for cases when the input falls close to the output voltage. In this mode, M_{HSCHG} is switched fully on, and M_{LSCHG} is disabled. The regulator will stay in 100% (or close to it) duty-cycle mode until either V_{PWR} rises above 4.7V, under which case V_{PWR} is clamped to a maximum of 4.7V, or the loop feedback demands a lower duty cycle. While

in 100% Duty Cycle mode, the output current limit is still operational.

The charger buck monitors the input current draw by sensing the voltage across RINSNSCHG which will allow the charger system to regulate the power draw out of the input adaptor to fit the needs of the system. During charging, if an input source is connected and the selected charging current plus load current exceeds the current limit set by the USBLMT[1:0] bits and detected across RINSNSCHG, the charger buck will behave like a constant current source, supplying the current limit. The VPWR voltage will droop, and the DCLMT interrupt signal is asserted. As the VPWR voltage approaches the V_{BAT} voltage, the charger pass transistor, M_{CHG}, will switch itself fully on as the charger control tries to maintain the programmed charge current. At some point, the charge current will start to decrease, as this current starts to get limited by the R_{ds(on)} of M_{CHG}. The V_{PWR} voltage will stabilize at a point where the charge current equates to the difference between the input current limit set by USBLMT[1:0] and the total system load current. If the load current by itself exceeds the input current limit, the VPWR voltage will fall more below the V_{BAT} voltage, and the excess current will come from the battery through M_{CHG}, which is still fully switched on in this instance. The USBLMT settings are maximum numbers and will not be exceeded, so a lower value should be targeted as a typical and ±5% accuracy is desired

In the previous case, where the battery is being discharged, M_{CHGBYP} provides an optional feature to reduce the series resistance between V_{BAT} and V_{PWR} , saving on overall system efficiency and battery life. The system can activate this function by asserting the CHGBYP bit high. So if CHGBYP is "1", and whenever V_{PWR} falls below V_{BAT} by 100 mV, the 900841 turns on MCHGBYP. If CHGBYP is "0", this function is deactivated. If MCHGBYP is not used, the CHGBYPGT pin must be connected to ground.

To prevent an over-voltage condition to the system, the charger buck monitors the voltage at the RAWCHG pin. If V_{RAWCHG} rises above 5.75 V, an over-voltage condition is detected, the over-voltage protection FET MOVPCHG is disabled, the charger buck is disabled, and the USBOVP interrupt signal is asserted and the RDSTATE register is updated to state 0x02 (AC Adaptor OVP). Such over-voltage condition can occur due to a faulty USB/AC adapter design or a voltage spike during the insertion of the adapter to the system. Input over-voltage protection is an optional feature, as there are other methods to prevent an over-voltage condition. Such methods, like a Zener clamp, can limit the input voltage to a 6.0 V maximum, under which case M_{OVPCHG} is not needed and can be removed. Using a high performance or well designed adaptor that can guarantee a maximum input voltage of 5.5 V, will eliminate the need for MOVPCHG. If any of these other methods fail, damage will occur to the IC. Without the presence of MOVPCHG, a maximum voltage will be exceeded for many parts of the IC.

Whenever the charger buck is disabled, the battery will supply power to the VPWR node through the charger pass

transistor element M_{CHG} , and also through M_{CHGBYP} if used. In that case, $M_{REVPCHG}$ switch is disabled to electrically isolate the input power connector from the battery and prevent reverse current draw from battery to connector. For lower power inputs, like a dedicated USB source, $M_{REVPCHG}$, can be replaced by a low forward voltage drop Schottky Diode, pointing the same direction as the $M_{REVPCHG}$ body diode. In this case, REVPCHGGT should be grounded. No specific Schottky diode is recommended. Any 2.0 A/30 V capable diode with low forward voltage drop can use used.

The system can assert the BATISO bit to turn off M_{CHG} , and M_{CHGBYP} if used, to isolate the battery from the system. In this case, V_{PWR} has to be higher than V_{BAT} and set, depending on the value of the battery, as explained in the first paragraph. Reference Power States and Control for more information.

LI-ION BATTERY CHARGER

FEATURES

- Complete charger for single-cell Li-lon batteries with an external PFET pass element
- Programmable constant charge current limit (I_{CHGCC})
- Programmable End-of-Charge (EOC) detection current (I_{CHGCOMP})
- Programmable trickle charge current (I_{TRKL})
- · Intelligent EOC detection to prevent false indication
- Programmable battery float voltage (V_{CHGCV})
- Programmable battery over-voltage (V_{OVRVOLT})
- Optional battery temperature monitoring NTC thermistor interface for charge qualification with two different temperature ranges for charging and discharging
- · Ability for trickle mode only charging
- Programmable smart timer for charge termination and detection of fault conditions (t_{CHG})
- · Programmable battery over-voltage protection
- Intelligent Interrupt and State reporting capabilities

Charger Operation

The charger provides the traditional Constant Current/ Constant Voltage (CC/CV) charging output with the preconditioning function (trickle charge) for deeply discharged batteries. Multiple parameters can be programmed through the SPI registers.

The charger is a Constant Current Regulator with V_{PWR} as its input and V_{BAT} as its output, with constant voltage headroom of 300 mV across it, V_{PWR} – V_{BAT}. It regulates the maximum charging current flowing into the battery (I_{CHGCC}) to the value set by SPI programming of the CHRGCC[2:0] bits. The 300 mV headroom includes the voltage drop across R_{SNSBAT} and R_{CC}.

The loop will regulate the voltage drop over the sense resistor R_{SNSBAT} by controlling M_{CHG} to a value resulting in a maximum constant current equal to I_{CHGCC} . Therefore, the value of R_{SNSBAT} influences the charge current, and its

accuracy directly effects the accuracy of I_{CHGCC} and $I_{CHGCOMP}$. A value of 100 m ±1% is recommended.

Charger Parameter Programming

Multiple charge parameters are programmable through the SPI interface:

- Battery float voltage (V_{CHGCV})
- Constant charge current (I_{CHGCC})
- End-of-Charge current (I_{CHGCOMP})
- Trickle charge current (I_{TRKL})
- Battery over-voltage (V_{OVRVOLT})
- Charge time monitor timer (t_{CHG})

Charge Starts and Charge Ends

A charging cycle cannot start until a valid voltage is detected at RAWCHG, CHRENB bit is set to 0, and no faults exist. A valid RAWCHG voltage is when V_{RAWCHG} is > 4.75 V. The USB interrupt signal is asserted when V_{RAWCHG} > 4.75 V. During a charging cycle, if the charger system experiences any fault, it stops charging and asserts the appropriate interrupt signal. When a charge cycle completes, the COMP interrupt signal is asserted indicating a normal completion of a charge cycle. What constitutes a charge cycle completion is examined later in this section.

CHARGER STATE MACHINE



Figure 63. Li-Ion Charger State Machine

TRICKLE CHARGE

Once the charger is enabled and if $V_{BAT} < V_{TRKL}$, the trickle charge starts. The trickle charge current $I_{CHGTRKL}$ is selectable with a default current of 40 mA, and is provided by

an internal current source between V_{PWR} and V_{BAT}, as can be seen in <u>Figure 63</u>. The trickle charge function consists of a simple comparator that monitors the battery voltage. The charger stays in the trickle mode as long as the battery voltage is below the trickle charge threshold (V_{TRKL}) of 3.0 V

and the total trickle charge time has not expired. If the trickle charge time expires before V_{BAT} exceeding V_{TRKL}, the charger is turned off and the appropriate state is set. If V_{BAT} rises above V_{TRKL} before the trickle charge time expires, we enter in the Quick Charge stage and I_{CHGCC} is used for charging. At any time during trickle charging, if a fault occurs, the charger turns off and an interrupt is asserted, according to the type of fault. The trickle charge time is always set to 1/4 of the set t_{CHG} timer. The t_{CHG} timer is reset when entering the trickle charge mode. V_{TRKL} detection is equipped with a 32 ms filter to debounce the transition between Trickle and Quick Charge modes. Regardless of the timer state, if V_{BAT} rises above V_{TRKL}, then the BATDET interrupt signal is asserted.

Trickle charging can be forced as well, by setting the bit TRICKLE = 1. In this case, the full t_{CHG} timer is used during trickle charge. In this mode, charging stops if the timer expires or V_{BAT} exceeds V_{CHGCV} triggers the EOC on forced trickle mode.

QUICK CHARGE

The fast charge includes the CC mode and the CV mode. A soft transition between the trickle mode and the CC mode is required to minimize the transient behavior at the input during the transition. The Constant Current value (I_{CHGCC}) can be set by SPI programming the CHRGCC[2:0] bits, and is regulated as explained previously. Once entering the CV mode, the battery voltage is held at the battery float voltage threshold V_{CHGCV}, which can be set by SPI programming the CHRGCV[3:0] bits. The charge current reduces gradually until the end of charge event EOC. The total charge time for the quick charge is limited by t_{CHG} .

The $\ensuremath{t_{\text{CHG}}}$ timer is reset when entering the fast charge mode.

If the battery voltage V_{BAT} exceeds the over-voltage threshold set by SPI programming the OVRVOLT[1:0] bits, the buck charger is turned off and the BATOVP interrupt signal is asserted.

END-OF-CHARGE (EOC)

For a charge cycle to be completed (EOC), two conditions are required to be simultaneously met: the battery voltage must be above the recharge threshold V_{RCHG} , and the charge current must fall below the EOC current $I_{CHGCOMP}$. $I_{CHGCOMP}$ can be set by SPI programming the CHRGCOMP[2:0] bits. A 1.0 ms filter is required to prevent fast transient current, triggering the EOC current threshold.





WATCHDOG TIMER

The charger is equipped with a watchdog timer that the Platform controller hub can enable and set for different times. Setups and responses are highlighted in <u>Figure 63</u>.

NTC INTERFACE

A battery pack may be equipped with a thermistor which value decreases over temperature (NTC). The NTC interface allows an external NTC thermistor to monitor the battery temperature and disable the charger when the temperature is outside of a specific window. The relationship between temperature T (in Kelvin) and the thermistor value (RT) is well

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characterized, and can be described as $R_T=R_0^*e^{(B^*(1/T - 1/T_0))}$, with T_0 being room temperature, R_0 the thermistor value at T_0 , and B being the so called B-factor which indicates the slope of the thermistor over temperature. The NTC interface can handle several standard B factors such as 3200, 3500, and 3900.

To read out the thermistor value, it is biased through a pullup resistor R_{NTC} from the VNTC pin, which switches the V_{CORE} voltage to bias the chain. This switch, along with the NTC comparators, is controlled through the TEMPEN bit.

During charging, the NTC comparators and the switch are turned on automatically for battery temperature monitoring,

and the temperature range is set at 0°C to 45°C. NTC circuitry cannot be disabled during charging.

During discharging, the user has an option to turn the NTC block off through the TEMPEN bit. Whenever an NTC ADC reading is desired or to keep battery temperature monitor on, this bit must be asserted. Turning this block off and disconnecting the switch saves on quiescent current and enhances battery life. During discharging, the battery temperature monitoring range is set at -10°C to 60°C.

The window thresholds are specified as a ratio of the $V_{\rm NTC}$ voltage. The battery thermistor check circuit compares the fraction of $V_{\rm NTC}$ at NTC pin, with two preset thresholds which

correspond to one of the previous ranges, depending if the IC is charging or discharging the battery.

During charging, if the battery temperature is not within range, charging is stopped and the TEMP interrupt signal is asserted, to indicate a battery temperature fault. During discharging if the battery temperature is not within range, the TEMP interrupt signal is asserted.

The tolerance should include the resistive divider error, as well as the comparator offset error. Other applications may not require an NTC interface. In that case, the NTC resistor is not populated and this feature is disabled.



Figure 65. NTC Thermistor Interface

COIN CELL BATTERY BACKUP/ CHARGER

The COIN CELL pin provides a connection for a coin cell backup battery or supercap. If the main battery is deeply discharged or removed, and in the absence of a USB/Wall input source, the RTC system and coin cell maintained logic, will switch over to the COIN CELL for backup power. A small capacitor should be placed from the COIN CELL pin to ground under all circumstances.

The coin cell charger circuit will function as a current limited voltage source, resulting in the CC/CV taper characteristic, typically used for rechargeable Lithium-Ion batteries. The coin cell charger is enabled via the COINCHGEN bit. which is enabled by default. The output voltage (V_{COIN}) is programmable through the VCOIN[2:0] bits. The coin cell charger voltage is programmable in the active state, where the charge current is fixed at I_{COINHI}. The coin cell charging will be stopped when V_{PWR} goes below V_{PWRUVF}. Reference Power Path Manager SPI Registers for a more detailed description of the coin cell related bits.

A large capacitor, electrolytic or super cap, can also be used instead of a lithium based coin cell. To avoid discharge by leakage currents from external components or by the 900841, the COINCHGEN bit should always remain set.

Coin cell charge is equipped with a disconnect circuitry that isolates the coin cell from any loads, if V_{COIN} goes below 2.0 V, to prevent the coin cell from being deeply discharged and damaged. This will also cause the ADC reading of the coin cell voltage to yield zero.

POWER PATH MANAGER SPI REGISTERS

POWER PATH MANAGER PLUS LI-ION CHARGER REGISTERS AND BITS DESCRIPTION

Table 78. Charger Interrupt/Mask Registers Structure and Bits Description

Name	Bits	Description			
CHRGINT (ADDR 0xD0 - R - Default Value: 0x00)					
Reserved	0	Reserved			
BATOVP	1	Battery over-voltage Interrupt Signal (V _{BAT} > V _{CHGCV} + V _{OVRVOLT}) x0 = No over-voltage condition x1 = Over-voltage condition			
TEMP	2	Battery over/under-temperature Interrupt Signal Battery temperature is out of valid window) :0 = No over/under-temperature condition :1 = Over/under-temperature condition			
COMP	3	Battery Charge Cycle Completion Interrupt Signal This signal is set any time a charging cycle is complete or the RDSTATE bits change. The RDSTEN bit controls how often this interrupt signal is asserted. If RDSTEN is 0 the following conditions must be true for the COMP interrupt to be set: VBAT > CHRGCV setting (V_{CHRGCV}) & I_{CHG} < CHRGCOMP setting (IEOC) x0 = Charge Cycle Not Complete x1 = Charge Cycle Complete If RDSTEN is 1 Then the following is true for the COMP interrupt x0 = Charge Cycle Not Complete x1 = RDSTATE register bits change			
USBDET	4	USB VBUS Detection Interrupt Signal. This is a dual edge interrupt signal that is set any time a valid USB device (V _{RAWCHG} > V _{RAWCHGDET}) is connected or disconnected x0 = No interrupts pending x1 = USB VBUS is connected/disconnected (refer to the SCHRGINT register)			
BATDET	5	Battery Detection Interrupt Signal This is a dual edge interrupt signal that is set any time a valid battery (VBAT > VTRKL) is connected or disconnected x0 = No interrupts pending x1 = battery is connected/disconnected (refer to the SCHRGINT register)			
DCLMT	6	Charge Input Current Limit Detection Interrupt Signal x0 = No Input Current Limit Detected x1 = Input Current Limit Detected			
USBOVP	7	Charge Input over-voltage Detection Interrupt Signal (V _{RAWCHG} > V _{RAWCHGOVP}) x0 = No Input over-voltage Detected x1 = Input over-voltage Detected			
		MCHRGINT (ADDR 0xD1 - R/W - Default Value: 0x00)			
Reserved	0	Reserved			
MBATOVP	1	Battery over-voltage Interrupt Signal Mask x0 = Unmask x1 = Mask			

Table 78.	Charger	Interrupt/Mask	Registers	Structure	and Bits	Description
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MCOMP 3 Battery Charge Cycle Completion Interrupt Signal Mask x0 = Unmask x1 = Mask MUSBDET 4 USB V _{BUS} Detection Interrupt Signal Mask x0 = Unmask x1 = Mask MBATDET 5 Battery Detection Interrupt Signal Mask x0 = Unmask x1 = Mask MBATDET 5 Battery Detection Interrupt Signal Mask x0 = Unmask x1 = Mask MDCLMT 6 Charge Input Current Limit Detection Interrupt Signal Mask x0 = Unmask x1 = Mask MUSBOVP 7 Charge Input Over-voltage Detection Interrupt Signal Mask x0 = Unmask x1 = Mask
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x1 = Mask MUSBOVP 7 Charge Input Over-voltage Detection Interrupt Signal Mask x0 = Unmask
MUSBOVP 7 Charge Input Over-voltage Detection Interrupt Signal Mask x0 = Unmask
x0 = Unmask
SCHRGINT (ADDR 0xD2 - R - Default Value: 0x00)
Reserved 0 Reserved
SBATOVP 1 Battery Over-voltage Status
x0 = Battery voltage is lower than the limit (< V_{CHGCV} + $V_{OVRVOLT}$)
x1 = Battery voltage is higher than the limit (> V _{CHGCV} + V _{OVRVOLT})
STEMP 2 Battery temperature Status
x0 = Battery temperature is within valid window
x1 = Battery temperature is out of valid window
SCOMP 3 Battery Charge Cycle Completion Status
x0 = Charge cycle not complete (RDSTEN = 0), state not changed (RDSTEN = 1)
x1 = charge cycle complete (RDSTEN = 0), state changed (RDSTEN = 1)
SUSBDET 4 Charger Input Voltage Status Signal
x0 = Charger input voltage not present (V _{RAWCHG} < V _{RAWCHGDET})
x1 = Charger input voltage present (V _{RAWCHG} > V _{RAWCHGDET})
SBATDET 5 Battery Present Status Signal
x0 = Battery not present (VBAT < VTRKL)
x1 = Battery present (VBAT > VTRKL)
SDCLMT 6 Charge Input Current Limit Status
x0 = Charger input current is lower than the limit (< I _{USBLMT}) x1 = Charger input current is higher than the limit (> I _{USBLMT})
SUSBOVP 7 Charger Input Over-voltage Status x0 = Charger input voltage is lower than the limit (< V _{RAWCHGOVP})
x^{0} = Charger input voltage is higher than the limit ($< V_{RAWCHGOVP}$) x1 = Charger input voltage is higher than the limit ($> V_{RAWCHGOVP}$)

Name	Bits		Description			
CHRGSTATE (ADDR 0xD3 - R - Default Value: 0x00)						
RDSTATE	3:0	Charger State Register				
		x00 = Battery Operation	x08 = Pre-charge 2			
		x01 = Standby Mode	x09 = Stop-charge 2			
		x02 = AC Adaptor OVP	x0A = Constant Voltage Mode			
		x03 = Battery Detect	x0B = Stop-Charge 3			
		x04 = Pre-charge 1	x0C = Stop-Charge 4			
		x05 = Charge Suspend	x0D = Stop-Charge 5			
		x06 = Stop-Charge 1	x0E = Forced Stop Charge			
		x07 = Quick Charge	x0F = Reserved			
Reserved	7:4	Reserved				
		CHRGCNTL (ADDR 0xD4	- R/W - Default Value: 0xA1)			
CHRENB	0	Battery Charger Enable Signal, Active low				
0	Ū	x0 = Enable Charger				
		x1 = Disable Charger				
TRICKLE	1	Trickle Charge Enable Signal				
ITTOREE		x0 = Automatic Trickle Charge				
		x1 = Forced Trickle Charge				
WDTEN	2	Watch Dog Timer Enable Signal				
WDIEN	2	x0 = Disable Watchdog Timer				
		x1 = Enable Watchdog Timer				
RDSTEN	3	State Register Update Control				
		x0 = Set the interrupt bit only when a charge cycle has completed.				
		x1 = Set the interrupt bit every time the charger change state.				
USBDETHEN	4	Not Supported, Reserved				
CHR	5	Don't Care for the charger				
		Will be used in combination with OTGB bit to control OTG Host operation				
BATISO	6	Isolate the Battery from the System, FET Control				
	-	x0 = FET(s) allowed to turn on (M_{CHG} and M_{CH}	SBYP)			
		x1 = FET(s) OFF (M_{CHG} and M_{CHGBYP})				
OTGB	7	Don't Care for the charger				
	-	Will be used in combination with CHR bit to cor	trol OTG Host operation			
		CHRGCRNT (ADDR 0xD5	- R/W - Default Value: 0x00)			
CHRGCC	3:0	Constant Current Charge Value I _{CHGCC}	, ,			
		x0 = 200 mA	x8 = 1000 mA			
		x1 = 300 mA	x9 = 1100 mA			
		x2 = 400 mA	xA = 1200 mA			
		x3 = 500 mA	xB = 1300 mA			
		x4 = 600 mA	xC = 1400 mA			
		x5 = 700 mA	xD = 1500 mA			
		x6 = 800 mA	xE = 1600 mA			
		x7 = 900 mA	xF = 1700 mA			

Table 79. Charger Status And Control Registers Structure and Bits Description

	-							
CHRGCOMP	6:4	Charge Complete Current Value						
		x0 = 40 mA	x4 = 200 mA					
		x1 = 80 mA	x5 = 240 mA					
		x2 = 120 mA	x6 = 280 mA					
		x3 = 160 mA	x7 = 320 mA					
Reserved	7	Reserved						
	CHRVOLT (ADDR 0xD6 - R/W - Default Value: 0x07)							
CHRGCV	3:0	Maximum Charge Battery Voltage V _{CHGCV}						
		x0 = 4.025 V	x8 = 4.225 V					
		x1 = 4.050 V	x9 = 4.250 V					
		x2 = 4.075 V	xA = 4.275 V					
		x3 = 4.100 V	xB = 4.300 V					
		x4 = 4.125 V	xC = 4.325 V					
		x5 = 4.150 V	xD = 4.350 V					
		x6 = 4.175 V	xE = 4.375 V					
		x7 = 4.200 V	xF = 4.400 V					
VDSSET	5:4	Not Supported, Reserved						
Reserved	7:6	Reserved						
		CHRGPROT (ADDR 0xD7 - R/W - De	fault Value: 0x3C)					
Reserved	1:0	Reserved						
WDTSET	3:2	Watchdog Timer Settings						
		x0 = 20 sec						
		x1 = 40 sec						
		x2 = 80 sec						
		x3 = 160 sec						
OVRVOLT	5:4	Maximum Charge (Battery) Over-voltage Threshold						
		(Over V _{CHRGCV})						
		x0 = 75 mV						
		x1 = 100 mV						
		x2 = 150 mV						
		x3 = 200 mV						
USBLMT	7:6	Charger Buck Input Over-current Limit						
		x0 = 100 mA						
		x1 = 500 mA						
		x2 = 1000 mA						
		x3 = 1800 mA						
		CHRGTIMER (ADDR 0xDB - R/W - De	fault Value: 0x03)					
CHRGTIMER	3:0	Charger Timer Settings						
		x0 = 1.0 hr	x8 = 9.0 hr					
		x1 = 2.0 hr	x9 = 10 hr					
		x2 = 3.0 hr	xA = 11 hr					
		x3 = 4.0 hr	xB = 12 hr					
		x4 = 5.0 hr	xC = 13 hr					
		x5 = 6.0 hr	xD = 14 hr					
		x6 = 7.0 hr	xE = 15 hr					
		x7 = 8.0 hr	xF = 16 hr					
	_							

Table 79. Charger Status And Control Registers Structure and Bits Description

Table 79. Charger Status And Control Registers Structure and Bits Description

Reserved	7:4	Reserved			
	DISCHRG (ADDR 0xDC - R/W - Default Value: 0x04)				
BATOCPEN	0	Not Supported, Reserved			
BATOVPEN	1	Not Supported, Reserved			
TEMPEN	2	NTC Block Enable Control			
		x0 = NTC Disabled			
		x1 = NTC Enabled			
Reserved	4:3	Reserved			
BATDETEN	5	Not Supported, Reserved			
Reserved	7:6	Reserved			

For a CHRGPROT2 register Description, reference **BATOCP**.

Table 80. Charger Protection Registers for Future Use

Name	Bits	Description						
PROTC	PROTCMD (ADDR 0xD9 - W - Default Value: 0x00)							
*	* 0 Not Supported, Reserved							
*	1	Not Supported, Reserved						
*	2	Not Supported, Reserved						
*	3	Not Supported, Reserved						
*	4	Not Supported, Reserved						
*	5	Not Supported, Reserved						
*	* 6 Not Supported, Reserved							
*	7	Not Supported, Reserved						

Table 80. Charger Protection Registers for Future Use

WDRCLR (ADDR 0xDA - W - Default Value: 0x03)							
*	* 0 Not Supported, Reserved						
*	1	Not Supported, Reserved					
*	2	Not Supported, Reserved					
*	3	Not Supported, Reserved					
*	4	Not Supported, Reserved					
*	5	Not Supported, Reserved					
*	6	Not Supported, Reserved					
*	7	Not Supported, Reserved					

POWER PATH MANAGER PLUS LI-ION CHARGER REGISTERS AND BITS DESCRIPTION

Table 81. FSL Charger Control Register Structure and Bits Description

Name	Bits	Description					
	FSLCHRGCNTL (ADDR 0x1D1 - R/W - Default Value: 0x13)						
CHGBYP	0	M _{CHGBYP} FET Control is Activated x0 = M _{CHGBYP} is not used (Default) x1 = M _{CHGBYP} is used and can be controlled					
COINCHEN	1	Coin cell Charger Enable/Disable x0 = Disable x1 = Enable (Default)					

Table 81. FSL Charger Control Register Structure and Bits Description

VCOIN	4:2	Coin cell Charger Output Voltage Setting
		x0 = 2.5 V
		x1 = 2.7 V
		x2 = 2.8 V
		x3 = 2.9 V
		x4 = 3.0 V (Default)
		x5 = 3.1 V
		x6 = 3.2 V
		x7 = 3.3 V
ITRKL	5	Trickle Charge Current Setting
		x0 = 40 mA (Default)
		x1 = 80 mA
BUCKDIS	6	Enable Control for the Charger Buck:
		x0 = Charger Buck Enabled (default)
		x1 = Charger Buck Disabled
Reserved	7	Reserved

AUDIO

FEATURES

The following is a list of the main features of the Audio Solution:

INTERFACE

- Two Interfaces: one Voice and one Audio
- Includes automatic sample rate detection in slave mode
- Uses high frequency 24/26 MHz clock
- · Supported word length: 16 bit and 32 bit only
- See also ADC/DAC section

ADC/DAC

- Voice ADC/DAC
 - · Sampling frequencies 8/16 kHz
 - ADC
 - •THD+N: -60 dB (0.1%) max
 - Idle channel noise: -87 dBp typ
 - DAC
 - •THD+N: -65 dBA (0.06%) max
 - Idle channel noise: -96 dBA typ
- Stereo ADC/DAC
 - Sampling frequencies
 - •8/11.025/12/16/22.05/24/26/32/44.1/48 kHz
 - ADC
 - •THD+N: -80 dBA (0.01%) max
 - SNR: 90 dBA typ
 - •Dynamic Range: 90 dBA typ
 - DAC
 - •THD+N: -80 dBA (0.01%) max •SNR: 100 dBA typ •Dynamic Range: 96 dBA typ

TRANSMIT PATH

- Transmit Line-up
 - Analog PGA -8.0 dB to +23 dB in 1.0 dB steps
 - Selectable preamplifier 0/12 dB
- Microphone Support
 - Two electret handset microphones with bias
 - One digital handset microphones with clock
 - · Headset microphone with bias and detection
 - Line in for car kit microphone
- Stereo Line Inputs
 - Selectable preamplifier -8/0/8/16 dB
 - · Routing to stereo ADC and to receive path

RECEIVE PATH

- Receive Line-up
 - Digital RX PGA for CDC and STDAC -57 dB to +6.0 dB in 1.0 dB steps
 - Analog RX PGA for line in -57 dB to +6.0 dB in 1.0 dB steps
 - Mixer and Mono Adder
- Stereo Loudspeaker Amplifiers
 - Battery supplied Class D with differential outputs
 - Gain internally set to 12 dB (differential)
 - Output power per channel: 500 mW_{RMS} into 8.0 Ω @ V_BAT=3.4 V, 1.0 W_{RMS} into 4.0 Ω
 - THD @ 500 mW_{RMS}: -50 dB(0.3%) max
 - Input referred noise: 50 mV_{RMS}A max
- · Ear piece amplifier
 - · Battery supplied Class AB with differential output
 - Differential output swing into 32 Ω: 4.0 V_{PP}
 - THD: -60 dB (0.1%) max
 - · Gain internally set to 10 dB (differential)

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- Input referred noise: 8.0 mV_{RMS}A
- · Headset amplifier
 - Class AB with Negative charge pump
 - · Capacitor less headset coupling (referenced to ground)
 - Single ended output swing: 2.0 V_{PP}
 - Output load: 32 Ω
 - Output power per channel: 20 mW_{RMS} typ
 - THD: -60 dBA(0.1%) max
 - Input referred noise: 8.0 mV_{RMS}A

- Gain: 0 dB +/- 0.5 dB
- Headset detection circuit through microphone bias
- Line-Out amplifier
 - · Class A single ended stereo outputs
 - Single ended output swing: 2.0 V_{PP} into 10 k Ω
 - Output load: 10 kΩ min
 - THD: -60 dBA (0.1%) max
 - Input referred noise: 10 mV_{RMS}A
 - Gain: 0 dB +/- 0.5 dB

DIGITAL AUDIO BUS

The digital audio interface consists of two busses; one dedicated to voice operation (PCM1) and the other dedicated to stereo audio (PCM2). Each bus consists of a bit clock, frame sync, receive data, and transmit data signal lines. Both

busses can be configured independently and be active at the same time. The drive strength for the outputs is controlled by the SLOPESEL[1:0] bits



Figure 66. Digital Audio Bus Interface

Table 82. Interface Driver Characteristics

Parameter	Condition	Minimum	Typical	Maximum	Units
I2SVCC Supply Range	Nominal Voltages	1.8		3.3	V
Input High BCL1, FS1, RX1		0.7*I2SVCC		I2SVCC	V
Input Low BCL1, FS1, RX1		0		0.3* I2SVCC	V
Output Low BCL1, FS1, TX1	Output sink 100 μA	0		0.2	V
Output High BCL1, FS1, TX1	Output source 100 µA	I2SVCC -0.2		I2SVCC	V
CPIN Supply	Nominal Voltage		1.8		V
Input High BCL2, FS2, RX2		0.7*CPIN		CPIN	V
Input Low BCL2, FS2, RX2		0		0.3* CPIN	V
Output Low BCL2, FS2, TX2	Output sink 100 μA	0		0.2	V
Output High BCL2, FS2, TX2	Output source 100 µA	CPIN -0.2		CPIN	V
TX1, TX2 Rise and Fall Time	CL=50 pF, IO=1.8 V				

Table 82. Interface Driver Characteristics



Figure 67. Interface Timing Diagram

Parameter	Description	Min	Тур	Max	Unit
t _{CLK}	BCL clock frequency	128	-	2048	kHz
t _{CLKH}	BCL clock high	220	-	-	ns
t _{CLKL}	BCL clock low	220	-	-	ns
t _{SYNCSET}	Sync setup time for short sync (master mode)	200	-	-	ns
	Sync setup time for short sync (slave mode)	20	-	-	ns
t _{SYNCHOLD}	Sync hold time for short sync (master mode)	200	-	-	ns
	Sync hold time for short sync (slave mode)	20	-	-	ns
t _{CLKSYNC}	Delay time from clock to long sync	-	-	15	ns
t _{SYNCTX}	Delay time from long sync to TX (slave mode)	-	-	20	ns
t _{CLKTX}	Delay time from clock edge to TX for short sync	-	-	20	ns
t _{ENDSYNC}	Delay time from BCL to long sync low after LSB	20	-	-	ns
t _{HIZOUT}	Delay time from LSB of TX to Hi-Z state	20	-	-	ns
t _{SETUP}	Set-up time for RX	20	-	-	ns
t _{HOLD}	Hold time for RX	20	-	-	ns

Table 83. Interface Timing Specifications

VOICE CODEC PROTOCOL

The serial interface protocol for the voice codec supports both single word per frame and multiple words per frame time-division multiplexed (TDM) modes, and can be used in either master or slave mode. Master mode is selected by setting the VCEMASTEN bit. In master mode, the voice codec generates the bit clock and frame sync signals, as long as the VCECLKEN bit is set. The data is transmitted and received in a two's complement format, MSB first, and can be clocked on the positive or negative edge of the bit clock. The active edge of the bit clock can be selected by the VCEBCLINV bit. The interface can operate with a short (bit

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length) or a long (word length) frame sync, which is selected by the VCELONGFS bit. The frame sync can also be inverted by setting the VCEFSINV bit.

The interface supports 1, 2, or 4 time slots per frame for Tx and Rx. The active slots used by the voice CODEC are controlled by the VCETXSLOT[1:0] and VCERXSLOT [1:0] bits. The short frame sync occurs 1 bit clock cycle before the data MSB, whereas the long frame sync is aligned with the MSB. For multiple time slots, an optional turn around time delay of 1 bit clock cycle can be added in between the slots by setting the VCETRNARND bit. Outside of the assigned

time slot, the transmit data line is tri-stated. The tri-state enable can be controlled by the VCETSB bit. The word length is controlled by the VCEWORDLEN[2:0] bits and the bit clock frequency is set with the VCECLKFRQ[2:0] bits.

In practice, only certain modes, defined as modes 1-3 and modes 5-6 will be used for the voice codec. The timing diagrams for these modes are given in Figure 68 and Figure 69. Note that where the TX1 line is shown at Hi-Z, the TX1 driver of the voice codec port is tri-stated and the TX1 line itself may be driven by another device in the application.



Figure 68. Voice CODEC Serial Interface Timing Diagram Modes 1-3





STEREO DAC AND ADC PROTOCOL

The serial interface protocol for the audio data uses either the I²S standard, Left-Justified or EIAJ Right-justified formats, and can be used in either master or slave mode. Master mode is selected by setting the STRMASTEN bit. In master mode, the stereo codec generates the bit clock and frame sync signals, as long as the STRCLKEN bit is set. The data is transmitted and received in a two's complement format, MSB first, and can be clocked on the positive or negative edge of the bit clock. The active edge of the bit clock can be selected by the STRBCLINV bit.

The interface operates with a long (word-length) frame sync, which also identifies left vs. right stereo channel words. In I^2S mode, the frame sync leads the data MSB by 1 bit clock

cycle, while in Left-justified mode the frame sync is aligned with the MSB of the data, and in Right-justified mode the frame sync is aligned with the LSB of the data. The mode is selected with the STRMODESEL bits. Note that in all modes, the left channel word is sent in the first half of the frame and the right channel word is sent in the second half of the frame. Supported word lengths are 16 to 32 bits. The word length is set with the STRWORDLEN[2:0] bits and the bit clock frequency is set with the STRCLKFRQ[2:0] bits. The frame sync can also be inverted by setting the STRFSINV bit. The tri-state enable can be controlled by the STRTSB bit.

The timing diagrams for these modes are given in Figure 70.



Figure 70. Stereo CODEC Serial Timing Diagram Examples, Mode 4

VOICE CODEC

The voice CODEC is based on two 14-bit A/D converters and a 14-bit D/A converter with integrated filtering. It supports several different clocking modes. The voice codec is supplied by V_{CORE} for its analog and $V_{COREDIG}$ for its digital sections. The analog is using the REFC bias and the half rail bias at REFA.

A/D CONVERTERS

The A/D portion of the voice CODEC consists of two A/D converters which convert the incoming analog audio signals coming from the microphone amplifiers into 14-bit linear PCM words at a rate of 8.0 kHz or 16 kHz. Following the A/D conversion, the audio signal is digitally band pass filtered. The A/D is enabled by setting the VCEADCEN bit. The sampling rate is set by the VCE8K16K bit.

Parameter	Condition	Minimum	Typical	Maximum	Units
Input Range	0 dBFS ⁽²¹⁾		1.36		V _{PP}
Absolute Gain	1.02 kHz, 0 dB Gain	-1.0		1.0	dB
PSRR	Relative to BP	80	90		dB _P
THD+N	1.02 kHz, 0 dBm0 ⁽²²⁾			-60	dB _P
Idle Channel Noise	0 dB Gain		-78		dBm0 _P
Intermodulation Distortion	SMTPE method 50 Hz/1020 Hz, 4:1 0 dBm0 total input level			-40	dB

Table 84. Voice CODEC A/D Performance Specifications

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Table 84. Voice CODEC A/D Performance Specifications

Crosstalk A/D to D/A	A/D 1.02 kHz, 0 dBm0,			-60	dB
	D/A 1.02 kHz, 0 dBm0 referred				
Enable Time	Including filters		3.0		ms
FILTERING		•		•	

Pass Band	0.4535*FS			Hz
Pass Band Ripple	-0.5		0.5	dB
Stop Band			0.56*FS	Hz
Stop Band Attenuation	60			dB
Group Delay		1.7/FS		S

Notes

21. Equivalent to +3.0 dBm0

Equivalent to 340 mVrms 22.

D/A CONVERTER

The D/A portion of the voice CODEC converts 14-bit linear PCM words entering at a rate of 8.0 kHz and 16 kHz into analog audio signals. Prior to this D/A conversion, the audio signal is digitally band-pass filtered. An optional high-pass filter can also be enabled by setting the VCEAUDHPF bit. The D/A is enabled by setting the PSCNTRX bit.

Parameter	Condition	Minimum	Typical	Maximum	Units
Output Range	0 dBFS ⁽²³⁾		2.0		V _{PP}
Absolute Gain	1.02 kHz, 0 dB Gain	-1.0		1.0	dB
PSRR	Relative to BP	80	90		dBA
THD+N	1.02 kHz, 0 dBm0 ⁽²⁴⁾			-65	dBA
Idle Channel Noise	0 dB Gain		-90		dBm0A
Intermodulation Distortion	SMTPE method 50 Hz/1020 Hz, 4:1 0 dBm0 total input level			-40	dB
Crosstalk A/D to D/A	A/D 1.02 kHz, 0dBm0,			-60	dB
	D/A 1.02 kHz, 0dBm0 referred				
Enable Time	Including filters		3.0		ms

FILTERING

Pass Band	0.4535*FS			Hz
Pass Band Ripple	-0.5		0.5	dB
Stop Band			0.5465*FS	Hz
Stop Band Attenuation	60			dB
Group Delay		2.3/FS		S

Notes

23. Equivalent to +3.0 dBm0

24. Equivalent to 500 mVrms

STEREO CODEC

The stereo CODEC is based on two 16-bit A/D converters and two 24-bit D/A converters. It supports several different clocking modes. The stereo DAC and ADC are supplied by VCORE for its analog and VCOREDIG for its digital sections. The voice ADC and the stereo ADC use the same converter cores, so both cannot be used at the same time. The analog circuits use the REFD bias and the half rail bias at REFA. The stereo converters incorporate a PLL to generate the proper clocks. The PLL does not require any external filtering.

Both the stereo ADC and stereo DAC will always operate at the same sample frequency using the same digital interface bus. The stereo DAC can be operated in parallel to the voice DAC, and their sampling rates are independent. The stereo ADC and DAC sampling rate is set by the STRSR[3:0] bits or may optionally be automatically detected in slave mode by setting the STRSRDET bit.

The audio CODEC supports the sampling frequencies of 8.0, 11.025, 12, 16, 22.05, 24, 26, 32, 44.1, and 48 kHz

Table 86. Stereo DAC Main Performance Specifications

D/A CONVERTERS

The stereo DAC is based on a 24-bit linear left and right channel D/A converter with integrated filtering. The stereo DAC is enabled by setting the PSCNTDA bit.

Parameter	Condition	Minimum	Typical	Maximum	Units
Output Range	0 dBFS ⁽²⁵⁾		2		V _{PP}
Absolute Gain	1.02 kHz, 0 dB gain	-0.5		+0.5	dB
PSRR	Relative to BP	90			dBA
THD+N	1.02 kHz, 0 dBm0 ⁽²⁶⁾		-85	-80	dBA
Dynamic Range	1.02 kHz	92	96		dBA
Signal to Noise Ratio	1.02 kHz	94	100		dBA
Intermodulation Distortion	SMTPE method 50 Hz/1020 Hz, 4:1 0 dBm0 total input level			-75	dB
Channel Separation				-75	dB
Enable Time	Including filters		3		ms

FILTERING

Pass Band		0.4535*FS		Hz
Pass Band Ripple		-0.5	0.5	dB
Stop Band			0.5465*FS	Hz
Stop Band Attenuation		85		dB
Phase Linearity	In pass band	-15	+15	0

Notes

25. Equivalent to +3.0 dBm0

26. Equivalent to 500 mVrms

A/D CONVERTER

The stereo ADC is based on a 16-bit linear left and right channel A/D converter with integrated filtering. The stereo

ADC is enabled by setting the STRADCEN bit. If the VCEADCEN bit is also set, it will take priority, so the ADC converters will be used in voice mode.

Table 1. Stereo	ADC Main	Performance	Specifications
Table 1. Slelev		Ferrornance	opecifications

Parameter	Condition	Minimum	Typical	Maximum	Units
Input Range	0 dBFS ⁽²⁷⁾		2		V _{PP}
Absolute Gain	1.02 kHz, 0 dB gain	-0.5		+0.5	dB
PSRR	Relative to BP	80	90		dBA
THD+N	1.02 kHz, 0 dBm0 ⁽²⁸⁾		-83		dBA
Dynamic Range	1.02 kHz		90		dBA
Signal to Noise Ratio	1.02 kHz		90		dBA
Intermodulation Distortion	SMTPE method 50 Hz/1020 Hz, 4:1 0 dBm0 total input level			-75	dB
Channel Separation				-75	dB
Enable Time	Including filters		3		ms

Table 1. Stereo ADC Main Performance Specifications

FILTERING				
Pass Band		0.4535*FS		Hz
Pass Band Ripple		-0.5	0.5	dB
Stop Band			0.56*FS	Hz
Stop Band Attenuation		60		dB
Phase Linearity	In pass band	-15	+15	0
Notes				
27. Equivalent to +3.0 dBm0				
28. Equivalent to 500 mVrms				

AUDIO TRANSMIT SECTION

Shown in Figure 71 is a schematic representation of the audio transmit section. The actual design implementation may differ.



Figure 71. Audio Transmit Section

MICROPHONE BIAS

Two microphone bias circuits are provided. The microphone supplies can be used to supply digital microphones and electret microphones. In the latter case, an

external sensitivity setting resistor needs to be added. The bias is enabled by setting respectively the MIC1BIAS and MIC2BIAS bit.

Table 87. Microphone Bias Parametric Specifications

Parameter	Condition	Minimum	Typical	Maximum	Units
Microphone Bias Output Voltage	C _{LOAD} <100 pF	2.00		2.20	V
Microphone Bias Current			200		μA
Output Current Capability	Source only	1000			μA
PSRR	Relative to BP, 217 Hz	100			dB
Output Noise				2.5	μVrmsp
Microphone Detect Voltage	MC2BEN=0	0.4			V

Microphone Detect Current Low	MC2BEN=1		50	μA
Microphone Detect Current High	MC2BEN=1 (29)	500	650	μA

Notes

29. For proper detection it is advised to use a microphone bias resistor not exceeding 2.7 k Ω

In case the supply voltage level is thought to be insufficient for digital microphones, the supply at MC1B can be raised from 2.1 to 2.7 V by setting the MIC1BIASMOD bit. However in this case, the output supply is no longer low noise. Raising the supply at MC1B has no effect on the output voltage at MC2B.

The microphone bias MC2B has an integrated accessory detection circuit for headphones, headset/microphone presence and for a button operation placed in parallel to the microphone. In order to operate properly, the headset must connect the microphone ring of the jack to the ground jack, in case no microphone is present. Accessory attach/detach events and headset button pushes are all debounced by 30 ms.

The accessory detect circuit can be enabled independently from the microphone or audio bias by setting the HSDETEN bit. When the audio bias and mic bias are both off, only the connection or disconnection of an accessory can be detected, not the specific type of accessory. In this mode, it is assumed that the accessory is a stereo headphone and the HPDET interrupt, which is sensitive to both edges, reflects attach and detach events. The HPDET interrupt can be masked by setting the MHPDET mask bit. Masking the interrupt does not prevent the interrupt from appearing in the interrupt registers, but prevents the PMICINT pin from asserting a hardware interrupt.

When the audio bias and MIC2 bias are enabled, the accessory detect circuit can distinguish between a stereo headphone (low-impedance), a headset microphone (medium-impedance), a headset button push (low-impedance) and connect/disconnect events. For headset button pushes, the circuit also distinguishes between momentary button pushes of less than 2 seconds duration and long button pushes of more than 2 seconds duration.

With audio bias and MIC2 bias enabled, connecting or disconnecting a headphone will assert the HPDET interrupt. Connecting a headset will assert the HSDET interrupt. Pushing the headset button and releasing it within 2 seconds will assert the SWMPINT (switch momentary push) interrupt and pushing the button and releasing it after more than 2 seconds will assert the SWLPINT (switch long push) interrupt. Each of these interrupts also has a corresponding mask bit. Note that if a headphone was detected and was later determined to be a headset, the HPDET interrupt will be cleared and the HSDET interrupt will be set. This situation can occur in two ways: (1) if the audio bias and MIC2 bias were off when the headset was connected, it will be detected as a headphone. If the biases are then turned on, the circuit will recognize that the accessory is actually a headset and will update the interrupts accordingly; (2) if the headset button

was being pushed while the headset was being plugged into the jack, it will appear to be a low-impedance accessory and will be detected as a headphone. When the button is finally released, the circuit will recognize that the accessory is actually a headset and will update the interrupts accordingly.

TRANSMIT INPUTS

The transmit inputs accept signals from a low level signal electret microphone as well as high signal level MEMS based microphones. In addition, it allows connecting a digital microphone. Finally, it allows on chip routing from the stereo line-in inputs.

The microphone input amplifiers are enabled by setting the PSCNTMIC1 and PSCNTMIC2 bits. The right channel input is selectable between a microphone connected to MC2IN and the line input RXINR by setting the RAMPSEL bit. The left channel input is selectable between a microphone connected to MC1IN and the line input RXINL by setting the LAMPSEL bit. Note that the input signals must be AC coupled. When in voice mode, (PCM1) MC1IN or RXINL is sent to the left and right channels by default, depending on the PSCNTMIC1 and LAMPSEL bits. In order to send MC2IN or RXINR to the left and right channels when in voice mode, the MC1IN amplifier must be disabled by setting PSCNTMIC1IN=0.

When in stereo mode, the audio signal from MC1IN, RXINL, or digital microphone on the MC1IN pin, is sent exclusively to the left channel of PCM2 data. When in stereo mode, the audio signal from MC2IN, RXINR, or digital microphone in MC2IN pin, is sent exclusively to the right channel of PCM2 data, as shown in <u>Figure 71</u>. When in voice mode, the active transmit input signal is sent to the left and right channels, except for the digital microphone on MC1IN, which is not supported in voice mode.

The MC2IN input is amplified by the ATXR pre-amplifier with course gain setting controlled with MIC2PRE[1:0]. The input amplifiers can also be muted by setting the RAMPMUT bit. The selected signal can be routed to the receive section and it can be converted by the ADC right channel. The ADC gain can be adjusted with the VCEPGATX[4:0] bits. Before transmitting to the digital serial interface, the volume of the digitized signal can be controlled with a fine gain setting through RAMPVL[5:0].

The MC1IN input is amplified by the ATXL pre-amplifier with course gain setting controlled with MIC1PRE[1:0]. The input amplifiers can also be muted by setting the LAMPMUT bit. The selected signal can be routed to the receive section and it can be converted by the ADC left channel. The ADC gain can be adjusted with the VCEPGATX[4:0] bits. Before transmitting to the digital bus interface, the volume of the converted signal can be controlled with a fine gain setting through LAMPVL[5:0].

Table 88.	Transmit Am	plifiers Performa	ance Specifications
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Parameter	Condition	Minimum	Typical	Maximum	Units
Gain Accuracy		-0.5		+0.5	dB
Amplifier Bias Current			200		μΑ
Crosstalk Between Inputs				-60	dB
PSRR	Relative to BP, 217 Hz	90			dB
THD	MC1IN, 1.02 kHz, 10 mVrms			-60	dB
Input Noise	Referred to REFA			1.5	μVrmsp

Digital microphones can be connected to the MC1IN and MC2IN inputs. The digital microphone is supplied from the microphone bias and clocked through the microphone clocking output, MCCLK. The resulting Pulse Density Modulated signal from the digital microphone is directly routed to the filter section of the ADC.

If a single digital microphone is used in the application, it should be connected to MC2IN, and PCM1 voice mode should be used in order to get the same data in the left and right channels. If PCM2 stereo mode is used, the digital microphone on the MC2IN signal is sent on the right channel of PCM1 data only. Voice mode is not supported for the digital microphone connected to the MC1IN pin.

If two digital microphones (dual dmics) are used in the application, PCM2 stereo mode must be used. In dual digital microphone mode, DMIC1 (MC1IN) data and DMIC2 (MC2IN) data is sent to the left and right channels of PCM2, respectively.

The MCCLK signal is enabled by setting the DMICCLKEN bit, and its frequency is selectable between 1.0 MHz and

2.0 MHz by setting the DMICCLK[0] bit. The exact clock frequency will vary as a function of the ADC sample rate. The MC2IN input is configured for digital microphone use by setting the MUXIN bit. Both the clock and the data stream are referenced with respect to MC2B. The gain of the digital microphone data to the digital serial interface can be controlled with the DMICVOL[5:0] bits. The signal from the digital microphone can be routed into the receive voice DAC path as a side tone, by clearing the DMICVUTFB bit, and its gain can be controlled with the DMICVLFB[5:0] bits. The digital micr data to the digital serial interface can be muted with the DMICMUT bit and the digital micr data to the voice DAC can be muted with the DMICMUTEFB bit.

The data routed to the PCM1 digital serial interface is selectable between the digital mic, and the right channel ADC by the PCM1RCH bit. Similarly, the data routed to the PCM2 digital serial interface is selectable between the digital mic and the left channel ADC, by the PCM2LCH bit, and is selectable between the digital mic and the right channel ADC by the PCM2RCH bit

Gain and Volume Setting for Bits RAMPVL[5:0], LAMPVL[5:0]	Gain and Volume Setting DMICVOL[5:0]	Gain	Units	Gain and Volume Setting for Bits MIC1PRE[1:0], MIC2PRE[1:0] *	Gain Mic / RXin	Units
000000	111111	-57	dB	00	0 / 0	dB
000001	111110	-56	dB	01	12 / 8	dB
				10	20 / 18	dB
111001 (default)	000110	0	dB	11	28 / 26	dB
				* These gain settings are obtained by		
111110	000001	+5	dB	0/+12 dB, 0/+8/+18 dB and -8/0/+8/+16 dB. The 0 dB t +7.0 dB settings in the ADC are not used		
111111	000000	+6	dB			

Table 89. Transmit Gain Control

AUDIO RECEIVE SECTION

The block diagram of the audio receive section is shown in Figure 72.



Figure 72. Audio Receive Section Diagram

GAIN CONTROL, MONO ADDER AND ROUTER

The gain of the digital audio in both left and right channels is controlled in the programmable digital gain amplifiers. To facilitate programming, independent settings are available for the voice call and stereo audio use cases through VDACVL[5:0], ADACVLR[5:0] and ADACVLL[5:0] respectively. The gain of the feedback path of the digital microphone can be set through DMICVLFB[5:0]. The gain of the analog audio from RXINR and RXINL or pre-amplified microphone inputs is controlled through the RAMPVLFB[5:0] and LAMPVLFB[5:0] bits. All the gain settings have the same granularity and range.

Table 90. Receive Gain Control

Gain and Volume Setting Bits xxx[5:0]	Gain	Units
000000	-57	dB
000001	-56	dB
111001 (default)	0	dB

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 Table 90.
 Receive Gain Control

111110	+5	dB
111111	+6	dB

The signal paths can be muted through the VMUTL, AMUTL, AMUTR bits. The muting of analog inputs is described in the transmit section.

The analog signal from the stereo DAC, the voice DAC, and the transmit section can be mixed; the left channels and voice DAC on the left channel mixer through MXLAUDL, MXLLINL, and MXLMNDAC. The right channels and voice DAC on the right channel mixer through MXRAUDR, MXRLINR, and MXRMNDAC. The resulting mixed analog signal is routed to the different output amplifiers.

EAR PIECE SPEAKER AMPLIFIER ASP

The left channel audio can be routed to the Asp amplifier, which drives the ear piece of the application in a bridge tied load configuration. The amplifier is supplied from the battery
power which avoids the use of an intermediate regulator stage. Its output is referenced with respect to REFA. The feedback network is fully integrated. The amplifier is enabled

by setting the PSCNTSPKR bit, with the output signal muted by setting the MUTASP bit.

Parameter	Condition	Minimum	Typical	Maximum	Units
Differential Output Swing		4.0			Vpp
Gain	SPP-SPM	9.5	10	10.5	dB
Amplifier Bias Current			1.75		mA
THD	Output 4.0 V _{PP}			-60	dB
PSRR	Relative to BP	90			dBA
Noise	Input referred			8.0	μVrmsA
Startup Time			100		μS
Isolation	Not routed	80			dB
Load-impedance	Resistance	25.6	32		Ω
	Inductance			1.0	mH
	Capacitance			100	pF

Table 91. Amplifier Asp Performance Specifications

LOUDSPEAKER AMPLIFIERS ALSPR AND ALSPL

The Class-D loudspeaker amplifiers Alspr and Alspl drive a set of low ohmic loudspeakers for speakerphone, ringing and music playback modes. The amplifiers are powered directly by the main battery and include a feedback system in order to reach a high PSRR performance. The amplifiers run at a frequency around 3.0 MHz. The outputs are half rail referenced. The feedback networks of the Alsp amplifiers are fully integrated. The right channel amplifier is enabled by setting the PSCNTSPR bit, the left channel amplifier by the PSCNTSPL bit. When enabled, the right and left channel audio paths are routed to their respective amplifiers. The output signal can be muted by setting the MUTSPKR and MUTSPKL bits.

Parameter	Condition	Minimum	Typical	Maximum	Units
Differential Output Power	BP = 3.4 V in 8.0 Ω	500	-	-	mW
	BP = 3.6 V in 4.0 Ω	1.0	-	-	W
Gain	LSPxP-LSPxM	10.6	-	11.6	dB
THD	500 mW			-50	dB
PSRR	Relative to BP	75			dBA
Noise	Input referred			50	μVrmsA
Startup Time			1.0		ms
Isolation	Not routed	80			dB
Load-impedance		3.2	8.0		Ω

HEADSET AMPLIFIERS AHSR AND AHSL

The Ahsr and Ahsl amplifiers are dedicated for driving a stereo headset, the Ahsr for the right channel and Ahsl for the left channel. The feedback networks are fully integrated. The amplifiers are enabled by setting the PSCNTLHPR and

PSCNTLHPL bits respectively. When enabled, the right channel audio is routed to the HSR output and the left channel audio to the HSL output. The output signal can be muted by setting the MUTHPR and MUTHPL bits.

Parameter	Condition ⁽³⁰⁾	Minimum	Typical	Maximum	Units
Single Ended Output Swing	In 32 Ω	2.0	-	-	V _{PP}
Gain		-0.5	0	0.5	dB

Table 93.	Amplifiers	Ahsr and	Ahsl	Performance	Specifications
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Amplifier Bias Current	Per Channel from CPIN	-	750	-	μA
THD	Output 2.0 V _{PP} , 32Ω	-		-60	dB
PSRR	Relative to BP	90	-	-	dBA
Noise	Input referred	-	-	8.0	μVrmsA
Startup Time	Including charge pump	-	1.0	-	ms
Isolation	Not routed	80	-	-	dB
Channel Separation		-	-	-75	dB
Load-impedance		12.8	32	-	Ω

Notes

30. Applies for Ahsr and Ahsl activated individually and simultaneously with CPIN=1.8 V

The outputs of the amplifiers are driven relative to true ground, which avoids using coupling capacitors for connecting a headset. The amplifiers are supplied from CPIN = 1.8 V while a single stage negative charge pump provides the CPOUT = -1.8 V supply rail. The charge pump is enabled when one of the headset amplifiers get enabled. The charge pump input pin (CPIN) can be connect to the internal VDDQ buck regulator in the application. In that case, VDDQ must be enabled prior to the headset amplifier, to ensure proper headset operation.

STEREO LINE OUT

The audio can be routed to the line-outs RXOUTR and RXOUTL. These outputs can be used for instance to route the audio to an accessory connected to a bottom connector, such as for a docking station with playback speakers. These outputs are enabled by setting the PCCNTLOR and PSCNTLOL bits.

Table 94. Line Out Performance Specifications

Parameter	Condition	Minimum	Typical	Maximum	Units
Single Ended Output Swing		2.0	-	-	V _{PP}
Gain		-0.5	0	0.5	dB
Amplifier Bias Current	Per channel	-	200	-	μΑ
THD	Output 2.0 V _{PP}	-	-	-60	dB
PSRR	Relative to BP	90	-		dBA
Noise	Input referred	-	-	10	μVrmsA
Startup Time		-	100	-	us
Isolation	Not routed	80	-	-	dB
Channel Separation		-	-	-75	dB
Load Impedance		10	-	-	kΩ

HEADPHONE/HEADSET DETECTION

The accessory detection of a headset, headphone or a push to talk button switch is done through the MIC2BIAS circuit (MC2B and MC2IN pins) in the 900841. A basic detection that there is an accessory attached to the system is

enabled even when MIC2BIAS is off (MIC2BIAS=0) in order to save system power. After a first detection is made, the firmware must enable MIC2BIAS in order to detect what kind of accessory or to detect between long or short button switches.



Figure 73. Connection of Audio Accessory Plug to SC900841 Pins

Figure 73 show the connection of an audio accessory plug to the 900841 audio pins.

There are four audio interrupts to distinguish between a headphone, a headset (cellular headset with a microphone), and push-to-talk (PPT) button switch press:

HPDET

- If MIC2BIAS = 0 : Accessory Attached
- If MIC2BIAS = 1 : Headphone Inserted/Removed
- Detect a 0.4 V threshold in MC2IN when a headphone is inserted / removed
 - Interrupt mask bit: MHPDET (1=masked, 0=unmasked)

HSDET = Headset Inserted/Removed

- Detect current drawing in MC2B pin when headset is inserted/removed
- Interrupt mask bit: MHSDET (1=masked, 0=unmasked)

SWMPINT = Momentary Button Press

- Detect a short button press of < 2.0 s in headset button.
- · Interrupt is set after the button is released
- Interrupt mask bit: MSWMPINT (1=masked, 0=unmasked)

SWLPINT = Long Button Press

- Detect a long button press of > 2.0 s in headset button
- Interrupt is set after the button is released
- Interrupt mask bit: MSWLPINT (1=masked, 0=unmasked)

These four interrupts are Level 2 interrupts that when set will trigger the Level 1 AUX interrupt (MAUX interrupt mask). All the above interrupts must be unmasked (by writing '0' to its respective interrupt mask) to be enabled. A SPI read will clear these interrupts and allow the detection of a following interrupt.

It is important to point out that HSDET and HPDET interrupts are used for insertion and removal of an audio accessory. For example, if a headset is inserted to the audio jack, a HPDET interrupt will be set and that will trigger the AUX interrupt. After the firmware does a SPI read both HPDET and AUX these bits will be automatically cleared ('0') by the PMIC. If the headphone is removed from the jack, HPDET will be set again to indicate that the headphone was removed.

The sequence of events below explains the flowchart in <u>Figure 74</u> should be followed by software to process and to enable these audio interrupts.

HSDETEN and AUDIOFF spi bits must be both set to '1' to enable the audio accessory detection circuit. All external jack inputs are debounced by 30 Lms.

FUNCTIONAL DEVICE OPERATION AUDIO

HSDET EN= 1 AUDIOOFF=1

- The insertion of an accessory in the headphone or headset jack when MIC2BIAS=0 will initially generate an HPDET interrupt independently if there is a headset or a headphone in the jack. The first HPDET interrupt means that an accessory was attached to the jack.
- The software must clear the first HPDET interrupt, and setup MIC2BIAS = 1 and AUDIOFF=0, according to the flowchart to be able to detect

between HSDET, HPDET, SWMPINT, and SWLPINT

 Once MIC2BIAS=1, the PMIC is able to detect all four accessory interrupts, depending on the load, voltage, or button press time. After the MIC2BIAS is enabled, a second occurrence of HPDET or HSDET means that the accessory was removed. These two interrupts are sensitive to both edges with a jack insertion or jack removal.





AUDIO REGISTERS AND BIT DESCRIPTIONS

Table 95. Audio Registers

Name	Bits	Description					
	AUD1 (ADDR 0x180 - R/W - Default Value: 0x80)						
VCEWORDLEN	2:0	Number of time slots per frame x0 = 1 Time slot x5 = 2 Time slots x6 = 4 Time slots					
VCELONGFS	3	x1-x4, x7 = Reserved Length of frame sync x0 = Bit long x1 = Word long					

VCEFSJST	4	Selects left or right justified frame for Mode 3
VCEBCLINV	5	Data clocking
		x0 = On falling edge BCL1
		x1 = On rising edge BCL1
VCEMASTEN	6	Bus operation
		x0 = Slave mode
		x1 = Master mode
VCETSB	7	State of TX1
		x0 = Tri-stated
		x1 = Active
	A	UD2 (ADDR 0x181 - R/W - Default Value: 0x00)
VCERESET	0	Voice ADC / DAC digital filters reset
		x0 = Self cleared
		x1 = Reset
VCE8K16K	1	Sample rate voice ADC/DAC
		x0 = 8.0 kHz
		x1 = 16 kHz
VCETXSLOT	3:2	Slot assignment voice data
		x0 = Not active in any slot
		x1 = Assigned to slot 0
		x2 = Assigned to slot 1
		x3 = Assigned to slot 2
VCECLKFRQ	6:4	Selects clock speed BCL1
		x0 = 2.048 MHz
		x1 = 256 kHz
		x2 = 128 kHz
		x3-x7 = Reserved
VCETRNARND	7	Extra clock cycle inserted between slots
		x0 = No extra clock cycle
		x1 = Extra clock cycle

AUD3 (ADDR 0x182 - R/W - Default Value: 0x80)

STRWORDLEN	2:0	Number of time slots per frame			
		x0 = Reserved	x4 = 2 Time slots 24 bit significant		
		x1 = 2 Time slots 16 bit significant	x5 = 2 Time slots 28 bit significant		
		x2 = 2 Time slots 18 bit significant	x6 = 2 Time slots 32 bit significant		
		x3 = 2 Time slots 20 bit significant	x7 = Reserved		
RSVD	3	Reserved (not used)			
RSVD	4	Reserved (not used)			
STRBCLINV	5	Data clocking			
		x0 = On falling edge BCL2			
		x1 = On rising edge BCL2			
STRMASTEN	6	Bus operation			
		x0 = Slave mode			
		x1 = Master mode			
STRTSB	7	State of TX2			
		x0 = Tri-stated			
		x1 = Active			

CTD CD		Sample rate stores ADC/DAC	יטו			
STRSR	3:0	Sample rate stereo ADC/DAC				
		x0 = 8.0 kHz	x6 = 26 kHz			
		x1 = 11.025 kHz	x7 = 32 kHz			
		x2 = 12 kHz	x8 = 44.1 kHz			
		x3 = 16 kHz	x9 = 48 kHz			
		x4 = 22.05 kHz	xA-xF = Reserved			
		x5 = 24 kHz				
STRCLKFRQ	6:4	Selects clock speed BCL2				
		x0 = 32 times FS2				
		x1 = 64 times FS2				
		x2 = 128 times FS2				
		x3-x7 = Reserved				
STRSRDET	7	Sample rate detection				
		x0 = Not enabled				
		x1 = Enabled				
	A	UD5 (ADDR 0x184 - R/W - Default Value: 0x	00)			
VCEDLM	0	Voice channel digital loop back mode				
		x0 = normal operation				
		x1 = digital loop back enabled				
VCEFSINV	1	Frame sync FS1 polarity inversion				
		x0 = Not inverted				
		x1 = Inverted				
VCECLKEN	2	Control FS and BITCLK generation in Master mode				
		x0 = clk gen disabled				
		x1 = clk gen enabled				
VCEAUDHPF	3	Voice DAC high pass filter				
		x0 = Disabled				
		x1 = Enabled				
VCERXSLOT	5:4	Selects which slot will be used to receive P	CM data			
Reserved	7:6	Reserved				
	A	UD6 (ADDR 0x185 - R/W - Default Value: 0x0				
STRMODESEL	1:0	PCM2 mode select				
		$x0 = I^2S$ mode				
		x1 = Left-justified				
		x2 = Right-justified				
		x3 = Reserved (defaults to right-justified)				
VCE2PCM2	2	Send voice data to PCM2 when '1'				
STRMONO	3	Digitally mix ADC input to both left and right channels				
Reserved	4	Reserved				
STRFSINV	5	Frame sync FS2 polarity inversion				
		x0 = Not inverted				
	1	vet — Inventeral				

x1 = Inverted

AUD4 (ADDR 0x183 - R/W - Default Value: 0x00)

STRCLKEN	6	Enable fsync and bitclk generation in master mode
		x0 = clk gen disabled
		x1 = clk gen enabled
STRRESET	7	Audio ADC / DAC digital filters reset
		x0 = Self cleared
		x1 = Reset
	AU	D7 (ADDR 0x186 - R/W - Default Value: 0x00)
DMICVOL	5:0	Digital microphone volume
MIC1BIASMOD	6	Microphone bias MC1B operating mode
		x0 = Electret microphone supply mode
		x1 = Digital microphone supply mode
Reserved	7	Reserved
	AU	D8 (ADDR 0x187 - R/W - Default Value: 0x80)
DMICVOLFB	5:0	Digital microphone volume
DMICMUTEFB	6	Digital microphone side tone path mute
		x0 = Not muted
		x1 = Muted
AUDIOOFF	7	Audio bias references on/off control
		x0 = references enabled
		x1 = references disabled
	AU	D9 (ADDR 0x188 - R/W - Default Value: 0x00)
DMICCLK	1:0	Digital microphone clock speed
		x0 = Around 1.0 MHz
		x1 = Around 2.0 MHz
		x2, x3 = Reserved
PCM1RCH	2	Voice interface TX1 right channel selector
		x0 = ADC right
		x1 = Digital microphone input
RSVD	3	Reserved (not used)
MIC2BIAS	4	Microphone bias MC2B enable
		x0 = Not enabled
		x1 = Enabled
DMICMUTE	5	Digital microphone mute
		x0 = Not muted
		x1 = Muted
MIC1BIAS	6	Microphone bias MC1B enable
		x0 = Not enabled
		x1 = Enabled
DMICCLKEN	7	Clock for digital microphone
		x0 = Disabled
		x1 = Enabled

AUD10 (ADDR 0x189 - R/W - Default Value: 0x00)

		· · · · ·
LAMPVL	5:0	Left transmit amplifier volume control
LAMPMUT	6	Left transmit amplifier signal mute
		x0 = Not muted
		x1 = Muted
LAMPSEL	7	Left transmit amplifier input selection
		x0 = MC1IN
		x1 = RXINL
	AU	JD11 (ADDR 0x18A - R/W - Default Value: 0x00)
RAMPVL	5:0	Right transmit amplifier volume control
RAMPMUT	6	Right transmit amplifier signal mute
		x0 = Not muted
		x1 = Muted
RAMPSEL	7	Right transmit amplifier input selection
		x0 = MC2IN
		x1 = RXINR
	AU	JD12 (ADDR 0x18B - R/W - Default Value: 0x00)
MIC2PRE	1:0	Preamplifier gain MC2IN input
MIC1PRE	3:2	Preamplifier gain MC1IN input
HSDETEN	4	Headset or headphone detect through MC2B detect circuit
		x0 = Disabled
		x1 = Enabled
MUXIN	5	MC1IN Mode select
		x0 = Analog input
		x1 = Digital input
PCM2RCH	6	Audio interface TX2 right channel selector
		x0 = ADC right
		x1 = Digital microphone input
PCM2LCH	7	Audio interface TX2 left channel selector
		x0 = ADC left
1	1	

AUD13 (ADDR 0x18C - R/W - Default Value: 0x00)

x1 = Digital microphone input

VCEPGATX	4:0	Volume control of voice ADC		
		x0 = -8.0 dB	x8 = 0 dB	
		x1 = -7.0 dB	x9 = 1.0 dB	
		x2 = -6.0 dB	xA = 2.0 dB	
		x3 = -5.0 dB	xB = 3.0 dB	
		x4 = -4.0 dB	xC = 4.0 dB	
		x5 = -3.0 dB	xD = 5.0 dB	
		x6= -2.0 dB	xE = 6.0 dB	
		x7= -1.0 dB	xF = 7.0 dB	
			x10 - x1F = Reserved.	
VCECLK	7:5	Selects voice clkin frequency, default is 26 MHz		

AUD14	ADDR 0x18D - R	/W - Default Value: 0x00)

	AU	D14 (ADDR 0x18D - R/W - Default Value: 0x00)	
STRADC16PG	2:0	Audio ADC PGA steps	
STRADC16PGEN	STRADC16PGEN 3 Enable ADC PGA		
STRCLK	6:4	Selects stereo clkin frequency, default is 26 MHz	
Reserved	7	Reserved	
	AU	D15 (ADDR 0x18E - R/W - Default Value: 0x00)	
VDACVL	5:0	Voice DAC volume control	
Reserved	6	Reserved	
VMUT	7	Voice DAC signal mute	
		x0 = Not muted	
		x1 = Muted	
	AU	D16 (ADDR 0x18F - R/W - Default Value: 0x00)	
ADACVLL	5:0	Audio DAC left volume control	
Reserved	6	Reserved	
AMUTL	7	Audio DAC left signal mute	
		x0 = Not muted	
		x1 = Muted	
	AU	D17 (ADDR 0x190 - R/W - Default Value: 0x00)	
ADACVLR	5:0	Audio DAC right volume control	
Reserved	6	Reserved	
AMUTR	7	Audio DAC Right signal mute	
		x0 = Not muted	
		x1 = Muted	
	AU	D18 (ADDR 0x191 - R/W - Default Value: 0x00)	
MUTASP	0	Ear piece amplifier signal mute	
		x0 = Not muted	
		x1 = Muted	
MUTHPR	1	Headset amplifier right mute	
		x0 = Not muted	
		x1 = Muted	
MUTHPL	2	Headset amplifier left mute	
		x0 = Not muted	
		x1 = Muted	
Reserved	3	Reserved	
MXLAUDL	4	Audio DAC left signal mixing	
		x0 = Not mixed on left mixer	
		x1 = Mixed on left mixer	
MXLMNDAC	MXLMNDAC 5 Voice DAC signal mixing		
	x0 = Not mixed on left mixer x1 = Mixed on left mixer		
	-		
Reserved	6	Reserved	
MXLLINL	7	Line in RXINL signal mixing x0 = Not mixed on left mixer	
		$x_0 = Not mixed on left mixer x_1 = Mixed on left mixer$	

AUD19 (ADDR 0x192 - R/W - Default Value: 0x00)

	AL	UD19 (ADDR 0x192 - R/W - Default Value: 0x00)
Reserved	0	Ear piece amplifier signal mute
		x0 = Not muted
		x1 = Muted
MUTSPKRR	1	Loudspeaker amplifier right mute
		x0 = Not muted
		x1 = Muted
MUTSPKRL	2	Loudspeaker amplifier left mute
		x0 = Not muted
		x1 = Muted
MXRAUDR	3	Audio DAC right signal mixing
		x0 = Not mixed on right mixer
		x1 = Mixed on right mixer
Reserved	4	Reserved
MXRMNDAC	5	Voice DAC signal mixing
		x0 = Not mixed on right mixer
		x1 = Mixed on right mixer
MXRLINR	6	Line in RXINR signal mixing
		x0 = Not mixed on right mixer
		x1 = Mixed on right mixer
Reserved	7	Reserved
	Al	UD20 (ADDR 0x193 - R/W - Default Value: 0x00)
RAMPVLFB	5:0	Transmit right channel side tone volume
Reserved	7:6	Reserved
	Al	UD21 (ADDR 0x194 - R/W - Default Value: 0x00)
LAMPVLFB	5:0	Transmit left channel side tone volume
Reserved	7:6	Reserved
	A	UD22 (ADDR 0x195 - R/W - Default Value: 0x00)
PSCNTSPKR	0	Ear piece amplifier enabling
	Ŭ	x0 = Disabled
		x1 = Enabled
PSCNTHPR	1	Headphone amplifier right enabling
		x0 = Disabled
		x1 = Enabled
PSCNTHPL	2	Headphone amplifier left enabling
	-	x0 = Disabled
		x1 = Enabled
PSCNTLOR	3	Line out amplifier right enabling
	_	x0 = Disabled
		x1 = Enabled
PSCNTLOL	4	Line out amplifier left amplifier enabling
		x0 = Disabled
		x1 = Enabled
Reserved	5	Reserved
	-	

PSCNTSPR	6	Loudspeaker amplifier right enabling
		x0 = Disabled
		x1 = Enabled
PSCNTSPL	7	Loudspeaker amplifier left enabling
		x0 = Disabled
		x1 = Enabled
	A	UD23 (ADDR 0x196 - R/W - Default Value: 0x00)
VCEADCEN	0	Voice ADC enabling
		x0 = Disabled
		x1 = Enabled
STRADCEN	1	Audio ADC enabling
		x0 = Disabled
		x1 = Enabled
PSCNTMIC2	2	MC2IN amplifier enabling
		x0 = Disabled
		x1 = Enabled
PSCNTMIC1	3	MC1IN amplifier enabling
		x0 = Disabled
		x1 = Enabled
PSCNTDA	4	Audio DAC enabling
		x0 = Disabled
		x1 = Enabled
PSCNTRX	5	Voice DAC enabling
		x0 = Disabled
		x1 = Enabled
SLOPESEL	7:6	Voice and audio bus drive strength
		AUD24 (ADDR 0x197 - R - Default Value: 0x00)
SWLPINT	0	Long switch push (> 2.0 sec) interrupt
		x0 = No long switch push detected
		x1 = Long switch push detected
SWMPINT	1	Momentary switch push interrupt
		x0 = No momentary switch push detected
		x1 = Momentary switch push detected
HPDET	2	Headphone detect interrupt
		x0 = Headphone detected
		x1 = No headphone detected
HSDET	3	Headset detect interrupt
		x0 = No headset detected
		x1 = Headset detected
Reserved	7:4	Reserved
	A	UD25 (ADDR 0x198 - R/W - Default Value: 0x00)
MSWLPINT	0	Long switch push interrupt mask
		x0 = Long switch push interrupt is unmasked
		and the second state wave bound in second state of the second stat

x1 = Long switch push interrupt is masked

FUNCTIONAL DEVICE OPERATION ADC SUBSYSTEM

Table 95. Audio Registers

1	Momentary switch push interrupt mask
	x0 = Momentary switch push interrupt is unmasked
	x1 = Momentary switch push interrupt is masked
2	Headphone detect interrupt mask
	x0 = Headphone detect interrupt is unmasked
	x1 = Headphone detect interrupt is masked
3	Headset detect interrupt mask
	x0 = Headset detect interrupt is unmasked
	x1 = Headset detect interrupt is masked
7:4	Reserved
	3

AUD26 (ADDR 0x199 - R/W - Default Value: 0x00)

TRIMEN	1:0	Enable trim offsets
Reserved	7:2	Reserved

ADC SUBSYSTEM

CONVERTER CORE

The ADC core is a 10 bit converter. The ADC core and logic run at an internally generated frequency of approximately 1.33 MHz. If an ADC conversion is requested while the PLL was not active, it will automatically be enabled by the ADC. A 32.768 kHz equivalent time base is derived from the 2.0 MHz clock to time ADC events. The ADC is

supplied from VCORE. The ADC core has an integrated auto calibration circuit which reduces the offset and gain errors.

The ADC will be used for sensing the current through select voltage regulators, touch screen support, PMIC thermal sensor, battery voltage, battery current, battery temperature and for sampling the battery coulomb counter.

Figure 75 is a representation of the ADC block.

Figure 75. ADC Block Representation

INPUT SELECTOR

The ADC has 22 input channels selected through the ADSEL[4:0] bits in the ADCADDRx register. <u>Table 96</u> gives an overview of the characteristics of each of these channels.

Table 96. ADC Inputs

Channel	SELECT[4:0]	ADC Input Signal	Input Level	Scaling	Scaled Version
0	00000	PMIC Die Temperature	1.2 – 2.4 V	x1	1.2 – 2.4 V
1	00001	VCC Current Sense	0 – 2.4 V	x1	0 – 2.4 V
2	00010	VNN Current Sense	0 – 2.4 V	x1	0 – 2.4 V
3	00011	VCC180 Current Sense	0 – 2.4 V	x1	0 – 2.4 V
4	00100	VDDQ Current Sense	0 – 2.4 V	x1	0 – 2.4 V
5	00101	V33 Current Sense	0 – 1.8 V	x4/3	0 – 2.4 V
6	00110	Battery Voltage (V _{BAT})	0 – 4.8 V	/2	0 – 2.4 V
7	00111	Battery Current	-60 – +60 mV ⁽³¹⁾	x20	-1.2 – +1.2 V
		(V _{BAT} – V _{ISNSBATN})			
8	01000	Adaptor Voltage	0 – 20 V	/10	0-2.0 V
9	01001	Battery Pack Thermistor	0 – 2.4 V	x1	0– 2.4 V

FUNCTIONAL DEVICE OPERATION ADC SUBSYSTEM

Table 96. ADC Inputs

Channel	SELECT[4:0]	ADC Input Signal	Input Level	Scaling	Scaled Version
10	01010	General Purpose ADIN10	0-200 mV / 0-2.0 V	10x / 1x	0 – 2.4 V
		Touch screen X+	0 – 1.2	x2	0-2.4 V
11	01011 General Purpose ADIN11		0-200 mV / 0-2.0 V	10x / 1x	0 – 2.4 V
		Touch screen X-	0 – 1.2	x2	0-2.4 V
12	01100	General Purpose ADIN12	0-200 mV / 0-2.0 V	10x / 1x	0 – 2.4 V
		Touch screen Y+	0 – 1.2	x2	0-2.4 V
13	01101	General Purpose ADIN13	0-200 mV / 0-2.0 V	10x / 1x	0-2.4 V
		Touch screen Y-	0 – 1.2	x2	0-2.4 V
14	01110	General Purpose ADIN14	0-200 mV / 0-2.0 V	10x / 1x	0-2.4 V
15	01111	General Purpose ADIN15	0-200 mV / 0-2.0 V	10x / 1x	0-2.4 V
16	10000	General Purpose ADIN16	0-200 mV / 0-2.0 V	10x / 1x	0 – 2.4 V
17	10001	General Purpose ADIN17	0-200 mV / 0-2.0 V	10x / 1x	0 – 2.4 V
18	10010	General Purpose ADIN18	0-200 mV / 0-2.0 V	10x / 1x	0-2.4 V
19	10011	General Purpose ADIN19	0-200 mV / 0-2.0 V	10x / 1x	0-2.4 V
20	10100	General Purpose ADIN20	0-200 mV / 0-2.0 V	10x / 1x	0-2.4 V
21	10101	General Purpose ADIN21	0-200 mV / 0-2.0 V	10x / 1x	0-2.4 V
22	10110	Reserved	Reserved	Reserved	Reserved
23	10111	Reserved	Reserved	Reserved	Reserved
24	11000	Reserved	Reserved	Reserved	Reserved
25	11001	Reserved	Reserved	Reserved	Reserved
26	11010	Reserved	Reserved	Reserved	Reserved
27	11011	Reserved	Reserved	Reserved	Reserved
28	11100	Reserved	Reserved	Reserved	Reserved
29	11101	Reserved	Reserved	Reserved	Reserved
30	11110	Reserved	Reserved	Reserved	Reserved
31	11111	Reserved	Reserved	Reserved	Reserved

Notes

31. Equivalent to -3.0 to +3.0 A of current with a 20 mOhm sense resistor

Some of the internal signals are first scaled to adapt the range to the input range of the ADC. Note that the 10 bit ADC core will convert over the entire scaled version of the input channel, so always from a 2.40 V full scale.

For some applications, an external resistor divider network may be used to scale down the voltage to be measured to the ADC input range. The source resistance presented by this may be greater than the maximum specified Rs, see ADC Section on <u>Table 3</u>. In that case, the readout value will be lower than expected due to the dynamic input impedance of the ADC converter. This readout error presents itself as a gain error which can be compensated for by factory phasing. An alternative is to place a 100 nF bypass capacitor at the ADIN input concerned.

RESERVED CHANNELS POSSIBLE USAGE

Only 22 of the possible 32 ADC channels are currently associated with an specific function. The remaining channels are currently designated as reserved channels for future needs. <u>Table 97</u> is a proposed usage for some of these channels for additional flexibility.

Table 97.	Possible	Reserved	Channels	Usage
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Channel	ADC Input Signal	Input Level	Scaling	Scaled Version
22	Application Supply (V _{PWR})	0 – 4.8 V	/2	0 – 2.4 V
23	Reserved	Reserved	Reserved	Reserved

Table 97. Possible Reserved Channels Usage

24	Charger Current	-300 – 300 mV ⁽³²⁾	x4	-1.2– +1.2 V
	(V _{ISNSBATP} – V _{ISNSBATN})			
25	Backup Voltage (V _{COINCELL})	0 – 3.6 V	x2/3	0 – 2.4 V
26	Battery Detect	0 – V _{CORE}	x5/6	0 – 2.31 V
27	Reserved	Reserved	Reserved	Reserved
28	Reserved	Reserved	Reserved	Reserved
29	Reserved	Reserved	Reserved	Reserved
30	Reserved	Reserved	Reserved	Reserved
31	Reserved	Reserved	Reserved	Reserved

Notes

32. Equivalent to -3.0 to +3.0 A of current with a 100 mOhm sense resistor

Activating the prior channels to provide the signal specified occurs by asserting the following bits to 1. If the following bits are 0, then these channels are reserved:

- VPWRCON for channel 22
- CHRGICON for channel 24
- LICON for channel 25
- BATDETVCON for channel 26

CONTROL

The ADC block consists of a 5-bit wide, 32-entry register file, which stores the address of the analog input for sampling. The 10-bit result is then stored in a separate register file 10+1 bits wide and 32 entries deep.

In order to operate the ADC, it has to be enabled first by setting the ADEN bit high in the ADCCNTL1 register. When the register ADCCNTL1 ADSTRT bit is enabled, the PMIC will cycle through the 3 + 5 bit selector addresses in registers ADCADDRx. The high 3-bits control the touch screen bias FETs, as described in Touch Screen Interface. The lower 5-bits address the ADC selector to connect one of 32 channels

to the ADC. The result of the ADC conversion is stored into the result registers (ADCSNSx), along with the input gain setting (1 MSB). An address in the selector table of 0x1F designates the stop location of the selection loop. At which point the interrupt flag bit 0 (RND), which can be masked through the MRND bit in the MADCINT register, is set in register ADCINT, bit 1 of the INTERRUPT register (ADC) is set, and the external PMICINT signal is asserted, if bit 1 of the INTMASK register is clear. The ADC sleeps for 0 to 27 ms as set by ADC register ADCCNTL1 through the ADSLP[2:0] bits and then repeats the selector cycle. The new data overwrites the old in the result registers. At most, all 32 result registers will be filled within 15.625 ms (2048/32 = 1/64 Hz). The result registers will not be read until the RND flag is set.

DEDICATED CHANNELS READING

Two different LSB value settings are possible by using the LSBSEL bit in the FSLADCCNTL register. LSBSEL = 0 is the default setting. See <u>Table 98</u> for more information

#	SELECT[4:0]	ADC INPUT SIGNAL	SIGNAL RANGE	LSB VALUE (LSBSEL = 0)	LSB VALUE (LSBSEL = 1)
0	00000	PMIC Die Temperature	1.2 – 2.4 V	0.4244 K	1C
1	00001	VCC Current Sense	4.2 A	4.1015 mA	10 mA
2	00010	VNN Current Sense	1.9 A	1.8554 mA	10 mA
3	00011	VCC180 Current Sense	0.5 A	0.4883 mA	10 mA
4	00100	VDDQ Current Sense	1.8 A	1.7578 mA	10 mA
5	00101	V33 Current Sense	1.7 A	1.6602 mA	10 mA
6	00110	Battery Voltage (V _{BAT})	4.8 V	4.6875 mV	10 mV
7	00111	Battery Current	6.0 A (-3.0 to 3.0 A)	5.8594 mA	10 mA
		(V _{BAT –} V _{ISNSBATN})			
8	01000	Adaptor Voltage	24 V	23.4375 mV	10 mV
9	01001	Battery Pack Thermistor	2.4 V	2.3438 mV	10mV

Table 98. ADC LSB Settings

FUNCTIONAL DEVICE OPERATION ADC SUBSYSTEM

Table 98. ADC LSB Settings

10	01010	General Purpose ADIN10	0-200 mV / 0-2.0 V	195.3 μV - 1.953 mv	195.3 μV - 1.953 mv	
		Touch screen X+	0 – 1.2	1.17 mV	1.17 mV	
11	01011	General Purpose ADIN11	0-200 mV / 0-2.0 V	195.3 μV - 1.953 mv	195.3 μV - 1.953 mv	
		Touch screen X-	0 – 1.2	1.17 mV	1.17 mV	
12	01100	General Purpose ADIN12	0-200 mV / 0-2.0 V	195.3 μV - 1.953 mv	195.3 μV - 1.953 mv	
		Touch screen Y+	0 – 1.2	1.17 mV	1.17 mV	
13	01101	General Purpose ADIN13	0-200 mV / 0-2.0 V	195.3 μV - 1.953 mv	195.3 μV - 1.953 mv	
		Touch screen Y-	0 – 1.2	1.17 mV	1.17 mV	
14	01110	General Purpose ADIN14	0-200 mV / 0-2.0 V	195.3 μV - 1.953 mv	195.3 μV - 1.953 mv	
15	01111	General Purpose ADIN15	0-200 mV / 0-2.0 V	195.3 μV - 1.953 mv	195.3 μV - 1.953 mv	
16	10000	General Purpose ADIN16	0-200 mV / 0-2.0 V	195.3 μV - 1.953 mv	195.3 μV - 1.953 mv	
17	10001	General Purpose ADIN17	0-200 mV / 0-2.0 V	195.3 μV - 1.953 mv	195.3 μV - 1.953 mv	
18	10010	General Purpose ADIN18	0-200 mV / 0-2.0 V	195.3 μV - 1.953 mv	195.3 μV - 1.953 mv	
19	10011	General Purpose ADIN19	0-200 mV / 0-2.0 V	195.3 μV - 1.953 mv	195.3 μV - 1.953 mv	
20	10100	General Purpose ADIN20	0-200 mV / 0-2.0 V	195.3 μV - 1.953 mv	195.3 μV - 1.953 mv	
21	10101	General Purpose ADIN21	0-200 mV / 0-2.0 V	195.3 μV - 1.953 mv	195.3 μV - 1.953 mv	
22	10110	Application Supply (V _{PWR})	0 – 4.8 V	4.6875 mV	4.6875 mV	
23	10111	Reserved	Reserved	Reserved	Reserved	
24	11000	Charger Current	-300– 300 mV ⁽³³⁾	2.9297 mA	2.9297 mA	
		(V _{ISNSBATP} – V _{ISNSBATN})				
25	11001	Backup Voltage (V _{COINCELL})	0 – 3.6 V	3.5156 mV	3.5156 mV	
26	11010	Battery Detect	0 – V _{CORE}	2.71 mV	2.71 mV	
27	11011	Reserved	Reserved	Reserved	Reserved	
28	11100	Reserved	Reserved	Reserved	Reserved	
29	11101	Reserved	Reserved	Reserved	Reserved	
30	11110	Reserved	Reserved	Reserved	Reserved	
31	11111	Reserved	Reserved	Reserved	Reserved	

Notes

33. Equivalent to -3.0 to +3.0 A of current with a 100 mOhm sense resistor

PMIC DIE TEMPERATURE

The die temperature can be read out on Channel 0 of the ADC. The relation between the read out code and temperature is given in <u>Table 99</u>.

Table 99. PMIC Die Temperature Voltage Reading

Parameter	Typical
Die Temperature Read Out Code at 25°C	1011000001
Temperature change per LSB	+0.4244 °C
Customer Defined LSB Value	1.0000 °C
Multiplier Value for Output Register	x2.36

CURRENT SENSING

The load current sourced by a select set of regulators can be measured and recorded by the ADC on channels 1 through 5. <u>Table 100</u> shows a summary of these regulators, type, and their current ranges.

Table 100. Regulators Current Sensing

Regulator	Туре	Current Range
VCC	Buck	0A – 3.5 A
VNN	Buck	0A – 1.6 A
VCC180	LDO	0A – 0.39 A
VDDQ	Buck	0A – 1.4 A
V33	Buck/Boost	0A – 1.4 A

BATTERY VOLTAGE

The battery voltage is read at the VBAT pin at channel 6. The battery voltage is first scaled by subtracting 2.40 V in order to fit the input range of the ADC.

Table for Battery Fortage Roading County					
Conversion Code	Voltage at ADC input	Voltage at VBAT			
1 111 111 111	2.400 V	4.800 V			
1 000 010 100	1.250 V	2.500 V			
0 000 000 000	0.000 V	0.000 V			

Table 101. Battery Voltage Reading Coding

BATTERY CURRENT

The current flowing out of and into the battery can be read via the ADC by monitoring the voltage drop across the sense resistor between the VBAT and ISNSBATN pins. The battery

Table 102. Battery Current Reading Coding

terminal voltage at VBAT and the voltage difference between VBAT and ISNSBATN are sampled simultaneously, but converted one after the other. This is done to efficiently perform the voltage and current reading at the same time.

The voltage difference between VBAT and ISNSBATN is first amplified to fit the ADC input range as V(VBAT -VISNSBATN)*20. Since battery current can flow in both directions, the conversion is read out in 2's complement format. Positive readings correspond to the current flow out of the battery, and negative readings to the current flowing into the battery.

The value of the sense resistor used, determines the accuracy of the result as well as the available conversion range. Note that excessively high values can impact the operating life of the system, due to extra voltage drop across the sense resistor.

Conversion Code	Voltage at ADC input ADC	V _{BAT} -V _{ISNSBAT}	Current Through 20 m	Current Flow
0 111 111 111	1200 mV	60.000 mV	3.000 A	From Battery
0 000 000 001	2.346 mV	0.117 mV	0.0059 A	From Battery
0 000 000 000	0.000 mV	0.000 mV	0.000 A	-
1 111 111 111	-2.346 mV	-0.117 mV	0.0059 A	To Battery
1 000 000 000	-1200 mV	-60.000 mV	3.000 A	To Battery

CHARGER INPUT VOLTAGE

One of the spare options is to read the charger voltage measured at the RAWCHG pin at Channel 8. The charger voltage is first scaled in order to fit the input range of the ADC.

Table 103.	Charger Inpu	t Voltage Reading	g Coding

Conversion Code	Voltage at ADC input	Voltage at VBAT
1 101 010 100	2.000 V	20.000 V
0 000 000 000	0.000 V	0.000 V

BATTERY THERMISTOR

Channel 9 is used to read out the battery pack thermistor. The thermistor will have to be biased with an external pull-up to a voltage rail greater than the ADC input range. In order to save current when the thermistor reading is not required, the thermistor is biased from VCORE through a cutoff switch connected to VNTC pin. A resistor divider network should assure the resulting voltage falls within the ADC input range.

GENERAL PURPOSE ANALOG INPUTS

There are twelve general purpose analog input channels that can be measured through the ADIN10-ADIN21 pins. Two voltage scaling (gain) settings can be selected to accommodate a wider range of inputs through the ADCCNTL3 and ADCCNTL4 registers. A gain of 0 sets a corresponding scaling factor of 1 (for an input range of 2.0 V) and a gain of 1 sets a corresponding scaling factor of 10 (for an input range of 200 mV).

Table 104. General Purpose Analog Inputs Reading Coding

Conversion Code	Voltage at ADC input	Voltage at ADINx Input	GAIN
1 111 111 111	2.400	0.200	1
1 011 111 111	1.800	0.150	
0 011 111 111	0.600	0.050	
0 000 000 000	0.000	0.000	
1 111 111 111	2.400	2.000	0
1 011 111 111	1.800	1.500	
0 011 111 111	0.600	0.500	
0 000 000 000	0.000	0.000	

APPLICATION SUPPLY (IF USED)

Channel 22 can be used to read the application supply voltage at the VPWR pin. This can be enabled by setting the VPWRCON bit in the FSLADCCNTL register high. The battery voltage is first scaled as VPWR/2 in order to fit the input range of the ADC.

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Conversion Code	Voltage at ADC input	Voltage at VPWR
1 111 111 111	2.400 V	4.800 V
1 000 010 100	1.250 V	2.500 V
0 000 000 000	0.000 V	0.000 V

Table 105. Application Supply Voltage Reading Coding

CHARGER CURRENT (IF USED)

Channel 24 can be used to read the charge current by monitoring the voltage drop over the charge current sense resistor. This can be enabled by setting the CHRGICON bit in the FSLADCCNTL register to 1. This resistor is connected between the ISNSBATP and ISNSBATN pins. The voltage difference is first amplified to fit the ADC input range as V(VISNSBATP-VISNSBATN)*4. The conversion is read out in a 2's complement format, see <u>Table 106</u>. The positive reading corresponds to the current flow from charger to battery, the negative reading to the current flowing into the charger terminal.

The value of the sense resistor used determines not only the accuracy of the result as well as the available conversion range, but also the charge current levels. It is therefore advised not to select another value other than those suggested in the ADC section of Table 3.

Table 106. Charger Current Reading Coding

CONVERSION CODE	VOLTAGE AT ADC INPUT	V _{BAT} - V _{ISNSBAT}	CURRENT THROUGH 20 M	CURRENT FLOW
0 111 111 111	1200 mV	300.000 mV	3.000 A	To Application/ Battery
0 000 000 001	2.346 mV	0.600 mV	0.0059 A	To Application/ Battery
0 000 000 000	0.000 mV	0.000 mV	0.000 A	-
1 111 111 111	-2.346 mV	-0.600 mV	0.0059 A	To Charger Connection
1 000 000 000	-1200 mV	-300.000 mV	3.000 A	To Charger Connection

BACKUP VOLTAGE (IF USED)

Channel 25 can be used to read the voltage of the coin cell connected to the COINCELL. This is enabled by setting the

LICON bit in the FSLADCCNTL register to 1. Since the voltage range of the coin cell exceeds the input voltage range of the ADC, the COINCELL voltage is first scaled as V_{COIN} *2/3.

Table 107.	. Backup (Coin (Cell) Voltage Reading Coding
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Conversion Code	Voltage at ADC input	Voltage at COINCELL
1 111 111 111	2.400 V	3.600 V
1 000 000 000	1.200 V	1.800 V
0 000 000 000	0.000 V	0.000 V

BATTERY DETECT (IF USED)

When a phone is on and supplied by the charger, SIM removal has to be detected to avoid fraudulent use of the phone. An easy way of doing so is to place the SIM card holder under the battery pack and perform a battery thermistor presence check. When the thermistor terminal becomes highimpedance, the battery is considered being removed. This detection function can be available at Channel 26 of the ADC by setting the BATDETVCON bit in the FSLADCCNTL register to 1. When not charging, the SIM removal function is not required to operate. Although the additional current drain due to the battery detect function is small, it is advised to disable the function when not charging to save this current.

TOUCH SCREEN INTERFACE

The PMIC touch screen support consists of four analog input channels with built in bias control. The BIAS FET control bits are part of the ADC round robin address register ADCADDRx. The touch screen X plate is connected to ADIN10 (X+) and ADIN11 (X-), while the Y plate is connected to ADIN12(Y+) and ADIN13(Y-). A local supply, TSREF, of 1.2 V will serve as a reference.

The system processor will handle the touch screen sequencing and any necessary conversion delays. The system processor will direct the desired bias control for every reading though the ADCADDRx registers. If FET biasing is enabled though the ADCADDRx registers, then touch screen readings will start according based on the channels chosen, and also by the ADCADDRx registers. If the touch screen is not used, then the above inputs can be used as general purpose inputs. In this case, the bias control will always be programmed to no bias.

Figure 76 is a touch screen representation.

Figure 76. Touch Screen Configuration Example

Touch Screen Pen detection bias can be enabled via the PENDETEN bit in the ADCCNTL1 register. When this bit is enabled and a pen touch is detected, the PENDET bit in register ADCINT is set and the PMICINT pin is asserted. This is to interrupt the system, because a touch screen pen touch has been detected at the next ADC cycle, unless the interrupt is masked.

The prior reference for the touch screen (Touch Bias) is TSREF and is powered from VCORE. In touch screen operation, TSREF is a dedicated regulator. No loads other than the touch screen should be connected here. When the ADC performs non touch screen conversions, the ADC does not rely on TSREF and the reference can be disabled. The readouts are designed such that the on chip switch resistances are of no influence to the overall readout. The readout scheme does not account for contact resistances, as present in the touch screen connectors. Therefore, the touch screen readings have to be calibrated by the user or in the factory, where one has to point with a stylus to the opposite corners of the screen. When reading out the X-coordinate, the 10-bit ADC reading represents a 10-bit coordinate with '0' for a coordinate equal to X- and full scale '1023' when equal to X+. When reading out the Y-coordinate, the 10-bit ADC reading represents a '10-bit ADC reading represents the voltage drop over the contact resistance created by the known current source multiplied by 2.

Plate Resistance X, Y	-	100	-	1000	Ω
Resistance Between Plates, Contact	-	180	-	1200	Ω
Capacitance Between Plates	-	0.5	2	-	nF
Contact Resistance Current Source	-	-	100	-	μA
Interrupt Current Source	-	-	20	-	μA
Interrupt Threshold	-	40	-	60	kΩ
Current Source Inaccuracy	-	-	-	20	%
Quiescent Current (Active Mode)		-	20	-	μA
Max Load Current (Active Mode)		-	-	20	mA
Settling Time (Position Measurement)	-	3.0	-	5.5	μS

Table 108. Touch Screen System Requirements

BATTERY COULOMB COUNTER

OVERVIEW

The current into and from the battery can be read out through the general purpose ADC as a voltage drop over the RCC sense resistor, see <u>Figure 77</u>. Together with the battery voltage reading, the battery capacity can be estimated. More

accurate battery capacity estimation can be obtained by using the integrated Coulomb Counter.

The Coulomb Counter (or CC) monitors the current flowing in/out of the battery by integrating the voltage drop across the battery current sense resistor RCC, followed by an A to D conversion. The result of the A to D conversion is used to increase/decrease the contents of an internal counter CCOUT[15:0]. This counter can be read out by software on

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two registers each with 8 bits of data, CCACCH[7:0] representing the CC reading high 8-bits, and CCACCL[7:0] representing the CC reading low 8-bits. The primary coulomb count that is made available to the host firmware through the SPI interface, using the above mentioned two registers. A 2s complement 16-bit value in which a negative sign bit, means the battery is discharging. A positive sign bit means the battery is charging, and the magnitude of the value represents the state of the battery charge, i.e., how much charge remains. The unmodified coulomb count, CCOUT[15:0] is also made available through the SPI interface, and registers RAWCCH and RAWCCL for the 8 high and 8 low bits of the 16-bit data. These two registers reside in the Freescale dedicated space. These can also be used for applications that do not require the 2s complement format.

This function will require a 100 nF output capacitor to perform a first order filtering of the signal across RCC. Due to the sampling of the A to D converter and the filtering applied, the longer the software waits before retrieving the information

from the CC, the higher the accuracy. The capacitor will be connected between the pins CFP and CFM, see Figure 77.

In the existing Freescale IP, the CCOUT counter is 16 bits. This counter is preferably reflecting 1 Coulomb per LSB. As a reminder, 1.0 Coulomb is the equivalent of 1.0 Ampere during 1.0 second, so a current of 20 mA during 1.0 hour is equivalent to 72 C. However, since the resolution is much finer than 1.0 C (LSB of 366.2 µC), the internal counts must first be rescaled. This can be done by setting the internal ONEC[14:0] bits. The CCOUT[15:0] counter is then increased by 1 with every ONEC[14:0] counts of the A to D converter. ONEC[14:0] = 2731 DEC yields 1C (2731*366.2 µC) count for CCOUT[15:0] with RCC=20 mOhm. For the current implementation, CCOUT[15:0] is desired to have an LSB of 10 mC. To achieve this, the ONEC register is set internally to 26 DEC yielding 10 mC count per LSB. The ONEC can be modified through the SPI in the Freescale dedicated space, using the **ONECLREG and ONECHREG registers**



Figure 77. Coulomb Counter Block diagram

At initial power-up, all the digital portions of the CC will be reset to their default values. The ONEC[14:0] will be programmed to the value of 26 DEC by default. The next step is to reset the CC by setting the CCCLEAR bit in the ADCCNTL1 register. The CCCLEAR is automatically cleared by the PMIC. Finally, the CC will always be running and counting the battery charge, and recording the reading in the CCOUT[15:0] register for as long as the CCEN bit in the ADCCNTL1 register is asserted. Unless the CC has no power or is in reset, the count will continue.

CCOUT[15]=1 indicates that the battery is discharging, while CCOUT[15]=0 indicates it is charging. When the CC count has reached 50% of full value (CCOUT[14] = 1), the OVERFLOW bit in register ADCINT is set and the PMICINT pin is asserted, unless the interrupt is masked, in order to interrupt the system from reading the value of the CC at the next ADC cycle. The interrupt service routine for the OVERFLOW interrupt will clear the first 15 bits of the CCADCA register (0-14), and counting will continue. The CCADCA register is never expected to reach 0x7FFF or 0xFFFF (bits 0-14 being all 1's). Note that if the battery is discharging, bit 15 will not be cleared after the OVERFLOW interrupt.

The digital portion of the CC is by default permanently corrected for offset and gain errors. Digital calibration can be disabled by setting the CCCALDB bit in register CCREG to 1.

Redundant control bits STARTCC and RSTCC are also provided in the CCCREG register in the Freescale dedicated space, so the user has the option to perform all coulomb counter controls using the coulomb counter registers, instead of using the GPADC registers. The coulomb counter enable is a logical OR of CCEN and STARTCC, and the coulomb counter reset is a logical OR of CCCLEAR and RSTCC. The user must take note of this to avoid uncertainty of whether the

coulomb counter is enabled, or in reset. Note that there is no way to preset the CCOUT counter to an arbitrary value - only to all zeros. Fuel gauging software must account for this reset condition, which corresponds to a fully discharged battery.

The coulomb counter block also includes a dithering circuit that can be enabled through the CCDITHER bit in the CCCREG register, to reduce spurious tones in the frequency spectrum of the coulomb count values. The circuit performs a random dithering of the integration period by +/- one cycle of the 32 kHz sampling clock. The dither signal is a pseudo-random bit pattern generated by a linear feedback shift register (LFSR).

For analog offset calibration, the coulomb counter block includes an input that is driven by the CCCALA bit in the CCCREG register. When this bit is set, the input terminals of the ADC's integrator are shorted together, and the current sense resistor is disconnected. The user may integrate for as short or as long a period as desired, using any particular value of ONEC, to determine the rate at which the integrator is changing with zero input signal. From this, the DC offset can be calculated and subtracted from future Coulomb count values by the fuel gauging software. The block also contains fault detection logic, which sets the CCFAULT bit in the CCCREG register, if the CCOUT counter overflows during charging - i.e., if the CCOUT count exceeds the maximum positive 15-bit value (32767) and causes a carry to the sign bit. This should not occur if the ONEC value is set appropriately for the total mAh of the battery (typically it is set to represent 1.0 C), due to the very large dynamic range of the Coulomb counter. If, however, a small ONEC value is set - representing much less than 1.0 C, the CCOUT counter may not have enough dynamic range to accommodate the total number of Coulombs of battery capacity, and the CCFAULT bit will be set. Note that CCFAULT does not cause an interrupt. It is simply a status bit that may be read at any time by the system firmware.

The block also includes a CCINVERT bit in the CCCREG register that allows the sense of coulomb counting to be reversed, so that negative values represent charging and positive values represent discharging.

ADC STATUS/CONTROL REGISTERS AND BIT DESCRIPTION

Reference the <u>Table 109</u> for read/write conditions and default state for each of these registers

Name	Bits	Description
		ADCINT (ADDR 0x5F - R - Default Value: 0x00)
RND	0	ADC Round Robin Cycle Completion Interrupt
		x0 = Not Completed
		x1 = Completed
PENDET	1	Touch Screen Pen Detection Interrupt
		x0 = Pen Not Detected
		x1 = Pen Detected
OVERFLOW	2	Coulomb Counter reached 50% of it full scale value Interrupt
		x0 = CC did not reach 50%
		x1 = CC reached 50%
Reserved	7:3	Reserved
		MADCINT (ADDR 0x60 - R/W -Default Value: 0x00)
MRND	0	ADC Round Robin Cycle Completion Interrupt Mask
		x0 = Unmask
		x1 = Mask
MPENDET	1	Touch Screen Pen Detection Interrupt Mask
		x0 = Unmask
		x1 = Mask
MOVERFLOW	2	Coulomb Counter reached 50% of it full scale value Interrupt Mask
		x0 = Unmask
		x1 = Mask
Reserved	7:3	Reserved

Table 109. ADC Interrupt/Mask Registers Structure and Bits Description

Name	Bits	Description			
ADCCNTL2 (ADDR 0x61 - R/W -Default Value: 0x00)					
ADSLP 2:0 ADC sleep time before starting another cycle					
		x0 = Continuous Loop	x4 = 18 ms		
		x1 = 4.5 ms	x5 = 22.5 ms		
		x2 = 9.0 ms	x6 = 27 ms		
		x3 = 13.5 ms	x7 = No Loop		
CCEN	3	Coulomb Counter Enable			
		x0 = Disable			
		x1 = Enable			
CCCLEAR	4	Coulomb Counter Reset Enable			
		x0 = Do not reset CC			
		x1 = CC reset			
PENDETEN	5	Enable Touch Screen Pen Detect Bias			
		x0 = Disabled			
		x1 = Enabled			
ADSTRT	6	ADC Round Robin Start Signal			
		x0 = Stop round robin after the current cycle			
		x1 = Start round robin			
ADEN	7	Bring the ADC out of low power state, this overrides wak	e from sleep		
		x0 = Disable in low power			
	x1 = Enable at full power				
		ADCCNTL3 (ADDR 0x62 - R/W -Defaul	t Value: 0x00)		
ADEXGAIN10	0	Gain bit for ADC channel 10, ignore when touch screen i	is biased		
		x0 = x1 (0-2.0 V input range)			
		x1 = x10 (0-200 mV input range)			
ADEXGAIN11	1	Gain bit for ADC channel 11, ignore when touch screen i	is biased		
		x0 = x1 (0-2.0 V input range)			
		x1 = x10 (0-200 mV input range)			
ADEXGAIN12	2	Gain bit for ADC channel 12, ignore when touch screen i	s biased		
		x0 = x1 (0-2.0 V input range)			
		x1 = x10 (0-200 mV input range)			
ADEXGAIN13	3	Gain bit for ADC channel 13, ignore when touch screen i	s biased		
		x0 = x1 (0-2.0 V input range)			
		x1 = x10 (0-200 mV input range)			
ADEXGAIN14	4	Gain bit for ADC channel 14			
		x0 = x1 (0-2.0 V input range)			
		x1 = x10 (0-200 mV input range)			
ADEXGAIN15	5	Gain bit for ADC channel 15			
		x0 = x1 (0-2.0 V input range)			
		x1 = x10 (0-200 mV input range)			
ADEXGAIN16	6	Gain bit for ADC channel 16			
		x0 = x1 (0-2.0 V input range)			
	x1 = x10 (0-200 mV input range)				

Table 110. ADC Control Registers Structure and Bits Description

Table 110. ADC Control Registers Structure and Bits Description

ADEXGAIN17	7	Gain bit for ADC channel 17			
		x0 = x1 (0-2.0 V input range)			
		x1 = x10 (0-200 mV input range)			
	ADCCNTL4 (ADDR 0X63 - R/W -DEFAULT VALUE: 0X00)				
ADEXGAIN18	0	Gain bit for ADC channel 18			
		x0 = x1 (0-2.0 V input range)			
		x1 = x10 (0-200 mV input range)			

ADEXGAIN19	1	Gain bit for ADC channel 19
		x0 = x1 (0-2.0 V input range)
		x1 = x10 (0-200 mV input range)
ADEXGAIN20	2	Gain bit for ADC channel 20
		x0 = x1 (0-2.0 V input range)
		x1 = x10 (0-200 mV input range)
ADEXGAIN21	3	Gain bit for ADC channel 21
		x0 = x1 (0-2.0 V input range)
		x1 = x10 (0-200 mV input range)
Reserved	7:4	Reserved

Table 111. ADC Channel Selector/Configuration Structure and bit Description

Name	Bits	Description			
	ADCSNSxH (x = 0 to 31)				
ADCHxH	6:0	7 MSBs of ADC result for Channel x			
GAINx	7	Gain bit for ADC channel x, x = 0 to 31			
		x0 = x1 (0-2.0 V input range)			
		x1 = x10 (0-200 mV input range)			

ADCSNSxL (x = 0 to 31)

ADCHxL	2:0	3 LSBs of ADC result for Channel x
Reserved	7:3	Reserved

ADCADDRX (X = 0 TO 31)

ADSELx	4:0	ADC Channel to be read Selection bits
		x00 = Channel 0
		x01 = Channel 1
		x1F = Channel 31
XPXMx	5	Turns on X+ and X- bias FETs, Refer to Figure 76
		x0 = FETS Off
		x1 = FETS On
YPYMx	6	Turns on Y+ and Y- bias FETs, Refer to Figure 76
		x0 = FETS Off
		x1 = FETS On
XMYPx	7	Turns on X- and Y+ bias FETs, Refer to Figure 76
		x0 = FETS Off
		x1 = FETS On

Table 111. ADC Channel Selector/Configuration Structure and bit Description

	CCADCHA (ADDR 0xC4 - R - 0x00)		
CCACCH	CCACCH 7:0 8 MSBs of Coulomb counter result, CCOUT[15:8]		
	CCADCLA (ADDR 0xC5 - R - 0x00)		
CCACCL	7:0	8 LSBs of Coulomb counter result, CCOUT[7:0]	

ADC STATUS/CONTROL REGISTERS AND BIT DESCRIPTION

Table 112. Extended ADC Control Register Structure and Bits Description

Name	Bits	Description
		FSLADCCNTL (ADDR 0x1DE - R/W - Default Value: 0x00)
VPWRCON	0	Enable channel 22 to read the V _{PWR} voltage
		x0 = Disable (Default)
		x1 = Enable
CHRGICON	1	Enable channel 24 to read the Battery charging current
		x0 = Disable (Default)
		x1 = Enable
LICON	2	Enable channel 25 to read the Backup Battery voltage
		x0 = Disable (Default)
		x1 = Enable
BATDETVCON	3	Enable channel 26 for battery detection
		x0 = Disable (Default)
		x1 = Enable
LSBSEL	4	ADC LSB Selection Bit
		x0 = Refer to <u>Table 98</u>
		x1 = Refer to <u>Table 98</u>
Reserved	7:4	Reserved

CCCREG (ADDR 0x1DF - R/W -Default Value: 0x00)

STARTCC	0	Redundant to CCEN
RSTCC	1	Redundant to CCCLEAR
CCDITHER	2	Coulomb Counter Dithering Enable
		x0 = Disable (Default)
		x1 = Enable
CCCALDB	3	Digital Offset and Gain Errors Calibration Enable
		x0 = Enable
		x1 = Disable (Default)
CCCALA	4	Analog Offset Calibration Enable
		x0 = Disable (Default)
		x1 = Enable
CCINVERT	5	Coulomb Counter Sign Inversion Bit
		x0 = Positive for Charging and Negative for Discharging (Default)
		x1 = Positive for Discharging and Negative for Charging
Reserved	6	Reserved

Table 112. Extended ADC Control Register Structure and Bits Description

	_	
CCFAULT	7	Charging Overflow Status Bit
		x0 = Coulomb Counter Reading is < Positive 32767
		x1 = Coulomb Counter Reading is > Positive 32767
		ONECLREG (ADDR 0x1E0 - R/W -Default Value: 0x1A)
ONEC[7:0]	7:0	8 LSBs of ONEC[14:0] internal register
		ONECHREG (ADDR 0x1E1 - R/W -Default Value: 0x00)
ONEC[14:8]	6:0	7 MSBs of ONEC[14:0] internal register
Reserved	7	Reserved
		RAWCCH (ADDR 0x1E2 - R/W - Default Value: 0x00
RAWCCH	7:0	8 MSBs CCOUT Raw Data
		RAWCCL (ADDR 0x1E3 - R/W - Default Value: 0x00)
RAWCCL	7:0	8 LSBs of CCOUT Raw Data
	1	I

GPIOS

DESCRIPTION

The 900841 has eight GPIOs, four GPOSWs for platform switches, and eight GPOs for platform control.

As outputs, the GPIOs and GPOSWs shall support CMOS/ OD signaling levels, based on the voltage level on the GPIOVCC and GPOSWVCC. The GPOs shall support CMOS signaling levels, based on the voltage level on the GPOVCC pin. As inputs, they need to be 3.6 V tolerant and should be de-bounced for a period of no more than 10 ms minimum.

The 900841 will provide one bank of eight configurable GPIO inputs/outputs, GPIO[7:0] for general purpose sensing and platform control. Only GPIOs support an input function.

The PMIC shall provide one bank of four GPOSW outputs, whose primary function will be to serve as gating signals for discrete platform VR switches.

GPOSW outputs vary from GPIOs in an important way. They are designed to support dynamic gating of sub-circuits from a main well or always on supply, and therefore require additional attention when switching. Specifically, GPOSWs must implement slew rate control to prevent dangerously high instantaneous inrush currents to previously isolated rails. For CMOS configured outputs, slew rate control will be specified in terms of output resistance at the GPOSW output pin. When operating as an open drain output, the slew rate specification is the same, but will be interpreted assuming an externally connected 100 k Ω (±1%) pull-up resistance.

Both GPIOs and GPOSWs are expected to switch between a high-impedance (>1.0 M Ω) state and a lowimpedance (20 Ω nominal) state when operating in open drain mode. When operating in CMOS mode, the outputs are expected to drive from the voltage supplied on the GPIOVCC pin with a 20 Ω output drive capability (for GPIOs) or GPOSWVCC pin (for GPOSWs).

The electrical characteristics of the output buffer will therefore be specified as relative percentages of the driving supply.

Any unused GPIO pin should be tied to ground on the board.

When any GPIO or GPOSW pin is configured as an open drain, the pull-up voltage cannot exceed that of the GPIOVCC and GPOSWVCC voltage level respectively.

<u>Table 113</u> shows the default state of the different GPIOs and their capabilities.

GPIO	Input	Output	CMOS	OD	Slew CNTL	Default Mode	Default Level	
GPIO0	Yes	Yes	Yes	Yes	No	Input	HI-Z	
GPIO1	Yes	Yes	Yes	Yes	No	Input	HI-Z HI-Z	
GPIO2	Yes	Yes	Yes	Yes	No	Input		
GPIO3	Yes	Yes	Yes	Yes	No	Input	HI-Z	
GPIO4	Yes	Yes	Yes	Yes	No	Input	HI-Z	
GPIO5	Yes	Yes	Yes	Yes	No	Input	HI-Z	
GPIO6	Yes	Yes	Yes	Yes	No	Input	HI-Z	
GPIO7	Yes	Yes	Yes	Yes	No	Input	HI-Z	

Table 113. GPIOs Capabilities and Default States

GPOSW0	No	Yes	Yes	Yes	Yes	OD	Low
GPOSW1	No	Yes	Yes	Yes	Yes	OD	Low
GPOSW2	No	Yes	Yes	Yes	Yes	OD	Low
GPOSW3	No	Yes	Yes	Yes	Yes	OD	Low
GPO0	No	Yes	Yes	No	No	CMOS	Low
GPO1	No	Yes	Yes	No	No	CMOS	Low
GPO2	No	Yes	Yes	No	No	CMOS	Low
GPO3	No	Yes	Yes	No	No	CMOS	Low
GPO4	No	Yes	Yes	No	No	CMOS	Low
GPO5	No	Yes	Yes	No	No	CMOS	Low
GPO6	No	Yes	Yes	No	No	CMOS	Low
GPO7	No	Yes	Yes	No	No	CMOS	Low

Table 113. GPIOs Capabilities and Default States

GPIO/GPOSW MODULE STRUCTURE

Figure 78 and Figure 79 illustrate the logical structure of the GPIOx and GPOSWx modules.



Figure 78. GPIO Module Structure

Figure 79. GPOSW Module Structure

GPOSW REQUIREMENTS

GPOSWs are recommended to be CMOS type outputs to utilize fully internal slew rate control, which is achieved through varying the output resistance. GPOSWs are powered from GPOSWVCC.

When configured as an open drain, the slew rate specification is the same, but will be interpreted, assuming an externally connected 100 k Ω (±1%) pull-up resistance. See Figure 80



Figure 80. PFET GPOSW Schematics with Slew Rate Control

GPIO/GPOSW STATUS/CONTROL REGISTERS AND BIT DESCRIPTION

Each individual GPIO and GPOSW module shall have a single 8-bit status and control register assigned to it. See <u>Table 114</u> for details.

The "x" in the bit names in the tables is from 0 to 7 for the GPIOs and 0 to 3 for the GPOSWs.

x0 = Output (x1 = Input (Bi DATAINx 2 The value in t Bit 1, DIRECT to be invalid t X0 = Electrica x1 = Electrica	rain tion Configuration Type selected by Bit 0) it 0 is ignored) the DATA_IN bit reflects the electrical state of the GPIOx pin at the time the register read was initiated. When FION, is 0 (Output Mode), the contents of this register are not required to be updated on reads and is assumed by the system controller. The PMIC should de-bounce the inputs over 1-10 ms to insure a clean transition. al Low ⁽³⁴⁾ al High ⁽³⁴⁾
x0 = Open Dr x1 = CMOS DIRx 1 GPIOx Direct x0 = Output (x1 = Input (Bi DATAINx 2 The value in t Bit 1, DIRECT to be invalid t X0 = Electrica x1 = Electrica	rain tion Configuration Type selected by Bit 0) it 0 is ignored) the DATA_IN bit reflects the electrical state of the GPIOx pin at the time the register read was initiated. When FION, is 0 (Output Mode), the contents of this register are not required to be updated on reads and is assumed by the system controller. The PMIC should de-bounce the inputs over 1-10 ms to insure a clean transition. al Low ⁽³⁴⁾ al High ⁽³⁴⁾
x1 = CMOS DIRx 1 GPIOx Direct x0 = Output (x1 = Input (Bi DATAINx 2 The value in t Bit 1, DIRECT to be invalid to X0 = Electrica x1 = Electrica	tion Configuration Type selected by Bit 0) it 0 is ignored) the DATA_IN bit reflects the electrical state of the GPIOx pin at the time the register read was initiated. When FION, is 0 (Output Mode), the contents of this register are not required to be updated on reads and is assumed by the system controller. The PMIC should de-bounce the inputs over 1-10 ms to insure a clean transition. al Low ⁽³⁴⁾ al High ⁽³⁴⁾
DIRx 1 GPIOx Direct x0 = Output (x1 = Input (Bi DATAINx 2 The value in t Bit 1, DIRECT to be invalid t X0 = Electrica x1 = Electrica	Type selected by Bit 0) it 0 is ignored) the DATA_IN bit reflects the electrical state of the GPIOx pin at the time the register read was initiated. When FION, is 0 (Output Mode), the contents of this register are not required to be updated on reads and is assumed by the system controller. The PMIC should de-bounce the inputs over 1-10 ms to insure a clean transition. al Low ⁽³⁴⁾ al High ⁽³⁴⁾
x0 = Output (x1 = Input (Bi DATAINx 2 The value in t Bit 1, DIRECT to be invalid t X0 = Electrica x1 = Electrica	Type selected by Bit 0) it 0 is ignored) the DATA_IN bit reflects the electrical state of the GPIOx pin at the time the register read was initiated. When FION, is 0 (Output Mode), the contents of this register are not required to be updated on reads and is assumed by the system controller. The PMIC should de-bounce the inputs over 1-10 ms to insure a clean transition. al Low ⁽³⁴⁾ al High ⁽³⁴⁾
x1 = Input (Bi DATAINx 2 The value in t Bit 1, DIRECT to be invalid t X0 = Electrica x1 = Electrica	it 0 is ignored) the DATA_IN bit reflects the electrical state of the GPIOx pin at the time the register read was initiated. When FION, is 0 (Output Mode), the contents of this register are not required to be updated on reads and is assumed by the system controller. The PMIC should de-bounce the inputs over 1-10 ms to insure a clean transition. al Low ⁽³⁴⁾ al High ⁽³⁴⁾
DATAINx 2 The value in t Bit 1, DIRECT to be invalid t X0 = Electrica x1 = Electrica	the DATA_IN bit reflects the electrical state of the GPIOx pin at the time the register read was initiated. When FION, is 0 (Output Mode), the contents of this register are not required to be updated on reads and is assumed by the system controller. The PMIC should de-bounce the inputs over 1-10 ms to insure a clean transition. al Low ⁽³⁴⁾ al High ⁽³⁴⁾
Bit 1, DIRECT to be invalid b X0 = Electrica x1 = Electrica	FION, is 0 (Output Mode), the contents of this register are not required to be updated on reads and is assumed by the system controller. The PMIC should de-bounce the inputs over 1-10 ms to insure a clean transition. al Low ⁽³⁴⁾ al High ⁽³⁴⁾
	-
	the DATA OUT his reflecte the desired electrical substitute table of the ODIOU size M/how Bit 4, DIDECTION is 1
(Input Mode),	the DATA_OUT bit reflects the desired electrical output state of the GPIOx pin. When Bit 1, DIRECTION, is 1, the contents of this register may still be read or written, but will not be reflected until the GPIOx is reverted Bit 1, DIRECTION, is 0) al Low ⁽³⁴⁾
x1 = Electrica	al High (CMOS) or High-impedance Output (Open-Drain) ⁽³⁴⁾
interrupt. The	t the interrupt definition. The MASK (00) determines if the corresponding interrupt flag bit is set or not on an e other logic levels will set the corresponding interrupt flag bit in the register upon the specific edge detection e level. They will also set bit 4 of the 1st level INTERRUPT register, see section Interrupt Controller for more
x0 = Mask.	
x1 = Negative	e Edge
x2 = Positive	Edge
x3 = Both Edg	ges
GPIDBNCx 7:6 These bits se	t the debounce time on the GPIOx when configured as inputs
x0 = No Debo	bunce
x1 = 10 ms	
x2 = 20 ms	
x3 = 30 ms	

Table 114. GPIO/GPOSW Register Structure and Bits Description

GPIOINT (ADDR 0xE8 - R - Default Value: 0x00)

GPIINT0	0	GPIO0 Interrupt Flag x0 = No Interrupt occurred or Masked Interrupt
		x1 = Interrupt occurred
GPIINT1	1	GPIO1 Interrupt Flag
		x0 = No Interrupt occurred or Masked Interrupt
		x1 = Interrupt occurred
GPIINT2	2	GPIO2 Interrupt Flag
		x0 = No Interrupt occurred or Masked Interrupt
		x1 = Interrupt occurred
GPIINT3	3	GPIO3 Interrupt Flag
		x0 = No Interrupt occurred or Masked Interrupt
		x1 = Interrupt occurred

Table 114. GPIO/GPOSW Register Structure and Bits Description

Name	Bits	Description							
GPIINT4	4	GPIO4 Interrupt Flag							
		x0 = No Interrupt occurred or Masked Interrupt							
		x1 = Interrupt occurred							
GPIINT5 5 GPIO5 Interrupt Flag									
		x0 = No Interrupt occurred or Masked Interrupt							
		x1 = Interrupt occurred							
GPIINT6	6	GPIO6 Interrupt Flag							
		x0 = No Interrupt occurred or Masked Interrupt							
	x1 = Interrupt occurred								
GPIINT7	7	GPIO7 Interrupt Flag							
		x0 = No Interrupt occurred or Masked Interrupt							
		x1 = Interrupt occurred							
<u>.</u>	. 1	GPOSWCTLx (x = 0 to 3)							

SWDRVx	0	GPOSWx Output Driver Type
		x0 = Open Drain
		x1 = CMOS
-	1	RESERVED
-	2	RESERVED
SWDOUTx	3	The value in the SWDOUTx bit reflects the desired electrical output state of the GPOSWx pin. X0 = Electrical Low ⁽³⁴⁾
		x1 = Electrical High (CMOS) or High-impedance Output (Open-drain) ⁽³⁴⁾
SLEWx	4:5	The value of the SLEWx Bits determines the level of slew rate control being exercised on the output's ramp rates. The level of slew rate control exercised is expected to hold true for both CMOS and Open Drain outputs. However, in the case of Open Drain outputs, the specified ramp rate is assuming an externally connected 100 k Ω (±1%) pull-up resistor (and no parallel capacitance).
		These values are met at the lowest supply voltage, GPOSWVCC = 1.8 V
		X0 = 50 Ω max (NFET) – 100 Ω max (PFET)
		X1 = 2.0 k Ω , ±35% at room temperature
		X2 = 20 k Ω , ±35% at room temperature
		X3 = 200 k Ω , ±25% at room temperature
SCRATCHx	6:7	These bits shall not exert any control over the operation of the GPOSWx, and are intended to be used as scratchpad registers by the system controller. Their contents are erased on POR.

Notes

34. See GPIOs electrical characteristics on Table 3

35. An unintended interrupt is caused if interrupt settings are reconfigured in the middle of an application, e.g. re-setting interrupt detection from detecting an interrupt on both edges to an interrupt on the rising edge. To mask any unwanted interrupt, change the GPIO interrupt detection to the new configuration, then clear Level 1 and level 2 interrupts. Finally unmask the GPIO Interrupt.

Table 115. GPO Register Structure and Bits Description

Name	Bits	Description									
<u> </u>	GPO (ADDR 0xF4 - R/W - Default Value: 0x00)										
GPO0	0	GPO0 Output Level									
		x0 = Low0									
		x1 = High (To voltage supplied on GPOVCC Pin)									
GPO1	1	GPO1 Output Level									
		x0 = Low									
		x1 = High (To voltage supplied on GPOVCC Pin)									

Table 115. GPO Register Structure and Bits Description

GPO2	2	GPO2 Output Level
		x0 = Low
		x1 = High (To voltage supplied on GPOVCC Pin)
GPO3	3	GPO3 Output Level
		x0 = Low
		x1 = High (To voltage supplied on GPOVCC Pin)
GPO4	4	GPO4 Output Level
		x0 = Low
		x1 = High (To voltage supplied on GPOVCC Pin)
GPO5	5	GPO5 Output Level
		x0 = Low
		x1 = High (To voltage supplied on GPOVCC Pin)
GPO6	6	GPO6 Output Level
		x0 = Low
		x1 = High (To voltage supplied on GPOVCC Pin)
GPO7	7	GPO7 Output Level
		x0 = Low
		x1 = High (To voltage supplied on GPOVCC Pin)

SPI REGISTER MAP

OVERVIEW

The SPI frame is organized as 24 bits. The first 16 bits is the write enable bit, 10-bit address and 5 "dead" bits between the data and address fields. The next 8 bits are the data bits. The one write enable bit selects whether the SPI transaction is a read or a write.

The addressable register map spans 1024 registers of 8 data bits each. The map is not fully populated. A summarized structure of the register set is given in the following tables. Expanded bit descriptions are included in the individual functional sections for application guidance.

SPI BIT MAP

The tables include the following fields:

- Block: This corresponds directly to the chapter, section or topic in which the detailed register description is included.
- Address: The register memory map address allocation in HEX format
- Register Name
- R/W: Defines if the register is a Read/Write register or only a Read register

- D7-D0: The 8-bit data included in the register with each bit's name and location within the field included
- Initial: The register's default value after power up
- Function: A short description of the register's function Some important notes about data in the table:
- Reserved registers/bits are not implemented in the design and they will always read as a 0
- Registers under the "FSL" block are Freescale dedicated registers and are not defined in the customer specifications. These registers represent additional functionality that Freescale is offering to enhance the performance of the overall system
- Registers under the "VD2" and "VD3" blocks are blocked from being used by Freescale
- The table only displays up to address 0x2FF. Address space between 0x300 and 0x3FF is reserved for future application use. Freescale is currently using the 0x300 to 0x3FF space for test and debug register implementation. This will not effect the application or any future use plans for this address space. The details of this space implementation are not discussed in this document.

Block	Address	Register Name	R/W	D7	D6	D5	D4	D3	D2	D1	D0	Initial	Function
Chip1	0x00	ID1	R	RSVD	RSVD	REV1[2:0]				VENDID1[2:0	0]	0x38	Chip1 ID
Chip2	0x01	ID2	R	RSVD	RSVD	REV2[2:0]			VENDID2[2:0]			0x00	Chip2 ID
Chip3	0x02	ID3	R	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Chip3 ID
Chip4	0x03	ID4	R	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Chip4 ID

Table 116. SPI Register Map

FUNCTIONAL DEVICE OPERATION SPI REGISTER MAP

Table 116. SPI Register Map

Block	Address	Register Name	R/W	D7	D6	D5	D4	D3	D2	D1	D0	Initial	Function
IRQ	0x04	INTERRUPT	R	EXT	AUX	VRFAULT	GPIO	RTC	CHR	ADC	PWRBTN	0x00	PMIC_INT sources, read clears
IRQ	0x05	INTMASK	R/W	MEXT	MAUX	MVRFAULT	MGPIO	MRTC	MCHR	MADC	MPWRBTN	0xFA	IRQ mask
CNTRL	0x06	CHIPCNTRL	R/W	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	WARMRST	COLDRST	0x00	PWRGD/RESET# control
RSVD	0x07	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
RSVD	0x08	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
RSVD	0x09	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
RSVD	0x0A	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
RSVD	0x0B	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
RSVD	0x0C	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
RSVD	0x0D	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
RSVD	0x0E	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
RSVD	0x0F		-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
RTC	0x10	RTCS	R/W	RSVD			-	SEC[6:0]			_	0x00	RTC Second
RTC	0x11	RTCSA	R/W				SECALA	ARM[7:0]				0x00	RTC Second Alarm
RTC	0x11	RTCM1	R/W	RSVD			020/12	MIN[6:0]				0x00	RTC Minutes
RTC	0x13	RTCMA	R/W				ΜΙΝΔΙ Δ	RM[7:0]				0x00	RTC Minutes Alarm
RTC	0x13	RTCH	R/W	PA-H	RSVD				15:01			0x00	RTC Hours
RTC	0x14 0x15	RTCHA	R/W	PA-HA	NOVE			HRS[5:0]					RTC Hours Alarm
					RSVD	RSVD	RSVD	HRSALARM[6:0] RSVD DOW[2:0]					
RTC	0x16	RTCDW	R/W	RSVD		RSVD	RSVD		15.01	0x01 0x01	RTC Day Of Week		
RTC	0x17	RTCDM	R/W	RSVD	RSVD	501/5		DOM[5:0]					RTC Day Of Month
RTC	0x18	RTCM2	R/W	19/20	RSVD RSVD MONTH[4:0]							0x01	RTC Month
RTC	0x19	RTCY	R/W		YEAR[7:0]						0x00	RTC	
RTC	0x1A	RTCA	R	UIP	-	DV[2:0] (=010b FIXED) RS[3:0] (=000b FIXED)				0x20	RTC Control A		
RTC	0x1B	RTCB	R/W	SET	PIE (=0) FIX	AIE	UIE	SQWE (=0) FIX	DM	HRMODE	DSE (=0) FIX	0x02	RTC Control B
RTC	0x1C	RTCC	R	IRQF	PF (=0) FIX	AF	UF	RSVD	RSVD	RSVD	RSVD	0x00	RTC Control C
RTC	0x1D	RTCD	R	VRT	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	RTC Control D
RTC	0x1E	RTCE	R/W		S	CRATCH[4:0]		1	POR	BKDET	OSCSTP	0x05	RTC Optional Detection
RTC	0x1F	ADJ	R/W	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	ADJ	0x00	RTC Adjustment
RTC	0x20	TRIM	R/W	RSVD	SIGN			TRIMV	AL[5:0]		1	0x00	RTC Trimming
RTC	0x21	CLKOUT	R/W	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	M32KCLK	0x00	32kHz clock output enable
RSVD	0x22	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
RSVD	0x23	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
RSVD	0x24	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
LED	0x25	LEDBRT0	R/W	LED1BL	.NK[1:0]	LED1BF	RT[1:0]	LED0BL	NK[1:0]	LED0E	BRT[1:0]	0x00	LED current
LED	0x26	LEDBRT1	R/W	LED3BL	.NK[1:0]	LED3BF	RT[1:0]	LED2BL	NK[1:0]	LED2E	BRT[1:0]	0x00	LED current
LED	0x27	LEDBRT2	R/W	LED5BL	.NK[1:0]	LED5BF	RT[1:0]	LED4BL	NK[1:0]	LED4E	BRT[1:0]	0x00	LED current
LCD	0x28	BKLTCNT	R/W	MLED3EN	MLED2EN	MLED1EN	RSVD	RSVD	RSVD	BKLT	SS[1:0]	0x00	LCD Backlight enable
LCD	0x29	BKLTFREQ	R/W	RSVD	PWMEN	RSVD	RSVD	RSVD	I	BKLTFREQ[2	:0]	0x00	PWM freq for external LCD-Driver
LCD	0x2A	BKLTBRTL	R/W				BKLTB	RT[7:0]				0x00	LCD Backlight brightness
LCD	0x2B	SSTRING	R/W	RSVD	RSVD	RSVD	RSVD	:	SILTBRT[2:0]	SLEDEN	0x00	4th String
RSVD	0x2C	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
RSVD	0x2D	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
	0x2E	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved

FUNCTIONAL DEVICE OPERATION SPI REGISTER MAP

Table 116. SPI Register Map

	I									T	1	-	
Block	Address	Register Name	R/W	D7	D6	D5	D4	D3	D2	D1	D0	Initial	Function
RSVD	0x2F	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
POWER	0x30	VRFAULTINT	R	RSVD	RSVD	RSVD	RSVD	RSVD	VRFAIL	BATOCP	THRM	0x00	Voltage Regulators Fault interrupt
POWER	0x31	MVRFAULTINT	R/W	RSVD	RSVD	RSVD	RSVD	RSVD	MVRFAIL	MBATOCP	MTHRM	0x03	Voltage Regulators Fault interrupt Mask
POWER	0x32	VCCLATCH	R/W	DVP1VRD				VIDVCC[6:0]]			0x7F	VCC VID CONTROL
POWER	0x33	VNNLATCH	R/W	DVP2VRD				VIDVNN[6:0]]			0x7F	VNN VID CONTROL
POWER	0x34	PWRMASK	R/W	M7	M6	M5	M4	M3	M2	M1	M0	0x00	Power register write mask
POWER	0x35	VCCCNT	R/W	RSVD	RSVD	AC	DACTLVCC[2	2:0]		CTLVCC[2:0	0]	0x24	VCC
POWER	0x36	VNNCNT	R/W	RSVD	RSVD	AC	DACTLVNN[2	2:0]		CTLVNN[2:0	0]	0x04	VNN
POWER	0x37	VDDQCNT	R/W	RSVD	RSVD	AO	ACTLVDDQ	2:0]		CTLVDDQ[2:	0]	0x04	VDDQ
POWER	0x38	V21CNT	R/W	RSVD	RSVD	A	DACTLV21[2	:0]		CTLV21[2:0]	0x07	V21
POWER	0x39	V15CNT	R/W	SELV1	5[1:0]	A	DACTLV15[2	:0]		CTLV15[2:0]	0x07	V15
POWER	0x3A	V33CNT	R/W	RSVD	RSVD	A	DACTLV33[2	:0]		CTLV33[2:0]	0x24	V33
POWER	0x3B	VYMX3GPACNT	R/W	SELYMX3	GPA[1:0]	AOA	CTLYMX3GP	A[2:0]	C.	TLYMX3GPA	[2:0]	0x24	YMX3GPA
POWER	0x3C	VYMX3GDCNT	R/W	SELYMX	3GD[1:0]	AOA	CTLYMX3GI	D[2:0]	C	TLYMX3GD[2	2:0]	0x24	VMX3GD
POWER	0x3D	VCCPAOACCNT	R/W	RSVD	RSVD	AOAC	TLVCCPAO	AC[2:0]	СТ	LVCCPAOAC	- C[2:0]	0x07	VCCPAOAC
POWER	0x3E	VCCPDDRCNT	R/W	RSVD	RSVD		CTLVCCPDD			TLVCCPDDR		0x3C	VCCPDDR
POWER	0x3F	VLBGCNT	R/W	RSVD	RSVD		ACTLVLBG			CTLVLBG[2:		0x24	VLBG
POWER	0x40	VCCACNT	R/W	RSVD	RSVD		ACTLVCCA	-		CTLVCCA[2:	-	0x3C	VCCA
POWER	0x41	VPMICCNT	R/W	RSVD	RSVD		ACTLVPMIC	-		CTLVPMIC[2:	-	0x07	VPMIC
POWER	0x42	VIMG25CNT	R/W	RSVD	RSVD						0x04	VIMG25	
POWER	0x43	VCC180CNT	R/W	RSVD	RSVD						0x3C	VCC180	
POWER	0x44	VCCPCNT	R/W	RSVD	RSVD	AOACTLVCCP[2:0]				CTLVCCP[2:	-	0x3C	VCCP
POWER	0x45	VAONCNT	R/W	RSVD	RSVD		ACTLVAON	-		CTLVAON[2:	-	0x07	VAON
POWER	0x46	VPANEL18CNT	R/W	RSVD	RSVD		TLVPANEL	-		LVPANEL18	-	0x24	VPANEL18
POWER	0x47	VMMCNT	R/W	RSVD	RSVD					CTLVMM[2:0		0x24	
POWER	0x48	VIMGACNT	R/W	SELIM			ACTLVIMGA	-		CTLVIMGA[2:	-	0x24	VIMGA
POWER	0x40	VIBCNT	R/W	SELVI			OACTLVIB[2			CTLVIB[2:0]	_	0x24	VIB
POWER	0x4A	VGYMXIOCNT	R/W	SELVGYN				-	C	TLVGYMXIO	0x24	GPS_YMX_IO	
POWER	0x4A	VWDYMXACNT	R/W	SELVUN								0x24	WIFIBT_DIG_YMX_ ANALOG
POWER	0x4C	VWYMXARFCNT	R/W	RSVD	RSVD	AOAC	TLVWYMXA	RF[2:0]	СТ	LVWYMXARF	F[2:0]	0x24	WIFIBT_YMX_ANA LOGRF
POWER	0x4D	VSDIOCNT	R/W	SELVS	DIO[1:0]	AO	ACTLVSDIO	[2:0]		CTLVSDIO[2:	:0]	0x64	VSDIO
POWER	0x4E	GYMX33CNT	R/W	RSVD	RSVD	AOA	CTLGYMX3	3[2:0]	C	TLGYMX33[2	2:0]	0x24	GPS_ANALOGRF_ WiMAX3.3
POWER	0x4F	VPANEL33CNT	R/W	RSVD	RSVD	AOAO	TLVPANEL	33[2:0]	CT	LVPANEL33	[2:0]	0x24	VCC_PANEL_3.3
POWER	0x50	VGP33CNT	R/W	RSVD	RSVD	AO	ACTLVGP33	[2:0]		CTLVGP33[2	:0]	0x24	VCC_GP_3.3
POWER	0x51	VAUDIOCNT	R/W	RSVD	RSVD	AOA	CTLVAUDIC	0[2:0]	0	TLVAUDIO[2	2:0]	0x00	VAUDIOCNT
RSVD	0x52	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
RSVD	0x53	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
RSVD	0x54	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
MEMORY	0x55	MEM1	R/W		1	I	SCRAT	CH[7:0]	1	J	L	0x00	Backup memory
MEMORY	0x56	MEM2	R/W				SCRAT					0x00	Backup memory
MEMORY	0x57	MEM3	R/W				SCRAT					0x00	Backup memory
MEMORY	0x58	MEM4	R/W				SCRAT					0x00	Backup memory

FUNCTIONAL DEVICE OPERATION

Table 116. SPI Register Map

Block	Address	Register Name	R/W	D7	D6	D5	D4	D3	D2	D1	D0	Initial	Function
MEMORY	0x59	MEM5	R/W		I	1	SCRAT	CH[7:0]	1	l'	1	0x00	Backup memory
MEMORY	0x5A	MEM6	R/W				SCRAT	CH[7:0]				0x00	Backup memory
MEMORY	0x5B	MEM7	R/W				SCRAT	CH[7:0]				0x00	Backup memory
MEMORY	0x5C	MEM8	R/W				SCRAT	CH[7:0]				0x00	Backup memory
RSVD	0x5D	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
RSVD	0x5E	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
ADC	0x5F	ADCINT	R	RSVD	RSVD	RSVD	RSVD	RSVD	OVERFLO	PENDET	RND	0x00	ADC interrupt
									W				
ADC	0x60	MADCINT	R/W	RSVD	RSVD	RSVD	RSVD	RSVD	MOVERFL OW	MPENDET	MRND	0x00	ADC interrupt Mask
ADC	0x61	ADCCNTL2	R/W	ADEN	ADSTRT	PENDETEN	CCCLEAR	CCEN		ADSLP[2:0]	I	0x00	ADC control
ADC	0x62	ADCCNTL3	R/W	ADEXGAIN1	ADEXGAIN	ADEXGAIN	ADEXGAI	ADEXGAIN	ADEXGAI	ADEXGAIN	ADEXGAIN	0x00	GAIN for AN10-
100	0.00		DAM	7	16	15	N14	13	N12	11	10	0.00	AN17
ADC	0x63	ADCCNTL4	R/W	RSVD	RSVD	RSVD	RSVD	ADEXGAIN 21	ADEXGAI N20	ADEXGAIN 19	ADEXGAIN 18	0x00	GAIN for AN18- AN21
ADC	0x64	ADCSNS0H	R	GAIN0		r	r	ADCH0H[9:3]]	r	r	0x00	ADC result
ADC	0x65	ADCSNS0L	R	RSVD	RSVD	RSVD	RSVD	RSVD		ADCH0L[2:0]	0x00	ADC result
ADC	0x66	ADCSNS1H	R	GAIN1		ł	ł	ADCH1H[9:3]]			0x00	ADC result
ADC	0x67	ADCSNS1L	R	RSVD	RSVD	RSVD	RSVD	RSVD		ADCH1L[2:0]	0x00	ADC result
ADC	0x68	ADCSNS2H	R	GAIN2				ADCH2H[9:3]]			0x00	ADC result
ADC	0x69	ADCSNS2L	R	RSVD	RSVD	RSVD	RSVD	RSVD	ADCH2L[2:0]				ADC result
ADC	0x6A	ADCSNS3H	R	GAIN3				ADCH3H[9:3]]				ADC result
ADC	0x6B	ADCSNS3L	R	RSVD	RSVD	RSVD	RSVD	RSVD		ADCH3L[2:0	0x00	ADC result	
ADC	0x6C	ADCSNS4H	R	GAIN4		I	I	ADCH4H[9:3]	 		0x00	ADC result	
ADC	0x6D	ADCSNS4L	R	RSVD	RSVD	RSVD	RSVD	RSVD	-	ADCH4L[2:0	0x00	ADC result	
ADC	0x6E	ADCSNS5H	R	GAIN5				ADCH5H[9:3]]			0x00	ADC result
ADC	0x6F	ADCSNS5L	R	RSVD	RSVD	RSVD	RSVD	RSVD	ADCH5L[2:0]		0x00	ADC result	
ADC	0x70	ADCSNS6H	R	GAIN6				ADCH6H[9:3]			0x00	ADC result	
ADC	0x71	ADCSNS6L	R	RSVD	RSVD	RSVD	RSVD	RSVD	-	ADCH6L[2:0	1	0x00	ADC result
ADC	0x72	ADCSNS7H	R	GAIN7			l	ADCH7H[9:3]	1	-	-	0x00	ADC result
ADC	0x73	ADCSNS7L	R	RSVD	RSVD	RSVD	RSVD	RSVD	-	ADCH7L[2:0	1	0x00	ADC result
ADC	0x74	ADCSNS8H	R	GAIN8			1	ADCH8H[9:3]	1			0x00	ADC result
ADC	0x75	ADCSNS8L	R	RSVD	RSVD	RSVD	RSVD	RSVD	-	ADCH8L[2:0	1	0x00	ADC result
ADC	0x76	ADCSNS9H	R	GAIN9				ADCH9H[9:3]	1	-	-	0x00	ADC result
ADC	0x77	ADCSNS9L	R	RSVD	RSVD	RSVD	RSVD	RSVD		ADCH9L[2:0]	0x00	ADC result
ADC	0x78	ADCSNS10H	R	GAIN10		l	1	ADCH10H[9:3	5]	-	-	0x00	ADC result
ADC	0x79	ADCSNS10L	R	RSVD	RSVD	RSVD	RSVD	RSVD	-	ADCH10L[2:0	ומ	0x00	ADC result
ADC	0x7A	ADCSNS11H	R	GAIN11			1	ADCH11H[9:3	5]			0x00	ADC result
ADC	0x7B	ADCSNS11L	R	RSVD	RSVD	RSVD	RSVD	RSVD	-	ADCH11L[2:0	ומ	0x00	ADC result
ADC	0x7C	ADCSNS12H	R	GAIN12				ADCH12H[9:3				0x00	ADC result
ADC	0x7D	ADCSNS12L	R	RSVD	RSVD	RSVD	RSVD	RSVD	-	ADCH12L[2:0	ומ	0x00	ADC result
ADC	0x7E	ADCSNS13H	R	GAIN13		I		ADCH13H[9:3	I		-	0x00	ADC result
ADC	0x7F	ADCSNS13L	R	RSVD	RSVD	RSVD	RSVD	RSVD	-	ADCH13L[2:0	וו	0x00	ADC result
ADC	0x80	ADCSNS14H	R	GAIN14				ADCH14H[9:3				0x00	ADC result
ADC	0x81	ADCSNS14L	R	RSVD	RSVD	RSVD	RSVD	RSVD	-	ADCH14L[2:(01	0x00	ADC result
ADC	0x82	ADCSNS15H	R	GAIN15				ADCH15H[9:3	51			0x00	ADC result
ADC	0x83	ADCSNS15L	R	RSVD	RSVD	RSVD	RSVD	RSVD	-	ADCH15L[2:0	01	0x00	ADC result
ADC	0x84	ADCSNS16H	R	GAIN16				ADCH16H[9:3				0x00	ADC result
ADC	0x85	ADCSNS16L	R	RSVD	RSVD	RSVD	RSVD	RSVD	-	ADCH16L[2:0	וו	0x00	ADC result
ADC	COXO	ADCONGIOL	ĸ	ROVD	ROVD	ROVD	NOVD	ROVD		הטטרווטבןע:נ	4	0,000	ADO IOSUIL

FUNCTIONAL DEVICE OPERATION SPI REGISTER MAP

Table 116. SPI Register Map

Block	Address	Register Name	R/W	D7	D6	D5	D4	D3	D2	D1	D0	Initial	Function
ADC	0x86	ADCSNS17H	R	GAIN17				ADCH17H[9:3]			0x00	ADC result
ADC	0x87	ADCSNS17L	R	RSVD	RSVD	RSVD	RSVD	RSVD	-	ADCH17L[2:	0]	0x00	ADC result
ADC	0x88	ADCSNS18H	R	GAIN18		Į	1	ADCH18H[9:3	1			0x00	ADC result
ADC	0x89	ADCSNS18L	R	RSVD	RSVD	RSVD	RSVD	RSVD	-	ADCH18L[2:0]			ADC result
ADC	0x8A	ADCSNS19H	R	GAIN19				ADCH19H[9:3	1				ADC result
ADC	0x8B	ADCSNS19L	R	RSVD	RSVD	RSVD	RSVD	RSVD	-	ADCH19L[2:	01	0x00	ADC result
ADC	0x8C	ADCSNS20H	R	GAIN20				ADCH20H[9:3				0x00	ADC result
ADC	0x8D	ADCSNS20L	R	RSVD	RSVD	RSVD	RSVD	RSVD	_	ADCH20L[2:	01	0x00	ADC result
ADC	0x8E	ADCSNS21H	R	GAIN21		1	1	ADCH21H[9:3				0x00	ADC result
ADC	0x8F	ADCSNS21L	R	RSVD	RSVD	RSVD	RSVD	RSVD	_	ADCH21L[2:	01	0x00	ADC result
ADC	0x90	ADCSNS22H	R	GAIN22				ADCH22H[9:3		•		0x00	ADC result
ADC	0x91	ADCSNS22L	R	RSVD	RSVD	RSVD	RSVD	RSVD	-	ADCH22L[2:	01	0x00	ADC result
ADC	0x92	ADCSNS23H	R	GAIN23				ADCH23H[9:3		•		0x00	ADC result
ADC	0x93	ADCSNS23L	R	RSVD	RSVD	RSVD	RSVD	RSVD	-	ADCH23L[2:	01	0x00	ADC result
ADC	0x94	ADCSNS24H	R	GAIN24				ADCH24H[9:3			-1	0x00	ADC result
ADC	0x95	ADCSNS24L	R	RSVD	RSVD	RSVD	RSVD	RSVD	_	ADCH24L[2:	01	0x00	ADC result
ADC	0x96	ADCSNS25H	R	GAIN25	1075	1075		ADCH25H[9:3			0]	0x00	ADC result
ADC	0x97	ADCSNS25L	R	RSVD	RSVD	RSVD	RSVD	RSVD	-	ADCH25L[2:	01	0x00	ADC result
ADC	0x98	ADCSNS26H	R	GAIN26	110712	1075		ADCH26H[9:3			0]	0x00	ADC result
ADC	0x99	ADCSNS26L	R	RSVD	RSVD	RSVD	RSVD	RSVD	_	ADCH26L[2:0]		0x00	ADC result
ADC	0x9A	ADCSNS27H	R	GAIN27	NOVE	NOVE		ADCH27H[9:3]				0x00	ADC result
ADC	0x9B	ADCSNS27L	R	RSVD	RSVD	RSVD	RSVD	RSVD	ADCH27L[2:0]			0x00	ADC result
ADC	0x9C	ADCSNS28H	R	GAIN28	ROVD	NOVD	ADCH28H[9:3]				0]	0x00	ADC result
ADC	0x9D	ADCSNS28L	R	RSVD	RSVD	RSVD	RSVD RSVD ADCH28L[2:0]				0x00	ADC result	
ADC	0x9E	ADCSNS29H	R	GAIN29	ROVE	NOVE	ADCH29H[9:3]				0]	0x00	ADC result
ADC	0x9E	ADCSNS29L	R	RSVD	RSVD	RSVD	RSVD	RSVD	-	ADCH29L[2:	01	0x00	ADC result
ADC	0xA0	ADCSNS30H	R	GAIN30	ROVE	NOVE		ADCH30H[9:3		AD011232[2.	0]	0x00	ADC result
ADC	0xA0	ADCSNS30L	R	RSVD	RSVD	RSVD	RSVD	RSVD	_	ADCH30L[2:	01	0x00	ADC result
ADC	0xA1	ADCSNS30L	R	GAIN31	NOVD	NOVD		ADCH31H[9:3		ADOI 130L[2.	0]	0x00	ADC result
ADC	0xA2	ADCSNS31L	R	RSVD	RSVD	RSVD	RSVD	RSVD	-	ADCH31L[2:	01	0x00	ADC result
ADC	0xA3	ADCADDR0	R/W	XMYP0	YPYM0	XPXM0	N3VD		ADSEL0[4:0	-	0]	0x00	ADC result
ADC	02A4	ADCADDRU	R/W	AWITEU	TETINO				AD3EL0[4.0	1		0,000	address
ADC	0xA5	ADCADDR1	R/W	XMYP1	YPYM1	XPXM1			ADSEL1[4:0]		0x00	ADC selector address
ADC	0xA6	ADCADDR2	R/W	XMYP2	YPYM2	XPXM2			ADSEL2[4:0]		0x00	ADC selector address
ADC	0xA7	ADCADDR3	R/W	XMYP3	YPYM3	XPXM3			ADSEL3[4:0]		0x00	ADC selector address
ADC	0xA8	ADCADDR4	R/W	XMYP4	YPYM4	XPXM4			ADSEL4[4:0]		0x00	ADC selector address
ADC	0xA9	ADCADDR5	R/W	XMYP5	YPYM5	XPXM5			ADSEL5[4:0]		0x00	ADC selector address
ADC	0xAA	ADCADDR6	R/W	XMYP6	YPYM6	XPXM6			ADSEL6[4:0]		0x00	ADC selector address
ADC	0xAB	ADCADDR7	R/W	XMYP7	YPYM7	XPXM7			ADSEL7[4:0]		0x00	ADC selector address
ADC	0xAC	ADCADDR8	R/W	XMYP8	YPYM8	XPXM8			ADSEL8[4:0]		0x00	ADC selector address
ADC	0xAD	ADCADDR9	R/W	XMYP9	YPYM9	XPXM9			ADSEL9[4:0]		0x00	ADC selector address

FUNCTIONAL DEVICE OPERATION

Table 116. SPI Register Map

Block	Address	Register Name	R/W	D7	D6	D5	D4	D3	D2	D1	D0	Initial	Function
ADC	0xAE	ADCADDR10	R/W	XMYP10	YPYM10	XPXM10	ADSEL10[4:0]						ADC selector address
ADC	0xAF	ADCADDR11	R/W	XMYP11	YPYM11	XPXM11	ADSEL11[4:0]						ADC selector address
ADC	0xB0	ADCADDR12	R/W	XMYP12	YPYM12	XPXM12	ADSEL12[4:0]						ADC selector address
ADC	0xB1	ADCADDR13	R/W	XMYP13	YPYM13	XPXM13			ADSEL13[4:0)]		0x00	ADC selector address
ADC	0xB2	ADCADDR14	R/W	XMYP14	YPYM14	XPXM14			ADSEL14[4:0)]		0x00	ADC selector address
ADC	0xB3	ADCADDR15	R/W	XMYP15	YPYM15	XPXM15			ADSEL15[4:0)]		0x00	ADC selector address
ADC	0xB4	ADCADDR16	R/W	XMYP16	YPYM16	XPXM16			ADSEL16[4:0)]		0x00	ADC selector address
ADC	0xB5	ADCADDR17	R/W	XMYP17	YPYM17	XPXM17			ADSEL17[4:0)]		0x00	ADC selector address
ADC	0xB6	ADCADDR18	R/W	XMYP18	YPYM18	XPXM18			ADSEL18[4:0)]		0x00	ADC selector address
ADC	0xB7	ADCADDR19	R/W	XMYP19	YPYM19	XPXM19			ADSEL19[4:0)]		0x00	ADC selector address
ADC	0xB8	ADCADDR20	R/W	XMYP20	YPYM20	XPXM20			ADSEL20[4:0)]		0x00	ADC selector address
ADC	0xB9	ADCADDR21	R/W	XMYP21	YPYM21	XPXM21			ADSEL21[4:0)]		0x00	ADC selector address
ADC	0xBA	ADCADDR22	R/W	XMYP22	YPYM22	XPXM22	ADSEL22[4:0]						ADC selector address
ADC	0xBB	ADCADDR23	R/W	XMYP23	YPYM23	XPXM23	ADSEL23[4:0]						ADC selector address
ADC	0xBC	ADCADDR24	R/W	XMYP24	YPYM24	XPXM24	ADSEL24[4:0]						ADC selector address
ADC	0xBD	ADCADDR25	R/W	XMYP25	YPYM25	XPXM25	ADSEL25[4:0]						ADC selector address
ADC	0xBE	ADCADDR26	R/W	XMYP26	YPYM26	XPXM26	ADSEL26[4:0]						ADC selector address
ADC	0xBF	ADCADDR27	R/W	XMYP27	YPYM27	XPXM27			ADSEL27[4:0)]		0x00	ADC selector address
ADC	0xC0	ADCADDR28	R/W	XMYP28	YPYM28	XPXM28			ADSEL28[4:0)]		0x00	ADC selector address
ADC	0xC1	ADCADDR29	R/W	XMYP29	YPYM29	XPXM29			ADSEL29[4:0	0]		0x00	ADC selector address
ADC	0xC2	ADCADDR30	R/W	XMYP30	YPYM30	XPXM30			ADSEL30[4:0	0]		0x00	ADC selector address
ADC	0xC3	ADCADDR31	R/W	XMYP31	YPYM31	XPXM31			ADSEL31[4:0)]		0x00	ADC selector address
ADC	0xC4	CCADCHA	R				CCACC	H[15:8]				0x00	Coulomb Counter ADC result
ADC	0xC5	CCADCLA	R				CCAC	CL[7:0]				0x00	Coulomb Counter ADC result
RSVD	0xC6	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
RSVD	0xC7	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
RSVD	0xC8	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
RSVD	0xC9	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
RSVD	0xCA	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
RSVD	0xCB	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
RSVD	0xCC	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
RSVD	0xCD	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
RSVD	0xCE	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
RSVD	0xCF	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved

FUNCTIONAL DEVICE OPERATION SPI REGISTER MAP

Table 116. SPI Register Map

Block	Address	Register Name	R/W	D7	D6	D5	D4	D3	D2	D1	D0	Initial	Function
CHARGER	0xD0	CHRGINT	R	USBOVP	DCLMT	BATDET	USBDET	COMP	TEMP	BATOVP	RSVD	0x00	Charger Interrupt
CHARGER	0xD1	MCHRGINT	R/W	MUSBOVP	MDCLMT	MBATDET	MUSBDET	MCOMP	MTEMP	MBATOVP	RSVD	0x00	Charger Interrupt Mask
CHARGER	0xD2	SCHRGINT	R	SUSBOVP	SDCLMT	SBATDET	SUSBDET	SCOMP	STEMP	SBATOVP	RSVD	0x00	Charger State
CHARGER	0xD3	CHRGSTATE	R	RSVD	RSVD	RSVD	RSVD		RDST	RDSTATE[3:0]		0x00	charge State
CHARGER	0xD4	CHRGCNTL	R/W	OTGB	BATISO	CHRG	USBDETH EN	RDSTEN	WDTEN	TRICKLE	CHRENB	0xA1	Charger control
CHARGER	0xD5	CHRGCRNT	R/W	RSVD	С	HRGCOMP[2:	0]		CHRGCC[3:0]			0x00	Max charge current rate (CC)
CHARGER	0xD6	CHRGVOLT	R/W	RSVD	RSVD	VDSSE	SET[1:0] CHRGCV[3:0]				0x07	Max charge voltage (CV)	
CHARGER	0xD7	CHRGPROT	R/W	USBLMT [1:0]		OVRVOLT [1:0]		WDTSET [1:0]		RSVD	RSVD	0x3C	V, I, and temp protection
CHARGER	0xD8	CHRGPROT2	R/W		TOCP[2:0]			0x60	Battery Current Limit (during discharge)				
CHARGER	0xD9	PROTCMD	W	*	*	*	*	*	*	*	*	0x00	
CHARGER	0xDA	WDTCLR	W	*	*	*	*	*	*	*	*	0x03	
CHARGER	0xDB	CHRGTIMER	R/W	RSVD	RSVD	RSVD	RSVD		CHGTI	MER[3:0]	1	0x03	Charger Timer
RSVD	0xDC	DISCHRG	R/W	RSVD	RSVD	BATDETEN	RSVD	RSVD	TEMPEN	BATOVPE N	BATOCPEN	0x04	Reserved
RSVD	0xDD	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
RSVD	0xDE	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
RSVD	0xDF	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
GPIO	0xE0	GPIOCNTL0	R/W	GPIDBN	IC0[1:0]	INTCTI	_0[1:0]	DATAOUT0	DATAIN0	DIR0	DRV0	0x03	GPIO control
GPIO	0xE1	GPIOCNTL1	R/W	GPIDBN	IC0[1:0]	INTCTL0[1:0]		DATAOUT0	DATAIN0	DIR0	DRV0	0x03	GPIO control
GPIO	0xE2	GPIOCNTL2	R/W	GPIDBN	IC0[1:0]	INTCTL0[1:0]		DATAOUT0	DATAIN0	DIR0	DRV0	0x03	GPIO control
GPIO	0xE3	GPIOCNTL3	R/W	GPIDBN	IC0[1:0] INTCTL0[1:0		_0[1:0]	DATAOUT0	DATAIN0	DIR0	DRV0	0x03	GPIO control
GPIO	0xE4	GPIOCNTL4	R/W	GPIDBN	IC0[1:0]			DATAOUT0	DATAIN0	DIR0	DRV0	0x03	GPIO control
GPIO	0xE5	GPIOCNTL5	R/W	GPIDBN	IC0[1:0]	INTCTI	_0[1:0]	DATAOUT0	DATAIN0	DIR0	DRV0	0x03	GPIO control
GPIO	0xE6	GPIOCNTL6	R/W	GPIDBN	IC0[1:0]	INTCTI	_0[1:0]	DATAOUT0	DATAIN0	DIR0	DRV0	0x03	GPIO control
GPIO	0xE7	GPIOCNTL7	R/W	GPIDBN	IC0[1:0]	INTCTI	_0[1:0]	DATAOUT0	DATAIN0	DIR0	DRV0	0x03	GPIO control
GPIO	0xE8	GPIOINT	R	GPIINT7	GPIINT6	GPIINT5	GPIINT4	GPIINT3	GPIINT2	GPIINT1	GPIINT0	0x00	GPIO Interrupt
RSVD	0xE9	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
RSVD	0xEA	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
RSVD	0xEB	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
GPIO	0xEC	GPOSWCTL0	R/W	SCRATO		SLEW		SWDOUTO	RSVD	RSVD	SWDRV0		GPIO control
GPIO	0xED	GPOSWCTL1	R/W	SCRATO		SLEW		SWDOUT1	RSVD	RSVD	SWDRV1	0x20	GPIO control
GPIO	0xEE	GPOSWCTL2	R/W	SCRATC		SLEW		SWDOUT2	RSVD	RSVD	SWDRV2	0x20	GPIO control
GPIO	0xEF	GPOSWCTL3	R/W	SCRATC		SLEW		SWDOUT3	RSVD	RSVD	SWDRV3	0x20	GPIO control
GPIO	0xF0	GPOSWCTL4	R/W	SCRATC		SLEW		SWDOUT4	RSVD	RSVD	SWDRV4	0x00	GPIO control
GPIO	0xF1	GPOSWCTL5	R/W	SCRATC		SLEW		SWDOUT5	RSVD	RSVD	SWDRV5	0x00	GPIO control
RSVD	0xF2	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
RSVD	0xF3	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
GPIO	0xF4	GPO	R/W	GP07	GPO6	GPO5	GPO4	GPO3	GPO2	GPO1	GPO0	0x00	GPO control
RSVD	0xF5	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
RSVD	0xF6	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
RSVD	0xF7	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
RSVD	0xF7 0xF8	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
VD2	0xF8 0xF9 -	-	-	KOVD	ROVD	ROVD		D2	ROVD	ROVD	ROVD	0,000	Reserved by
V DZ	0xF9 - 0xFF	-	-				VI	52				-	Customer
FUNCTIONAL DEVICE OPERATION SPI REGISTER MAP

Table 116. SPI Register Map

Block	Address	Register Name	R/W	D7	D6	D5	D4	D3	D2	D1	D0	Initial	Function
VD3	0x100 - 0x132	-	-		L	1	VE)3	1	L	1	-	Reserved by Customer
RSVD	0x133 - 0x17F	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
FSL	0x180	AUD1	R/W	VCETSB	VCEMAST EN	VCEBCLIN V	VCEFSJS T	VCELONGF S	VC	VCEWORDLEN[2:0]		0x80	Voice Port PCM1
FSL	0x181	AUD2	R/W	VCETRNAR ND	VC	CECLKFRQ[2	0]	VCETXS	LOT[1:0]	VCE8K16K	VCERESET	0x00	Voice Port PCM1
FSL	0x182	AUD3	R/W	STRTSB	STRMAST EN	STRBCLIN V	RSVD	RSVD	ST	RWORDLEN	[2:0]	0x80	Audio Port PCM2
FSL	0x183	AUD4	R/W	STRSRDET	ST	RCLKFRQ[2:	0]		STRS	R[3:0]		0x00	Audio Port PCM2
FSL	0x184	AUD5	R/W	RSVD	RSVD	VCERXS	LOT[1:0]	VCEAUDH PF	VCECLKE N	VCEFSINV	VCEDLM	0x00	Misc Voice Control
FSL	0x185	AUD6	R/W	STRRESET	STRCLKEN	STRFSINV	RSVD	STRMONO	VCE2PCM 2	STRMODE SEL	RSVD	0x00	Misc Audio Control
FSL	0x186	AUD7	R/W	RSVD	MIC1BIAS MOD			DMICV	OL[5:0]			0x00	Digital MIC Contro
FSL	0x187	AUD8	R/W	AUDIOOFF	DMICMUT EFB			DMICVC	DLFB[5:0]			0x80	Digital MIC Contro
FSL	0x188	AUD9	R/W	DMICCLKEN	MIC1BIAS	DMICMUTE	MIC2BIAS	DMIC2EN	PCM1RCH	DMICO	CLK[1:0]	0x00	MIC Control
FSL	0x189	AUD10	R/W	LAMPSEL	LAMPMUT			LAMP	VL[5:0]			0x00	MIC / Line-In Control
FSL	0x18A	AUD11	R/W	RAMPSEL	RAMPMUT			RAMP	VL[5:0]			0x00	MIC / Line-In Control
FSL	0x18B	AUD12	R/W	PCM2LCH	PCM2RCH	MUXIN	HSDETEN	MIC1PI	RE[1:0]	E[1:0] MIC2PRE[1:0]			MIC / Line-In Control
FSL	0x18C	AUD13	R/W		VCECLK[2:0]			v	CEPGATX[4	:0]		0x00	Voice ADC Contro
FSL	0x18D	AUD14	R/W	RSVD		STRCLK[2:0] STRADC16 STRADC16PG[2:0] PGEN				0x00	Stereo ADC Contro		
FSL	0x18E	AUD15	R/W	VMUT	RSVD			VDAC	VL[5:0]			0x00	Voice DAC Contro
FSL	0x18F	AUD16	R/W	AMUTL	RSVD			ADACV	/LL[5:0]			0x00	Audio DAC Left Control
FSL	0x190	AUD17	R/W	AMUTR	RSVD			ADACV	/LR[5:0]			0x00	Audio DAC Right Control
FSL	0x191	AUD18	R/W	MXLLINL	RSVD	MXLMNDA C	MXLAUDL	RSVD	MUTHPL	MUTHPR	MUTASP	0x00	Left Mixer and Output Select
FSL	0x192	AUD19	R/W	RSVD	MXRLINR	MXRMNDA C	RSVD	MXRAUDR	MUTSPKR L	MUTSPKR R	RSVD	0x00	Right Mixer and Output Select
FSL	0x193	AUD20	R/W	RSVD	RSVD		•	RAMPV	LFB[5:0]	•	•	0x00	Analog loop back Right ch Control
FSL	0x194	AUD21	R/W	RSVD	RSVD			LAMPVI	LFB[5:0]			0x00	Analog loop back Left ch Control
FSL	0x195	AUD22	R/W	PSCNTSPL	PSCNTSP R	RSVD	PSCNTLO L	PSCNTLOR	PSCNTHP L	PSCNTHP R	PSCNTSPK R	0x00	Power Control
FSL	0x196	AUD23	R/W	SLOPES	SEL[1:0]	PSCNTRX	PSCNTDA	PSCNTMIC 1	PSCNTMI C2	STRADCE N	VCEADCEN	0x00	Power Control
FSL	0x197	AUD24	R	RSVD	RSVD	RSVD	RSVD	HSDET	HPDET	SWMPINT	SWLPINT	0x00	Headset Detect Interrupt
FSL	0x198	AUD25	R/W	RSVD	RSVD	RSVD	RSVD	MHSDET	MHPDET	MSWMPIN T	MSWLPINT	0x0F	Headset Detect Interrupt Mask
FSL	0x199	AUD26	R/W	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	TRI	MEN	0x00	Trim enable
FSL	0x19A	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
FSL	0x19B	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
FSL	0x19C	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
FSL	0x19D	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
FSL	0x19E	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
FSL	0x19F	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
			1	1	1	RSVD	1	1	1	1		1	

FUNCTIONAL DEVICE OPERATION SPI REGISTER MAP

Table 116. SPI Register Map

Block	Address	Register Name	R/W	D7	D6	D5	D4	D3	D2	D1	D0	Initial	Function
FSL	0x1A1	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
FSL	0x1A2	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
FSL	0x1A3	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
FSL	0x1A4	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
FSL	0x1A5	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
FSL	0x1A6	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
FSL	0x1A7	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
FSL	0x1A8	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
FSL	0x1A9	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
FSL	0x1AA	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
FSL	0x1AB	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
FSL	0x1AC	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
FSL	0x1AD	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
FSL	0x1AE	FSLMEM1	R/W				SCRAT	CH[7:0]				0x00	Backup memory
FSL	0x1AF	FSLMEM2	R/W				SCRAT	CH[7:0]				0x00	Backup memory
FSL	0x1B0	FSLMEM3	R/W				SCRAT	CH[7:0]				0x00	Backup memory
FSL	0x1B1	FSLMEM4	R/W				SCRAT	CH[7:0]				0x00	Backup memory
FSL	0x1B2	FSLMEM5	R/W				SCRAT	CH[7:0]				0x00	Backup memory
FSL	0x1B3	FSLMEM6	R/W				SCRAT	CH[7:0]				0x00	Backup memory
FSL	0x1B4	FSLMEM7	R/W				SCRAT	CH[7:0]				0x00	Backup memory
FSL	0x1B5	FSLMEM8	R/W		SCRATCH[7:0]					0x00	Backup memory		
FSL	0x1B6	FSLMEM9	R/W				SCRAT	CH[7:0]				0x00	Backup memory
FSL	0x1B7	FSLMEM10	R/W		SCRATCH[7:0]						0x00	Backup memory	
FSL	0x1B8	FSLMEM11	R/W				SCRAT	CH[7:0]				0x00	Backup memory
FSL	0x1B9	FSLMEM12	R/W				SCRAT	CH[7:0]				0x00	Backup memory
FSL	0x1BA	FSLMEM13	R/W				SCRAT	CH[7:0]				0x00	Backup memory
FSL	0x1BB	FSLMEM14	R/W				SCRAT	CH[7:0]				0x00	Backup memory
FSL	0x1BC	FSLMEM15	R/W				SCRAT	CH[7:0]				0x00	Backup memory
FSL	0x1BD	FSLMEM16	R/W				SCRAT	CH[7:0]				0x00	Backup memory
FSL	0x1BE	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
FSL	0x1BF	FSLOUTDRVCN TL1	R/W	RESETBI	DRV[1:0]	PMICINTI	DRV[1:0]	VRCOMPE	3DRV[1:0]	PWRGD	DRV[1:0]	0x00	Digital Outputs Drive Strength
FSL	0x1C0	FSLOUTDRVCN TL2	R/W	V33END	RV[1:0]	V3GPAEN	DRV[1:0]	CLK26MI	DRV[1:0]	CLK32K	DRV[1:0]	0x04	Digital Outputs Drive Strength
FSL	0x1C1	FSLOUTDRVCN TL3	R/W	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	SPISE	DODRV	0x01	Digital Outputs Drive Strength
FSL	0x1C2	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
FSL	0x1C3	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
FSL	0x1C4	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
FSL	0x1C5	FSLVOTGCNTL1	R/W	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	VOTGDISD SCH	0x01	VOTG Discharge Enable Control
FSL	0x1C6	FSLVOTGCNTL2	R/W	RSVD	RSVD	AO	ACTLVOTG	2:0]		CTLVOTG[2:0	0]	0x24	VOTG Control
FSL	0x1C7	FSLVYMXPACN TL	R/W	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	VYMXPADI SDSCH	0x01	VYMXPA Discharge Enable Control
FSL	0x1C8	FSLTONTCNTL1	R/W	VYMX3GTO NT	RSVD	VDDQTON T	RSVD	VNNTONT	RSVD	VCCTONT	RSVD	0xAA	Buck Turn On time control (DVS Clk)
FSL	0x1C9	FSLVCCLATCH	R	RSVD				VIDVCC[6:0]				0x7F	VCC VID CONTROL
FSL	0x1CA	FSLVNNLATCH	R	RSVD				VIDVNN[6:0]				0x7F	VNN VID CONTROL

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FUNCTIONAL DEVICE OPERATION SPI REGISTER MAP

Table 116. SPI Register Map

FSL (FSL (FSL (FSL (0x1CB 0x1CC 0x1CD 0x1CD 0x1CE 0x1CF	FSLTONTCNTL2 FSLFAULT1 FSLFAULT2	R/W R	RSVD	RSVD	RSVD	RSVD	VACTONIT	RSVD	V21TONT	RSVD	0xAA	Durk Tr. O. II
FSL (FSL (FSL (0x1CD 0x1CE		R			-	RSVD	V15TONT	ROVD	V2110IN1	ROVD	0,,,,,,	Buck Turn On time control (DVS Clk)
FSL (0x1CE	FSLFAULT2		V3GPAFAUL T	VYMX3GF AULT	V33FAULT	V15FAULT	V21FAULT	VDDQFAU LT	VNNFAUL T	VCCFAULT	0x00	Regulator Fault Flag
FSL (R	VPMICFAUL T	VPNL18FA ULT	VCC180FA ULT	VCCAFAU LT	VBGFAULT	VBKLTFA ULT	VOTGFAU LT	VYMXPAFA ULT	0x00	Regulator Fault Flag
	0x1CF	FSLFAULT3	R	VCCPFAULT	VMMFAUL T	VAONFAUL T	VCCPDDR FAULT	VCCPAOA CFAULT	VYMCGPS FAULT	VYMXYFIF AULT	VYMXYFI18 FAULT	0x00	Regulator Fault Flag
		FSLFAULT4	R	RSVD	RSVD	RSVD	RSVD	VSDIOFAU LT	VVIBFAUL T	VIMG28FA ULT	VIMG25FA ULT	0x00	Regulator Fault Flag
FSL	0x1D0	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
FSL	0x1D1	FSLCHRGCNTL	R/W	RSVD	BUCKDIS	ITRKL		VCOIN[4:2]		COINCHE N	CHGBYP	0x13	Charger Control
FSL	0x1D2	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
FSL	0x1D3	FSLVBKLTCNTL	R/W	TWOPTWO EN	BKLTFREQ 2[2:0]	BKLTFREQ 2[2:0]	BKLTFRE Q2[2:0]	MLED4EN	BKLTLED[2:0]	BKLTIMAX	BKLTIMAX	0x07	Backlight LED Control
FSL	0x1D4	FSL4STRING	R/W	BKLTBRT2[7 :0]	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Secondary Backlight Duty Cycle
FSL	0x1D5	FSLVBKLTADAP T	R/W	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	S4ADAPT	0x00	Adaptive Boost Control
FSL	0x1D6	FSLLEDR1CNTL	R/W			LEDR1D	C[5:0]			LEDR	1BLNK	0xFC	Duty Cycle Control for LEDR1
FSL	0x1D7	FSLLEDG1CNTL	R/W		LEDG1DC[5:0] LEDG1BLNK						0xFC	Duty Cycle Control for LEDG1	
FSL	0x1D8	FSLLEDB1CNTL	R/W		LEDB1DC[5:0] LEDB1BLNK						0xFC	Duty Cycle Control for LEDB1	
FSL	0x1D9	FSLLEDR2CNTL	R/W			LEDR2D	C[5:0]			LEDR	2BLNK	0xFC	Duty Cycle Control for LEDR2
FSL	0x1DA	FSLLEDG2CNTL	R/W			LEDG2D	C[5:0]			LEDG	2BLNK	0xFC	Duty Cycle Control for LEDG2
FSL (0x1DB	FSLLEDB2CNTL	R/W			LEDB2D	C[5:0]			LEDB	2BLNK	0xFC	Duty Cycle Control for LEDB2
FSL (0x1DC	FSLLEDRAMPC NTL	R/W	RSVD	RSVD	LEDB2RAM P	LEDG2RA MP	LEDR2RAM P	LEDB1RA MP	LEDG1RA MP	LEDR1RAM P	0x00	Ramp Control for RGB LEDs
FSL (0x1DD	-	-	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	RSVD	0x00	Reserved
FSL	0x1DE	FSLADCCNTL	R/W	RSVD	TSPAS	ADCCAL	LSBSEL	BATDETVC ON	LICON	CHRGICO N	VPWRCON	0x00	ADC Spare Channel Control
FSL	0x1DF	CCCREG	R/W	CCFAULT	RSVD	RSVD	CCCALA	CCCALDB	CCDITHE R	RSTCC	STARTCC	0x00	Coulomb Counter control & status
FSL	0x1E0	ONECLREG	R/W				ONEC	C[7:0]				0x1A	Coulomb Counter "oneC" value
FSL	0x1E1	ONECHREG	R/W	RSVD				ONEC[14:8]				0x00	Coulomb Counter "oneC" value
FSL	0x1E2	RAWCCH	-		RAWCC[15:8]						0x00	Unmodified Coulomb Counter output	
FSL	0x1E3	RAWCCL	-		RAWCC[7:0]						0x00	Unmodified Coulomb Counter output	
FSL	0x1E4	FSLPLLCNTL	R/W	RSVD	RSVD RSVD RSVD PLLEN PLL16MEN PLLDIVIDE[2:0]					0x1B	Reserved		
	0x1E5 - 0x1FA	-	-	RSVD	RSVD RSVD RSVD RSVD RSVD RSVD RSVD RSVD						0x00	Reserved	
FSL	0x1FB	BUCK_TOP_LVS H_5	R/W	BUCK_V15_ BUCK_V15_PWRSTG_EN<6:0>						0x7F	Switching Regulator Debug		
FSL	0x1FC	BUCK_TOP_LVS H_4	R/W	BUCK_V21_ EN							0x7F	Switching Regulator Debug	
FSL	0x1FD	BUCK_TOP_LVS H_3	R/W	BUCK_VYM X3G_EN								0x7F	Switching Regulator Debug
FSL	0x1FE	BUCK_TOP_LVS H_2	R/W	BUCK_VDD Q_EN			BUCK_V	DQ_PWRST	G_EN[6:0]			0x7F	Switching Regulator Debug

FUNCTIONAL DEVICE OPERATION HARDWARE DESIGN CONSIDERATIONS

Table 116. SPI Register Map

Block	Address	Register Name	R/W	D7	D6	D5	D4	D3	D2	D1	D0	Initial	Function
RSVD	0x1FF	-	-	RSVD	0x00	Reserved							
VD2	0x200 - 0x227	-	-				VE)2				-	Reserved by Customer
RSVD	0x228 - 0x2FF	-	-	RSVD	0x00	Reserved							

HARDWARE DESIGN CONSIDERATIONS

EXTERNAL COMPONENT REQUIREMENT

Table 117. External Components BOM

Component	Value	Package	Description	Qty	Part #	Manufacturer
	<u>. </u>		PMIC Chipset		1	
900841	-	MAPBGA	Main PMIC	1	-	Freescale
900842	-	WLCSP	Buck-Boost Regulator (3.3 V rail)	1	-	Freescale
	l.		VCC - (0.65 - 1.2 V) / 3.5 A VID CPU BUCK with External F	ETs		
Cincc	10 μF	0603	Ceramic Capacitor, 6.3 V, X5R	1	GRM188R60J106ME47D	Murata
Cocc	22 μF	0603	Ceramic Capacitor, 4.0 V, X5R	4	AMK107BJ226MA-T	Taiyo Yuden
Lcc	0.68 μH	4x4x2	Saturation current = 4.8 A for 10% drop, DCR_max = 25.3 mohm	1	XPL4020	Coilcraft
Mhscc	46 mohm	BGA	High Side P-FET	1	FDZ293P	Fairchild
MIscc	23 mohm	BGA	Low Side N-FET	1	FDZ294N	Fairchild
			VNN - (0.65 - 1.2 V) / 1.6 A VID CPU BUCK with External F	ETs		
Cinnn	10 μF	0603	Ceramic Capacitor, 6.3 V, X5R	1	GRM188R60J106ME47D	Murata
Conn	22 μF	0603	Ceramic Capacitor, 4.0 V, X5R	2	AMK107BJ226MA-T	Taiyo Yuden
Lnn	1.0 μH	3.3x3.3x1.4	Saturation current = 2.3 A for 10% drop, DCR_max = 55 mohm	1	LPS3314-102ML	Coilcraft
Mnn	95 mohm 68 mohm	MicroFET	High Side P-FET and Low Side N-FET housed in one package	1	FDMA1032CZ	Fairchild
			VDDQ - 1.8 V / 1.3 A BUCK			
Cinddq	10 μF	0603	Ceramic Capacitor, 6.3 V, X5R	1	GRM188R60J106ME47D	Murata
Coddq	22 μF	0603	Ceramic Capacitor, 4.0 V, X5R	2	AMK107BJ226MA-T	Taiyo Yuden
Lddq	0.50 μH	2.0x2.0x1.0	Saturation current = 1.8 A for 10% drop, DCR_max = 45 mohm	1	XPL2010-501ML	Coilcraft
			V21 - 2.1 V / 1.0 A BUCK			
Cin21	10 μF	0603	Ceramic Capacitor, 6.3 V, X5R	1	GRM188R60J106ME47D	Murata
Co21	22 μF	0603	Ceramic Capacitor, 4.0 V, X5R	1	AMK107BJ226MA-T	Taiyo Yuden
L21	0.50 μH	2.0x2.0x1.0	Saturation current = 1.8 A for 10% drop, DCR_max = 45 mohm	1	XPL2010-501ML	Coilcraft
			V15 - 1.5 V(or 1.6 V) / 1.5 A BUCK			
Cin15	10 μF	0603	Ceramic Capacitor, 6.3 V, X5R	1	GRM188R60J106ME47D	Murata
Co15	22 μF	0603	Ceramic Capacitor, 4.0 V, X5R	2	AMK107BJ226MA-T	Taiyo Yuden
L15	0.50 μH	2.0x2.0x1.0	Saturation current = 1.8 A for 10% drop, DCR_max = 45 mohm	1	XPL2010-501ML	Coilcraft
			VYMX3G - (YMX: 1.25 V or 3G: 0.6 - 1.375 V) / 1.0 A BUC	к		
Cinymx3g	10 μF	0603	Ceramic Capacitor, 6.3 V, X5R	1	GRM188R60J106ME47D	Murata
Coymx3g	22 μF	0603	Ceramic Capacitor, 4.0 V, X5R	1	AMK107BJ226MA-T	Taiyo Yuden
Lymx3g	0.50 μH	2.0x2.0x1.0	Saturation current = 1.8 A for 10% drop, DCR_max = 45 mohm	1	XPL2010-501ML	Coilcraft
			VYMXPA - 4.2 V / 0.7 A Non-Sync Boost			
Cinymxpa	10 μF	0603	Ceramic Capacitor, 6.3 V, X5R	1	GRM188R60J106ME47D	Murata

FUNCTIONAL DEVICE OPERATION HARDWARE DESIGN CONSIDERATIONS

Component	Value	Package	Description	Qty	Part #	Manufacturer
Coymxpa	22 μF	0805	Ceramic Capacitor, 10 V, X5R	1	LMK212BJ226MG-T	Taiyo Yuden
Lymxpa	2.2 μH	3x3x1.5	Saturation current = 2.1 A for 20% drop, DCR_max = 110 mohm	1	LPS3015-222M	Coilcraft
Dymxpa	-	MICROSMP	SCHOTTKY 1.0 A 20 V	1	MSS1P2L-E3/89A	Vishay
Мутхра	46 mohm	BGA	P-FET Switch	0	FDZ293P	Fairchild
			VOTG - 5.0 V / 0.35 A Non-Sync Boost			
Cinotg	10 μF	0603	Ceramic Capacitor, 6.3 V, X5R	1	GRM188R60J106ME47D	Murata
Cootg	47 μF	0805	Ceramic Capacitor, 6.3 V, X5R	1	JMK212BJ476MG-T	Taiyo Yuden
Lotg	2.2 μH	3x3x1.0	Saturation current = 1.4 A for 20% drop, DCR_max = 220 mohm	1	LPS3010-222M	Coilcraft
Dotg	-	FLIPKY	SCHOTTKY 30 V 0.5 A	1	IR0530CSPTR	Vishay
Motg	85 mohm	WLCSP	P-FET Switch	1	FDZ191P	Fairchild
		VBK	(LT - 5s3p (Backlight) and 5s1p (Camera Scene) / 120 mA Non	-sync	Boost	
Cinbklt	10 μF	0603	Ceramic Capacitor, 6.3 V, X5R	1	GRM188R60J106ME47D	Murata
Cobklt	10 μF	1206	Ceramic Capacitor, 25 V, X5R	1	GRM31CR61E106KA12L	Murata
Lbklt	2.2 μH	3x3x1.5	Saturation current = 2.1 A for 20% drop, DCR_max = 110 mohm	1	LPS3015-222M	Coilcraft
Dbklt	-	FLIPKY	SCHOTTKY 30 V 0.5 A	1	IR0530CSPTR	Vishay
			V33 - 3.3 V / 1.4 A Buck-Boost - Standalone Chip			
Cin33	10 μF	0603	Ceramic Capacitor, 6.3 V, X5R	1	GRM188R60J106ME47D	Murata
Co33	22 μF	0805	Ceramic Capacitor, 10 V, X5R	2	LMK212BJ226MG-T	Taiyo Yuden
L33	1.0 μH	3.3x3.3x1.4	Saturation current = 2.3 A for 10% drop, DCR_max = 55 mohm	1	LPS3314-102ML	Coilcraft
Ccore33	1.0 μF	0402	Ceramic Capacitor, 6.3 V, X5R	1	GRM155R60J105ME19D	Murata
Cbgbyp33	100 nF	0201	Ceramic Capacitor, 6.3 V, X5R	1	GRM033R60J104KE19D	Murata
			VBG - 1.25 V/2.0 mA LDO & VCCA - 1.5 V/150 mA LDC)	•	
Cin1p8	100 nF	0201	Ceramic Capacitor, 6.3 V, X5R	1	GRM033R60J104KE19D	Murata
Cobg	1.0 μF	0402	Ceramic Capacitor, 6.3 V, X5R	1	GRM155R60J105ME19D	Murata
Cocca	2.2 μF	0402	Ceramic Capacitor, 6.3 V, X5R	1	GRM155R60J225ME15D	Murata
		VCC	180- 1.8 V/390 mA LDO & VPNL18- 1.8 V/225 mA LDO & - 1.8 \	//50 m	A LDO	
Cin2p1	0.47 μF	0402	Ceramic Capacitor, 6.3 V, X5R	1	GRM155R60J474KE19D	Murata
Cocc180	2.2 μF	0402	Ceramic Capacitor, 6.3 V, X5R	1	GRM155R60J225ME15D	Murata
Copnl18	2.2 μF	0402	Ceramic Capacitor, 6.3 V, X5R	1	GRM155R60J225ME15D	Murata
Copmic	2.2 μF	0402	Ceramic Capacitor, 6.3 V, X5R	1	GRM155R60J225ME15D	Murata
	I		VYMXYFI18 - (YMX:1.8 V/200 mA - YFI:1.8 V/200 mA) LE	ю	· · · · · · · · · · · · · · · · · · ·	
Cinymxyfi18	100 nF	0201	Ceramic Capacitor, 6.3 V, X5R	1	GRM033R60J104KE19D	Murata
Coymxyfi18	2.2 μF	0402	Ceramic Capacitor, 6.3 V, X5R	1	GRM155R60J225ME15D	Murata
			VYMXYFI - (YMX:2.5 V/150 mA - YFI:1.2 V/60 mA) LDC)		
Cinymxyfi	100 nF	0201	Ceramic Capacitor, 6.3 V, X5R	1	GRM033R60J104KE19D	Murata
Coymxyfi	2.2 μF	0402	Ceramic Capacitor, 6.3 V, X5R	1	GRM155R60J225ME15D	Murata
			VYMXGPS - (YMX:1.3 V/350 mA - GPS:1.8 V/170 mA) LE	ю		
Cinymxgps	100 nF	0201	Ceramic Capacitor, 6.3 V, X5R	1	GRM033R60J104KE19D	Murata
Coymxgps	2.2 μF	0402	Ceramic Capacitor, 6.3 V, X5R	1	GRM155R60J225ME15D	Murata
VCCPAOAC- 1	l.05 V/155 mA	LDO & VCCI	PDDR - 1.05 V/60 mA LDO & VAON - 1.2 V/250 mA LDO &VMM	- 1.2 V	/5.0 mA LDO & VCCP - 1.0	5 V/445 mA LDO
Cin1p5	0.47 μF	0402	Ceramic Capacitor, 6.3 V, X5R	1	GRM155R60J474KE19D	Murata
Coccpaoac	2.2 μF	0402	Ceramic Capacitor, 6.3 V, X5R	1	GRM155R60J225ME15D	Murata
Coccpddr	1.0 μF	0402	Ceramic Capacitor, 6.3 V, X5R	1	GRM155R60J105ME19D	Murata
Coaon	2.2 μF	0402	Ceramic Capacitor, 6.3 V, X5R	1	GRM155R60J225ME15D	Murata

Table 117. External Components BOM

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FUNCTIONAL DEVICE OPERATION HARDWARE DESIGN CONSIDERATIONS

Table 117. External Components BOM

Component	Value	Package	Description	Qty	Part #	Manufacturer
Comm	1.0 μF	0402	Ceramic Capacitor, 6.3 V, X5R	1	GRM155R60J105ME19D	Murata
Сосср	2.2 μF	0402	Ceramic Capacitor, 6.3 V, X5R	1	GRM155R60J225ME15D	Murata
			VIMG25- 2.5 V/80 mA LDO & VIMG28- 2.8 V/225 mA LD	0		
Cinimg	100 nF	0201	Ceramic Capacitor, 6.3 V, X5R	1	GRM033R60J104KE19D	Murata
Coimg25	2.2 μF	0402	Ceramic Capacitor, 6.3 V, X5R	1	GRM155R60J225ME15D	Murata
Coimg28	2.2 μF	0402	Ceramic Capacitor, 6.3 V, X5R	1	GRM155R60J225ME15D	Murata
	I	1 1	VVIB - xV/200 mA LDO	1		
Cinvib	100 nF	0201	Ceramic Capacitor, 6.3 V, X5R	1	GRM033R60J104KE19D	Murata
Covib	2.2 μF	0402	Ceramic Capacitor, 6.3 V, X5R	1	GRM155R60J225ME15D	Murata
	Ň	/PNL33 - 3.3 V	//100 mA Switch & VGP33 - 3.3 V/60 mA Switch & VYMXGPS3	3 - 3.3	V/60 mA Switch	
CopnI33	100 nF	0201	Ceramic Capacitor, 6.3 V, X5R	1	GRM033R60J104KE19D	Murata
Cogp33	100 nF	0201	Ceramic Capacitor, 6.3 V, X5R	1	GRM033R60J104KE19D	Murata
Coymxgps33	100 nF	0201	Ceramic Capacitor, 6.3 V, X5R	1	GRM033R60J104KE19D	Murata
		11	VSDIO - 3.3 V/215 mA Switch OR 1.8 V/215 mA LDO	1		
Cinsdio	100 nF	0201	Ceramic Capacitor, 6.3 V, X5R	1	GRM033R60J104KE19D	Murata
Cosdio	4.7 μF	0402	Ceramic Capacitor, 6.3 V, X5R	1	ECJ-0EB0J475M	Panasonic
Rsdio	470 mohm	0402	Chip Resistor, 1%	1	ERJ-2BQFR47X	Panasonic
Msdio	95 mohm	SC70	PFET, switch	1	FDG332PZ	Fairchild
		11	Internal Supplies	1		
Ccore	2.2 μF	0402	Ceramic Capacitor, 6.3 V, X5R	1	GRM155R60J225ME15D	Murata
Ccoredig	2.2 μF	0402	Ceramic Capacitor, 6.3 V, X5R	1	GRM155R60J225ME15D	Murata
Ccoreref	100 nF	0201	Ceramic Capacitor, 6.3 V, X5R	1	GRM033R60J104KE19D	Murata
		11	Audio	1		
Rmcbiasr	2.2 kohm	0201	Chip Resistor, 5% - Handset Microphone	1	ERJ-1GEJ222C	Panasonic
Cmc1r	220 nF	0201	Ceramic Capacitor, 6.3 V, X5R - Handset Microphone	1	GRM033R60G224ME15D	Murata
Rmcbiasl	2.2 kohm	0201	Chip Resistor, 5% - Handset Microphone 2, Optional	0	ERJ-1GEJ222C	Panasonic
Cmc1I	220 nF	0201	Ceramic Capacitor, 6.3 V, X5R - Handset Microphone 2, Optional	0	JMK063BJ224MP-F	Taiyo Yuden
Rmcbias2	2.2 kohm	0201	Chip Resistor, 5% - Headset Microphone	1	ERJ-1GEJ222C	Panasonic
Cmc2	220 nF	0201	Ceramic Capacitor, 6.3 V, X5R - Headset Microphone	1	JMK063BJ224MP-F	Taiyo Yuden
Crxinl	220 nF	0201	Ceramic Capacitor, 6.3 V, X5R	1	JMK063BJ224MP-F	Taiyo Yuden
Crxinr	220 nF	0201	Ceramic Capacitor, 6.3 V, X5R	1	JMK063BJ224MP-F	Taiyo Yuden
Crxoutl	100 nF	0201	Ceramic Capacitor, 6.3 V, X5R	1	GRM033R60J104KE19D	Murata
Crxoutr	100 nF	0201	Ceramic Capacitor, 6.3 V, X5R	1	GRM033R60J104KE19D	Murata
Ccpin	1.0 F	0402	Ceramic Capacitor, 6.3 V, X5R - Charge Pump Input Cap	1	GRM155R60J105ME19D	Murata
Ccpout	2.2 μF	0402	Ceramic Capacitor, 6.3 V, X5R	1	GRM155R60J225ME15D	Murata
Сср	1.0 μF	0402	Ceramic Capacitor, 6.3 V, X5R - Charge Pump Flying Cap	1	GRM155R60J105ME19D	Murata
Crefa	100 nF	0201	Ceramic Capacitor, 6.3 V, X5R - Reference A	1	GRM033R60J104KE19D	Murata
Crefb	100 nF	0201	Ceramic Capacitor, 6.3 V, X5R - Reference B	1	GRM033R60J104KE19D	Murata
Crefd	1.0 μF	0402	Ceramic Capacitor, 6.3 V, X5R - Reference D	1	GRM155R60J105ME19D	Murata
XTALAUDIO	26 MHz	2x1.6x0.45	26.000 MHz Crystal	1	NX2016AB-26MHZ SB1	NDK
Cxtalaudio1	15 pF	0201	Ceramic Capacitor, 25 V, C0G	1	GRM0335C1E150JD01D	Murata
Cxtalaudio2	15 pF	0201	Ceramic Capacitor, 25 V, C0G	1	GRM0335C1E150JD01D	Murata

FUNCTIONAL DEVICE OPERATION HARDWARE DESIGN CONSIDERATIONS

Component	Value	Package	Description	Qty	Part #	Manufacturer
			Switching Charger			
Crawchg	1.0 μF	0603	Ceramic Capacitor, 35 V, X5R	1	GMK107BJ105KA-T	Taiyo Yuden
Movpchg	46 mohm	BGA	P-FET Switch, 20 V - Better area and efficiency	1	FDZ293P	Fairchild
Mrevpchg	46 mohm	BGA	P-FET Switch, 20 V - Better area and efficiency	1	FDZ293P	Fairchild
Rinsnschg	100 mohm	0805	Chip Resistor, 1%, 0.333 W	1	RP2012T-R10-F	Susumu
Cinchg	10 μF	0805	Ceramic Capacitor, 16 V, X5R	1	GRM21BR61C106KE15L	Murata
Mswchg	95 mohm 68 mohm	MicroFET	High Side P-FET and Low Side N-FET housed in one package	1	FDMA1032CZ	Fairchild
Lchg	1.0 μH	3.3x3.3x1.4	Saturation current = 2.3 A for 10% drop, DCR_max = 55 mohm	1	LPS3314-102ML	Coilcraft
Cochg	22 μF	0805	Ceramic Capacitor, 10 V, X5R	2	LMK212BJ226MG-T	Taiyo Yuden
Mchg	85 mohm	WLCSP	Pass FET for Linear Charger and Switch for application supply	1	FDZ191P	Fairchild
Mchgbyp	30 mohm	MicroFET	Bypass Switch to reduce drop from V_{BAT} to V_{PWR} - Optional	1	FDMA510PZ	Fairchild
Rsnsbat	100 mohm	1206	Chip Resistor, 1%, 0.5 W	1	ERJ-8BWFR100V	Panasonic
Rcc	20 mohm	0805	Chip Resistor, 1%, 0.25 W - Increased in power for 5.0 A operation	1	ERJ-6BWFR020V	Panasonic
Ccc	100 nF	0201	Ceramic Capacitor, 6.3 V, X5R	1	GRM033R60J104KE19D	Murata
Rntc	10 kohm	0201	Chip Resistor, 1%	1	ERJ-1GEF1002C	Panasonic
			Coin cell			
Ccoin	100 nF	0201	Ceramic Capacitor, 6.3 V, X5R	1	GRM033R60J104KE19D	Murata
			ADC			
Cadref	1.0 μF	0402	Ceramic Capacitor, 6.3 V, X5R	1	GRM155R60J105ME19D	Murata
			Oscillator and Real Time Clock - RTC			
XTALRTC	32.768 kHz	3.2x1.5x0.9	CRYSTAL 32.768 kHZ 12.5 pF SMD	1	ABS07-32.768KHZ-T	Abracon
Cxtalrtc1	22 pF	0201	Ceramic Capacitor, 25 V, C0G	1	GRM0335C1E220JD01D	Murata
Cxtalrtc2	22 pF	0201	Ceramic Capacitor, 25 V, C0G	1	GRM0335C1E220JD01D	Murata
			NotesGPIOs & GPOSWs & GPOs & Power Butto	n		
Rpullupx	100 kohm	0201	Chip Resistor, 1% - Pull-up Resistors for OD configured GPIOs	0	ERJ-1GEF1003C	Panasonic
			ESD/EMI Components			
-	33 pF	0201	Ceramic Capacitor, 25 V, C0G - Handset Microphone Bias	1	GRM0335C1E330JD01D	Murata
-	33 pF	0201	Ceramic Capacitor, 25 V, C0G - Handset Microphone 1	1	GRM0335C1E330JD01D	Murata
-	33 pF	0201	Ceramic Capacitor, 25 V, C0G - Handset Microphone 2, Optional	0	GRM0335C1E330JD01D	Murata
-	33 pF	0201	Ceramic Capacitor, 25 V, C0G - Headset Microphone Bias	1	GRM0335C1E330JD01D	Murata
-	33 pF	0201	Ceramic Capacitor, 25 V, C0G - Handset Ear piece	1	GRM0335C1E330JD01D	Murata
-	33 pF	0201	Ceramic Capacitor, 25 V, C0G - Handset Ear piece	1	GRM0335C1E330JD01D	Murata
-	33 pF	0201	Ceramic Capacitor, 25 V, C0G - Handset Loudspeaker	1	GRM0335C1E330JD01D	Murata
-	33 pF	0201	Ceramic Capacitor, 25 V, C0G - Handset Loudspeaker	1	GRM0335C1E330JD01D	Murata
-	-	-	Headset Microphone and Headphones	1	EMI ESD	On Semi
-	-	-	Handset Loudspeaker	1	EMI ESD	On Semi

Table 117. External Components BOM

Freescale does not assume liability, endorse, or warrant components from external manufacturers that are referenced in circuit drawings or tables. While Freescale offers component recommendations in this configuration, it is the customer's responsibility to validate their application.

PACKAGING

PACKAGE DIMENSIONS

For the most current package revision, visit <u>www.freescale.com</u> and perform a keyword search using the "98A" listed below.



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TITLE: PBGA, THIN PROFIL	_E,	DOCUMENT NO	98ASA10841D	REV: O
FINE PITCH, 338 I/		CASE NUMBER	: 2037–01	11 JUN 2008
11 X 11 PKG, INTERSTITIAL PI	ITCH (MAP)	STANDARD: NO	N-JEDEC	

VK SUFFIX 338-PIN 98ASA10841D REVISION 0 NOTES:

1. ALL DIMENSIONS IN MILLIMETERS.

2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.

/3. MAXIMUM SOLDER BALL DIAMETER MEASURED PARALLEL TO DATUM A.

4. DATUM A, THE SEATING PLANE, IS DETERMINED BY THE SPHERICAL CROWNS OF THE SOLDER BALLS.



 $\ensuremath{\mathsf{PARALLELISM}}$ MEASUREMENT SHALL EXCLUDE ANY EFFECT OF MARK ON TOP SURFACE OF PACKAGE.

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TITLE: PBGA, THIN PROFIL	_E,	DOCUMENT NO: 98ASA10841D REV: (
FINE PITCH, 338 I,	•	CASE NUMBER	2: 2037–01	06 JUN 2008		
11 X 11 PKG, INTERSTITIAL P	ITCH (MAP)	STANDARD: NO	DN-JEDEC			

VK SUFFIX 338-PIN 98ASA10841D REVISION 0

PACKAGE MECHANICAL OUTLINE DRAWING

The package style is an 11x11 fine interstitial pitch, thin profile PBGA. The package has a semi populated matrix that includes 338 balls. The ball count includes 322 assigned signal pins and four sets of 4 corner balls.

PACKAGE ASSEMBLY RECOMENDATIONS

For improved protection against mechanical shock,

Freescale recommends applying corner glue to the mounted SC900841 BGA package. This corner glue application is described in the AN3954 - "PCB Layout Guidelines for SC900841 and SCCSP900842 application note.

Freescale's preferred material for the corner glue application is the Loctite 3128 board level adhesive applied at a 0° or 45° dispense angle in a continuous motion and with the fillet length extended to a minimum of 3 ball rows and columns at each corner.

REVISION HISTORY

REVISION HISTORY

REVISION	DATE	DESCRIPTION OF CHANGES
2.0	2/2011	Initial release

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